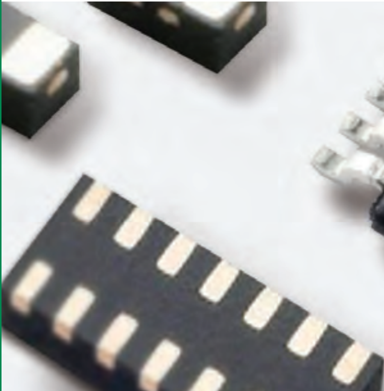
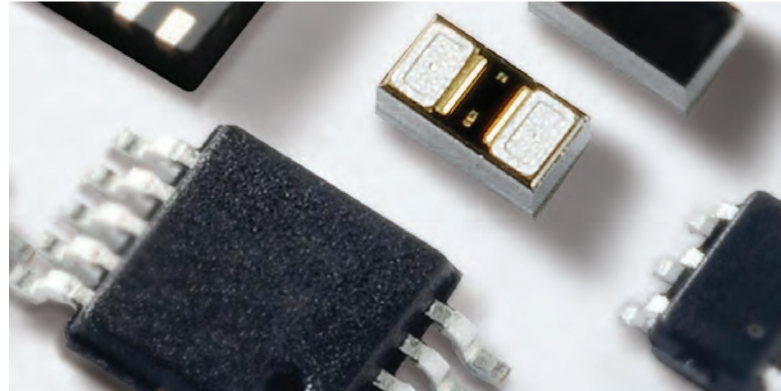


PRODUCT CATALOG & DESIGN GUIDE



# TVS DIODE ARRAY

## Transient Voltage Suppression SPA® Diode

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Port Protection Examples
Definitions and Terms
Transient Voltage Threats and Scenarios
ESD Suppression Strategies and Standards
Legal Disclaimers

| Series Name | Package Type | Working Voltage | Capacitance | Number of Channels | ESD Rating (Contact Discharge, IEC61000-4-2) | Clamping Voltage ($t_P$=8/20µs) | Maximum Surge Rating ($t_P$=8/20µs) | Lead Free/ Green | RoHS Compliant |
|---|---|---|---|---|---|---|---|---|---|
| **General Purpose ESD Protection (SCR Diode Array)** | | | | | | | | | |
| **SP720** | PDIP SOIC | 2-30V | 3pF | 14 | 4kV | 2V @ 1A | 3A | • | • |
| **SP721** | PDIP SOIC | 2-30V | 3pF | 6 | 4kV | 2V @ 1A | 3A | • | • |
| **SP723** | PDIP SOIC | 2-30V | 5pF | 6 | 8kV | 2V @ 2A | 7A | • | • |
| **SP724** | SOT23 | 2-20V | 3pF | 4 | 8kV | 2V @ 1A | 3A | • | • |
| **SP725** | SOIC | 2-30V | 5pF | 4 | 8kV | 2V @ 2A | 9A | • | • |
| **General Purpose ESD Protection (TVS Discretes and Arrays)** | | | | | | | | | |
| **SP05** | SC70, SOT23, SOT143, MSOP | 5.5V | 30pF | 2 / 3 / 4 / 5 / 6 | 30kV | | | • | • |
| **SP1001** | SC70, SOT553, SOT563, SOT963 | 5.5V | 8pF | 2 / 4 / 5 | 15kV | 8.0V @ 1A | 2A | • | • |
| **SP1002** | SC70 | 6.0V | 5pF | 1 / 2 | 8kV | 9.2V @ 1A | 2A | • | • |
| **SP1003** | SOD723, SOD882 | 5.0V | 30pF | 1 | 30kV | 12.0V @ 7A | 7A | • | • |
| **SP1004** | SOT953 | 6.0V | 5pF | 4 | 8kV | 10V @ 1A | 1A | • | • |
| **SP1005** | 0201 (Flipchip) 0402 (SOD882) | 6.0V | 30pF | 1 | 30kV | 9.3V @ 1A | 10A | • | • |
| **SP1006** | 0201 (µDFN-2) | 6.0V | 25pF | 1 | 30kV | 8.3V @ 1A | 5A | • | • |
| **SP1007** | 0201 (Flipchip) 0402 (SOD882) | 6.0V | 3.5pF | 1 | 8kV | 11.2V @ 1A | 2A | • | • |
| **SP1008** | 0201 (Flipchip) | 6.0V | 6pF | 1 | 15kV | 10.7V @ 1A | 2.5A | • | • |
| **SP1011** | µDFN-6 | 6.0V | 7pF | 4 | 15kV | 8.7V @ 1A | 2A | • | • |
| **SD05** | SOD323 | 5.0V | 350pF | 1 | 30kV | 8.0V @ 1A | 30A | • | • |
| **SD05C** | SOD323 | 5.0V | 200pF | 1 | 30kV | 8.0V @ 1A | 30A | • | • |
| **Low Capacitance ESD Protection** | | | | | | | | | |
| **SP3001** | SC70 | 6.0V | 0.65pF | 4 | 8kV | 9.5V @ 1A | 2.5A | • | • |
| **SP3002** **SP0504S** | SC70, SOT23, µDFN-6 SOT23 | 6.0V | 0.85pF | 4 | 12kV | 9.5V @ 1A | 4.5A | • | • |
| **SP3003** | µDFN-6, SC70, SOT5x3, MSOP10 | 6.0V | 0.65pF | 2 / 4 / 8 | 8kV | 10.0V @ 1A | 2.5A | • | • |
| **SP3004** | SOT563 | 6.0V | 0.85pF | 4 | 12kV | 10.0V @ 1A | 4A | • | • |
| **SP3010** | µDFN-10 | 6.0V | 0.45pF | 4 | 8kV | 10.8V @ 1A | 3A | • | • |
| **SP3011** | µDFN-14 | 6.0V | 0.40pF | 6 | 8kV | 11.0V @ 1A | 3A | • | • |
| **SP3012** | µDFN-10, µDFN-14 | 5.0V | 0.50pF | 4 / 6 | 12kV | 6.6V @ 1A | 4A | • | • |
| **SP0524P** | µDFN-10 | 5.0V | 0.50pF | 4 | 12kV | 6.6V @ 1A | 4A | • | • |
| **SP3021** | 0402 (SOD882) | 5.0V | 0.50pF | 1 | 8kV | 13.1V @ 1A | 2A | • | • |
| **SP3030** | 0402 (SOD882) | 5.0V | 0.50pF | 1 | 20kV | 9.2V @ 1A | 3A | • | • |
| **SP3031** | 0402 (SOD882) | 5.0V | 0.80pF | 1 | 10kV | 6.9V @ 1A | 5A | • | • |
| **Lightning Surge Protection** | | | | | | | | | |
| **SRV05** | SOT23 | 6.0V | 2.4pF | 4 | 20kV | 11.5V @ 5A | 10A | • | • |
| **SP4060** | MSOP | 2.5V | 4.4pF | 8 | 30kV | 8.0V @ 10A | 20A | • | • |
| **SP2504N** | µDFN-10 | 2.5V | 3.5pF | 4 | 30kV | 6.3V @ 5A | 20A | • | • |
| **SP3304N** | µDFN-10 | 3.3V | 3.5pF | 4 | 30kV | 7V @ 5A | 20A | • | • |
| **SLVU2.8** | SOT23 | 2.8V | 2.0pF | 1 | 30kV | 13.9V @ 24A | 40A | • | • |
| **SLVU2.8-4** | SOIC | 2.8V | 2.0pF | 4 | 30kV | 13.9V @ 24A | 40A | • | • |
| **SR70** | SOT143 | 70V | 2.0pF | 2 | 30kV | 12V @ 30A | 40A | • | • |
| **SP2502L** | SOIC | 3.3V | 5.0pF | 2 | 30kV | 20V @ 75A | 75A | • | • |
| **LC03-3.3** | SOIC | 3.3V | 9.0pF | 2 | 30kV | 17V @ 100A | 150A | • | • |
| **SP03-3.3** | SOIC | 3.3V | 16pF | 2 | 30kV | 15V @ 100A | 150A | • | • |
| **SP03-6** | SOIC | 6.0V | 16pF | 2 | 30kV | 20V @ 100A | 150A | • | • |
| **SRDA05** | SOIC-8 | 5.0V | 8pF | 4 | 30kV | 9.2V @ 1A | 30A | • | • |
| **SR05** | SOT143 | 5.0V | 8pF | 2 | 30kV | 9.8V @ 1A | 25A | • | • |

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# TVS Diode Array Technology and Applications Overview

## Introduction to TVS Diode Arrays (SPA® Diodes)

Littelfuse Silicon Protection Array family of TVS Diode Arrays (SPA® Diodes) are designed to protect analog and digital signal lines, such as USB and HDMI, from various transient threats using the lowest possible clamp voltage. They offer broader application use and improved impulse protection performance over conventional diodes.

These robust devices safely absorb repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard, without performance degradation.

### Key Features

- Low capacitance 30pF to 0.40pF typically
- High level of protection:
  - ESD IEC 61000-4-2: Contact discharge up to ±30kV; Air discharge up to ±30kV
  - Lightning, IEC 61000-4-5; Immunity up to 150A
  - EFT IEC 61000-4-4 40A
- Low clamping voltage compared to other technologies
- Up to 14 inputs protection
- Space saving arrays and ultra-small 0201 and 0402 devices for mounting close to ports for optimal protection
- RoHS compliant, Lead-Free and Halogen-Free devices

## How they Work?

Littelfuse TVS Diode Array devices provide high level protection against Electrostatic Discharge (ESD), Electromagnetic Interference (EMI) and Lightning, mainly for sensitive digital and analogue input circuits, on data, signal, or control lines operating on power supplies.

These devices work in two ways. First, they absorb transients with diodes, to steer the current, and then, an avalanching or zener diode, clamps the voltage levels. This prevents the device from exceeding its voltage rating. During over-voltage fault conditions, the device must have a low clamp voltage at the specified current wave form to protect sensitive IC's and ports.

In normal operation, the reverse stand off voltage must be higher than the equipment supply/working voltage, with low leakage current to prevent power supply loading. The device capacitance must be low enough to reduce input signal distortion. The device package must have a small footprint and low height to enable a high density Printed Circuit Board (PCB) layout.

The device must withstand multiple ESD pulses as specified in the IEC 61000-4-2.

## Data Protocols and End Applications

The diagrams on the next page show the relationship between Data Rates (Protocol), Applications, and Littelfuse TVS Diode Arrays (SPA® Diodes).

The top diagram shows the standard data protocols, associated data rates, example end applications, and applicable Littelfuse SPxxxx device series. Similarly, the bottom diagram shows common end applications and applicable SPxxxx devices in table format.

This information, along with the example circuit protection configuration diagrams on the following pages, and within each data sheet, is intended to help circuit designers determine which Littelfuse suppressors are most appropriate for the situation.

Most electronic products today use several port and data protocol types, and so require multple strategies of protection at each possible ESD transient entry point.

## Concern About Capacitance

As data rate and data integrity concerns increase, so should concern about the capacitance of the suppression device.

For example, audio and mouse ports on most PCs use relatively slow data rates where capacitance of the ESD protector is not very important.

However, in today's higher bandwidth applications, the designer must be very conscientious about the parasitic capacitance of the protection device, to ensure that it does not cause signal degradation at very high frequencies.

As data rates have continued to push higher (e.g. USB3.0, Gigabit Ethernet, HDMI, etc) chipsets have become more sensitive to ESD and other electrical transients by virtue of their small geometry processing. The only technology currently capable of preserving signal integrity and providing very low clamping voltages are Littelfuse SPA® Diodes.

Other key characteristics such as leakage current, number of lines of protection, ESD immunity, and footprint also need to be considered, especially where there are overlaps in the recommended Littelfuse ESD suppressor line.

If you require further assistance in selecting the appropriate Littelfuse ESD suppressor for your specific circuit, please contact your local Littelfuse products representative.

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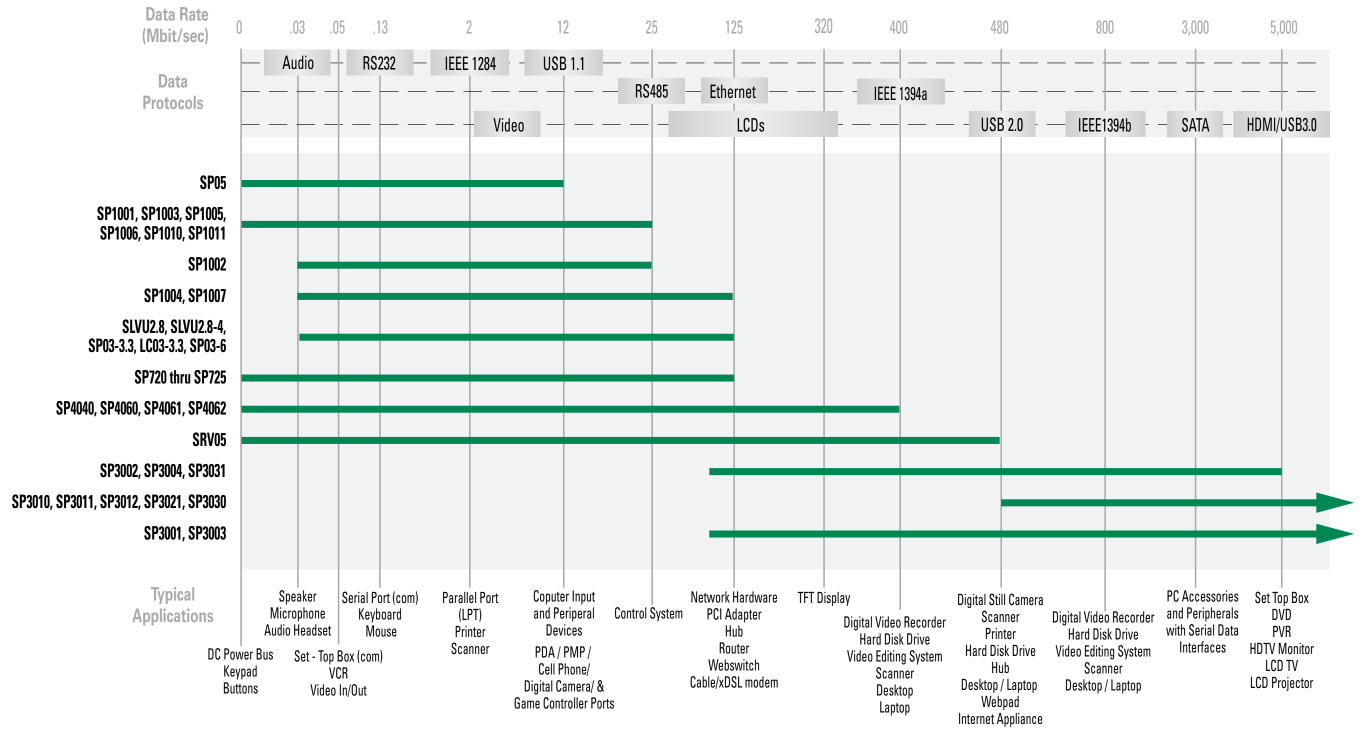
**For additional information including reference design examples, please visit www.littelfuse.com/SPA**

## PRODUCT SERIES AND APPLICABLE DATA RATES AND PROTOCOLS




## PRODUCT SERIES AND RELATED END APPLICATIONS

| Product Series | SP05 | SP0504S | SP0524P | SP1001 | SP1002 | SP1003 | SP1004 | SP1005 | SP1006 | SP1007 | SP1008 | SP1011 | SD05 | SD05C | SP720 | SP721 | SP723 | SP724 | SP725 | SP3001 | SP3002 | SP3003 | SP3004 | SP3010 | SP3011 | SP3012 | SP3021 | SP3030 | SP3031 | SP03-3.3 | LC03-3.3 | SP03-6 | SLVU2.8 | SLVU2.8-4 | SRV05 | SP2502L | SP4060 | SP2504N | SP3304N | SR70 | SRDA05 | SR05 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| **Audio Lines** | X | | | X | X | X | X | X | | X | X | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **Low speed I/O Port** | X | | | X | X | X | X | X | X | | X | X | X | X | X | X | X | X | X | | | | | | | | | | | | | | X | | X | | | | | | X | X |
| **USB 1.1 Port** | X | | | X | | | | | | | | X | | | | | | | | | | | | | | | | | | | | | | | X | | | | | | X | X |
| **USB 2.0 Port** | | X | | | | | | | | | | | | | | | | | | X | X | X | X | | | | X | X | X | | | | | | X | | | | | | | |
| **USB 3.0 Port** | | | X | | | | | | | | | | | | | | | | | | | | | X | X | X | X | X | | | | | | | | | | | | | | |
| **1394 Port** | | X | X | | | | | | | | | | | | | | | | | X | X | X | X | X | | X | X | X | X | | | | | | | | | | | | | |
| **HDMI Port** | | X | X | | | | | | | | | | | | | | | | | X | X | X | X | X | X | X | X | X | X | | | | | | | | | | | | | |
| **LCD Display Monitors** | X | X | | X | | | X | | | | | X | | | | | | | | X | X | X | X | | | | | | | | | | | | | | X | | | | | |
| **Handheld Device LCD Display** | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **SIM Socket** | X | | | X | | X | | X | X | X | X | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **Memory Card Interface** | X | | | X | | X | X | | X | | | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **Keypads/Buttons** | X | | | X | | X | X | X | X | X | | X | X | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **Analog Video** | X | | | X | X | X | X | X | X | X | X | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| **Ethernet Port** | | X | X | | | | | | | | | | | | | | | | | X | X | X | X | | | X | | | X | X | X | X | X | X | X | X | X | X | X | | X | X |
| **T1/E1/T3/E3** | | X | X | | | | | | | | | | | | | | | | | X | X | X | X | | | X | | | | X | X | X | X | X | X | X | X | X | X | | X | X |
| **xDSL** | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | X | X | X |
| **DC Power Port** | | | | | | X | | | | | | | X | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

NOTE: The application summaries listed here are for reference only. Determination of suitability for a specific application is the responsibility of the customer.

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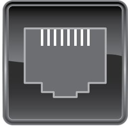
# Port Protection Examples

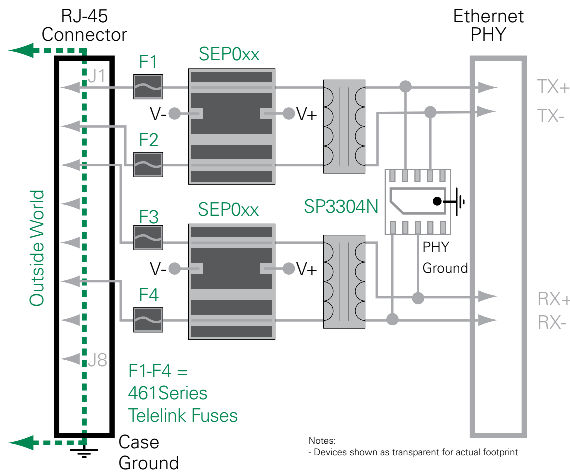


## BROADBAND NETWORK PORT PROTECTION

The following are examples of the implementation of ESD and lightning suppression for Ethernet ports (RJ-45 connectors). Note that the diagrams shown below represent 10Mbps and 100Mbps applications -- For 1Gbps applications, the circuit protection should be double of what is shown. For additional design examples, guidance and application assistance, please contact Littelfuse.

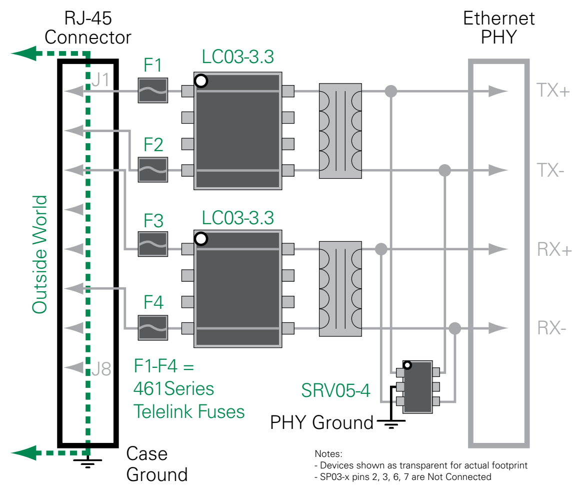
### Inter-Building - Robust Lightning Protection

The diagram show below is typical for outdoor network line and equipment applications. The SIDACtor® and TVS Diode Array combination is rated up to 500A, per the GR-1089 standard.



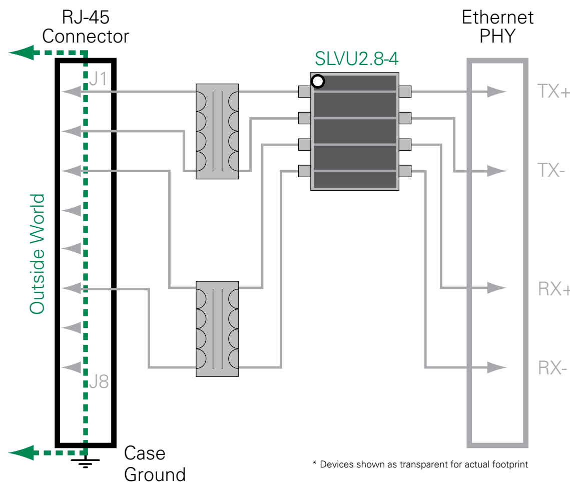

### Intra-Building - Robust Lightning Protection

The diagram show below is typical for indoor network line and equipment applications. The TVS Diode Array device combination is rated up to 100A, per the GR-1089 standard.



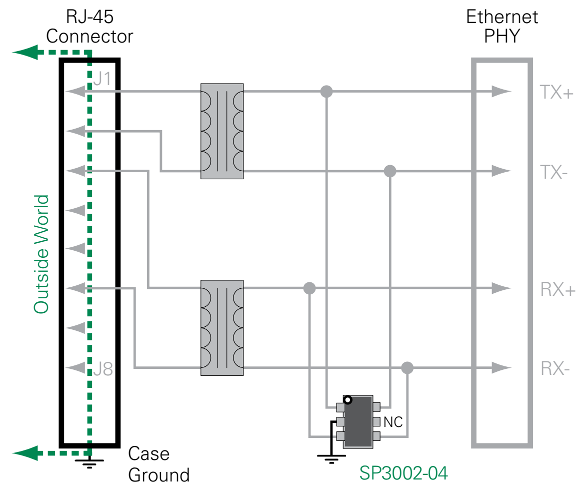

### Basic Lightning Protection

The diagram shown below is typical for basic lightning (differential only) of indoor/outdoor network line and equipment applications (Example: office environment equipment).




### Basic ESD Protection

The diagram shown below is typical for basic ESD protection of indoor network line and equipment applications (Examples: home office / consumer electronics peripheral devices).

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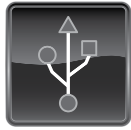
# Port Protection Examples (continued)

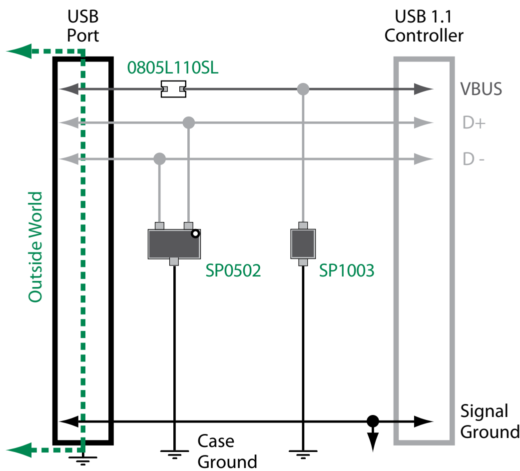


## PERIPHERAL / STORAGE DATA PORT PROTECTION

The following are examples of ESD suppression for high speed data ports such as USB and eSATA. For additional design examples, guidance and application assistance, please contact Littelfuse.

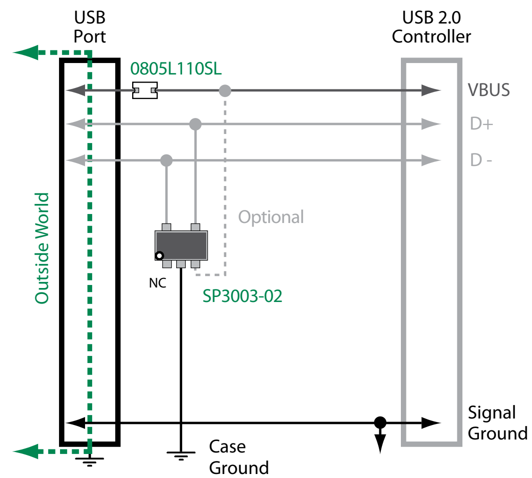
### USB 1.1

Data speeds up to 12 Mbps



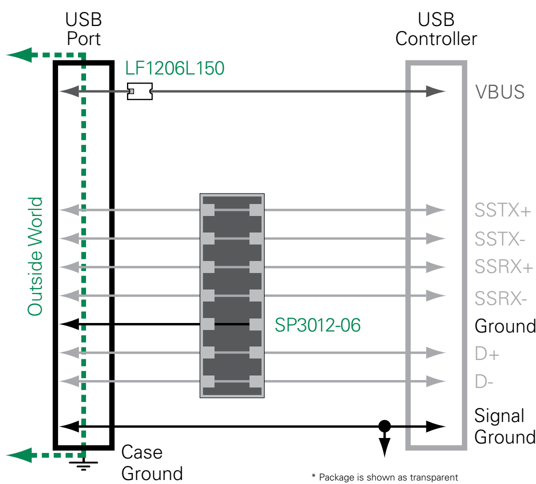

### USB 2.0

Data speeds up to 480 Mbps



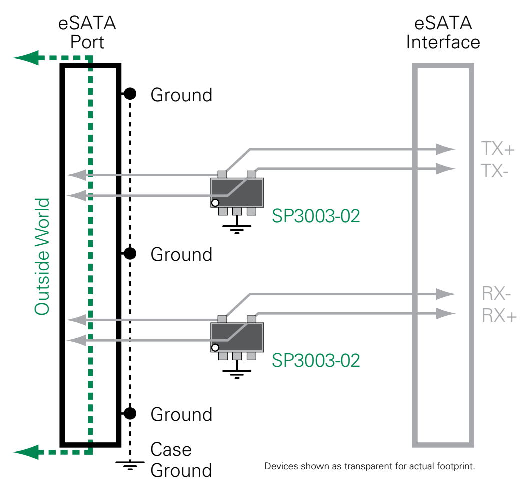

### USB 3.0

Data speeds up to 5 Gbps




### eSATA

Data speeds up to 3 Gbps

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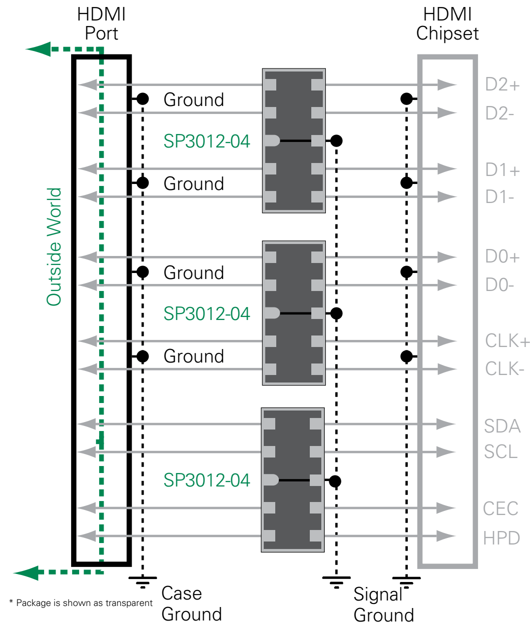
# Port Protection Examples (continued)

## ENTERTAINMENT ELECTRONICS PORT PROTECTION

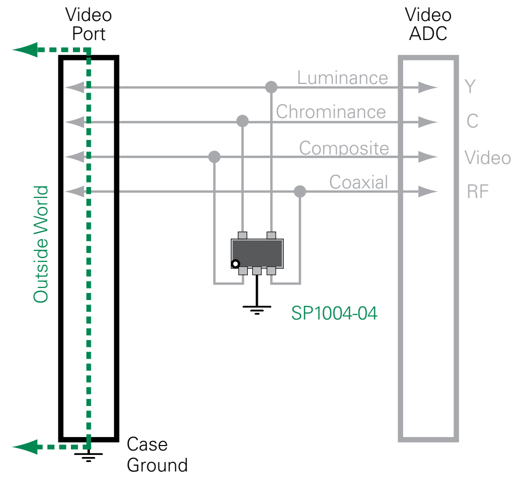
The following are examples of ESD suppression for ports common to entertainment electronics.
For additional design examples, guidance and application assistance, please contact Littelfuse.

### High Definition Multimedia Inteface (HDMI)

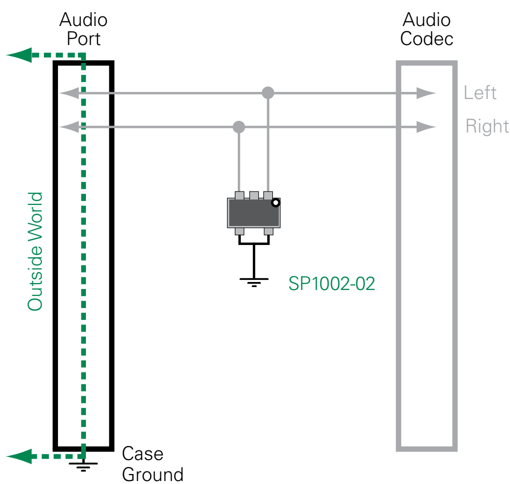
Data speeds up to 3.4 Gbps per pair



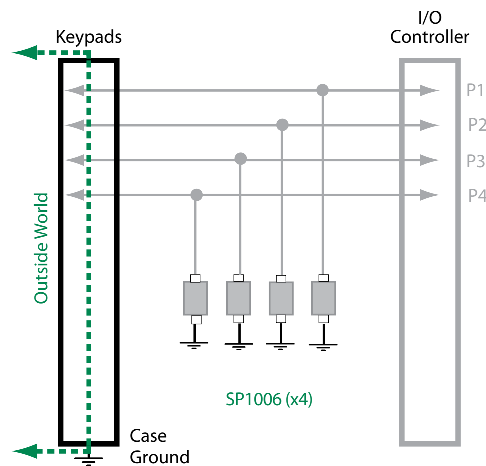

### Analog Video Port




### Analog audio (Speaker/Microphone)




### Keypad / push button ESD protection




**For additional reference design examples, please view the product data sheets within this catalog or visit the application reference design section of our web site http://www.littelfuse.com/technical-resources/application-designs.aspx**

To assure suitability of any Littelfuse device, be sure to test the device within the end application under conditions of intended use.

# Definitions and Terms

## Definitions

### Operating Voltage Range ($V_{SUPPLY}$; SP72x Series only)

The range limits of the power supply voltage that may be across the V+ and V- terminals. The SCR/Diode arrays do not have a fixed breakover or operating voltage. These devices 'float' between the input and power supply rails and thus the same device can operate at any potential within its range.

### Forward Voltage Drop (SP72x Series only)

The maximum forward voltage drop between an input pin and respective power supply pin for a specific forward current.

### Reverse Voltage Drop or Breakdown Voltage

The voltage at which an input pin will begin to conduct current to the respective power pin. This parameter is usually stated at a specific reverse current.

### Reverse Standoff Voltage or Reverse Working Maximum

The device $V_R$ or $V_{RWM}$ should be equal to or greater than the peak operating voltage of circuit (or part of the circuit) to be protected. This is to ensure that the TVS Diode Array does not clip the signal voltage.

### Reverse Leakage Current

Maximum leakage current the protection device conducts in the off-state measured at specified voltage.

### Clamping Voltage

Maximum voltage which can be measured across the protector when subjected to the stated peak pulse current. The "$I_{PP}$" or Peak Pulse Current is typically an 8x20μs waveform that aims to reduce voltage spikes or overshoots due to parasitic PCB inductance.

### Input Leakage Current (SP72x Series only)

The DC current that is measured at the input pins at the stated voltage supplied to the input.

### Quiescent Supply Current (SP72x Series only)

The maximum DC current into V+ and V- pins with $V_{SUPPLY}$ at its maximum voltage.

### Capacitance

The capacitance measured between the input pin and a reference (usually GND) with a 1MHz, 30 $mV_{RMS}$ signal.

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# Transient Voltage Threats and Scenarios

## Transient Threats – What Are Transients?

Voltage Transients are defined as short duration surges of electrical energy and are the result of the sudden release of energy previously stored or induced by other means, such as heavy inductive loads or lightning. In electrical or electronic circuits, this energy can be released in a predictable manner via controlled switching actions, or randomly induced into a circuit from external sources.

Repeatable transients are frequently caused by the operation of motors, generators, or the switching of reactive circuit components. Random transients, on the other hand, are often caused by Lightning and Electrostatic Discharge (ESD). Lightning and ESD generally occur unpredictably, and may require elaborate monitoring to be accurately measured, especially if induced at the circuit board level. Numerous electronics standards groups have analyzed transient voltage occurrences using accepted monitoring or testing methods. The key characteristics of several transients are shown in the table below.

| | VOLTAGE | CURRENT | RISE-TIME | DURATION |
|---|---|---|---|---|
| Lighting | 25kV | 20kA | 10 µs | 1ms |
| Switching | 600V | 500A | 50µs | 500ms |
| EMP | 1kV | 10A | 20ns | 1ms |
| ESD | 8kV | 30A | <1ns | 100ns |

Table 1. Examples of transient sources and magnitude

## Characteristics of Transient Voltage Spikes

Transient voltage spikes generally exhibit a "double exponential" wave, as shown below for lightning and ESD.

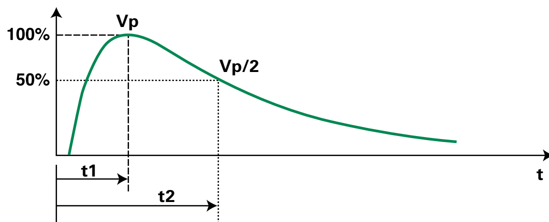


Figure 1. Lightning Transient Waveform

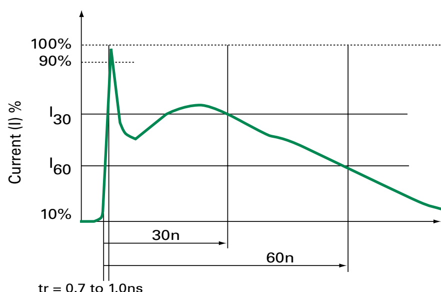


Figure 2. ESD Test Waveform

The exponential rise time of lightning is in the range 1.2µsec to 10µsec (essentially 10% to 90%) and the duration is in the range of 50µsec to 1000µsec (50% of peak values). ESD on the other hand, is a much shorter duration event. The rise time has been characterized at less than 1.0ns. The overall duration is approximately 100ns.

## Why are Transients of Increasing Concern?

Component miniaturization has resulted in increased sensitivity to electrical stresses. Microprocessors for example, have structures and conductive paths which are unable to handle high currents from ESD transients. Such components operate at very low voltages, so voltage disturbances must be controlled to prevent device interruption and latent or catastrophic failures.

Sensitive microprocessors are prevelant today in a wide range of devices. Everything from home appliances, such as dishwashers, to industrial controls and even toys use microprocessors to improve functionality and efficiency.

Most vehicles now also employ multiple electronic systems to control the engine, climate, braking and, in some cases, steering, traction and safety systems.

Many of the sub- or supporting components (such as electric motors or accessories) within appliances and automobiles present transient threats to the entire system.

Careful circuit design should factor environmental scenarios as well as the potential effects of these related components. Table 2 below shows the typical vulnerability of various component technologies.

| Device Type | Vulnerability (volts) |
|---|---|
| VMOS | 30-1800 |
| MOSFET | 100-200 |
| GaAsFET | 100-300 |
| EPROM | 100 |
| JFET | 140-7000 |
| CMOS | 250-3000 |
| Schottky Diodes | 300-2500 |
| Bipolar Transistors | 380-7000 |
| SCR | 680-1000 |

Table 2: Range of device vulnerability (typical).

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# Transient Voltage Threats and Scenarios (continued)

## Electrostatic Discharge (ESD)

Electrostatic discharge is characterized by very fast rise times and very high peak voltages and currents. This energy is the result of an imbalance of positive and negative charges between objects.

ESD that is generated by everyday activities can far surpass the vulnerability threshold of standard semiconductor technologies. Following are a few examples:

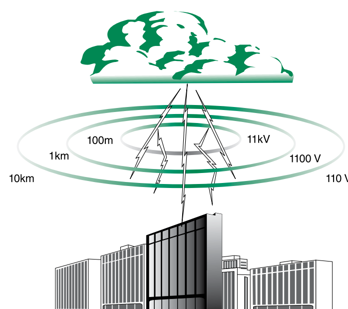
- **Walking across a carpet:**
  35kV @ RH = 20%;1.5kV @ RH = 65%
- **Walking across a vinyl floor:**
  12kV @ RH = 20%;250V @ RH = 65%
- **Worker at a bench:**
  6kV @ RH = 20%;100V @ RH = 65%
- **Vinyl envelopes:**
  7kV @ RH = 20%;600V @ RH = 65%
- **Poly bag picked up from desk:**
  20kV @ RH = 20%;1.2kV @ RH = 65%

## Lightning Induced Transients

Even though a direct strike is clearly destructive, transients induced by lightning are not the result of a direct strike.

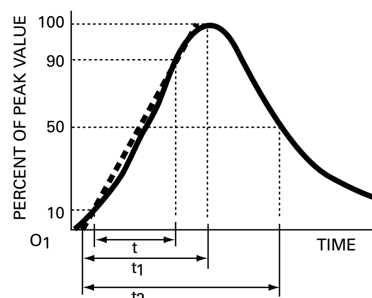
When a lightning strike occurs, the event creates a magnetic field which can induce transients of large magnitude in nearby electrical cables.

A cloud-to-cloud strike will effect not only overhead cables, but also buried cables. Even a strike 1 mile distant (1.6km) can generate 70 volts in electrical cables.




In a cloud-to-ground strike (as shown at right) the transient-generating effect is far greater.

This diagram shows a typical current waveform for induced lightning disturbances.




## Inductive Load Switching

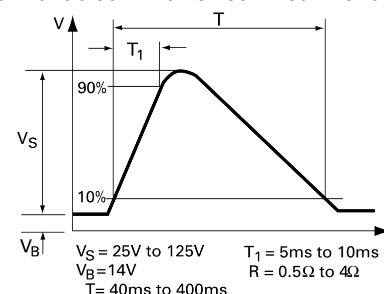
The switching of inductive loads generates high energy transients which increase in magnitude with increasingly heavy loads. When the inductive load is switched off, the collapsing magnetic field is converted into electrical energy which takes the form of a double exponential transient. Depending on the source, these transients can be as large as hundreds of volts and hundreds of Amps, with duration times of 400 milliseconds.

Typical sources of inductive transients include:

- **Generator**
- **Motor**
- **Relay**
- **Transformer**

These examples are common in electrical and electronic systems. Because the sizes of the loads vary according to the application, the wave shape, duration, peak current and peak voltage are all variables which exist in real world transients. Once these variables can be approximated, a suitable suppressor technology can be selected.

The diagram at right shows a transient which is the result of stored energy within the alternator of an automobile charging system.




A similar transient can also be caused by other DC motors in a vehicle. For example, DC motors power amenities such as power locks, seats and windows. These various applications of a DC motor can produce transients that are just as harmful to the sensitive electronic components as transients created in the external environment.

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# ESD Suppression Strategies and Standards

## Why Implement Circuit Protection?

It is important to consider that most electronic equipment will spend 99% of its useful life in environments where it is subject to ESD.

ESD can be generated from a wide range of everyday factors such as very dry air, static from plastics, or walking across a floor or carpet, and can be present during every phase of useful life from manufacturing, to product shipping, receiving, to field handling.

Electrostatic Discharge (ESD) causes millions of dollars worth of damage to electrical components, rendering circuit boards non-functional, and corrupting or erasing vital data. Often the damage is not detectable until a malfunction occurs. That could take weeks, months, or even years before an unpredictable and premature breakdown causes a field failure.

If you use electronic components or boards in your products, adding devices that suppress ESD damage can result in preventing damage to your company reputation and bottom line. Other tangible benefits include:

- Higher manufacturing yields
- Less rework and inventory
- Reduced overall costs
- Fewer field failures and warranty calls
- Increased product reliability
- More repeat business

Companies can also face legal liabilities if the product fails due to ESD/Transient damage. So it is important to include ESD/Transient Immunity in all phases of the project.

It is wise to factor Electrostatic Discharge (ESD) Immunity strategies early in design processes. If a device in development fails ESD immunity tests–the scramble to avoid complete redesign often leads to higher parts cost and more manual assembly during manufacturing.

There is little time to fully analyze which components do and do not provide ESD immunity. Worse, under pressure, finding comprehensive information tailored to ESD immunity design is very difficult, leaving your product vulnerable to ESD/Transient damage.

Littelfuse associates can help you address these challenges, offering extensive application expertise and product testing capabilities. Please contact your local Littelfuse representative for assistance.

## ESD Electrical Characteristics

ESD, in contrast to switching and surge transients, has a very short transition from zero to maximum current and voltage. The rise time of an ESD event is less than 1 nanosecond (1ns), while the other transients take longer than 1 microsecond (1μs) to reach their peaks.

The International Electrotechnical Commission (IEC) has developed a model of an ESD event for the user environment. The model defined in the IEC61000-4-2 standard is used for determining if systems (computers, networks, cell phones, set top boxes, etc.) are susceptible to ESD events. The test specification quantifies the methodology for introducing ESD into the system as well as the various voltage and current levels that define the ESD event.

Internal circuits or ICs have some level of ESD protection "on chip"; however, they are almost always much less than the typical ESD levels seen in the field. Furthermore, the internal ICs are commonly evaluated using a manufacturing environment test standard (MIL-STD-883, Method 3015) that generates voltages and current levels far below that of the IEC "system level" standard. The current levels can differ by more than 100 fold, and more about this is discussed on page 13 in the section titled "ESD Immunity Test Standards".

## ESD Damage Risks

A transient discharged into an electronic system creates three general types of adverse effects:

**1. Soft Failures/Data Corruption:** can occur to a part of the data stream, or the system may latch up. This is a temporary problem and is solved by data correction (for data corruption) or by re-booting the system (for latch up).

**2. Latent Defects:** A component might be partially degraded, but able to function properly. Typically a latent defect may cause a system to fail prematurely.

**3. Catastrophic Failures:** An internal component is rendered inoperable, and cannot function properly. This is a permanent condition. In the case of **Junction Burnout**, a short circuit condition is created in a transistor of the circuit. The metallic interconnect (Trace Line) is "pulled through" one of the semiconductor layers (Alloy Spike) or one of the semi conducting junctions is directly short circuited (Junction Short). In **Oxide Punch-Through**, the metallic interconnect is "pulled through" the oxide layer to provide a short circuit on the signal line. In **Metallization Burnout**, the metallic interconnect is melted, much like a fuse. It creates an open circuit condition on the signal line.

The use of ESD circuit protection components like Littelfuse SPA® Diodes will help you avoid such problems.

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# ESD Suppression Strategies and Standards (continued)

## ESD Suppression and Circuit Design Considerations

Proper use of circuit protection helps to reduce ESD risks. Littelfuse TVS Diode Arrays possess the speed, clamping voltage, and residual current levels that will protect today's sensitive semiconductors and electronic circuitry. Many devices present an extremely low parasitic capacitance to prevent signal degradation in high-speed/ high bandwidth communications.

When selecting ESD suppressors, designers need to consider potential coupling paths that would allow ESD to enter the circuit. These weak points should be considered for diode array protection, selected with characteristics appropriate for the component sensitivity, and the equipment and environment where it will be used.

## Common ESD Entry Points

ESD quickly finds weak spot(s) and will sneak into devices using a wide range of potential coupling paths. Careful consideratation about potential weak points, and taking steps to seal off those paths and fortify the most vulnerable electronic components is vital. Below are ways an ESD pulse can enter an electronic device:

1. An initial electric field from an arc can capacitively couple over a large surface area. It can appear like a signal to high-impedance analog circuits and measure up to 4000 V/m

2. Current or charge from the arc can be injected and:

- Smash through insulating layers in the component and damage the gates of MOSFETs and CMOS devices
- Trigger a latch-up in CMOS devices
- Short circuit reverse and forward-biased PN junctions
- Melt bonding wires

3. A voltage pulse on conductors caused by current ($V = L * dI/dt$) whether from ground, power or signal wiring, can spread into every device that is linked

4. An intense magnetic field emitted from an ESD arc can have a frequency range of 1 to 500Mhz, which can inductively couple into every nearby wiring loop and be as high as 15 A/m

5. An electro-magnetic field generated by the arc's magnetic field can radiate and couple into long wires that act like receiving antennas

## ESD Suppression Strategies

### Chip Level ESD Protection

In the heart of the device is the integrated circuitry (IC) responsible for its processing and communication function.

Typically, trade-offs for the chip designer are ESD protection versus die space and the demand of smaller and faster chips-which require sub-micron processes and very fine line widths. As more ESD protection structures are incorporated into the chip, survivability increases. The choice is either less space available for functional circuitry or make the chip larger.

In today's market, "smaller and faster" is the goal, and ESD protection is sacrificed for more on-chip space to boost functionality and speed. Consequently, circuits will become more sensitive to ESD and other transients.

Input and output port connections allow the free flow of data – including transients. ESD can enter a port–or the disconnected end of the cable while connecting/ disconnecting cables. It will then travel through the connector to the PC board and propagate down the data lines toward the ICs.

Littelfuse offers ultra-small packages to provide maximum protection with a minimum of space. The suppressor devices are installed between the data line and the chassis ground (parallel connection) and shunt the ESD transient from the data line to the ground. Optimally, diode array devices should be the first thing a transient should encounter on the board.

NOTE: For high-speed signal pins, devices with extremely low capacitance levels should be used. Consult www.littelfuse.com for more detailed information on which products offer best protection for high-speed connectors.

### Board Level ESD Protection

Especially critical in portable systems is the board layout. Parasitic inductance in the protection path can result in significant voltage overshoot, easily getting past the insulation barriers and damaging the the circuit. This is especially critical in the case of fast rise-time transients such as ESD or EFT. However, the need for board-level protection will vary from system to system.

Factors determining level of need:

- The board layout
- ESD capabilities of the IC
- Physical ability of ESD transients to get on the data lines

Empirical testing can also be done to help determine the system's susceptibility.

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# ESD Suppression Strategies and Standards (continued)

## ESD Prevention During and After Manufacturing

Manufacturers typically include structures stamped directly on the die to provide some ESD protection of the circuits through the manufacturing process. Production environments tightly control and take precautions to ensure that static electricity levels on personnel and equipment are minimized. For example, when handling parts or their containers, workers wear wrist straps, anti-static garments and work at grounded workstations. Various environmental controls (humidity/air ionization) are also implemented. Finally, by transporting products in special electrostatic shield packaging ensures safe arrival to the customer.

More powerful transients await as the product moves outside the controlled factory environment. Often designers and/or engineers will need to provide additional off-chip, board-level solutions to fill in the gaps.

Ultimately, hardware or board designers must add supplementary ESD devices to protect these sensitive chipsets from the high level ESD threats seen in the field.

## Supplemental ESD Protection

When deciding on more ESD protection, the next step is to identify the appropriate suppressor. Consider the following specifications to make an appropriate selection:

- Capacitance
- Peak voltage and clamping level
- Dynamic Resistance
- Leakage current
- Standoff Voltage or Reverse Working Maximum
- Number of lines to be protected
- Package

**Capacitance** is becoming an extremely important criterion since the data rates at which electronic products are communicating continue to increase. As previously mentioned, the **Clamping Level** of the suppressor determines how much of the ESD transient is eliminated. A related value is the **Peak Voltage.** As the suppressor transitions from high to low resistance, a portion of the ESD transient is transmitted before the clamping voltage is established. The **Dynamic Resistance** is a value calculated by taking the difference in clamping voltage at two different current levels and can be used to compare the effectiveness various ESD protection technologies. See our application note, "Selecting an Appropriate ESD Device" for more information. These are important factors for those IC's that do not have a substantial amount of on-chip ESD protection. In this case, it is important that as little ESD as possible is actually experienced by the IC. For these circuits, Littelfuse TVS Diode Arrays (SPA® Diodes) are ideal. They have extremely low peak and clamping voltages due to their low dynamic resistance to provide ultimate protection for the IC.

**Leakage Current** is the amount of current passed through the suppressor as the circuit operates normally (i.e. at the rated voltage or $V_{RWM}$). It is an important consideration for applications where the main power supply is battery driven. In these cases, the suppressor should allow as little leakage as possible, to avoid draining the battery unnecessarily.

Suppressors have varied **Standoff Voltage or Reverse Working Maximum** specifications determined by their construction. This is used to determine if the part is suitable for given circuit parameters. For example, a 5 VDC-rated part should not be used for ESD protection on a 9 VDC bus. The excess voltage may cause degradation of the part or even catastrophic failure due to excessive heating caused by DC current flow.

Another consideration is the **Number Of Lines To Be Protected.** This is determined by the system's data protocol. For example, USB buses have two or six data lines, HDMI has 8 data lines, 10/100/1000 BaseT Ethernet uses four to eight lines, etc. In cases where multiple data lines will be protected, it may be desirable to use a **Package** that has multiple channels (i.e. an array) to save board space and installation costs. Littelfuse TVS Diode Arrays are available in discrete and multi-channel packages to offer a broad selection of high quality devices to the circuit and board designer.

## Suppressor Location

Place the suppressor as near the line that it is protecting as possible, and as close as possible to the point of ESD entry. ESD transients should hit the suppressor first on entry to the board. Because ESD is such a fast rise-time event, any distance between the protected line and the ESD suppressor will mean more transient voltage to the IC.

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# ESD Suppression Strategies and Standards (continued)

## ESD Immunity Test Standards

To test their products, manufacturers may apply one of several methods using either the CDM (Charged Device Model), MM (Machine Model), and/or HBM (Human Body Model). MIL-STD-883 Method 3015 and IEC61000-4-2 are testing standards commonly applied:

### MIL-STD-883 Method 3015

Historically, analog and digital designers have been required to have ESD protection "on-chip" to protect the IC during manufacturing. The most commonly used ESD standard in the manufacturing environment is the MIL-STD-883, Method 3015 and it's also referred to as the Human Body Model (HBM). This model discharges a 100pF capacitor through a 1500Ω resistor into the device under test. The table below points out the four test levels as defined in the standard.

| HBM Level | Contact Discharge (kV) | Peak Current (A) |
|---|---|---|
| 1 | ±0.5 | 0.33 |
| 2 | ±1 | 0.67 |
| 3 | ±2 | 1.33 |
| 4 | ±4 | 2.67 |

The maximum level required for a typical IC had been ±2kV up until 2007, but today that level has been drastically reduced to ±0.5kV. Obviously, this has helped chip designers save valuable silicon area for more functionality, but in turn, it has made the IC much more susceptible to damage from ESD.

### IEC61000-4-2

Conversely, equipment manufacturers have traditionally used an ESD standard defined by the IEC (International Electrotechnical Commission) for system or application level testing. This model uses a 150pF capacitor which is discharged through a 330Ω resistor. The table below displays the four test levels as defined in the standard.

| IEC Level | Contact Discharge (kV) | Peak Current (A) |
|---|---|---|
| 1 | ±2 | 7.5 |
| 2 | ±4 | 15 |
| 3 | ±6 | 22.5 |
| 4 | ±8 | 30 |

Most all manufacturers require that their equipment pass Level 4, or ±8kV, as a minimum, however, some are looking for increased reliability and require that their devices pass a much higher level like ±15kV or ±30kV.

The system level ESD test defined by the IEC produces a substantial increase in peak current compared to the military standard. If an IC is rated for 0.5kV per the MIL-STD and the equipment manufacturer tests this same IC at 8kV per the IEC specification, the chip will see nearly a 100 fold increase in peak current (i.e. 0.33A vs. 30A)!

## Additional Transient Immunity Considerations

### Film Resistors

In-line film resistors between inputs and off-board connectors provide minimal transient protection and are often damaged themselves.

### Component Quality

Active components play the biggest role towards ESD/ Transient immunity. If using substitute and/or secondary source components, test and analyze them thoroughly. Though functionally equivalent, they may lack the ESD/ Transient immunity of the preferred components.

### Multi-Suppressor Combinations

ESD protection through use of SPA® Diodes included in combination with other filters and transient suppressors is another strategy for inputs, outputs and power ports. See www.Littelfuse.com for more information.

### Preventive Software Programming

The basic requirement of good software is to cleanly handle abnormal operations, no matter the cause.

### Internal Moving Parts

Equipment with moving parts can become its own ESD/ Transient generator. Printers and copiers are especially susceptible because they carry paper through paper rollers and use toner. In general, the problem areas include sliding parts, rolling parts, flexing parts, flowing liquids and airflow carrying particles or liquid droplets.

Finally, once the design has been approved, it's tempting to substitute components in effort to boost product performance. Often newer chips and components are faster but more sensitive to transients causing new emissions and immunity problems. Keep fully informed, as periodically suppliers can make changes to components that may affect ESD Immunity. Test the new parts to determine if they are still effective. Planning is key, in the event the new product doesn't work or the company ceases producing it, having several backup plans will help your company face unforseen challenges.

## For More Information

Please visit www.littelfuse.com/esd for technical notes and application advice articles that address ways to reduce catastrophic failures and allow the equipment to reliably withstand certain ESD events.

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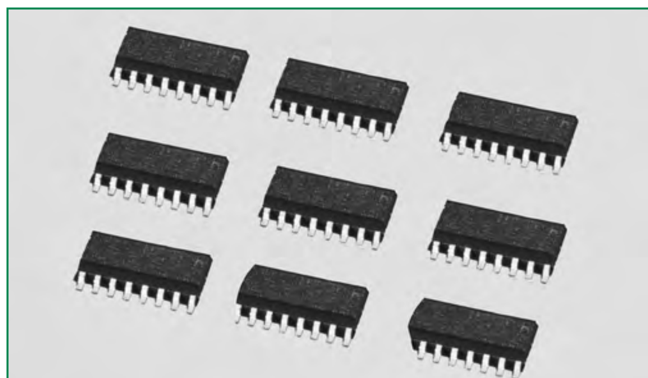
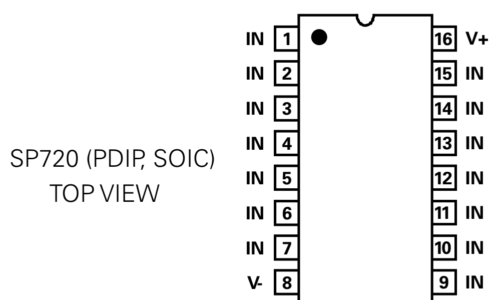
# SP720 Series 3pF 4kV Diode Array

RoHS Pb GREEN

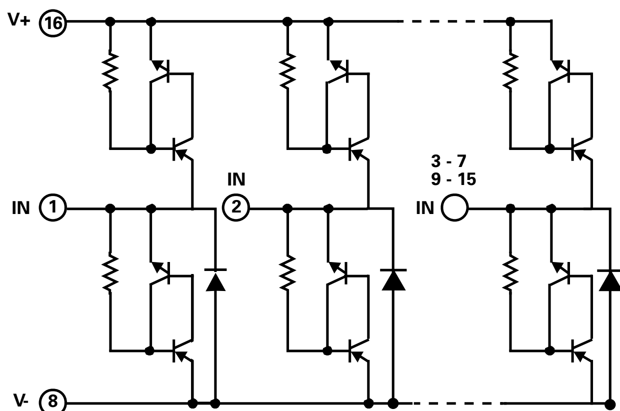


## Pinout

SP720 (PDIP, SOIC)
TOP VIEW




## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## Description

The SP720 is an array of SCR/Diode bipolar structures for ESD and over-voltage protection to sensitive input circuits. The SP720 has 2 protection SCR/Diode device structures per input. A total of 14 available inputs can be used to protect up to 14 external signal or bus lines. Over-voltage protection is from the IN (pins 1-7 and 9-15) to V+ or V-.

The SCR structures are designed for fast triggering at a threshold of one $+V_{BE}$ diode threshold above V+ (Pin 16) or a $-V_{BE}$ diode threshold below V- (Pin 8). From an IN input, a clamp to V+ is activated if a transient pulse causes the input to be increased to a voltage level greater than one $V_{BE}$ above V+. A similar clamp to V- is activated if a negative pulse, one $V_{BE}$ less than V-, is applied to an IN input. Standard ESD Human Body Model (HBM) Capability is:

## Features

- ESD Interface Capability for HBM Standards
  - MIL STD 3015.7 ........ 15kV
  - IEC 61000-4-2, Direct Discharge,
  - Single Input ........ 4kV (Level 2)
  - Two Inputs in Parallel ........ 8kV (Level 4)
  - IEC 61000-4-2, Air Discharge ........ 15kV (Level 4)
- High Peak Current Capability
  - IEC 61000-4-5 (8/20μs) ........ ±3A
  - Single Pulse, 100μs Pulse Width ........ ±2A
  - Single Pulse, 4μs Pulse Width ........ ±5A
- Designed to Provide Over-Voltage Protection
  - Single-Ended Voltage Range to ........ +30V
  - Differential Voltage Range to ........ ±15V
- Fast Switching ........ 2ns Risetime
- Low Input Leakages ........ 1nA at 25° (Typ)
- Low Input Capacitance ........ 3pF (Typ)
- An Array of 14 SCR/Diode Pairs
- Operating Temperature Range ........ -40°C to 105°C

## Applications

- Microprocessor/Logic Input Protection
- Data Bus Protection
- Analog Device Input Protection
- Voltage Clamp

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Continuous Supply Voltage, (V+) - (V-) | +35 | V |
| Forward Peak Current, $I_{IN}$ to $V_{CC}$, $I_{IN}$ to GND (Refer to Figure 5) | ±2, 100μs | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

Note:
ESD Ratings and Capability - See Figure 1, Table 1
Load Dump and Reverse Battery (Note 2)

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Thermal Resistance (Typical, Note 1) | $\theta_{JA}$ | °C/W |
| PDIP Package | 90 | °C/W |
| SOIC Package | 130 | °C/W |
| Maximum Storage Temperature Range | -65 to 150 | °C |
| Maximum Junction Temperature (Plastic Package) | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC Lead Tips Only) | 260 | °C |

1. $\theta_{JA}$ is measured with the component mounted on an evaluation PC board in free air.

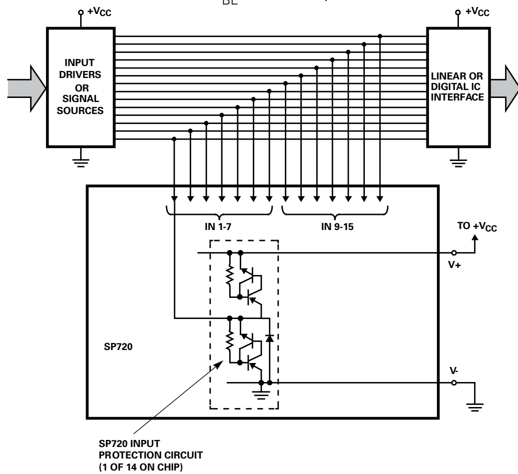
## Electrical Characteristics $T_A$ = -40°C to 105°C, $V_{IN}$ = 0.5$V_{CC}$ , Unless Otherwise Specified

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Operating Voltage Range, $V_{SUPPLY}$ = [(V+) - (V-)] | $V_{SUPPLY}$ | | - | 2 to 30 | - | V |
| Forward Voltage Drop: | | $I_{IN}$ = 1A (Peak Pulse) | | | | |
| IN to V- | $V_{FWDL}$ | | - | 2 | - | V |
| IN to V+ | $V_{FWDH}$ | | - | 2 | - | V |
| Input Leakage Current | $I_{IN}$ | | -20 | 5 | 20 | nA |
| Quiescent Supply Current | $I_{QUIESCENT}$ | | - | 50 | 200 | nA |
| Equivalent SCR ON Threshold | | Note 3 | - | 1.1 | - | V |
| Equivalent SCR ON Resistance | | $V_{FWD}/I_{FWD}$; Note 3 | - | 1 | - | Ω |
| Input Capacitance | $C_{IN}$ | | - | 3 | - | pF |
| Input Switching Speed | $t_{ON}$ | | - | 2 | - | ns |

Notes:
2. In automotive and battery operated systems, the power supply lines should be externally protected for load dump and everse battery V+ and V- pins are connected to the same supply voltage source as the device or control line under protection, a current limiting resistor should be connected in series between the external supply and the SP720 supply pins to limit reverse battery current to within the rated maximum limits. Bypass capacitors of typically 0.01μF or larger from the V+ and V- pins to ground are recommended.
3. Refer to the Figure 3 graph for definitions of equivalent "SCR ON Threshold" and "SCR ON Resistance." These characteristics are given here for thumb-rule nformation to determine peak current and dissipation under EOS conditions.

## Typical Application of the SP720

(Application as an Input Clamp for Over-voltage, greater than 1$V_{BE}$ Above V+ or less than -1$V_{BE}$ below V-)

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## ESD Capability

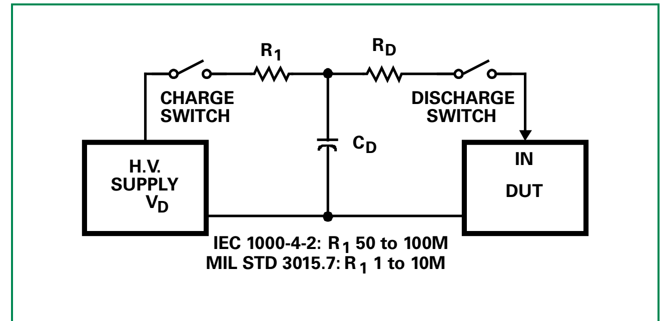
ESD capability is dependent on the application and defined test standard. The evaluation results for various test standards and methods based on Figure 1 are shown in Table 1.

For the "Modified" MIL-STD-3015.7 condition that is defined as an "in-circuit" method of ESD testing, the V+ and V- pins have a return path to ground and the SP720 ESD capability is typically greater than 15kV from 100pF through 1.5kΩ. By strict definition of MIL-STD-3015.7 using "pin-to-pin" device testing, the ESD voltage capability is greater than 6kV. The MIL-STD-3015.7 results were determined from AT&T ESD Test Lab measurements.

The HBM capability to the IEC 61000-4-2 standard is greater than 15kV for air discharge (Level 4) and greater than 4kV for direct discharge (Level 2). Dual pin capability (2 adjacent pins in parallel) is well in excess of 8kV (Level 4).

For ESD testing of the SP720 to EIAJ IC121 Machine Model (MM) standard, the results are typically better than 1kV from 200pF with no series resistance.

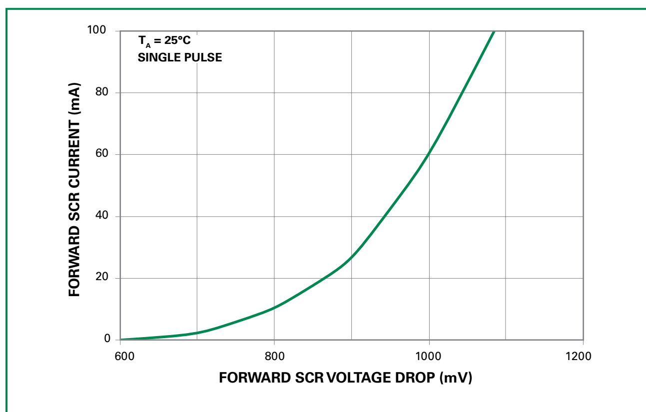
### Figure 1: Electrostatic Discharge Test



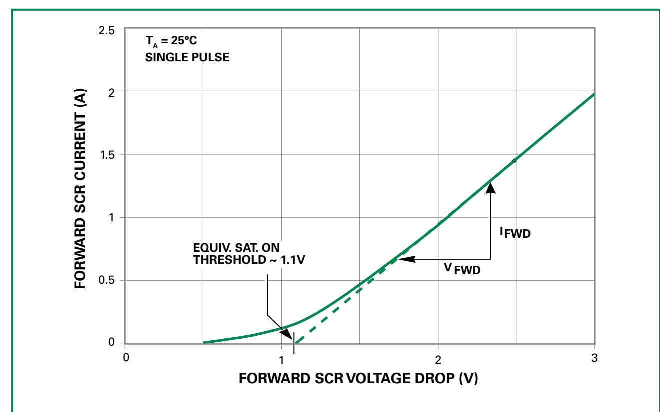

### Table 1: ESD Test Conditions

| Standard | Type/Mode | $R_D$ | $C_D$ | $\pm V_D$ |
|---|---|---|---|---|
| MIL STD 3015.7 | Modified HBM | 1.5kΩ | 100pF | 15kV |
| | Standard HBM | 1.5kΩ | 100pF | 6kV |
| IEC 61000-4-2 | HBM, Air Discharge | 330Ω | 150pF | 15kV |
| | HBM, Direct Discharge | 330Ω | 150pF | 4kV |
| | HBM, Direct Discharge, Two Parallel Input Pins | 330Ω | 150pF | 8kV |
| EIAJ IC121 | Machine Model | 0kΩ | 200pF | 1kV |

### Figure 2: Low Current SCR Forward Voltage Drop Curve




### Figure 3: High Current SCR Forward Voltage Drop Curve

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## Peak Transient Current Capability for Long Duration Surges

The peak transient current capability rises sharply as the width of the current pulse narrows. Destructive testing was done to fully evaluate the SP720's ability to withstand a wide range of transient current pulses. The circuit used to generate current pulses is shown in Figure 4.

The test circuit of Figure 4 is shown with a positive pulse input. For a negative pulse input, the (-) current pulse input goes to an SP720 'IN' input pin and the (+) current pulse input goes to the SP720 V- pin. The V+ to V- supply of the SP720 must be allowed to float. (i.e., It is not tied to the ground reference of the current pulse generator.) Figure 5 shows the point of overstress as defined by increased leakage in excess of the data sheet published limits.

The maximum peak input current capability is dependent on the V+ to V- voltage supply level, improving as the supply voltage is reduced. Values of 0, 5, 15 and 30 voltages are shown. The safe operating range of the transient peak current should be limited to no more than 75% of the measured overstress level for any given pulse width as shown in Figure 5.

When adjacent input pins are paralleled, the sustained peak current capability is increased to nearly twice that of a single pin. For comparison, tests were run using dual pin combinations 1+2, 3+4, 5+6, 7+9, 10+11, 12+13 and 14+15.

The overstress curve is shown in Figure 5 for a 15V supply condition. The dual pins are capable of 10A peak current for a 10µs pulse and 4A peak current for a 1ms pulse. The complete for single pulse peak current vs. pulse width time ranging up to 1 second are shown in Figure 5.

**Figure 4: Typical SP720 Peak Current Test Circuit with a Variable Pulse Width Input**

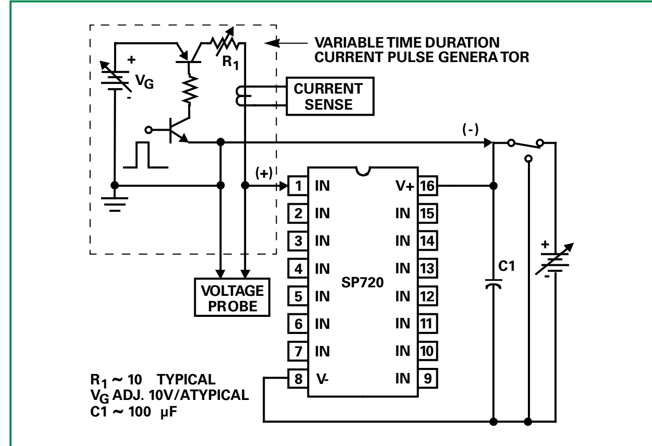
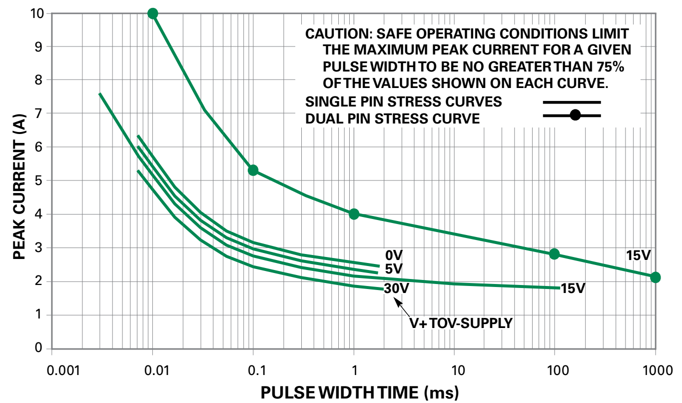



**Figure 5: SP720 Typical Nonrepetitive Peak Current Pulse Capability**

Showing the Measured Point of Overstress in Amperes vs pulse width time in milliseconds ($T_A$ = 25°C)

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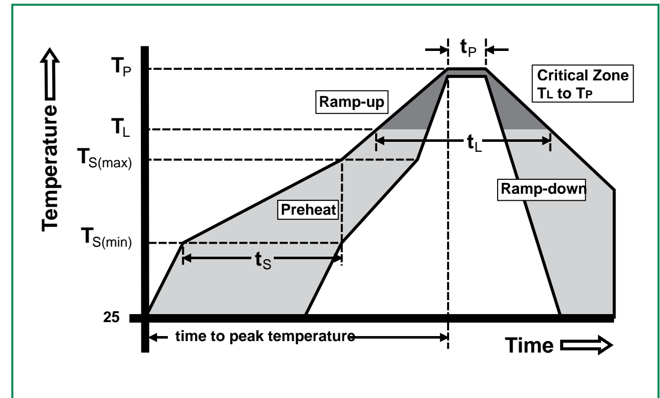
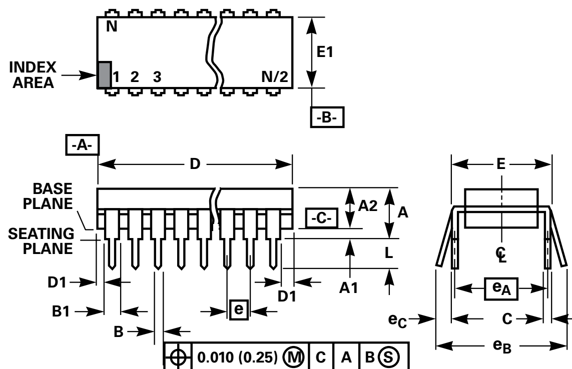
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions Dual-In-Line Plastic Packages (PDIP)




| Package | PDIP | | | | |
|---|---|---|---|---|---|
| Pins | 16 Lead Dual-in-Line | | | | |
| JEDEC | MS-001 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | - | 5.33 | - | 0.210 | 4 |
| **A1** | 0.39 | - | 0.015 | - | 4 |
| **A2** | 2.93 | 4.95 | 0.115 | 0.195 | - |
| **B** | 0.356 | 0.558 | 0.014 | 0.022 | - |
| **B1** | 1.15 | 1.77 | 0.045 | 0.070 | 8, 10 |
| **C** | 0.204 | 0.355 | 0.008 | 0.014 | - |
| **D** | 18.66 | 19.68 | 0.735 | 0.775 | 5 |
| **D1** | 0.13 | - | 0.005 | - | 5 |
| **E** | 7.62 | 8.25 | 0.300 | 0.325 | 6 |
| **E1** | 6.10 | 7.11 | 0.240 | 0.280 | 5 |
| **e** | 2.54 BSC | | 0.100 BSC | | - |
| **$e_A$** | 7.62 BSC | | 0.300 BSC | | 6 |
| **$e_B$** | - | 10.92 | - | 0.430 | 7 |
| **L** | 2.93 | 3.81 | 0.115 | 0.150 | 4 |
| **N** | 16 | | 16 | | 9 |

Notes:

1. Controlling Dimensions: INCH. in case of conflict between English and Metric dimensions, the inch dimensions control.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
4. Dimensions A, A1 and L are measured with the package seated in JE-DEC seating plane gauge GS-3.
5. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
6. E and $e_A$ are measured with the leads constrained to be perpendicular to datum -C-.
7. $e_B$ and $e_C$ are measured at the lead tips with the leads unconstrained. $e_C$ must be zero or greater.
8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
9. N is the maximum number of terminal positions.
10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

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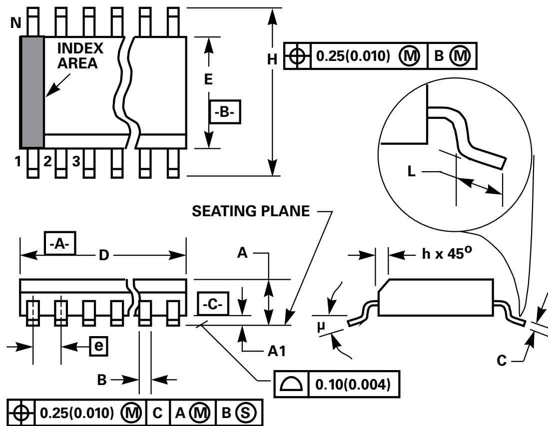
## Package Dimensions — Small Outline Plastic Packages (SOIC)

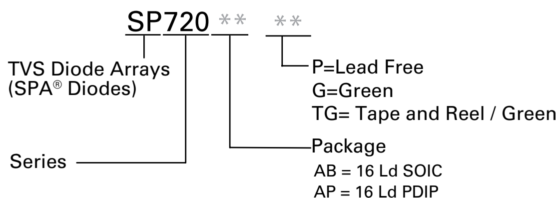



| Package | SOIC | | | | |
|---|---|---|---|---|---|
| Pins | 16 | | | | |
| JEDEC | MS-012 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 1.35 | 1.75 | 0.0532 | 0.0688 | - |
| **A1** | 0.10 | 0.25 | 0.0040 | 0.0098 | - |
| **B** | 0.33 | 0.51 | 0.013 | 0.020 | 9 |
| **C** | 0.19 | 0.25 | 0.0075 | 0.0098 | - |
| **D** | 9.80 | 10.00 | 0.3859 | 0.3937 | 3 |
| **E** | 3.80 | 4.00 | 0.1497 | 0.1574 | 4 |
| **e** | 1.27 BSC | | 0.050 BSC | | - |
| **H** | 5.80 | 6.20 | 0.2284 | 0.2440 | - |
| **h** | 0.25 | 0.50 | 0.0099 | 0.0196 | 5 |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 | 6 |
| **N** | 16 | | 16 | | 7 |
| **μ** | 0° | 8° | 0° | 8° | - |

Notes:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension:MILLIMETER. Converted inch dimensions are not necessarily exact.

## Part Numbering System




See Ordering Information section for specific options available

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

## Ordering Information

| Part Number | Temp. Range (°C) | Package | Environmental Informaton | Marking | Min. Order |
|---|---|---|---|---|---|
| SP720APP | -40 to 105 | 16 Ld PDIP | Lead-free | SP720AP(P) [1] | 1500 |
| SP720ABG | -40 to 105 | 16 Ld SOIC | Green | SP720A(B)G [2] | 1920 |
| SP720ABTG | -40 to 105 | 16 Ld SOIC Tape and Reel | Green | SP720A(B)G [2] | 2500 |

Notes:

1. SP720AP(P) means device marking either SP720AP or SP720APP.
2. SP720A(B)G means device marking either SP720AG or SP720ABG which are good for types SP720ABG and SP720ABTG.

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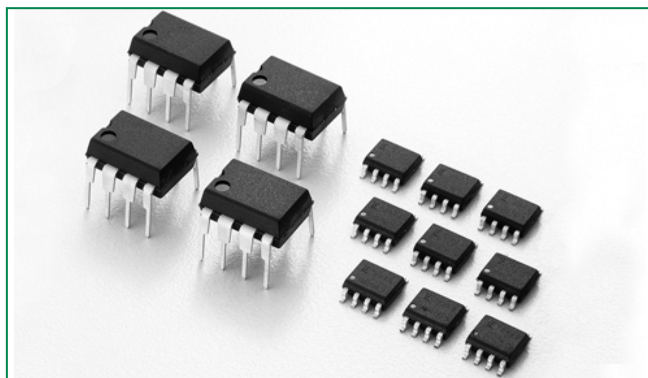
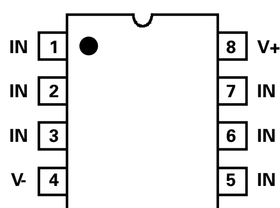
# SP721 Series 3pF 4kV Diode Array

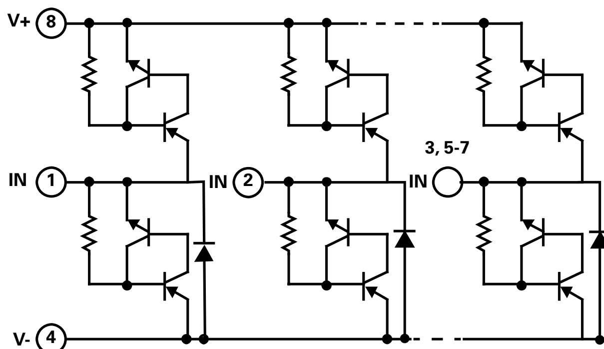
RoHS Pb GREEN



## Pinout




## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

## Description

The SP721 is an array of SCR/Diode bipolar structures for ESD and over-voltage protection to sensitive input circuits. The SP721 has 2 protection SCR/Diode device structures per input. There are a total of 6 available inputs that can be used to protect up to 6 external signal or bus lines. Over-voltage protection is from the IN (Pins 1 - 3 and Pins 5 - 7) to V+ or V-.

The SCR structures are designed for fast triggering at a threshold of one $+V_{BE}$ diode threshold above V+ (Pin 8) or a $-V_{BE}$ diode threshold below V- (Pin 4). From an IN input, a clamp to V+ is activated if a transient pulse causes the input to be increased to a voltage level greater than one $V_{BE}$ above V+. A similar clamp to V- is activated if a negative pulse, one $V_{BE}$ less than V-, is applied to an IN input. Standard ESD Human Body Model (HBM) Capability is:

## Features

- ESD Interface Capability for HBM Standards
  - MIL STD 3015.7 ............ 15kV
  - IEC 61000-4-2, Direct Discharge,
  - Single Input ............ 4kV (Level 2)
  - Two Inputs in Parallel ............ 8kV (Level 4)
  - IEC 61000-4-2, Air Discharge ............ 15kV (Level 4)
- High Peak Current Capability
  - IEC 61000-4-5 (8/20μs) ............ ±3A
  - Single Pulse, 100μs Pulse Width ............ ±2A
  - Single Pulse, 4μs Pulse Width ............ ±5A
- Designed to Provide Over-Voltage Protection
  - Single-Ended Voltage Range to ............ +30V
  - Differential Voltage Range to ............ ±15V
- Fast Switching ............ 2ns Rise Time
- Low Input Leakages ............ 1nA at 25°C Typical
- Low Input Capacitance ............ 3pF Typical
- An Array of 6 SCR/Diode Pairs
- Operating Temperature Range ............ -40°C to 105°C

## Applications

- Microprocessor/Logic Input Protection
- Data Bus Protection
- Analog Device Input Protection
- Voltage Clamp

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Continuous Supply Voltage, (V+) - (V-) | +35 | V |
| Forward Peak Current, $I_{IN}$ to $V_{CC}$, $I_{IN}$ to GND (Refer to Figure 5) | ±2, 100μs | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

Note:

ESD Ratings and Capability (Figure 1, Table 1)

Load Dump and Reverse Battery (Note 2)

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Thermal Resistance (Typical, Note 1) | $\theta_{JA}$ | °C/W |
| PDIP Package | 160 | °C/W |
| SOIC Package | 170 | °C/W |
| Maximum Storage Temperature Range | -65 to 150 | °C |
| Maximum Junction Temperature (Plastic Package) | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s)(SOIC Lead Tips Only) | 260 | °C |

1. $\theta_{JA}$ is measured with the component mounted on an evaluation PC board in free air.

## Electrical Characteristics $T_A$ = -40°C to 105°C, $V_{IN}$ = 0.5$V_{CC}$ , Unless Otherwise Specified

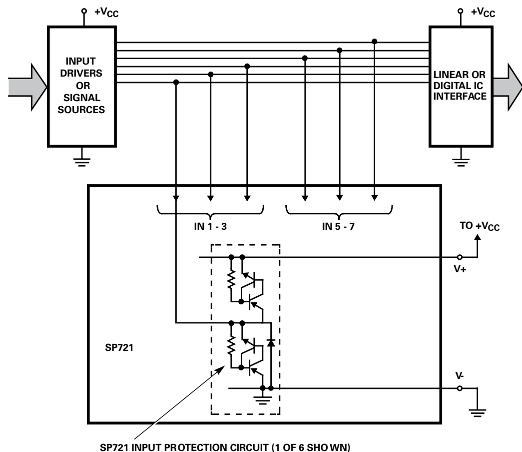
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Operating Voltage Range, | $V_{SUPPLY}$ | | - | 2 to 30 | - | V |
| $V_{SUPPLY}$ = [(V+) - (V-)] | | | | | | |
| Forward Voltage Drop | | | | | | |
| IN to V- | $V_{FWDL}$ | $I_{IN}$ = 1A (Peak Pulse) | - | 2 | - | V |
| IN to V+ | $V_{FWDH}$ | | - | 2 | - | V |
| Input Leakage Current | $I_{IN}$ | | -20 | 5 | +20 | nA |
| Quiescent Supply Current | $I_{QUIESCENT}$ | | - | 50 | 200 | nA |
| Equivalent SCR ON Threshold | | Note 3 | - | 1.1 | - | V |
| Equivalent SCR ON Resistance | | $V_{FWD}/I_{FWD}$; Note 3 | - | 1 | - | Ω |
| Input Capacitance | $C_{IN}$ | | - | 3 | - | pF |
| Input Switching Speed | $t_{ON}$ | | - | 2 | - | ns |

Notes:

2. In automotive and battery operated systems, the power supply lines should be externally protected for load dump and reverse battery. When the V+ and V- Pins are connected to het same supply voltage source as the device or control line under protection, a current limiti ng resistor should be connected in series between the external supply and the SP721 supply pins to limit reverse battery current to within the rated maximum limits. Bypass capacitors of typically 0.01μF or larger romf the V+ and V- Pins to ground are recommended.
3. Refer to the Figure 3 graph for definitions of equivalent "SCR ON Threshold" and "SCR ON Resistance". These characteristics are given here for thumb-rule nformation to determine peak current and dissipation under EOS conditions.

## Typical Application of the SP721

(Application as an Input Clamp for Over-voltage, Greater than 1$V_{BE}$ Above V+ or less than -1$V_{BE}$ below V-)

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## ESD Capability

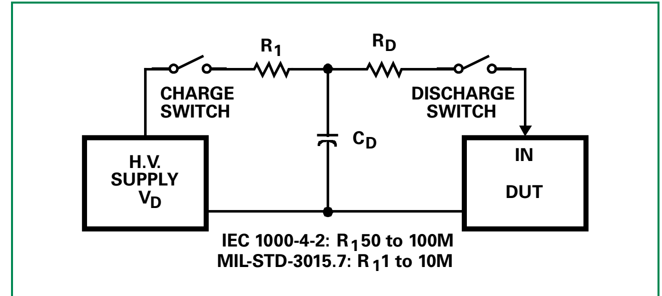
ESD capability is dependent on the application and defined test standard.The evaluation results for various test standards and methods based on Figure 1 are shown in Table 1.

For the "Modified"MIL-STD-3015.7 condition that is defined as an "in-circuit" method of ESD testing, the V+ and V- pins have a return path to ground and the SP721 ESD capability is typically greater than 15kV from 100pF through 1.5kΩ.By strict definition of MIL-STD-3015.7 using "pin-to-pin"device testing, the ESD voltage capability is greater than 6kV.The MIL-STD-3015.7 results were determined from AT&T ESD Test Lab measurements.

The HBM capability to the IEC 61000-4-2 standard is greater than 15kV for air discharge (Level 4) and greater than 4kV for direct discharge (Level 2).Dual pin capability (2 adjacent pins in parallel) is well in excess of 8kV (Level 4).

For ESD testing of the SP721 to EIAJ IC121 Machine Model (MM) standard, the results are typically better than 1kV from 200pF with no series resistance.

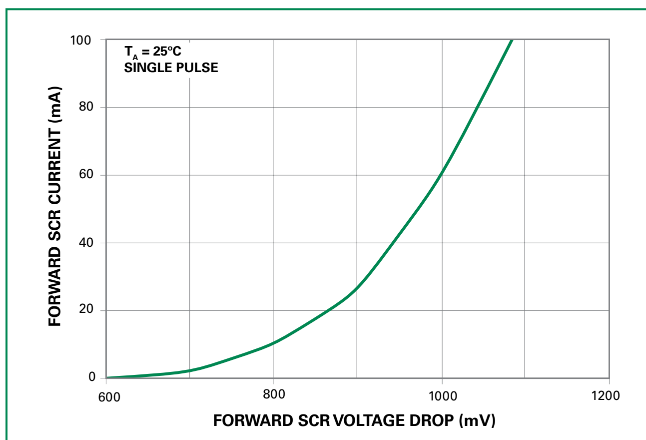
### Figure 1: Electrostatic Discharge Test



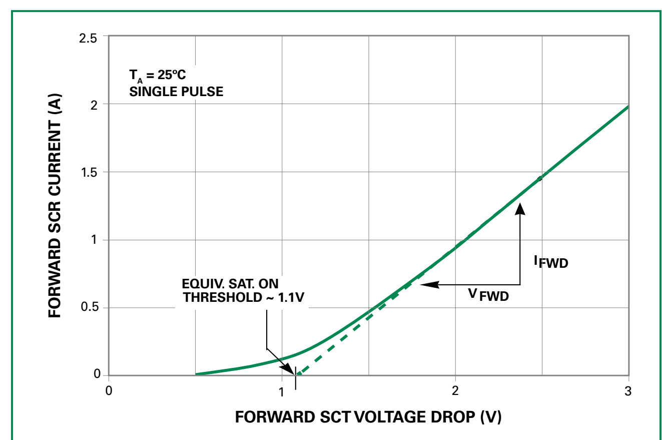

### Table 1: ESD Test Conditions

| Standard | Type/Mode | $R_D$ | $C_D$ | $\pm V_D$ |
|---|---|---|---|---|
| MIL STD 3015.7 | Modified HBM | 1.5kΩ | 100pF | 15kV |
| | Standard HBM | 1.5kΩ | 100pF | 6kV |
| IEC 61000-4-2 | HBM, Air Discharge | 330Ω | 150pF | 15kV |
| | HBM, Direct Discharge | 330Ω | 150pF | 4kV |
| | HBM, Direct Discharge, Two Parallel Input Pins | 330Ω | 150pF | 8kV |
| EIAJ IC121 | Machine Model | 0kΩ | 200pF | 1kV |

### Figure 2: Low Current SCR Forward Voltage Drop Curve




### Figure 3: High Current SCR Forward Voltage Drop Curve

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## Peak Transient Current Capability of the SP721

The peak transient current capability rises sharply as the width of the current pulse narrows. Destructive testing was done to fully evaluate the SP721's ability to withstand a wide range of peak current pulses vs time. The circuit used to generate current pulses is shown in Figure 4.

The test circuit of Figure 4 is shown with a positive pulse input. For a negative pulse input, the (-) current pulse input goes to an SP721 'IN' input pin and the (+) current pulse input goes to the SP721 V- pin. The V+ to V- supply of the SP721 must be allowed to float. (i.e., It is not tied to the ground reference of the current pulse generator.) Figure 5 shows the point of overstress as defined by increased leakage in excess of the data sheet published limits.

The maximum peak input current capability is dependent on the ambient temperature, improving as the temperature is reduced. Peak current curves are shown for ambient temperatures of 25°C and 105°C and a 15V power supply condition. The safe operating range of the transient peak current should be limited to no more than 75% of the measured overstress level for any given pulse width as shown in the curves of Figure 5.

Note that adjacent input pins of the SP721 may be paralleled to improve current (and ESD) capability. The sustained peak current capability is increased to nearly twice that of a single pin.

**Figure 4: Typical SP721 Peak Current Test Circuit with a Variable Pulse Width Input**

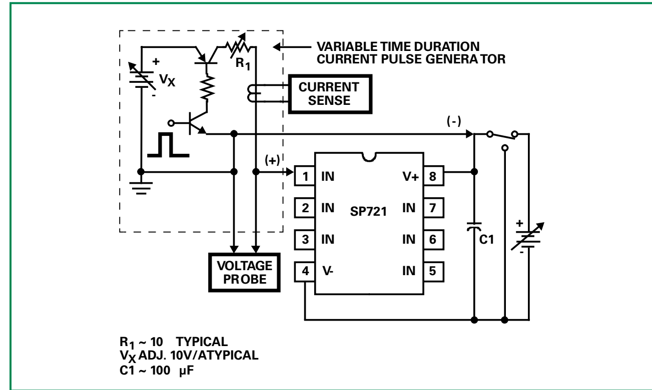
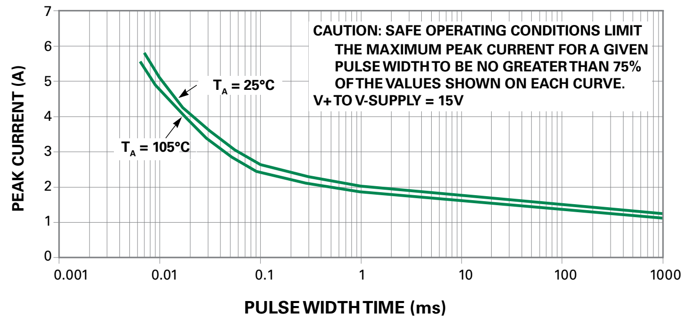



**Figure 5: SP721 Typical Single Peak Current Pulse Capability**

Showing the Measured Point of Overstress in Amperes vs pulse width time in milliseconds



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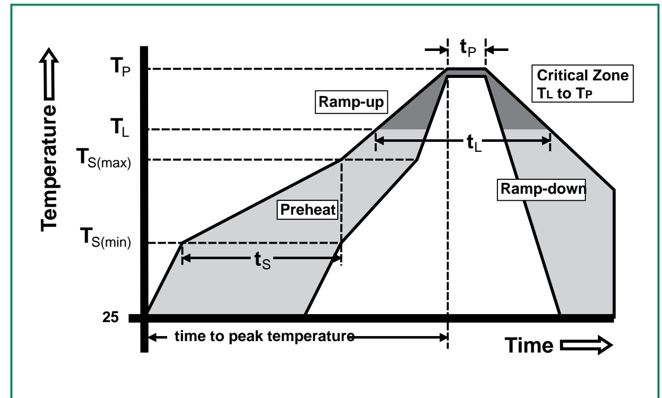
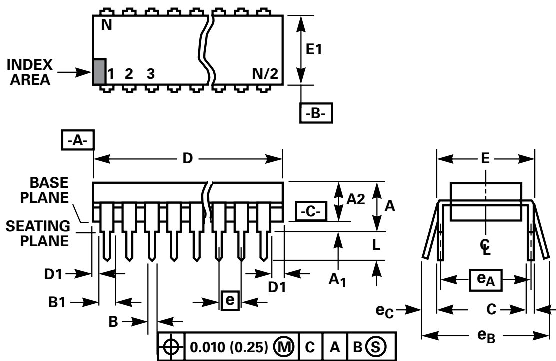
Expertise Applied | Answers Delivered

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — Dual-In-Line Plastic Packages (PDIP)




Notes:

1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
5. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
6. E and $e_A$ are measured with the leads constrained to be perpendicular to datum -C- .
7. $e_B$ and $e_C$ are measured at the lead tips with the leads unconstrained. $e_C$ must be zero or greater.
8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
9. N is t he maximum number of terminal positions.
10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

| Package | PDIP | | | | |
|---|---|---|---|---|---|
| Pins | 8 Lead Dual-in-Line | | | | |
| JEDEC | MS-001 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | - | 5.33 | - | 0.210 | 4 |
| **A1** | 0.39 | - | 0.015 | - | 4 |
| **A2** | 2.93 | 4.95 | 0.115 | 0.195 | - |
| **B** | 0.356 | 0.558 | 0.014 | 0.022 | - |
| **B1** | 1.15 | 1.77 | 0.045 | 0.070 | 8, 10 |
| **C** | 0.204 | 0.355 | 0.008 | 0.014 | - |
| **D** | 9.01 | 10.16 | 0.355 | 0.400 | 5 |
| **D1** | 0.13 | - | 0.005 | - | 5 |
| **E** | 7.62 | 8.25 | 0.300 | 0.325 | 6 |
| **E1** | 6.10 | 7.11 | 0.240 | 0.280 | 5 |
| **e** | 2.54 BSC | | 0.100 BSC | | - |
| **$e_A$** | 7.62 BSC | | 0.300 BSC | | 6 |
| **$e_B$** | - | 10.92 | - | 0.430 | 7 |
| **L** | 2.93 | 3.81 | 0.115 | 0.150 | 4 |
| **N** | 8 | | 8 | | 9 |

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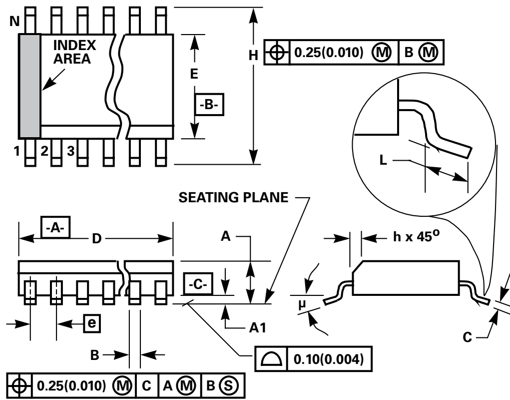
## Package Dimensions — Small Outline Plastic Packages (SOIC)

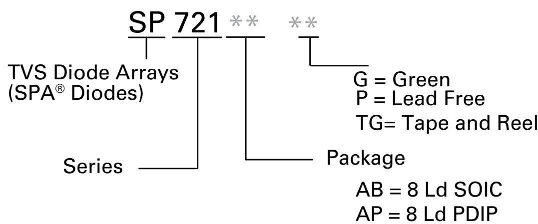



| Package | SOIC | | | | |
|---|---|---|---|---|---|
| Pins | 8 | | | | |
| JEDEC | MS-012 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 1.35 | 1.75 | 0.0532 | 0.0688 | - |
| **A1** | 0.10 | 0.25 | 0.0040 | 0.0098 | - |
| **B** | 0.33 | 0.51 | 0.013 | 0.020 | 9 |
| **C** | 0.19 | 0.25 | 0.0075 | 0.0098 | - |
| **D** | 4.80 | 5.00 | 0.1890 | 0.1968 | 3 |
| **E** | 3.80 | 4.00 | 0.1497 | 0.1574 | 4 |
| **e** | 1.27 BSC | | 0.050 BSC | | - |
| **H** | 5.80 | 6.20 | 0.2284 | 0.2440 | - |
| **h** | 0.25 | 0.50 | 0.0099 | 0.0196 | 5 |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 | 6 |
| **N** | 8 | | 8 | | 7 |
| **μ** | 0° | 8° | 0° | 8° | - |

Notes:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Inter-lead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

## Part Numbering System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

## Ordering Information

| Part Number | Temp. Range (°C) | Package | Environmental Informaton | Marking | Min. Order |
|---|---|---|---|---|---|
| SP721APP | -40 to 105 | 8 Ld PDIP | Lead-free | SP721AP(P) 1 | 2000 |
| SP721ABG | -40 to 105 | 8 Ld SOIC | Green | SP721A(B)G 2 | 1960 |
| SP721ABTG | -40 to 105 | 8 Ld SOIC Tape and Reel | Green | SP721A(B)G 2 | 2500 |

Notes:

1. SP721AP(P) means device marking either SP721AP or SP721APP.
2. SP721A(B)G means device marking either SP721AG or SP721ABG which are good for types SP721ABG and SP721ABTG.

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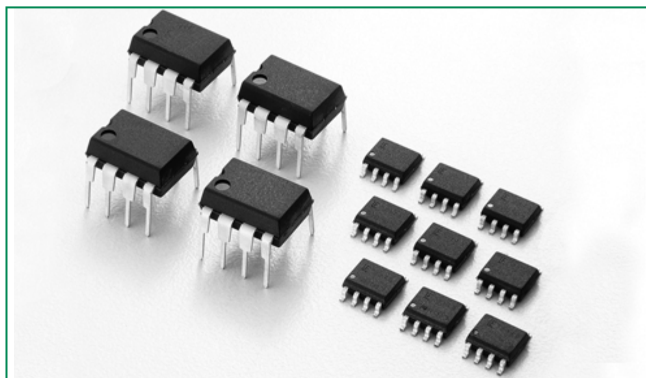
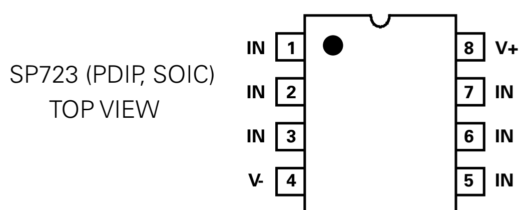
# SP723 Series 5pF 8kV Diode Array

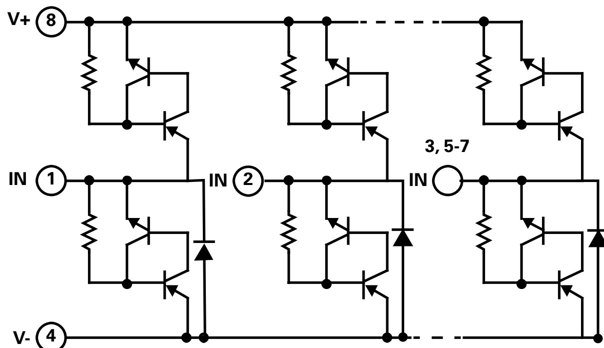
RoHS Pb GREEN



## Pinout




## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

## Description

The SP723 is an array of SCR/Diode bipolar structures for ESD and over-voltage protection of sensitive input circuits. The SP723 has 2 protection SCR/Diode device structures per input. There are a total of 6 available inputs that can be used to protect up to 6 external signal or bus lines. Over-voltage protection is from the IN (Pins 1 - 3 and Pins 5 - 7) to V+ or V-.

The SCR structures are designed for fast triggering at a threshold of one $+V_{BE}$ diode threshold above V+ (Pin 8) or a $-V_{BE}$ diode threshold below V- (Pin 4). From an IN input, a clamp to V+ is activated if a transient pulse causes the input to be increased to a voltage level greater than one $V_{BE}$ above V+. A similar clamp to V- is activated if a negative pulse, one $V_{BE}$ less than V-, is applied to an IN input.

Refer to Fig 1 and Table 1 for further details. Refer to Application Note AN9304 and AN9612 for further detail.

## Features

- ESD Interface per HBM Standards
  - IEC 61000-4-2, Direct Discharge .......... 8kV (Level 4)
  - IEC 61000-4-2, Air Discharge...............15kV (Level 4)
  - MIL-STD-3015.7 ................................................25kV
- Peak Current Capability
  - IEC 61000-4-5 8/20μs Peak Pulse Current.......... ±7A
  - Single Transient Pulse, 100μs Pulse Width ......... ±4A
- Designed to Provide Over-Voltage Protection
  - Single-Ended Voltage Range to ....................... +30V
  - Differential Voltage Range to ........................... ±15V
- Fast Switching.............................................2ns Risetime
- Low Input Leakages...........................2nA at 25°C Typical
- Low Input Capacitance....................................5pF Typical
- An Array of 6 SCR/Diode Pairs
- Operating Temperature Range....................-40°C to 105°C

## Applications

- Microprocessor/Logic Input Protection
- Data Bus Protection
- Analog Device Input Protection
- Voltage Clamp

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Continuous Supply Voltage, (V+) - (V-) | +35 | V |
| Forward Peak Current, $I_{IN}$ to $V_{CC}$, $I_{IN}$ to GND (Refer to Figure 5) | ±4, 100µs | A |
| Peak Pulse Current, 8/20µs | ±7 | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

Note:

ESD Ratings and Capability (Figure 1, Table 1)

Load Dump and Reverse Battery (Note 2)

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Thermal Resistance (Typical, Note 1) | $\theta_{JA}$ | °C/W |
| PDIP Package | 160 | °C/W |
| SOIC Package | 170 | °C/W |
| Storage Temperature Range | -65 to 150 | °C |
| Maximum Junction Temperature (Plastic Package) | 150 | °C |
| Lead Temperature (Soldering 20-40s) (SOIC Lead Tips Only) | 260 | °C |

1. $\theta_{JA}$ is measured with the component mounted on an evaluation PC board in free air.

## Electrical Characteristics $T_A$ = -40°C to 105°C, $V_{IN}$ = 0.5$V_{CC}$ , Unless Otherwise Specified

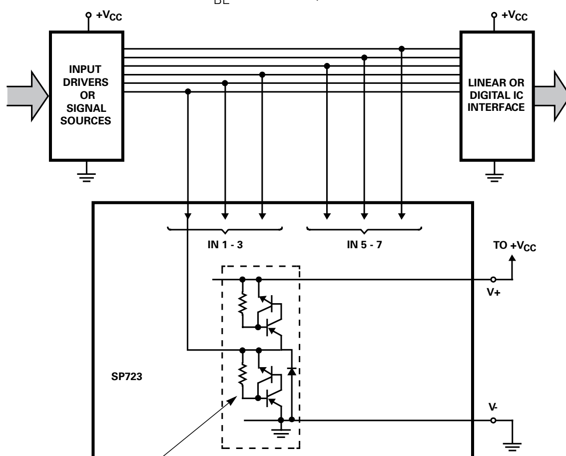
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Operating Voltage Range, $V_{SUPPLY}$ =[(V+)-(V-)] | $V_{SUPPLY}$ | | - | 2 to 30 | - | V |
| Forward Voltage Drop | | | | | | |
| IN to V- | $V_{FWDL}$ | $I_{IN}$=2A(Peak Pulse) | - | 2 | - | V |
| IN to V+ | $V_{FWDH}$ | | - | 2 | - | V |
| Input Leakage Current | $I_{IN}$ | | -20 | 5 | 20 | nA |
| Quiescent Supply Current | $I_{QUIESCENT}$ | | - | 50 | 200 | nA |
| Equivalent SCR ON Threshod | | Note 3 | - | 1.1 | - | V |
| Equivalent SCR ON Resistance | | $V_{FWD}/I_{FWD}$; Note 3 | - | 0.5 | - | Ω |
| Input Capacitance | $C_{IN}$ | | - | 5 | - | PF |
| Input Switching Speed | $t_{ON}$ | | - | 2 | - | ns |

Notes:

2. In automotive ans battery operated systems, the power supply lines should be externally protected for load dump and reverse battery. When the V+ and V- Pins are connected to the same supply voltage source as the device or control line under protection, acurrent limiting resistor should be connectied in series between the external supply and the SP723 supply pins to limit reverse battery current to within the rated maximum limits. Bypass capacitors of typically 0.01µF or larger from the V+ and V- Pins to ground are recommended.
3. Refer to the Figure 3 graph for determine peak current and dessipation under EOS conditions.

## Typical Application of the SP723

(Application as an Input Clamp for Over-voltage, Greater than 1$V_{BE}$ Above V+ or less than -1$V_{BE}$ below V-)

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## ESD Capability

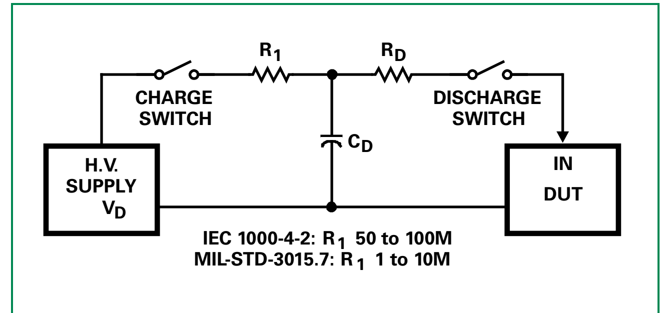
ESD capability is dependent on the application and defined test standard.The evaluation results for various test standards and methods based on Figure 1 are shown in Table 1.

The SP723 has a Level 4 HBM capability when tested as a device to the IEC 61000-4-2 standard. Level 4 specifies a required capability greater than 8kV for direct discharge and greater than 15kV for air discharge.

For the "Modified" MIL-STD-3015.7 condition that is defined as an "in-circuit" method of ESD testing, the V+ and V- pins have a return path to ground and the SP723 ESD capability is typically greater than 25kV from 100pF through 1.5kΩ. By strict definition of MIL-STD-3015.7 using "pin-to-pin" device testing, the ESD voltage capability is greater than 10kV.

For the SP723 EIAJ IC121 Machine Model (MM) standard, the ESD capability is typically greater than 2kV from 200pF with no series resistance.

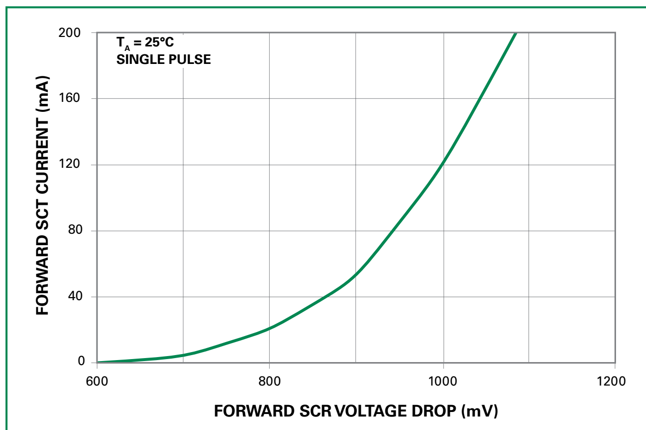
### Figure 1: Electrostatic Discharge Test



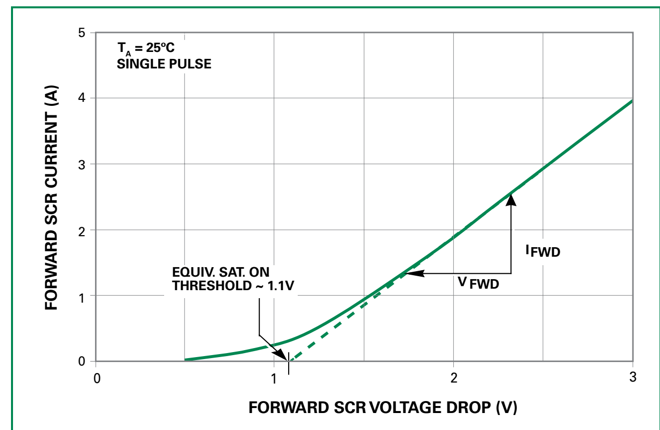

### Table 1: ESD Test Conditions

| Standard | Type/Mode | $R_D$ | $C_D$ | $\pm V_D$ |
|---|---|---|---|---|
| IEC 1000-4-2 (Level 4) | HBM, Air Discharge | 330 Ω | 150pF | 15kV |
| | HBM, Direct Discharge | 330 Ω | 150pF | 8kV |
| MIL-STD-3015.7 | Modified HBM | 1.5k Ω | 100pF | 25kV |
| | Standard HBM | 1.5k Ω | 100pF | 10kV |
| EIAJ IC121 | Machine Model | 0k Ω | 200pF | 2kV |
| EIAJ IC121 | Machine Model | 0kΩ | 200pF | 1kV |

### Figure 2: Low Current SCR Forward Voltage Drop Curve




### Figure 3: High Current SCR Forward Voltage Drop Curve

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## Peak Transient Current Capability of the SP723

The peak transient current capability rises sharply as the width of the current pulse narrows. Destructive testing was done to fully evaluate the SP723's ability to withstand a wide range of peak current pulses vs time. The circuit used to generate current pulses is shown in Figure 4.

The test circuit of Figure 4 is shown with a positive pulse input. For a negative pulse input, the (-) current pulse input goes to an SP723 'IN' input pin and the (+) current pulse input goes to the SP723 V- pin. The V+ to V- supply of the SP723 must be allowed to float. (i.e., It is not tied to the ground reference of the current pulse generator.) Figure 5 shows the point of overstress as defined by increased leakage in excess of the data sheet published limits.

The maximum peak input current capability is dependent on the ambient temperature, improving as the temperature is reduced. Peak current curves are shown for ambient temperatures of 25°C and 105°C and a 15V power supply condition. The safe operating range of the transient peak current should be limited to no more than 75% of the measured overstress level for any given pulse width as shown in the curves of Figure 5.

Note that adjacent input pins of the SP723 may be paralleled to improve current (and ESD) capability. The sustained peak current capability is increased to nearly twice that of a single pin.

**Figure 4: Typical SP723 Peak Current Test Circuit with a Variable Pulse Width Input**

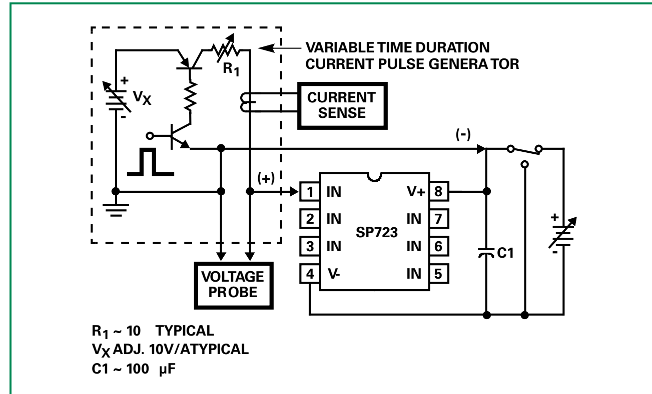
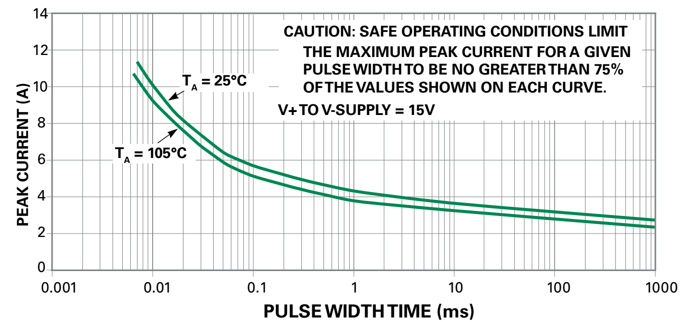



**Figure 5: SP723 Typical Single Peak Current Pulse Capability**

Showing the Measured Point of Overstress in Amperes vs pulse width time in milliseconds

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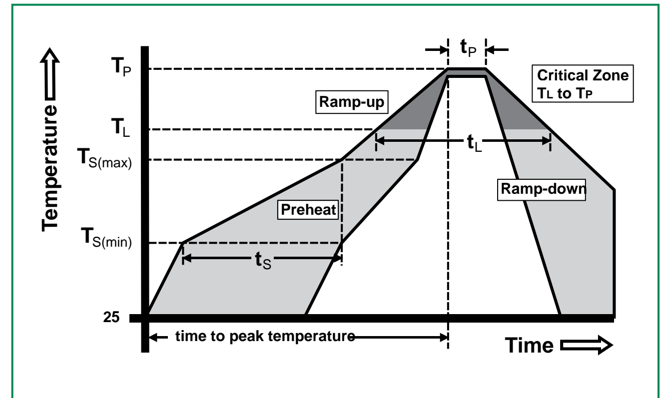
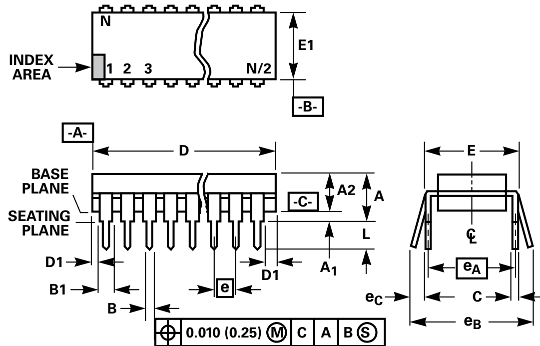
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — Dual-In-Line Plastic Packages (PDIP)




| Package | PDIP | | | | |
|---|---|---|---|---|---|
| Pins | 8 | | | | |
| JEDEC | MS-001 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| A | - | 5.33 | - | 0.210 | 4 |
| A1 | 0.39 | - | 0.015 | - | 4 |
| A2 | 2.93 | 4.95 | 0.115 | 0.195 | - |
| B | 0.356 | 0.558 | 0.014 | 0.022 | - |
| B1 | 1.15 | 1.77 | 0.045 | 0.070 | 8, 10 |
| C | 0.204 | 0.355 | 0.008 | 0.014 | - |
| D | 9.01 | 10.16 | 0.355 | 0.400 | 5 |
| D1 | 0.13 | - | 0.005 | - | 5 |
| E | 7.62 | 8.25 | 0.300 | 0.325 | 6 |
| E1 | 6.1 | 7.11 | 0.240 | 0.280 | 5 |
| e | 2.54 BSC | | 0.100 BSC | | - |
| $e_A$ | 7.62 BSC | | 0.300 BSC | | 6 |
| $e_B$ | - | 10.92 | - | 0.430 | 7 |
| L | 2.93 | 3.81 | 0.115 | 0.150 | 4 |
| N | 8 | | 8 | | 9 |

Notes:

1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
5. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
6. E and $e_A$ are measured with the leads unconstrained to be perpendicular to datum -C-.
7. $e_B$ and $e_C$ are measured at the lead tips with the leads uncon-strained. $e_C$ must be zero or greater.
8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
9. N is the maximum number of terminal positions.
10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

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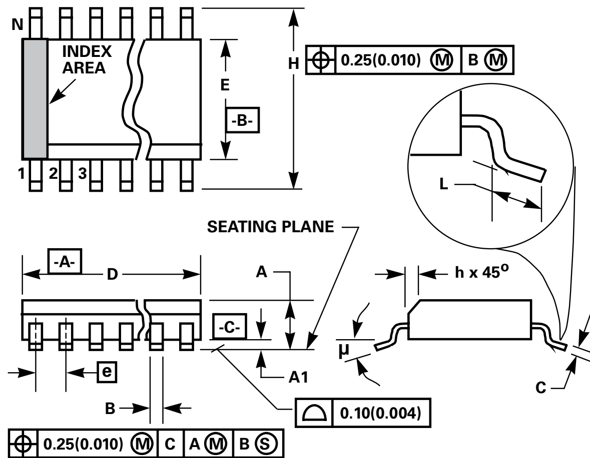
## Package Dimensions — Small Outline Plastic Packages (SOIC)

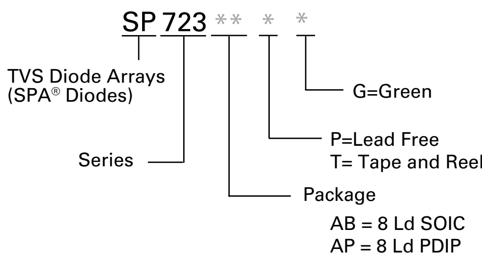



| Package | SOIC | | | | |
|---|---|---|---|---|---|
| Pins | 8 | | | | |
| JEDEC | MS-012 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 1.35 | 1.75 | 0.0532 | 0.0688 | - |
| **A1** | 0.10 | 0.25 | 0.0040 | 0.0098 | - |
| **B** | 0.33 | 0.51 | 0.013 | 0.020 | 9 |
| **C** | 0.19 | 0.25 | 0.0075 | 0.0098 | - |
| **D** | 4.80 | 5.00 | 0.1890 | 0.1968 | 3 |
| **E** | 3.80 | 4.00 | 0.1497 | 0.1574 | 4 |
| **e** | 1.27 BSC | | 0.050 BSC | | - |
| **H** | 5.80 | 6.20 | 0.2284 | 0.2440 | - |
| **h** | 0.25 | 0.50 | 0.0099 | 0.0196 | 5 |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 | 6 |
| **N** | 8 | | 8 | | 7 |
| **μ** | 0° | 8° | 0° | 8° | - |

Notes:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Inter-lead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The eadl width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension:MILLIMETER. Converted inch dimensions are not necessarily exact.

## Part Numbering System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

## Ordering Information

| Part Number | Temp. Range (°C) | Package | Environmental Informaton | Marking | Min. Order |
|---|---|---|---|---|---|
| SP723APP | -40 to 105 | 8 Ld PDIP | Lead-free | SP723AP(P) [1] | 2000 |
| SP723ABG | -40 to 105 | 8 Ld SOIC | Green | SP723A(B)G [2] | 1960 |
| SP723ABTG | -40 to 105 | 8 Ld SOIC Tape and Reel | Green | SP723A(B)G [2] | 2500 |

Notes:

1. SP723AP(P) means device marking either SP723AP or SP723APP.
2. SP723A(B)G means device marking either SP723AG or SP723ABG which are good for types SP723ABG and SP723ABTG.

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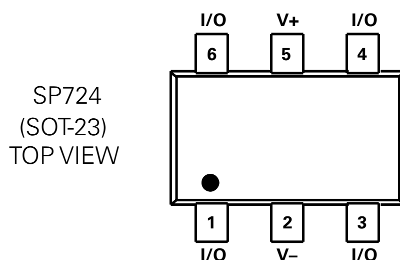
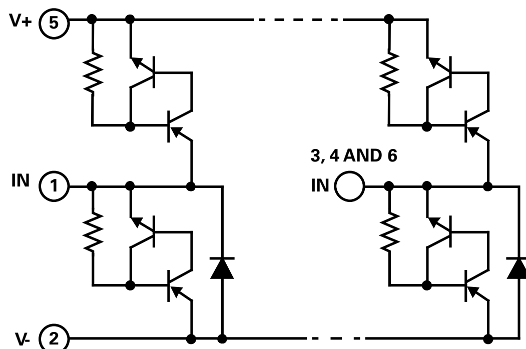
# SP724 Series 3pF 8kV Diode Array

RoHS Pb GREEN

## Pinout




## Functional Block Diagram




Notes:

1. The design of the SP724 SCR/Diode ESD Protection Arrays are covered by Littelfuse patent 4567500.
2. The full ESD capability of the SP724 is achieved when wired in a circuit that includes connection to both the V+ and V- pins. When handling individual devices, follow proper procedures for electrostatic discharge.

## Description

The SP724 is a quad array of transient voltage clamping circuits designed to suppress ESD and other transient over-voltage events. The SP724 is used to help protect sensitive digital or analog input circuits on data, signal, or control lines operating on power supplies up to 20VDC.

The SP724 is comprised of bipolar SCR/diode structures to protect up to four independent lines by clamping transients of either polarity to the power supply rails. The SP724 offers very low leakage (1nA Typical) and low input capacitance (3pF Typical). Additionally, the SP724 is rated to withstand the IEC 61000-4-2 ESD specification for both contact and air discharge methods to level 4.

The SP724 is connected to the sensitive input line and its associated power supply lines. Clamping action occurs during the transient pulse, turning on the diode and fast triggering SCR structures when the voltage on the input line exceeds one $V_{BE}$ threshold above the V+ supply (or one $V_{BE}$ threshold below the V- supply). Therefore, the SP724P operation is unaffected by poor power supply regulation or voltage fluctuations within its operating range.

## Features

- An Array of 4 SCR/Diode Pairs in 6-Lead SOT-23
- ESD Capability per HBM Standards
  - IEC 61000-4-2, Direct Discharge .......... 8kV (Level 4)
  - IEC 61000-4-2, Air Discharge...............15kV (Level 4)
  - MIL STD 3015.7.............................................. >8kV
- Input Protection for Applications with Power Supplies Up to +20V (Single-Ended Voltage), and ±10V (Differential Voltage)
- Peak Current Capability
  - IEC 61000-4-5 (8/20μs) ...................................... ±3A
  - Single Pulse, 100μs Pulse Width ..................... ±2.2A
- Low Input Leakage........................................ 1nA Typical
- Low Input Capacitance....................................3pF Typical
- Operating Temperature Range....................-40°C to 105°C

## Applications

- Microprocessor/Logic Input Protection
- Data Bus Protection
- Analog Device Input Protection
- Voltage Clamp

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Continuous Supply Voltage, (V+) - (V-) | +20 | V |
| Forward Peak Current, $I_{IN}$ to $V_{CC}$ , GND (Refer to Figure 5) | ±2.2, 100μs | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

Note:

ESD Ratings and Capability - See Figure 1, Table 1

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Thermal Resistance (Typical, Note 3) | $\theta_{JA}$ | °C/W |
| SOT Package | 220 | °C/W |
| Maximum Storage Temperature Range | -65 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOT - Lead Tips Only) | 260 | °C |

Note: 3. $\theta_{JA}$ is measured with the component mounted on an evaluation PC board in free air.

## Electrical Characteristics $T_A$ = -40°C to 105°C, $V_{IN}$ = 0.5$V_{CC}$ , Unless Otherwise Specified

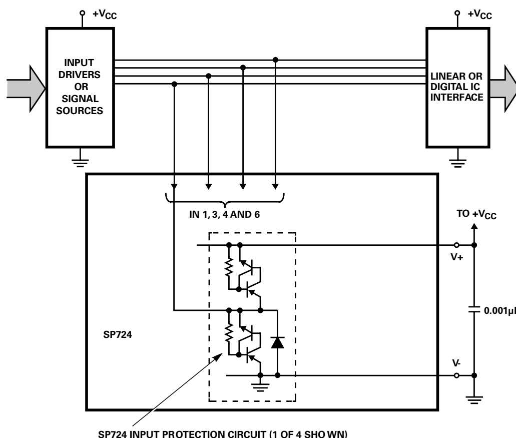
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Operating Voltage Range, $V_{SUPPLY}$ = [(V+) - (V-)] (Notes 4, 5) | $V_{SUPPLY}$ | | 1 | - | 20 | V |
| Forward Voltage Drop | | | | | | |
| Forward Voltage Drop IN to V- | $V_{FWDL}$ | $I_{IN}$ = 1A (Peak Pulse) | - | 2 | - | V |
| IN to V+ | $V_{FWDH}$ | | - | 2 | - | V |
| Input Leakage Current | $I_{IN}$ | | -10 | 1 | 10 | nA |
| Quiescent Supply Current | $I_{QUIESCENT}$ | V+ = 20V, V- = GND | - | - | 100 | nA |
| Equivalent SCR ON Threshold | | (Note 6) | - | 1.1 | - | V |
| Equivalent SCR ON Resistance | | $V_{FWD}/I_{FWD}$ (Note 6) | - | 1.0 | - | Ω |
| Input Capacitance | $C_{IN}$ | | - | 3 | - | pF |

Notes:

4. In automotive and other battery charging systems, the SP724 power supply lines should be externally protected for load dump and reverse battery. When the V+ and V- Pins are connected to the same supply voltage source as the device or control line under protection, a current limiting resistor should be connected in series between the external supply and the SP724 supply pins to limit reverse battery current to within the rated maximum limits.
5. Bypass capacitors of typically 0.01μF or larger should be connected closely between the V+ and V- Pins for all applications.
6. Refer to the Figure 3 graph for definitions of equivalent "SCR ON Threshold" and "SCR ON Resistance". These characteristics are given here for information to determine peak current and dissipation under EOS conditions.

## Typical Application of the SP724

Application as an Input Clamp for Over-voltage, Greater than 1$V_{BE}$ Above V+ or less than -1$V_{BE}$ below V-)

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## ESD Capability

ESD rating is dependent on the defined test standard. The evaluation results for various test standards and methods based on Figure 1 are shown in Table 1.3

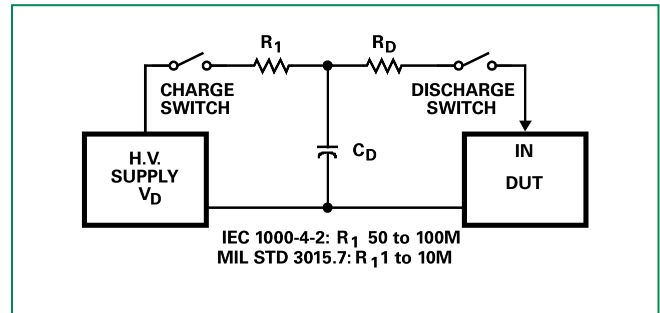
The SP724 has a Level 4 rating when tested to the IEC 61000-4-2 Human Body Model (HBM) standard and connected in a circuit in which the V+ and V- pins have a return path to ground. Level 4 specifies a required capability greater than 8kV for direct discharge and greater than 15kV for air discharge.

The "Modified" MIL-STD-3015.7 condition is defined as an "in-circuit" method of ESD testing, the V+ and V- pins have a return path to ground. The SP724 ESD capability is greater than 8kV with 100pF discharged through 1.5kΩ. By strict definition of the standard MIL-STD-3015.7 method using "pin-to-pin" device testing, the ESD voltage capability is greater than 2kV.

For the SP724 EIAJ IC121 Machine Model (MM) standard, the ESD capability is typically greater than 1.8kV with 200pF discharged through 0kΩ.

The Charged Device model is based upon the self-capacitance of the SOT-23 package through 0kΩ.

### Figure 1: Electrostatic Discharge Test

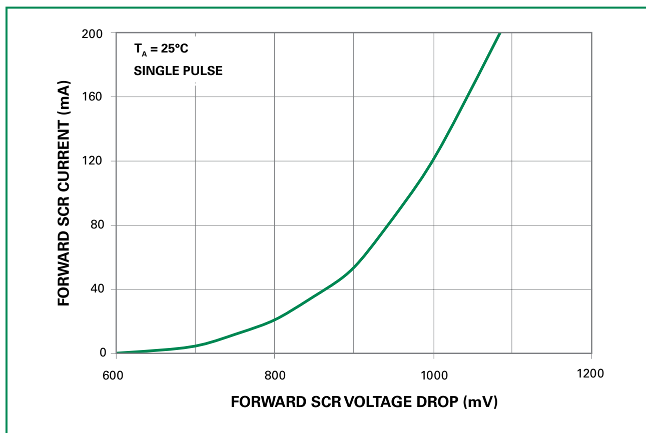



### Table 1: ESD Test Conditions

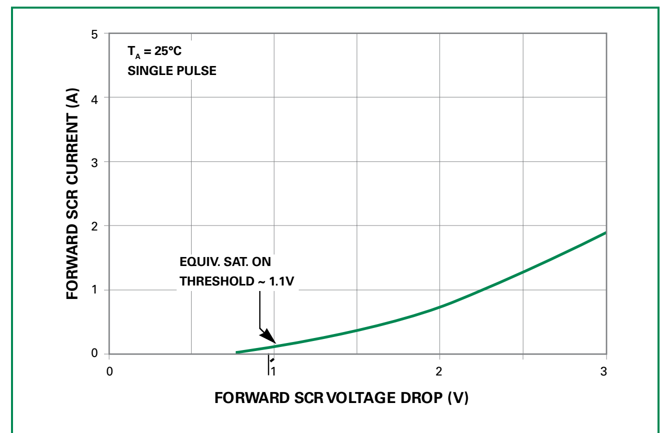
| Standard | Type/Mode | $R_D$ | $C_D$ | $\pm V_D$ |
|---|---|---|---|---|
| IEC 61000-4-2 (Level 4) | HBM, Air Discharge | 330 Ω | 150pF | 15kV |
| | HBM, Direct Discharge | 330 Ω | 150pF | 8kV |
| MIL-STD-3015.7 | Modified HBM | 1.5k Ω | 100pF | 8kV † |
| | Standard HBM | 1.5k Ω | 100pF | 2kV |
| EIAJ IC121 | Machine Model | 0k Ω | 200pF | 400V |
| US ESD DS 5.3 | Charged Device Model | 0k Ω | NA | 3kV |

†Upper limit of laboratory test set.

### Figure 2: Low Current SCR Forward Voltage Drop Curve




### Figure 3: High Current SCR Forward Voltage Drop Curve

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## Peak Transient Current Capability for Long Duration Surges

The peak transient current capability is inversely proportional to the width of the current pulse. Testing was done to fully evaluate the SP724's ability to withstand long duration current pulses using the circuit of Figure 4. Figure 5 shows the point of overstress as defined by increased leakage in excess of the data sheet published limits. The safe operating range of the transient peak current should be limited to no more than 75% of the measured overstress level for any given pulse width as shown in the curve of Figure 5.

The test circuit of Figure 4 is shown with a positive pulse input. For a negative pulse input, the (-) current pulse input goes to an SP724 'IN' input pin and the (+) current pulse input goes to the SP724 V- pin. The V+ to V- supply of the SP724 must be allowed to float. (i.e., It is not tied to the ground reference of the current pulse generator.)

Note that two input pins of the SP724 may be paralleled to improve current (and ESD) capability. The sustained peak current capability is increased to nearly twice that of a single pin.

**Figure 4: Typical SP724 Peak Current Test Circuit with a Variable Pulse Width Input**

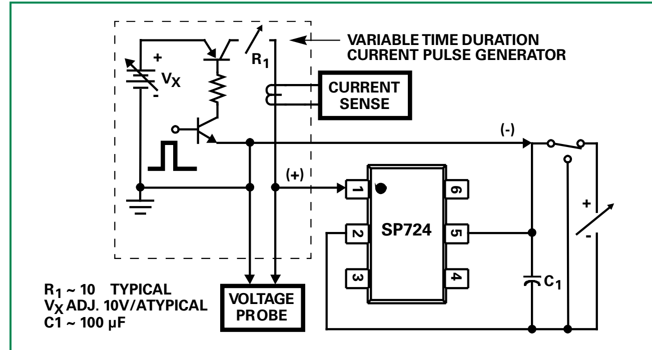
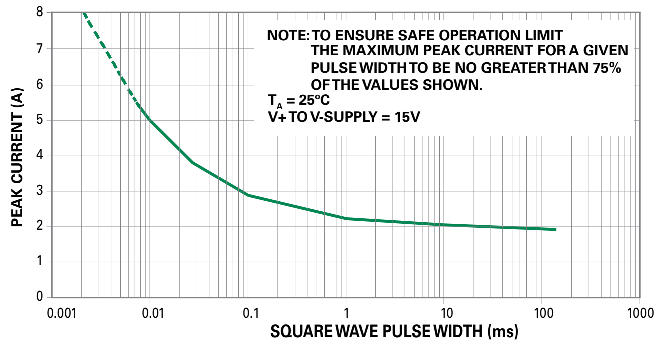



**Figure 5: SP724 Typical Nonrepetitive Peak Current Pulse Capability**

Showing the Measured Point of Overstress in Amperes vs pulse width time in milliseconds

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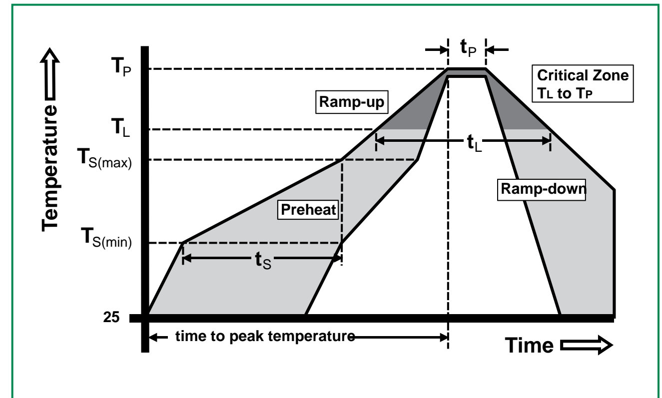
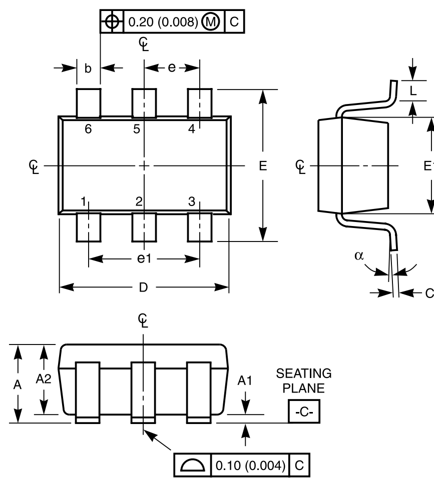
## Soldering Parameters

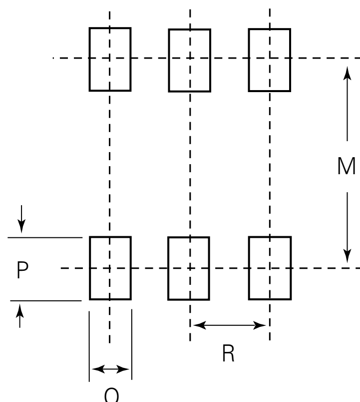
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — Small Outline Transistor Plastic Packages (SOT23-6)




### Recommended Solder Pad Layout




| Package | SOT23-6 | | | | |
|---|---|---|---|---|---|
| Pins | 6 | | | | |
| JEDEC | MO-178 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 0.900 | 1.450 | 0.035 | 0.057 | - |
| **A1** | 0.000 | 0.150 | 0.000 | 0.006 | - |
| **A2** | 0.900 | 1.300 | 0.035 | 0.051 | - |
| **b** | 0.350 | 0.500 | 0.0138 | 0.0196 | - |
| **C** | 0.080 | 0.220 | 0.0031 | 0.009 | - |
| **D** | 2.800 | 3.000 | 0.11 | 0.118 | 3 |
| **E** | 2.600 | 3.000 | 0.102 | 0.118 | - |
| **E1** | 1.500 | 1.750 | 0.06 | 0.069 | 3 |
| **e** | 0.95 Ref | | 0.0374 ref | | - |
| **e1** | 1.9 Ref | | 0.0748 Ref | | - |
| **L** | 0.100 | 0.600 | 0.004 | 0.023 | 4,5 |
| **N** | 6 | | 6 | | 6 |
| **a** | 0° | 10° | 0° | 10° | - |
| **M** | | 2.590 | | 0.102 | - |
| **O** | | 0.690 | | .027 TYP | - |
| **P** | | 0.990 | | .039 TYP | - |
| **R** | | 0.950 | | 0.038 | - |

Notes:

1. Dimensioning and tolerances per ANSI 14.5M-1982.
2. Package conforms to EIAJ SC-74 (1992).
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Footlenth L measured at reference to seating plane.
5. “L” is the length of flat foot surface for soldering to substrate.
6. “N” is the number of terminal positions.
7. Controling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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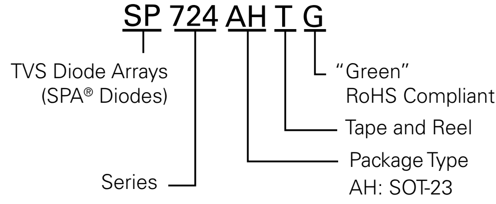
## Part Numbering System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

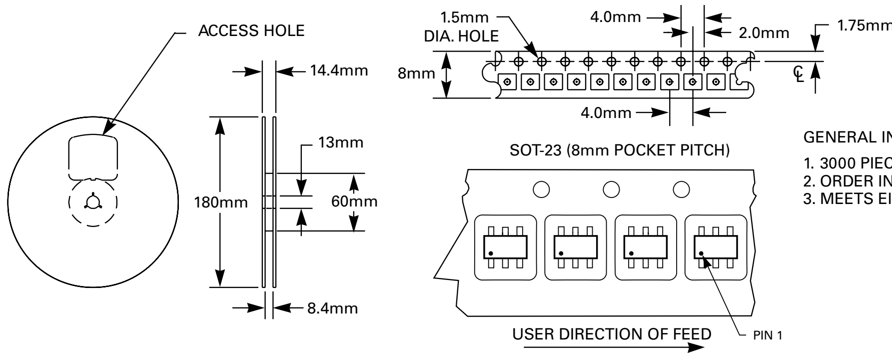
Notes:
1. All dimensions are in millimeters.
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Temp. Range (°C) | Package | Marking | Min. Order Qty. |
|---|---|---|---|---|
| SP724AHTG | -40 to 105 | Tape and Reel | 724G | 3000 |

## Embossed Carrier Tape & Reel Specification — SOT23-6

8mm TAPE AND REEL




GENERAL INFORMATION
1. 3000 PIECES PER REEL.
2. ORDER IN MULTIPLES OF FULL REELS ONLY.
3. MEETS EIA-481 REVISION "A" SPECIFICATIONS.

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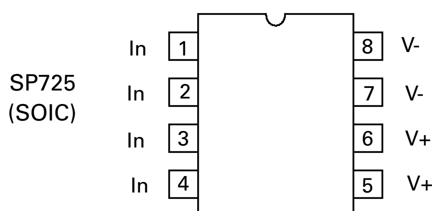
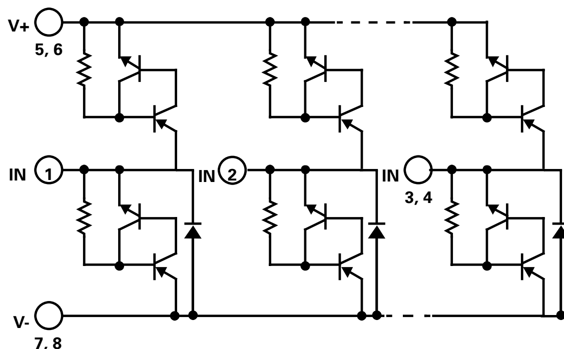
# SP725 Series 5pF 8kV Diode Array

## Pinout




## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

## Description

The SP725 is an array of SCR/Diode bipolar structures for ESD and overvoltage protection of sensitive input circuits. The SP725 has 2 protection SCR/Diode device structures per input. There are a total of 4 available inputs that can be used to protect up to 4 external signal or bus lines. Over-voltage protection is from the IN (Pins 1 - 4) to V+ or V-.

The SCR structures are designed for fast triggering at a threshold of one $+V_{BE}$ diode threshold above V+ (Pin 5,6) or one $-V_{BE}$ diode threshold below V- (Pin 7,8). From an IN input, a clamp to V+ is activated if a transient pulse causes the input to be increased to a voltage level greater than one $V_{BE}$ above V+. A similar clamp to V- is activated if a negative pulse, one $V_{BE}$ less than V-, is applied to an IN input.

Refer to Fig 1 and Table 1 for further details. Refer to Application Note AN9304 and AN9612 for further detail.

## Features

- ESD Interface per HBM Standards
  - IEC 61000-4-2, Direct Discharge .......... 8kV (Level 4)
  - IEC 61000-4-2, Air Discharge...............15kV (Level 4)
  - MIL-STD-3015.7 ................................................25kV
- Peak Current Capability
  - IEC 61000-4-5 8/20 μs Peak Pulse Current..... ± 14 A
  - Single Transient Pulse, 100 μs Pulse Width ...... ± 8 A
- Designed to Provide Over-Voltage Protection
  - Single-Ended Voltage Range to ....................... +30V
  - Differential Voltage Range to ........................... ±15V
- Fast Switching.............................................2ns Risetime
- Low Input Leakages..........................5 nA at 25 °C Typical
- Low Input Capacitance..................................5 pF Typical
- An Array of 4 SCR/Diode Pairs
- Operating Temperature Range..................-40 °C to 105 °C

## Applications

- Microprocessor/Logic Input Protection
- Data Bus Protection
- Analog Device Input Protection
- Voltage Clamp

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Continuous Supply Voltage, (V+) - (V-) | +35 | V |
| Forward Peak Current, $I_{IN}$ to $V_{CC}$ , $I_{IN}$ to GND (Refer to Figure 5) | ± 8, 100 µs | A |
| Peak Pulse Current, 8/20µs | ± 14 | A |
| ESD Ratings and Capability (Figure 1, Table 1) Load Dump and Reverse Battery (Note 2) | | |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Thermal Resistance (Typical, Note 1) | $\theta_{JA}$ | °C/W |
| SOIC Package | 170 | °C/W |
| Storage Temperature Range | -65 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

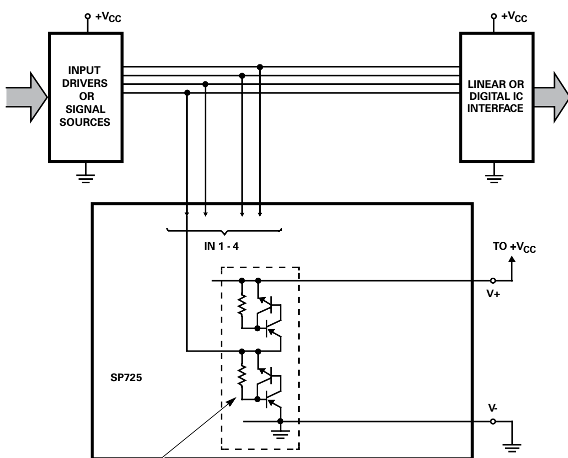
## Electrical Characteristics $T_A$ = -40°C to 105°C, $V_{IN}$ = 0.5$V_{CC}$ , Unless Otherwise Specified

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Operating Voltage Range, $V_{SUPPLY}$ = [(V+) - (V-)] | $V_{SUPPLY}$ | | - | 2 to 30 | - | V |
| Forward Voltage Drop IN to V- | $V_{FWDL}$ | $I_{IN}$ = 2A (Peak Pulse) | - | 2 | - | V |
| IN to V+ | $V_{FWDH}$ | | - | 2 | - | V |
| Input Leakage Current | $I_{IN}$ | | -20 | 5 | +20 | nA |
| Quiescent Supply Current | $I_{QUIESCENT}$ | | - | 50 | 200 | nA |
| Equivalent SCR ON Threshold | | (Note 3) | - | 1.1 | - | V |
| Equivalent SCR ON Resistance | | $V_{FWD}/I_{FWD}$ ; (Note 3) | - | 0.5 | - | Ω |
| Input Capacitance | $C_{IN}$ | | | 5 | - | pF |
| Input Switching Speed | $t_{ON}$ | | - | 2 | - | ns |

Notes:
1. $\theta_{JA}$ is measured with the component mounted on an evaluation PC board in free air
2. In automotive and battery operated systems, the power supply lines should be externally protected for load dump and reverse battery V+ and V- pins are connected to the same supply voltage source as the device or control line under protection, a current limiting resistor should be connected in series between the external supply and the SP725 supply pins to limit reverse battery current to within the rated maximum limits. Bypass capacitors of typically 0.01µF or larger from the V+ and V- pins to ground are recommended.
3. Refer to the Figure 3 graph for definitions of equivalent "SCR ON Threshold" and "SCR ON Resistance." These characteristics are given here for thumb-rule information to determine peak current and dissipation under EOS conditions.

## Typical Application of the SP725

(Application as an Input Clamp for Overvoltage, Greater than 1$V_{BE}$ Above V+ or less than -1$V_{BE}$ below V-)

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## ESD Capability

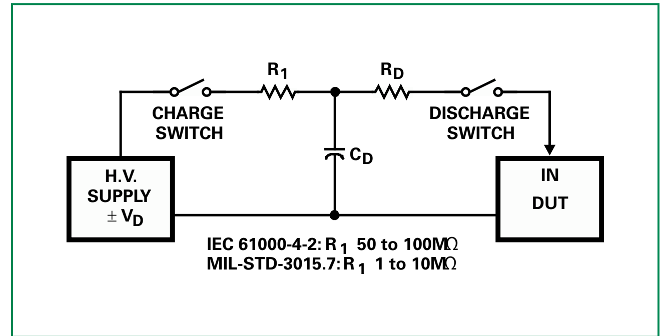
ESD capability is dependent on the application and defined test standard.The evaluation results for various test standards and methods based on Figure 1 are shown in Table 1.

The SP725 has a Level 4 HBM capability when tested as a device to the IEC 61000-4-2 standard. Level 4 specifies a required capability greater than 8kV for direct discharge and greater than 15kV for air discharge.

For the "Modified" MIL-STD-3015.7 condition that is defined as an "incircuit" method of ESD testing, the V+ and V- pins have a return path to ground and the SP725 ESD capability is typically greater than 25kV from 100pF through 1.5kΩ . By strict definition of MIL-STD-3015.7 using "pinto-pin" device testing, the ESD voltage capability is greater than 10kV.

For the SP725 EIAJ IC121 Machine Model (MM) standard, the ESD capability is typically greater than 2kV from 200pF with no series resistance.

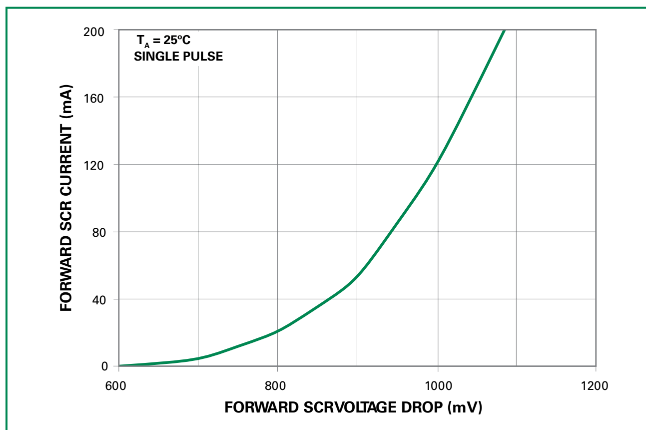
### Figure 1: Electrostatic Discharge Test



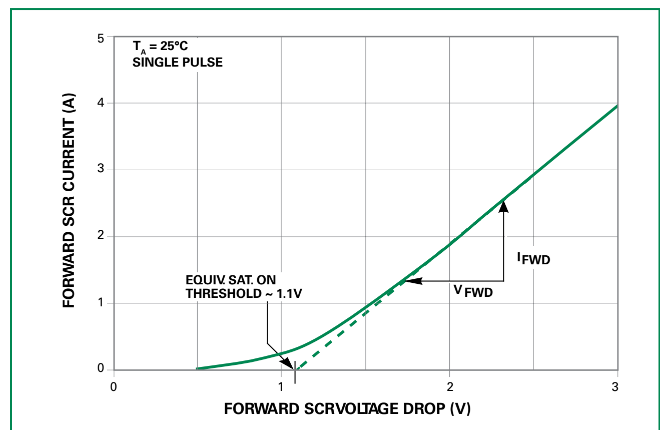

### Table 1: ESD Test Conditions

| Standard | Type/Mode | $R_D$ | $C_D$ | $\pm V_D$ |
|---|---|---|---|---|
| IEC 61000-4-2 (Level 4) | HBM, Air Discharge | 330 Ω | 150pF | 15kV |
| | HBM, Direct Discharge | 330 Ω | 150pF | 8kV |
| MIL-STD-3015.7 | Modified HBM | 1.5k Ω | 100pF | 25kV |
| | Standard HBM | 1.5k Ω | 100pF | 10kV |
| EIAJ IC121 | Machine Model | 0k Ω | 200pF | 2kV |

### Figure 2: Low Current SCR Forward Voltage Drop Curve




### Figure 3: High Current SCR Forward Voltage Drop Curve

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## Peak Transient Current Capability for Long Duration Surges

The peak transient current capability rises sharply as the width of the current pulse narrows. Destructive testing was done to fully evaluate the SP725 's ability to withstand a wide range of peak current pulses vs time. The circuit used to generate current pulses is shown in Figure 4.

The test circuit of Figure 4 is shown with a positive pulse input. For a negative pulse input, the (-) current pulse input goes to an SP725 'IN' input pin and the (+) current pulse input goes to the SP725 V- pin. The V+ to V- supply of the SP725 must be allowed to float. (i.e., It is not tied to the ground reference of the current pulse generator.) Figure 5 shows the point of overstress as defined by increased leakage in excess of the data sheet published limits.

The maximum peak input current capability is dependent on the ambient temperature, improving as the temperature is reduced. Peak current curves are shown for ambient temperatures of 25 ° C and 105 ° C and a 15V power supply condition. The safe operating range of the transient peak current should be limited to no more than 75% of the measured overstress level for any given pulse width as shown in the curves of Figure 5.

Note that adjacent input pins of the SP725 may be paralleled to improve current (and ESD) capability. The sustained peak current capability is increased to nearly twice that of a single pin.

**Figure 4: Typical SP725 Peak Current Test Circuit with a Variable Pulse Width Input**

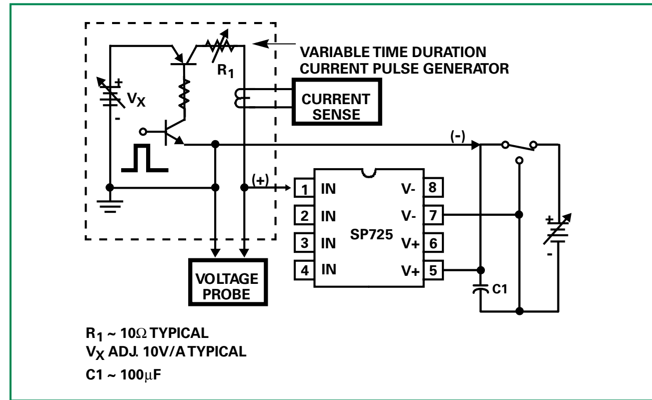
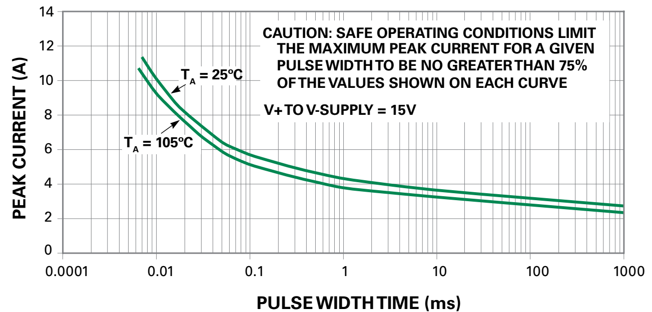



**Figure 5: SP725 Typical Nonrepetitive Peak Current Pulse Capability**

Showing the Measured Point of Overstress in Amperes vs pulse width time in milliseconds

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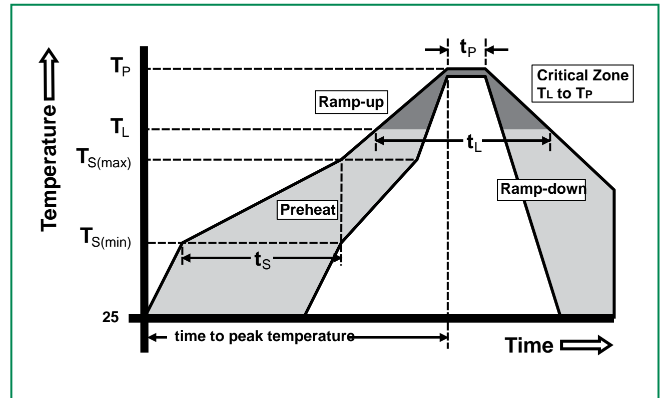
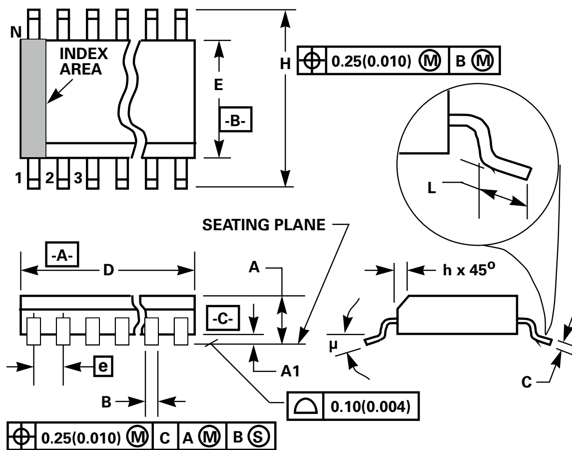
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — Small Outline Plastic Packages (SOIC)




| Package | SOIC | | | | |
|---|---|---|---|---|---|
| Pins | 8 | | | | |
| JEDEC | MS-012 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 1.35 | 1.75 | 0.0532 | 0.0688 | - |
| **A1** | 0.10 | 0.25 | 0.0040 | 0.0098 | - |
| **B** | 0.33 | 0.51 | 0.013 | 0.020 | 9 |
| **C** | 0.19 | 0.25 | 0.0075 | 0.0098 | - |
| **D** | 4.80 | 5.00 | 0.1890 | 0.1968 | 3 |
| **E** | 3.80 | 4.00 | 0.1497 | 0.1574 | 4 |
| **e** | 1.27 BSC | | 0.050 BSC | | - |
| **H** | 5.80 | 6.20 | 0.2284 | 0.2440 | - |
| **h** | 0.25 | 0.50 | 0.0099 | 0.0196 | 5 |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 | 6 |
| **N** | 8 | | 8 | | 7 |
| **μ** | 0° | 8° | 0° | 8° | - |

Notes:

1. Symbols are defined in the “MO Series Symbol List” in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension “D” does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension “E” does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. “L” is the length of terminal for soldering to a substrate.
7. “N” is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width “B”, as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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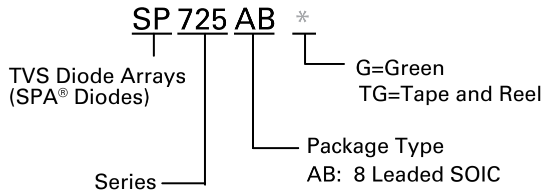
## Part Numbering System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

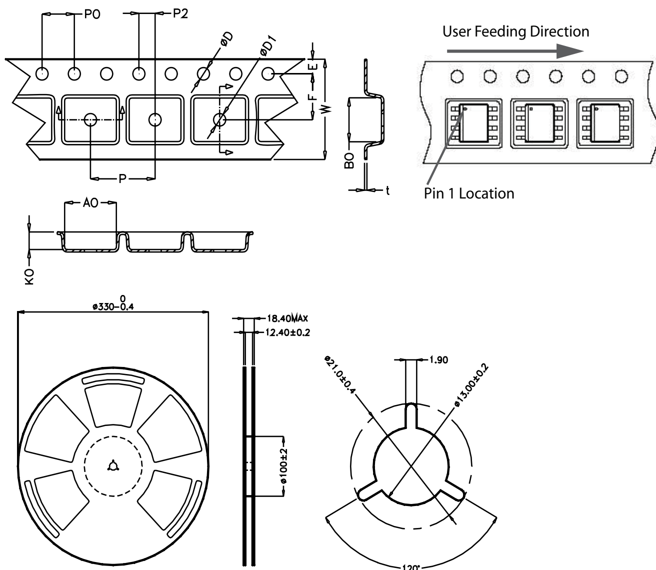
Notes:
1. All dimensions are in millimeters.
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4.Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Temp. Range (°C) | Package | Marking | Min. Order Qty. |
|---|---|---|---|---|
| SP725ABG | -40 to 105 | 8 Ld SOIC | SP725AB(T)G [1] | 1960 |
| SP725ABTG | -40 to 105 | 8 Ld SOIC Tape and Reel | SP725AB(T)G [1] | 2500 |

Notes:
1. SP725AB(T)G means device marking either SP725ABG or SP725ABTG.

## Embossed Carrier Tape & Reel Specification - SOIC Package




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

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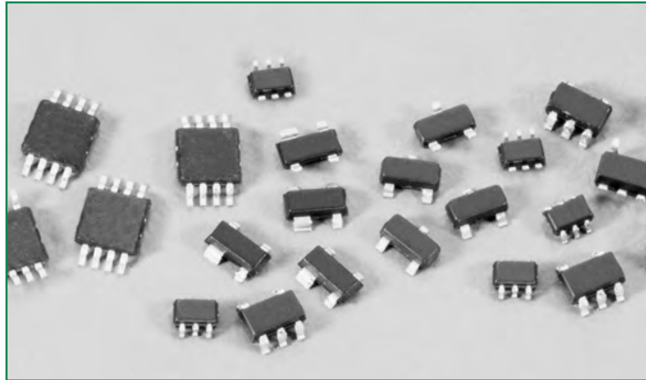
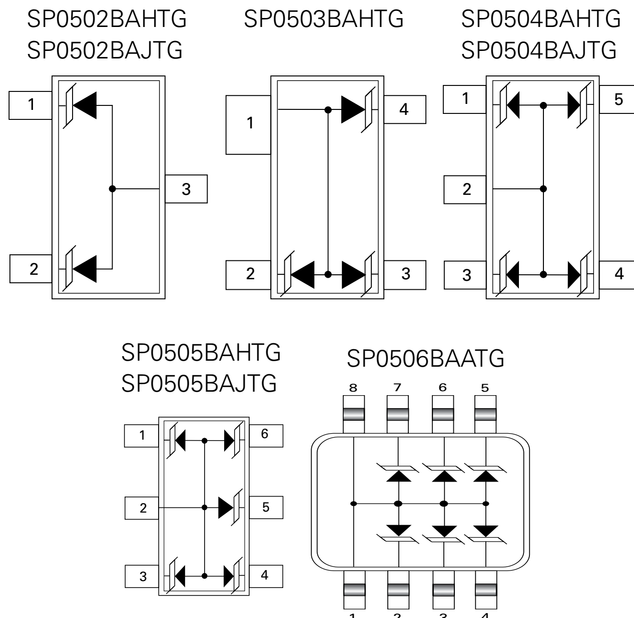
# SP05 Series - 30pF 30kV Unidirectional TVS Array

HF RoHS Pb GREEN



## Pinout




## Description

This surface mount family of arrays suppresses ESD and other transient overvoltage events. Used to meet the International Electrotechnical Compatibility (IEC transient immunity standards IEC 61000-4-2 for Electrostatic Discharge Requirements), these devices can help protect sensitive digital or analog input circuits on data, signal, or control lines with voltage levels up to 5VDC.

The monolithic silicon arrays are comprised of specially designed structures for transient voltage suppression (TVS). The size and shape of these structures have be tailored for transient protection. The low capacitance and clamp voltage are ideal for high speed signal line protection.

## Features

- An Array of 2, 3, 4, 5 or 6 TVS Avalanche Diodes in a ultra small SC70, SOT-23, SOT-143 or MSOP packages
- ESD Capability Standards
  - IEC 61000-4-2, Direct Discharge ........ 30kV (Level 4)
  - IEC 61000-4-2, Air Discharge.............. 30kV (Level 4)
  - MIL STD 883 3015.7..........................................30kV
- Input Protection for Applications Up to 5VDC
- Fast Response Time ..................................................<1ns
- Low Input Capacitance...................................30pF Typical
- Operating Temperature Range..................... -40°C to 85°C

## Applications

- Mobile phone handsets
- Personal Digital Assistants (PDA)
- Portable handheld equipment (Laptop, Palmtop computers)
- Computer port, keyboard (USB1.1)
- Digital still cameras
- Digital video cameras
- MP3 players

## Additional Information

Datasheet

Resources

Samples

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

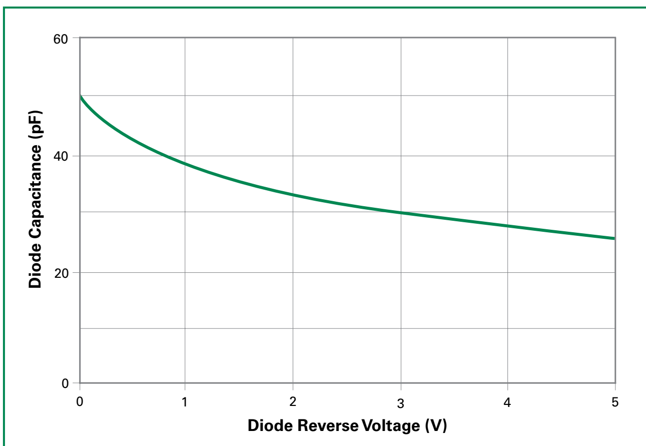
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –40 to 125 | °C |
| Package Power Dissipation<br>SC70<br>SOT23-3, SOT23-5, SOT23-6, SOT143<br>MSOP | <br>0.2<br>0.225<br>0.5 | <br>W<br>W<br>W |

## Electrical Characteristics $T_A$ = +25°C, Unless Otherwise Specified

| Parameter | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|
| Reverse Standoff Voltage | $I_R \leq 1\mu A$ | - | - | 5.5 | V |
| Reverse Standoff Leakage Current | V = 5.0V | | 1 | 100 | nA |
| Signal Clamp Voltage | | | | | |
| Positive | I = 1mA | 6.0 | | 8.5 | V |
| Negative | I = 10mA | -1.2 | -0.8 | -0.4 | V |
| Clamp Voltage during ESD | | | | | |
| MIL-STD-883 Method 3015 (HBM) test | | | | | |
| + 8kV | | | 12 | | V |
| - 8kV | | | -8 | | V |
| ESD Test Level (1) | | | | | |
| IEC-61000-4-2, Contact discharge | | 30 | | | kV |
| MIL-STD-883 Method 3015 (HBM) | | 30 | | | kV |
| Capacitance | 2.5V @ 1MHz | | 30 | | pF |
| Turn on/off Time | | | <1 | | ns |
| Temperature Range | | | | | |
| Operating | | -40 | | 85 | °C |
| Storage | | -65 | | 150 | °C |
| Diode Dynamic Resistance | | | | | |
| Forward Conduction | | | 1.0 | | Ω |
| Reverse Conduction | | | 1.4 | | Ω |

Note:
(1) ESD voltage applied between channel pins and ground, one pin at a time; all other channel pins are open; all ground pins are grounded.

## Typical Diode Capacitance vs. Reverse Voltage

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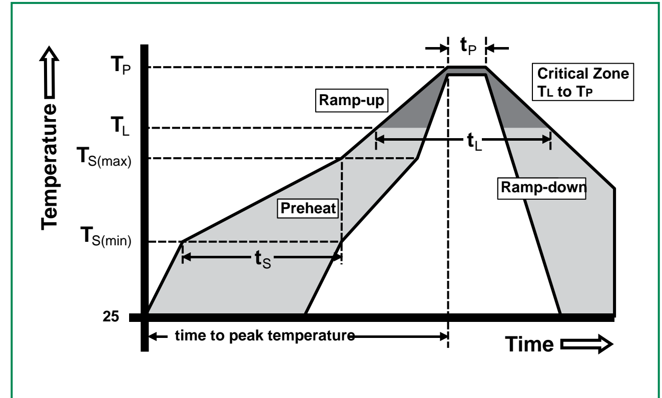
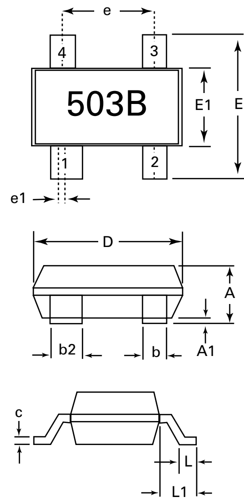
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

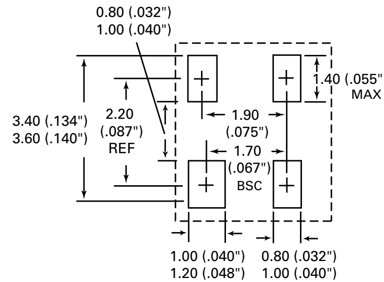



## Package Dimensions — SOT143




SP0503BAHTG - SOT143-4

Recommended Pad Layout




| Package | SOT143-4 | | | |
|---|---|---|---|---|
| Pins | 4 | | | |
| JEDEC | TO-253 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.8 | 1.22 | 0.03 | 0.048 |
| **A1** | 0.05 | 0.15 | 0.002 | 0.006 |
| **b** | 0.30 | 0.50 | 0.012 | 0.020 |
| **b2** | 0.76 | 0.89 | 0.030 | 0.035 |
| **c** | 0.08 | 0.20 | 0.003 | 0.008 |
| **D** | 2.80 | 3.04 | 0.110 | 0.120 |
| **E** | 2.10 | 2.64 | 0.082 | 0.104 |
| **E1** | 1.20 | 1.40 | 0.047 | 0.055 |
| **e** | 1.92 BSC | | 0.076 BSC | |
| **e1** | 0.20 BSC | | 0.008 BSC | |
| **L** | 0.4 | 0.6 | 0.016 | 0.024 |
| **L1** | 0.550 REF | | 0.022 REF | |

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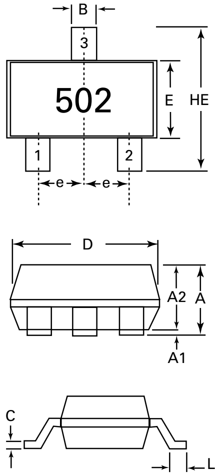
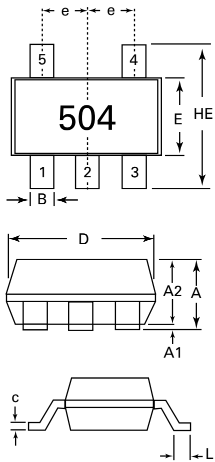
## Package Dimensions — SC70



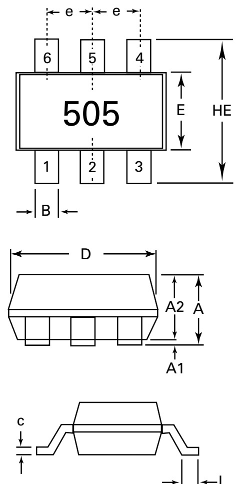

SP0502BAJTG - SC70-3

| Package | SC70-3 | | | |
|---|---|---|---|---|
| Pins | 3 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.00 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.66 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |



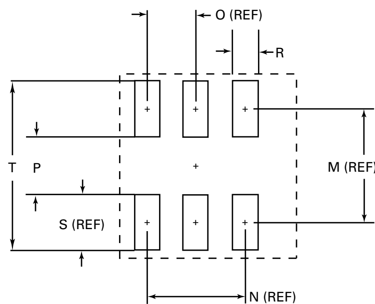

SP0504BAJTG - SC70-5

| Package | SC70-5 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.00 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |




SP0505BAJTG - SC70-6

Recommended Pad Layout




| Package | SC70-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.00 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |
| **M** | - | 1.60 | - | 0.063 |
| **N** | - | 1.30 | - | 0.051 |
| **O** | - | 0.65 | - | 0.026 |
| **P** | - | 0.70 | - | 0.028 |
| **R** | - | 0.35 | - | 0.014 |
| **S** | - | 0.90 | - | 0.035 |
| **T** | - | 2.50 | - | 0.098 |

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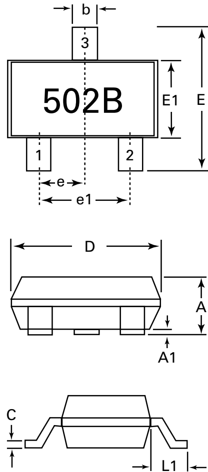
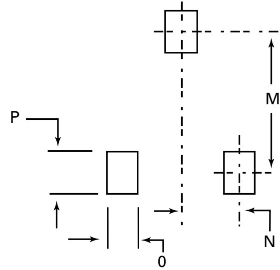
## Package Dimensions — SOT23

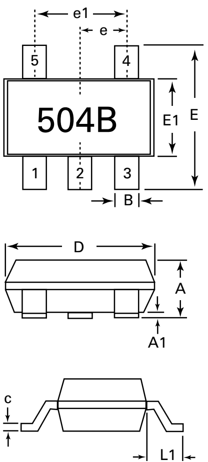



SP0502BAHTG - SOT23-3

Recommended Pad Layout

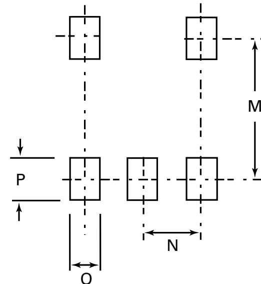



| Package | SOT23-3 | | | |
|---|---|---|---|---|
| Pins | 3 | | | |
| JEDEC | TO-236 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.89 | 1.12 | 0.035 | 0.044 |
| **A1** | 0.01 | 0.1 | 0.0004 | 0.004 |
| **b** | 0.3 | 0.5 | 0.012 | 0.020 |
| **c** | 0.08 | 0.2 | 0.003 | 0.008 |
| **D** | 2.8 | 3.04 | 0.110 | 0.120 |
| **E** | 2.1 | 2.64 | 0.083 | 0.104 |
| **E1** | 1.2 | 1.4 | 0.047 | 0.055 |
| **e** | 0.95 BSC | | 0.038 BSC | |
| **e1** | 1.90 BSC | | 0.075 BSC | |
| **L1** | 0.54 REF | | 0.021 REF | |
| **M** | | 2.29 | | .090 |
| **N** | | 0.95 | | 0.038 |
| **O** | | 0.78 | | .030TYP |
| **P** | | 0.78 | | .030TYP |

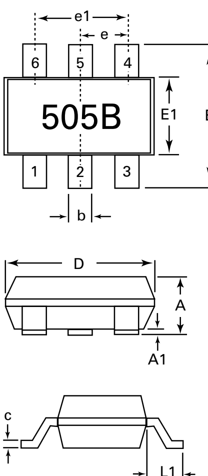



SP0504BAHTG - SOT23-5

Recommended Pad Layout

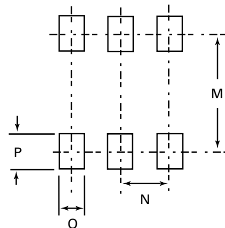



| Package | SOT23-5 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| JEDEC | MO-178 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | - | 1.45 | - | 0.057 |
| **A1** | 0 | 0.15 | 0 | 0.006 |
| **b** | 0.3 | 0.5 | 0.012 | 0.020 |
| **c** | 0.08 | 0.22 | 0.003 | 0.009 |
| **D** | 2.75 | 3.05 | 0.108 | 0.120 |
| **E** | 2.6 | 3.0 | 0.102 | 0.118 |
| **E1** | 1.45 | 1.75 | 0.057 | 0.069 |
| **e** | 0.95 BSC | | 0.038 BSC | |
| **e1** | 1.90 BSC | | 0.075 BSC | |
| **L1** | 0.60 REF | | 0.024 REF | |
| **M** | | 2.59 | | .102 |
| **N** | | 0.95 | | .038 |
| **O** | | 0.69 | | .027TYP |
| **P** | | 0.99 | | .039TYP |




SP0505BAHTG - SOT23-6

Recommended Pad Layout




| Package | SOT23-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-178 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | - | 1.45 | - | 0.057 |
| **A1** | 0 | 0.15 | 0 | 0.006 |
| **b** | 0.3 | 0.5 | 0.012 | 0.020 |
| **c** | 0.08 | 0.22 | 0.003 | 0.009 |
| **D** | 2.75 | 3.05 | 0.108 | 0.120 |
| **E** | 2.6 | 3.0 | 0.102 | 0.118 |
| **E1** | 1.45 | 1.75 | 0.057 | 0.069 |
| **e** | 0.95 BSC | | 0.038 BSC | |
| **e1** | 1.90 BSC | | 0.075 BSC | |
| **L1** | 0.60 REF | | 0.024 REF | |
| **M** | | 2.59 | | .102 |
| **N** | | 0.95 | | 0.038 |
| **O** | | 0.69 | | .027TYP |
| **P** | | 0.99 | | .039TYP |

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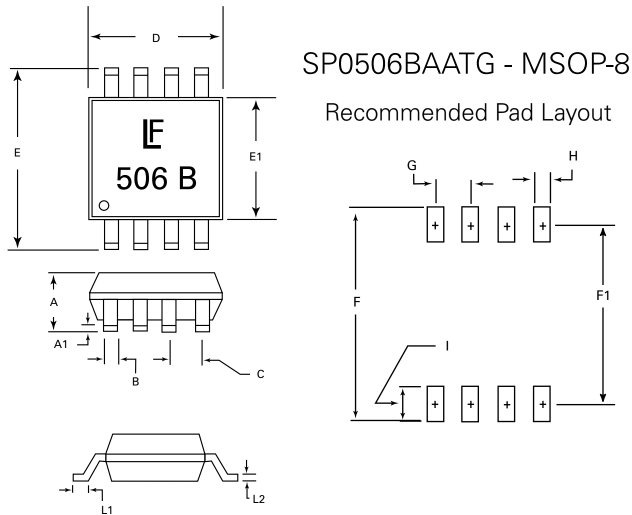
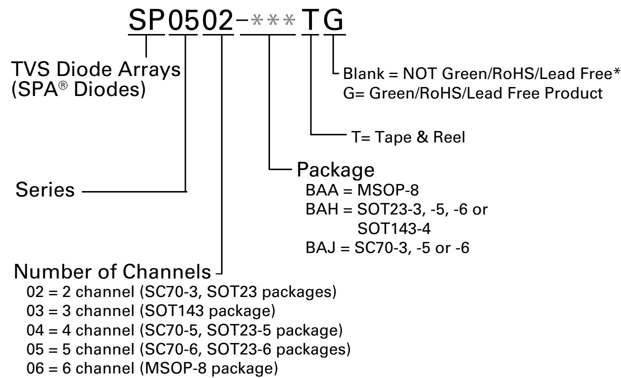
## Package Dimensions — MSOP




| Package | MSOP | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MO-187 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **D** | 2.90 | 3.10 | 0.114 | .122 |
| **E** | 4.78 | 4.98 | .188 | .196 |
| **E1** | 2.90 | 3.10 | .114 | .122 |
| **A** | 0.87 | 1.17 | .034 | .046 |
| **A1** | 0.05 | 0.25 | .002 | 0.010 |
| **B** | - | 0.30TYP | - | 0.012TYP |
| **C** | - | 0.65TYP | - | 0.026TYP |
| **L1** | 0.52 | 0.54 | 0.020 | 0.021 |
| **L2** | - | 0.18TYP | - | .007TYP |
| **F** | - | 5.28 | - | .208 |
| **F1** | - | 4.24 | - | .167 |
| **G** | - | 0.65 | - | 0.026 |
| **H** | - | 0.38 | - | .015 |
| **I** | - | 1.04 | - | .041 |

## Part Numbering System




## Ordering Information

*NOTE: To order NON-Green/RoHS/Lead Free version of product, remove "G" at the end of part number.

| Part Number | CH | Package Type | Quantity Per Reel |
|---|---|---|---|
| SP0502BAHTG | 2 | SOT23-3 | 3000 |
| SP0503BAHTG | 3 | SOT143-4 | 3000 |
| SP0504BAHTG | 4 | SOT23-5 | 3000 |
| SP0505BAHTG | 5 | SOT23-6 | 3000 |
| SP0506BAATG | 6 | MSOP-8 | 4000 |
| SP0502BAJTG | 2 | SC70-3 | 3000 |
| SP0504BAJTG | 4 | SC70-5 | 3000 |
| SP0505BAJTG | 5 | SC70-6 | 3000 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | "G" Green version - Matte Tin (Sn) |
| **Lead Material** | Copper / Iron Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes:
1. All dimensions are in millimeters.
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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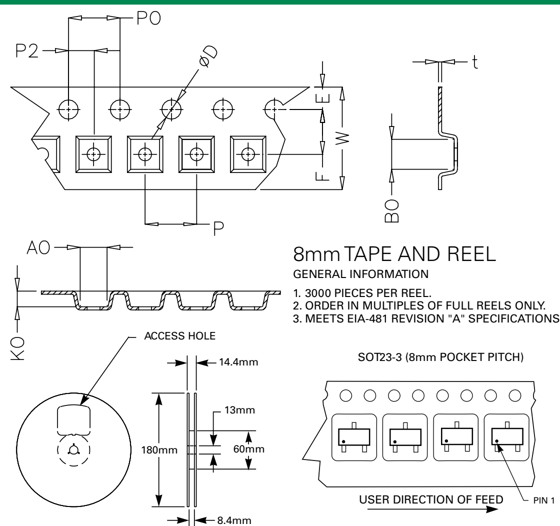
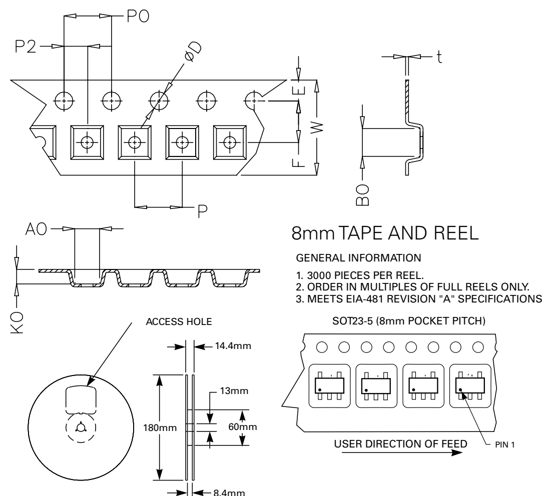
## Embossed Carrier Tape & Reel Specification — SOT23-3



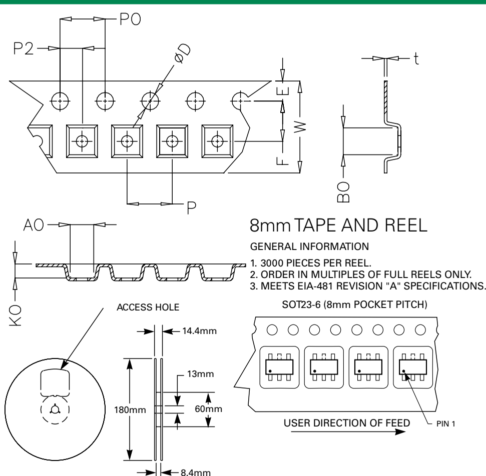

| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.40 | 3.60 | 0.134 | 0.142 |
| **P2** | 1.90 | 2.10 | 0.075 | 0.083 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **W** | 7.70 | 8.30 | 0.303 | 0.327 |
| **P** | 3.90 | 4.10 | 0.154 | 0.161 |
| **A0** | 3.05 | 3.25 | 0.120 | 0.128 |
| **B0** | 2.67 | 2.87 | 0.105 | 0.113 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.22 | 0.24 | 0.009 | 0.009 |

## Embossed Carrier Tape & Reel Specification — SOT23-5




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.40 | 3.60 | 0.134 | 0.142 |
| **P2** | 1.90 | 2.10 | 0.075 | 0.083 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **W** | 7.70 | 8.30 | 0.303 | 0.327 |
| **P** | 3.90 | 4.10 | 0.154 | 0.161 |
| **A0** | 3.05 | 3.25 | 0.120 | 0.128 |
| **B0** | 2.67 | 2.87 | 0.105 | 0.113 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.22 | 0.24 | 0.009 | 0.009 |

## Embossed Carrier Tape & Reel Specification — SOT23-6




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.40 | 3.60 | 0.134 | 0.142 |
| **P2** | 1.90 | 2.10 | 0.075 | 0.083 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **W** | 7.70 | 8.30 | 0.303 | 0.327 |
| **P** | 3.90 | 4.10 | 0.154 | 0.161 |
| **A0** | 3.05 | 3.25 | 0.120 | 0.128 |
| **B0** | 2.67 | 2.87 | 0.105 | 0.113 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.22 | 0.24 | 0.009 | 0.009 |

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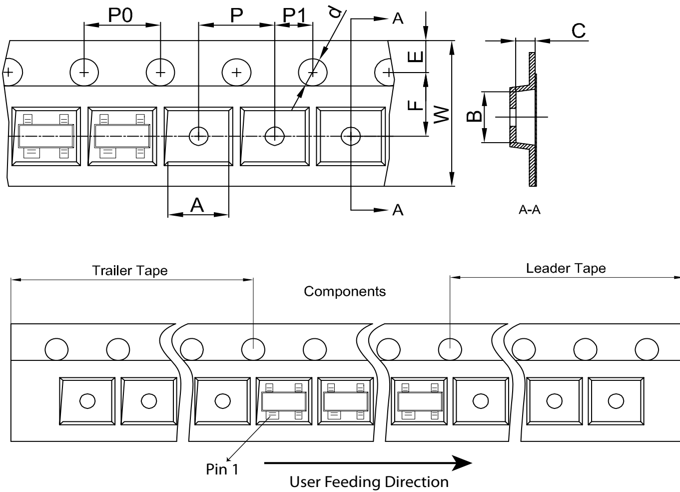
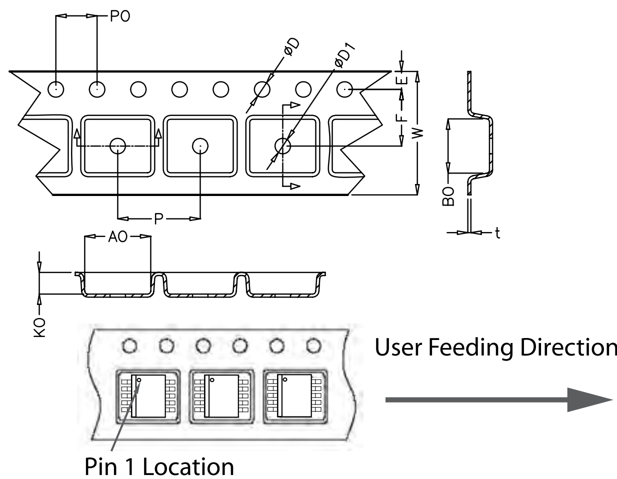
## Embossed Carrier Tape & Reel Specification — SOT143-4



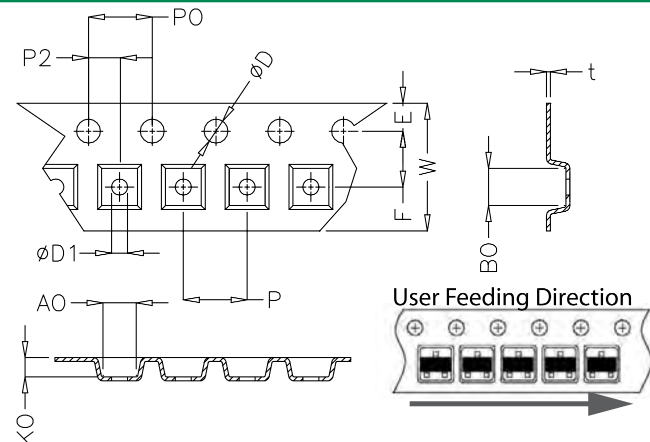

| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| A | 3.09 | 3.09 | 0.122 | 0.130 |
| B | 2.70 | 2.90 | 1.106 | 0.114 |
| C | 1.21 | 1.41 | 0.048 | 0.056 |
| d | 1.40 | 1.60 | 0.055 | 0.102 |
| E | 1.65 | 0.85 | 0.065 | 0.073 |
| F | 3.45 | 3.65 | 0.133 | 0.142 |
| P0 | 4.10 | 3.90 | 0.154 | 0.161 |
| P | 4.10 | 3.90 | 0.154 | 0.161 |
| P1 | 1.90 | 2.10 | 0.075 | 0.083 |
| W | 7.90 | 8.10 | 0.311 | 0.319 |

## Embossed Carrier Tape & Reel Specification — MSOP-8




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 5.40 | 5.60 | 0.213 | 0.220 |
| D | 1.50 | 1.60 | 0.059 | 0.063 |
| D1 | 1.50 Min | | 0.059 Min | |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| W | 11.70 | 12.30 | 0.461 | 0.484 |
| P | 7.90 | 8.10 | 0.311 | 0.319 |
| A0 | 5.20 | 5.40 | 0.205 | 0.213 |
| B0 | 3.30 | 3.40 | 0.126 | 0.134 |
| K0 | 1.20 | 1.40 | 0.047 | 0.055 |
| t | 0.30 ± 0.05 | | 0.012± 0.002 | |

## Embossed Carrier Tape & Reel Specification — SC70-3




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.064 | 0.073 |
| F | 3.45 | 3.55 | 0.135 | 0.139 |
| P2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 1.40 | 1.60 | 0.055 | 0.063 |
| D1 | 1.00 | 1.25 | 0.039 | 0.049 |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| W | 7.70 | 8.10 | 0.303 | 0.318 |
| P | 3.90 | 4.10 | 0.153 | 0.161 |
| A0 | 2.14 | 2.34 | 0.084 | 0.092 |
| B0 | 2.24 | 2.44 | 0.088 | 0.096 |
| K0 | 1.12 | 1.32 | 0.044 | 0.052 |
| t | 0.27 Max | | 0.010 Max | |

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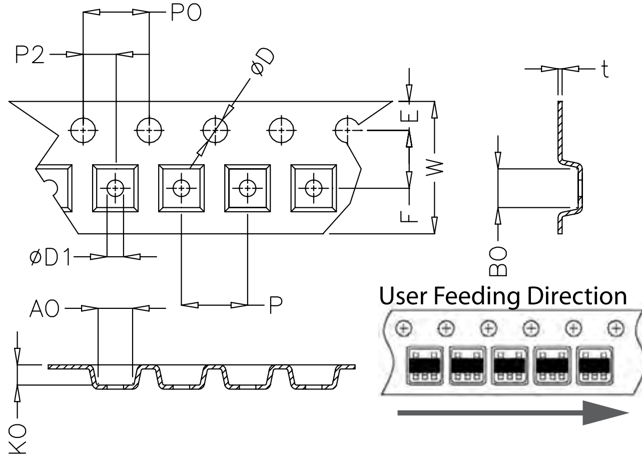
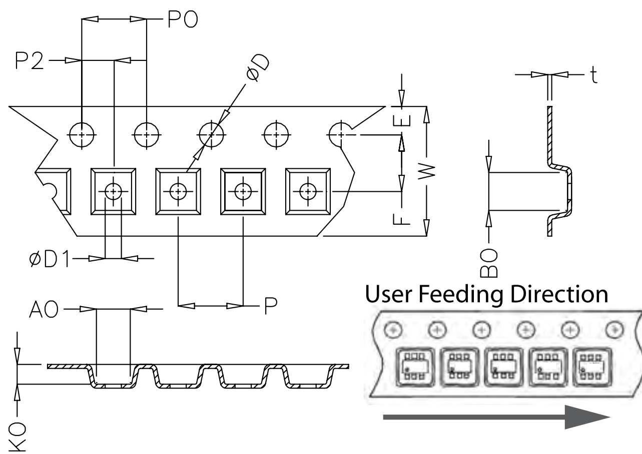
## Embossed Carrier Tape & Reel Specification — SC70-5




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.14 | 2.34 | 0.084 | 0.092 |
| **B0** | 2.24 | 2.44 | 0.088 | 0.096 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.27 Max | | 0.010 Max | |

## Embossed Carrier Tape & Reel Specification — SC70--6




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.14 | 2.34 | 0.084 | 0.092 |
| **B0** | 2.24 | 2.44 | 0.088 | 0.096 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.27 Max | | 0.010 Max | |

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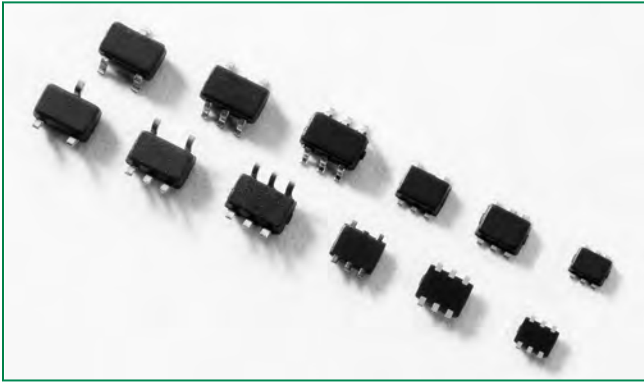
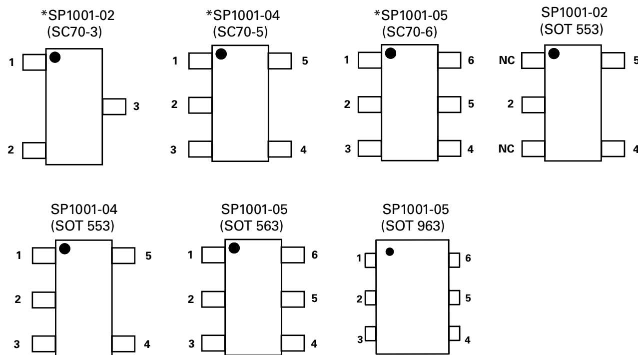
# SP1001 Series - 8pF 15kV Unidirectional TVS Array



## Description

Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high-speed signal pins.

## Pinout




*Note: AEC-Q101 qualified

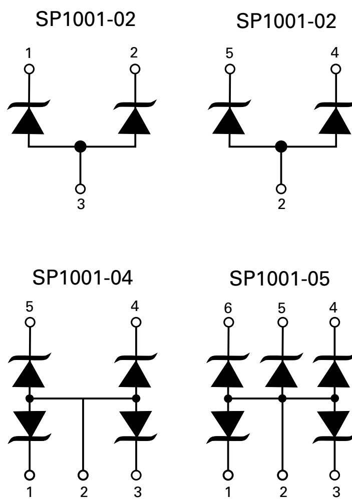
## Features

- Low capacitance of 8pF (TYP) per I/O
- ESD protection of ±15kV contact discharge, ±30kV air discharge, (Level 4, IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5μA (MAX) at 5V
- Small package saves board space
- Lightning protection, IEC61000-4-5, 2A (8/20μs)
- AEC-Q101 qualified (SC70-x packages)

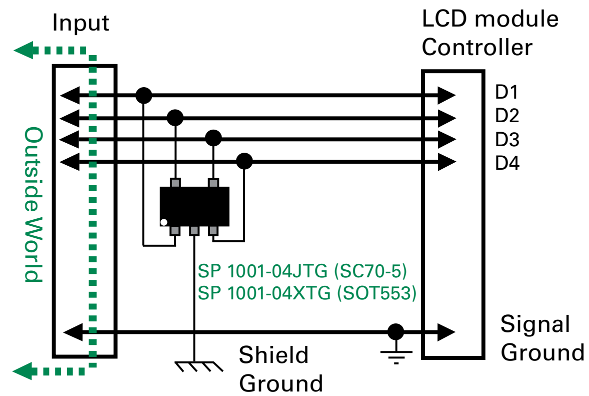
## Applications

- Computer Peripherals
- Mobile Phones
- Digital Cameras
- Desktops/Notebooks
- LCD/PDP TVs
- Set Top Boxes
- DVD Players
- MP3/PMP

## Functional Block Diagram




## Application Example




## Additional Information

**Datasheet**

**Resources**

**Samples**

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

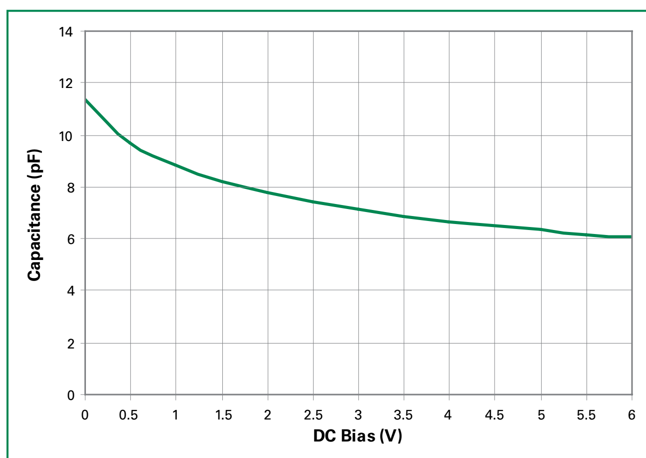
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20s-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Forward Voltage Drop | $V_F$ | $I_F$=10mA | 0.7 | 0.9 | 1.2 | V |
| Reverse Voltage Drop | $V_R$ | $I_R$=1mA | 6.0 | | 8.5 | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 5.5 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 8.0 | 11.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 9.7 | 13.0 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.7 | | Ω |
| ESD Withstand Voltage[1,2] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±15 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 12 | | pF |
| | | Reverse Bias=2.5V | | 8 | | pF |
| | | Reverse Bias=5V | | 7 | | pF |

Notes:
[1] Parameter is guaranteed by device characterization
[2] A minimum of 1,000 ESD pulses are applied at 1s intervals between the anode and common cathode of each diode

## Capacitance vs. Reverse Bias




## Design Consideration

Because of the fast rise-time of the ESD transient, placement of ESD devices is a key design consideration. To achieve optimal ESD suppression, the devices should be placed on the circuit board as close to the source of the ESD transient as possible. Install the ESD suppressors directly behind the connector so that they are the first board-level circuit component encountered by the ESD transient. They are connected from signal/data line to ground.

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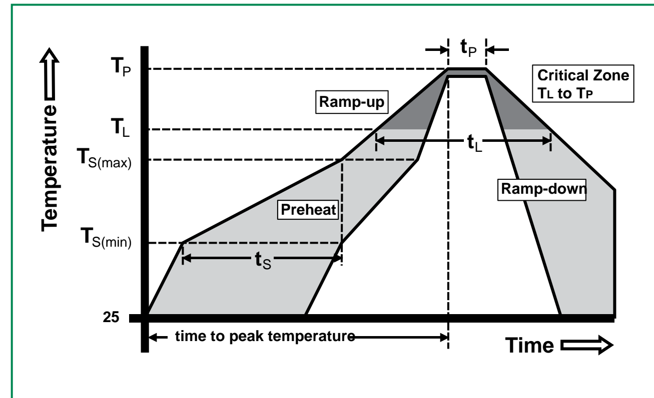
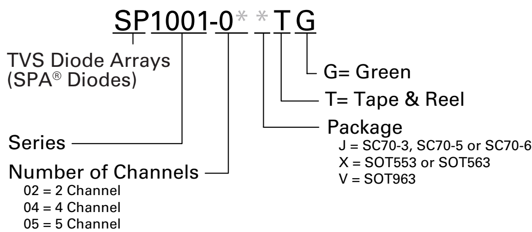
## Soldering Parameters

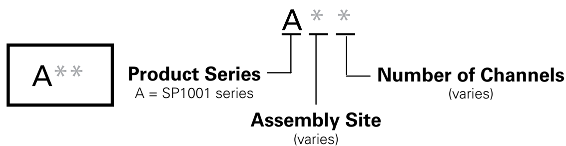
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1001-02JTG | SC70-3 | A*2 | 3000 |
| SP1001-02XTG | SOT553 | A*2 | 3000 |
| SP1001-04JTG | SC70-5 | A*4 | 3000 |
| SP1001-04XTG | SOT553 | A*4 | 3000 |
| SP1001-05JTG | SC70-6 | A*5 | 3000 |
| SP1001-05VTG | SOT963 | A*5 | 8000 |
| SP1001-05XTG | SOT563 | A*5 | 3000 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin (SC70-x) Pre-Plated Frame (SOT5x3, SOT963) |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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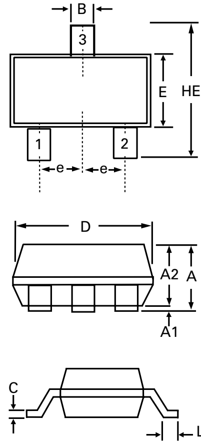
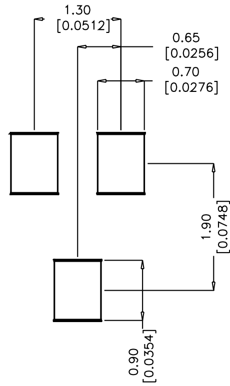
## Package Dimensions — SC70

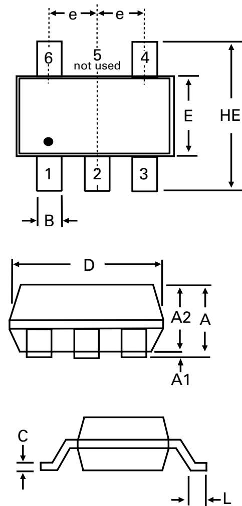


### SC70-3

Solder Pad Layout

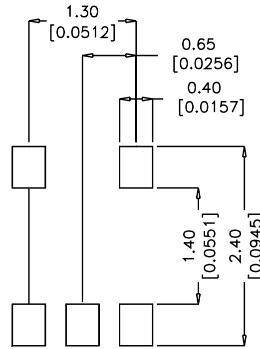



| Package | SC70-3 | | | |
|---|---|---|---|---|
| Pins | 3 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.66 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

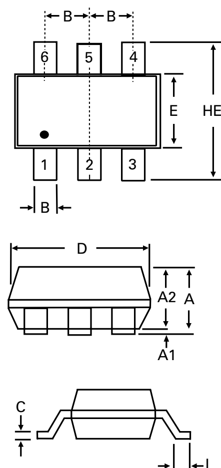


### SC70-5

Solder Pad Layout

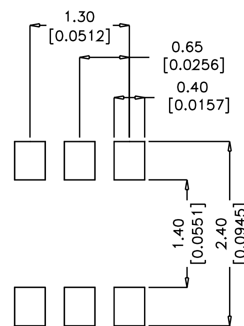



| Package | SC70-5 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |



### SC70-6

Solder Pad Layout




| Package | SC70-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

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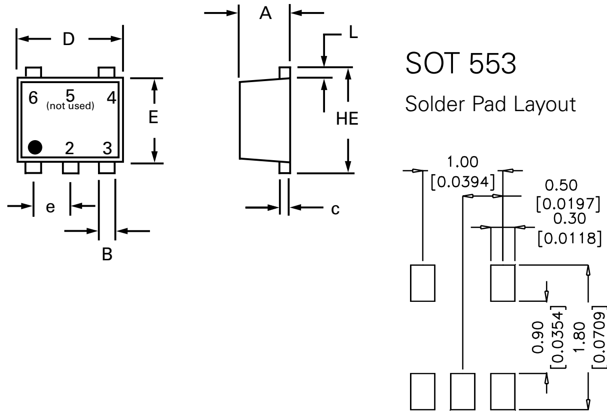
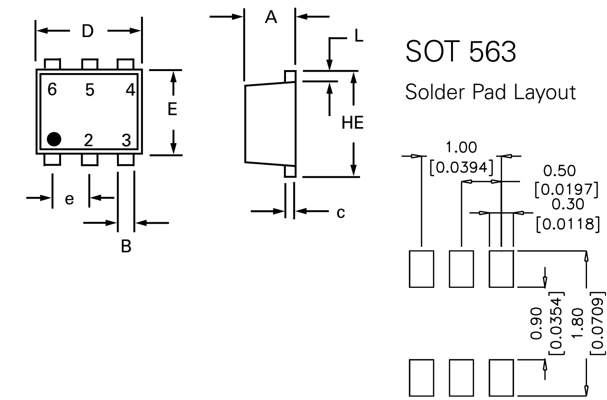
## Package Dimensions — SOT553 and SOT563

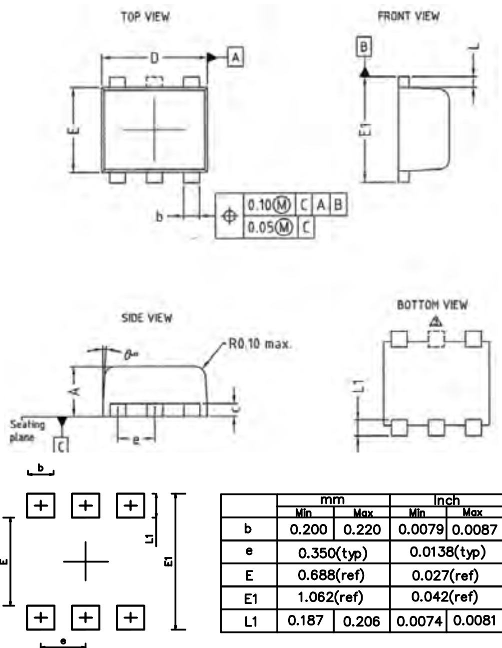



| Package | SOT 553 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.50 | 0.60 | 0.020 | 0.024 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.18 | 0.003 | 0.007 |
| **D** | 1.50 | 1.70 | 0.059 | 0.067 |
| **E** | 1.10 | 1.30 | 0.043 | 0.051 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **L** | 0.10 | 0.30 | 0.004 | 0.012 |
| **HE** | 1.50 | 1.70 | 0.059 | 0.067 |




| Package | SOT 563 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.50 | 0.60 | 0.020 | 0.024 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.18 | 0.003 | 0.007 |
| **D** | 1.50 | 1.70 | 0.059 | 0.067 |
| **E** | 1.10 | 1.30 | 0.043 | 0.051 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **L** | 0.10 | 0.30 | 0.004 | 0.012 |
| **HE** | 1.50 | 1.70 | 0.059 | 0.067 |

## Package Dimensions — SOT963




| | mm | | Inch | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| b | 0.200 | 0.220 | 0.0079 | 0.0087 |
| e | 0.350(typ) | | 0.0138(typ) | |
| E | 0.688(ref) | | 0.027(ref) | |
| E1 | 1.062(ref) | | 0.042(ref) | |
| L1 | 0.187 | 0.206 | 0.0074 | 0.0081 |

Recommanded Solder Pad Layout

| Package | SOT 963 | | | | | |
|---|---|---|---|---|---|---|
| Pins | 6 | | | | | |
| | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| **A** | 0.44 | 0.48 | 0.50 | 0.0173 | 0.0189 | 0.0197 |
| **B** | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| **c** | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 |
| **D** | 0.95 | 1.00 | 1.05 | 0.037 | 0.039 | 0.041 |
| **E** | 0.75 | 0.80 | 0.85 | 0.029 | 0.031 | 0.033 |
| **E1** | 0.95 | 1.00 | 1.05 | 0.037 | 0.039 | 0.041 |
| **e** | 0.35 BSC | | | 0.014 BSC | | |
| **L** | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 |
| **L1** | 0.125 | 0.15 | 0.175 | 0.005 | 0.006 | 0.007 |
| **ø** | 3 ° | 5 ° | 7 ° | 3 ° | 5 ° | 7 ° |

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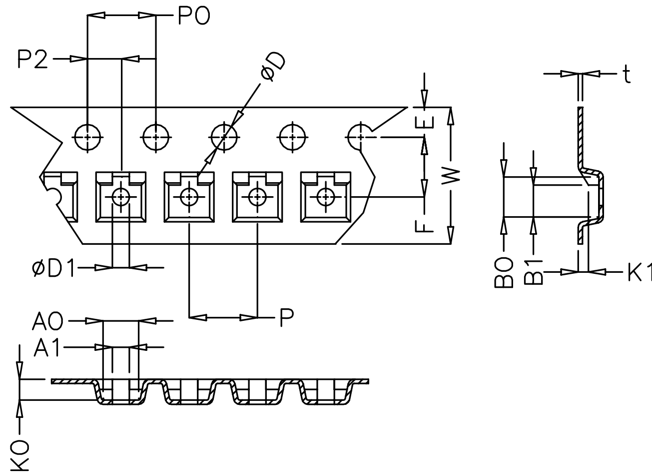
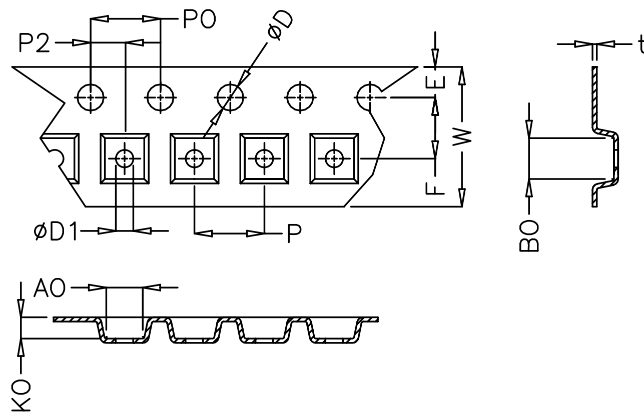
## Embossed Carrier Tape & Reel Specification — SC70-3




| Dimensions | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.30 | 2.50 | 0.090 | 0.098 |
| **A1** | 1.00 Ref | | 0.039 Ref | |
| **B0** | 2.30 | 2.50 | 0.090 | 0.098 |
| **B1** | 1.90 Ref | | 0.074 | |
| **K0** | 1.10 | 1.30 | 0.043 | 0.051 |
| **K1** | 0.60 Ref | | 0.023 Ref | |
| **t** | 0.27 max | | 0.010 | |

## Embossed Carrier Tape & Reel Specification — SC70-5 and SC70-6




| Dimensions | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.14 | 2.34 | 0.084 | 0.092 |
| **B0** | 2.24 | 2.44 | 0.088 | 0.096 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.27 max | | 0.010 max | |

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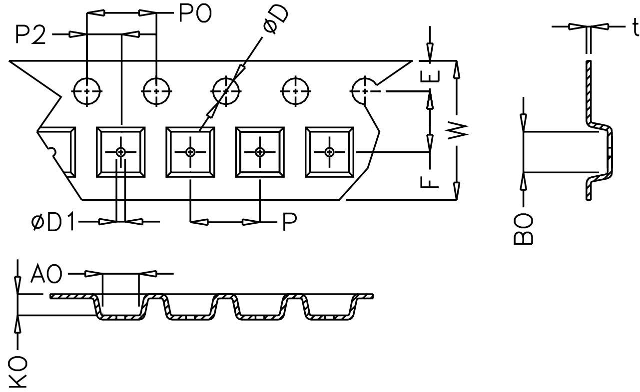
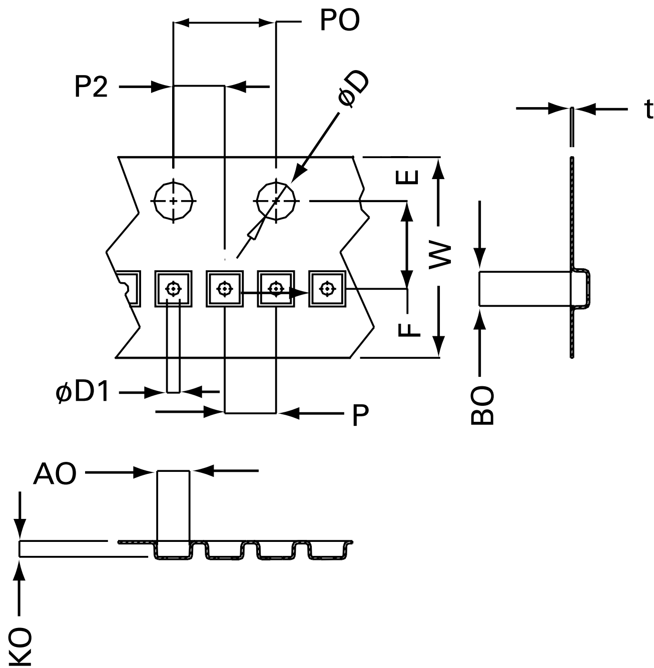
## Embossed Carrier Tape & Reel Specification — SOT553 and SOT563




### Dimensions

| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 0.45 | 0.55 | 0.017 | 0.021 |
| **P0** | 3.90 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 1.73 | 1.83 | 0.068 | 0.072 |
| **B0** | 1.73 | 1.83 | 0.068 | 0.072 |
| **K0** | 0.64 | 0.74 | 0.025 | 0.029 |
| **t** | 0.22 max | | .009 max | |

## Embossed Carrier Tape & Reel Specification – SOT963




### Dimensions

| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.136 | 0.140 |
| **D1** | 0.45 | 0.55 | 0.018 | 0.022 |
| **D** | 1.50 min | | 0.059 min | |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.575 ± 0.008 | |
| **P** | 1.95 | 2.05 | 0.077 | 0.081 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **W** | 7.90 | 8.20 | 0.311 | 0.323 |
| **A0** | 1.11 | 1.21 | 0.044 | 0.048 |
| **B0** | 1.11 | 1.21 | 0.044 | 0.048 |
| **K0** | 0.58 | 0.68 | 0.023 | 0.027 |
| **t** | 0.22 max | | 0.009 max | |

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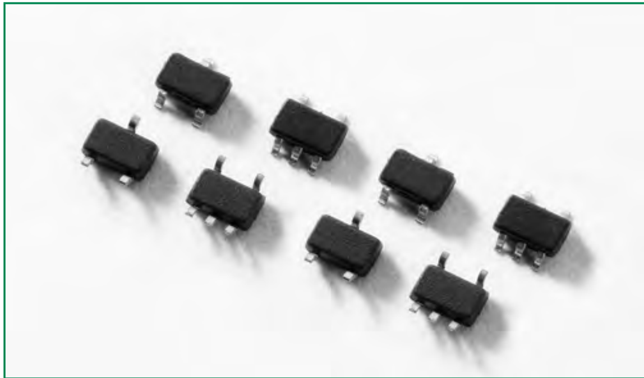
# SP1002 Series 5pF 8kV Bidirectional TVS Array

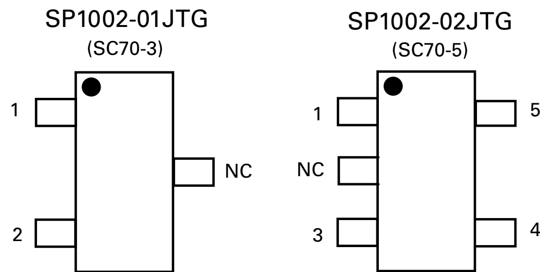
RoHS Pb GREEN



## Description

Back-to-Back Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high-speed signal pins.

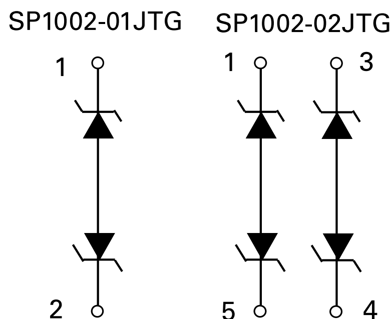
## Pinout




## Features

- Low capacitance of 5pF (TYP) I/O to I/O
- ESD protection of ±8kV contact discharge, ±15kV air discharge, (Level 4, IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5μA (MAX) at 5V
- Small package saves board space
- Lightning Protection, IEC61000-4-5, 2A (8/20μs)

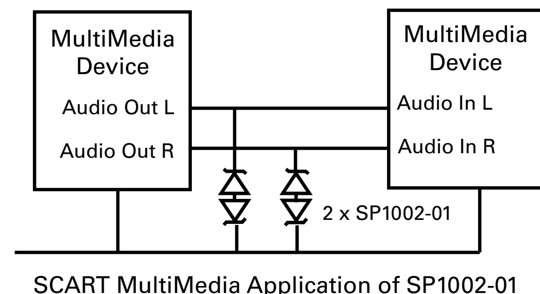
## Functional Block Diagram




## Applications

- Computer Peripherals
- Mobile Phones
- Digital Cameras
- Desktops/Notebooks
- LCD/PDP TVs
- Set Top Boxes
- DVD Players
- MP3/PMP

## Application Example




SCART MultiMedia Application of SP1002-01

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

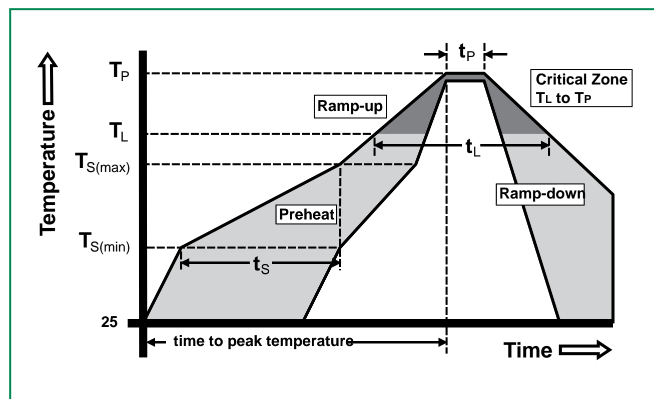
## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Voltage Drop | $V_D$ | $I_R$=1mA | 6.0 | | 9.5 | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA with 1 I/O at GND | | | 6.0 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V with I/O at GND | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.2 | 13.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 11.2 | 16.0 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 2.0 | | Ω |
| ESD Withstand Voltage[1,2] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 6 | | pF |
| | | Reverse Bias=2.5V | | 5 | | pF |
| | | Reverse Bias=5V | | 5 | | pF |

Notes:
[1] Parameter is guaranteed by device characterization
[2] A minimum of 1,000 ESD pulses are applied at 1s intervals

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes max. |
| Do not exceed | | 260°C |

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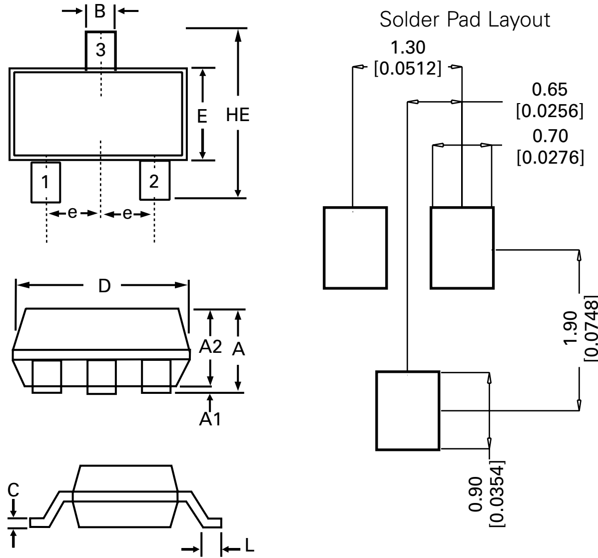
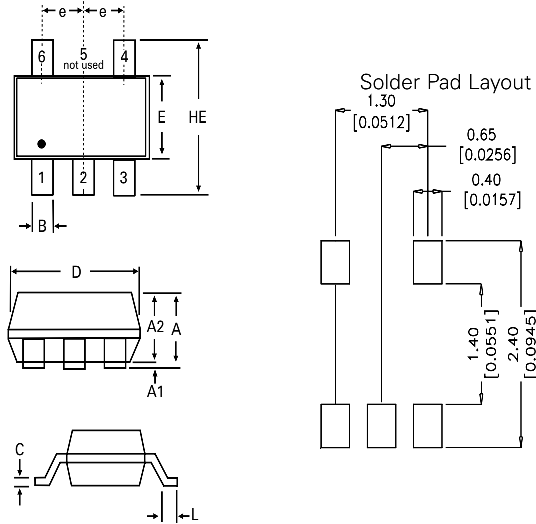
## Package Dimensions — SC70-3




| Package | SC70-3 | | | |
|---|---|---|---|---|
| Pins | 3 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.66 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Package Dimensions — SC70-5




| Package | SC70-5 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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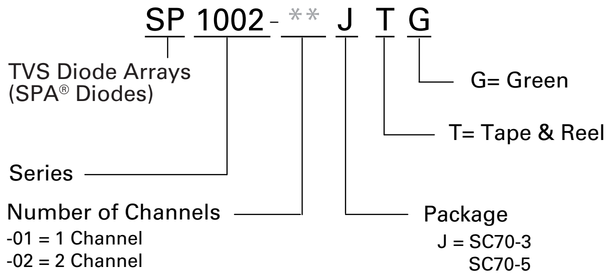
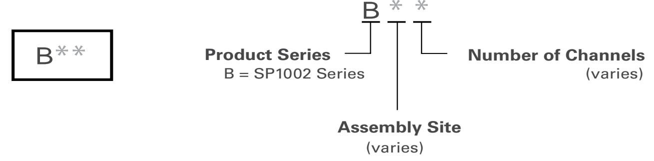
Specifications are subject to change without notice.

## Part Numbering System



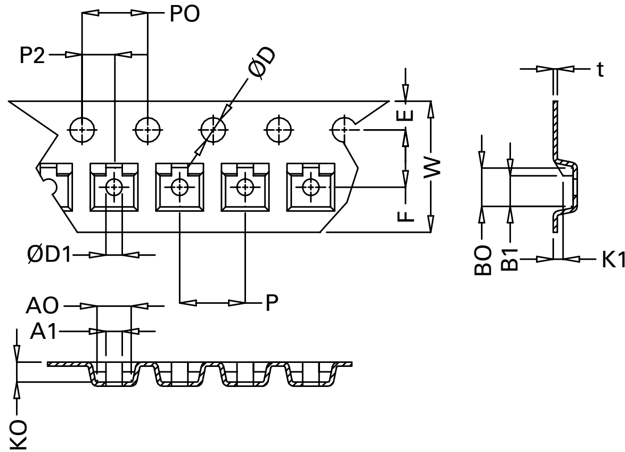

## Part Marking System




## Ordering Information

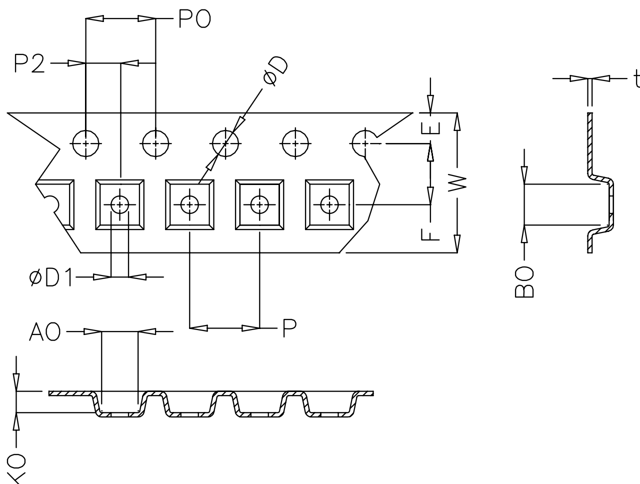
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1002-01JTG | SC70-3 | B*1 | 3000 |
| SP1002-02JTG | SC70-5 | B*2 | 3000 |

## Embossed Carrier Tape & Reel Specification — SC70-3




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 3.45 | 3.55 | 0.135 | 0.139 |
| P2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 1.40 | 1.60 | 0.055 | 0.063 |
| D1 | 1.00 | 1.25 | 0.039 | 0.049 |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| 10P0 | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| W | 7.70 | 8.10 | 0.303 | 0.318 |
| P | 3.90 | 4.10 | 0.153 | 0.161 |
| A0 | 2.30 | 2.50 | 0.090 | 0.098 |
| A1 | 1.00 Ref | | 0.039 Ref | |
| B0 | 2.30 | 2.50 | 0.090 | 0.098 |
| B1 | 1.90 Ref | | 0.074 | |
| K0 | 1.10 | 1.30 | 0.043 | 0.051 |
| K1 | 0.60 Ref | | 0.023 Ref | |
| t | 0.27 max | | 0.010 | |

## Embossed Carrier Tape & Reel Specification — SC70-5 and SC70-6




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 3.45 | 3.55 | 0.135 | 0.139 |
| P2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 1.40 | 1.60 | 0.055 | 0.063 |
| D1 | 1.00 | 1.25 | 0.039 | 0.049 |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| 10P0 | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| W | 7.70 | 8.10 | 0.303 | 0.318 |
| P | 3.90 | 4.10 | 0.153 | 0.161 |
| A0 | 2.14 | 2.34 | 0.084 | 0.092 |
| B0 | 2.24 | 2.44 | 0.088 | 0.096 |
| K0 | 1.12 | 1.32 | 0.044 | 0.052 |
| t | 0.27 max | | 0.010 max | |

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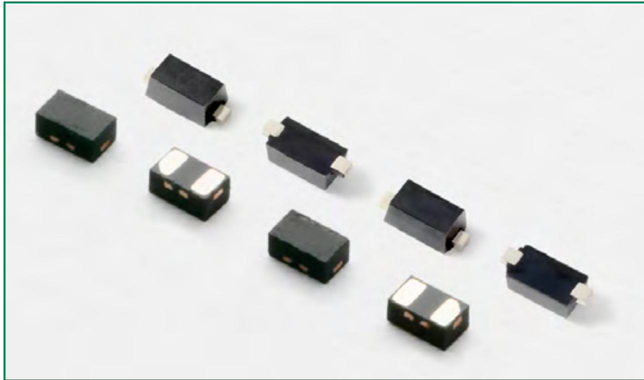
# SP1003 Series - 30pF 30kV Unidirectional Discrete TVS

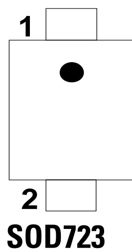
HF RoHS Pb GREEN



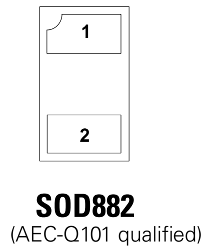
## Description

Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at ±30kV (contact discharge, IEC 61000-4-2) without performance degradation. Additionally, each diode can safely dissipate 7A of 8/20μs surge current (IEC61000-4-5) with very low clamping voltages.

## Pinout




**SOD723**

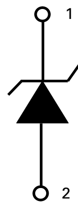



**SOD882**
(AEC-Q101 qualified)

## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 7A (8/20μs)
- Low leakage current of 100nA (MAX) at 5V
- Tiny SOD723/ SOD882 (JEDEC MO-236) package saves board space
- Fits solder footprint of industry standard 0402 (1005) devices
- AEC-Q101 qualified (SOD882 package)

## Functional Block Diagram




## Applications

- Mobile phones
- Smart phones
- PDAs
- Portable navigation devices
- Digital cameras
- Portable medical devices

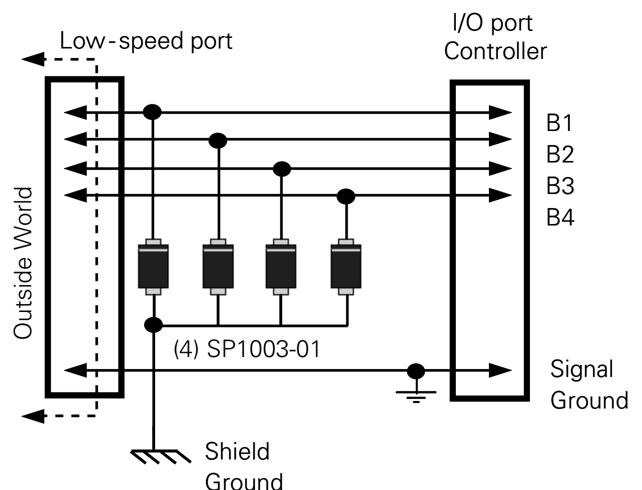
## Additional Information

**Datasheet**

**Resources**

**Samples**

## Application Example




Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Pulse Current ($t_p$=8/20μs) | 7.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

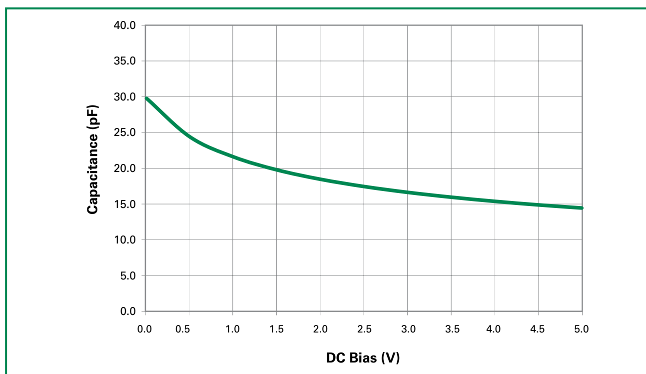
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

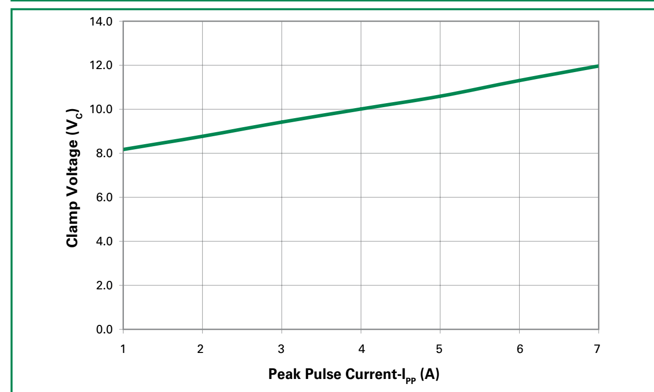
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Forward Voltage Drop | $V_F$ | $I_F$ = 10mA | | 0.8 | 1.2 | V |
| Reverse Voltage Drop | $V_R$ | $I_R$=1mA | 6.0 | 7.8 | 8.5 | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 5.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 100 | nA |
| Clamp Voltage[1] | $V_C$ | $I_{pp}$=6A $t_p$=8/20μs | | 11.4 | | V |
| | | $I_{pp}$=7A $t_p$=8/20μs | | 12.0 | | V |
| Dynamic Resistance | $R_{DYN}$ | TLP, $t_p$ =100ns, 1/O to GND | | 0.25 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | | ±30 | | kV |
| | | IEC61000-4-2 (Air Discharge) | | ±30 | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 30 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Clamping Voltage vs. $I_{PP}$

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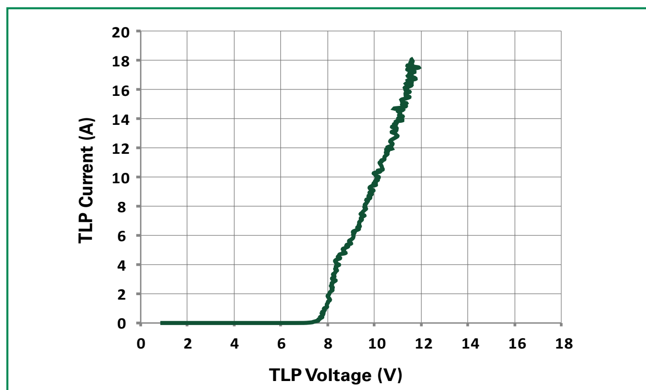
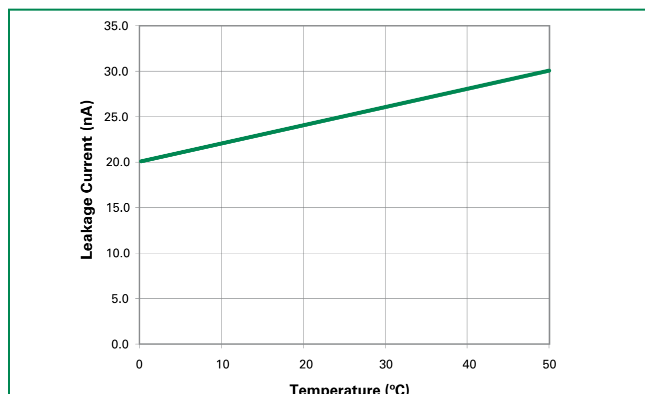
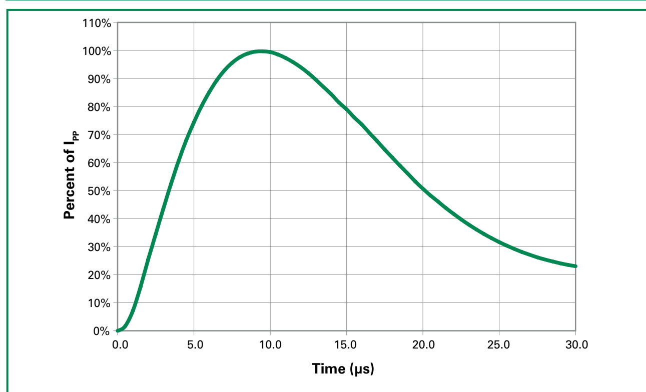
## Transmission Line Pulsing (TLP) Plot




## Leakage vs. Temperature

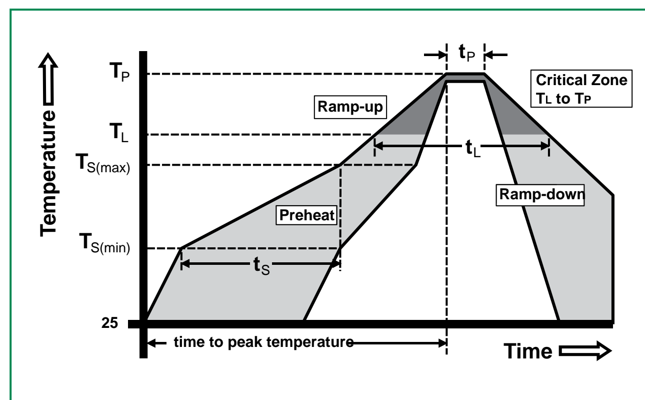



## Pulse Waveform




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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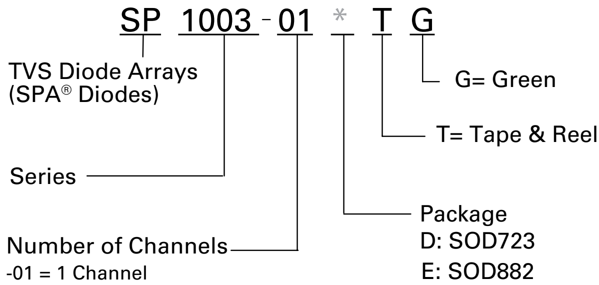
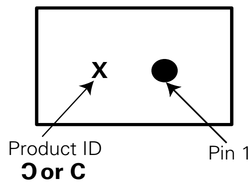
## Part Numbering System




## Part Marking System




## Product Characteristics

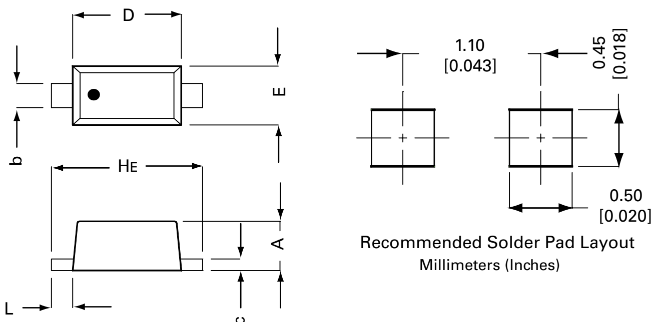
| Lead Plating | Pre-Plated Frame or Matte Tin |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1003-01DTG | SOD723 | Ↄ or C | 8,000 |
| SP1003-01ETG | SOD882 | Ↄ or C | 10,000 |

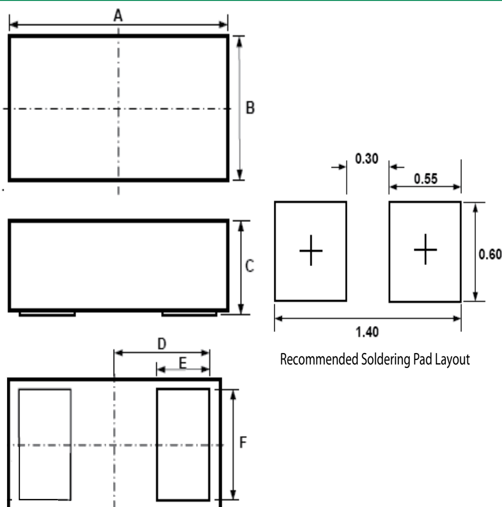
## Package Dimensions — SOD723



Recommended Solder Pad Layout
Millimeters (Inches)

| Symbol | SOD723 | | | |
|---|---|---|---|---|
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.46 | 0.65 | 0.018 | 0.026 |
| **b** | 0.23 | 0.35 | 0.009 | 0.014 |
| **c** | 0.08 | 0.13 | 0.003 | 0.005 |
| **D** | 0.90 | 1.10 | 0.035 | 0.043 |
| **E** | 0.58 | 0.64 | 0.023 | 0.025 |
| **HE** | 1.37 | 1.47 | 0.054 | 0.058 |
| **L** | 0.15 | 0.25 | 0.006 | 0.010 |

## Package Dimensions — SOD882




0.30
0.55
0.60
1.40
Recommended Soldering Pad Layout

| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **B** | 0.50 | 0.60 | 0.70 | 0.020 | 0.024 | 0.028 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | | 0.45 | | | 0.018 | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

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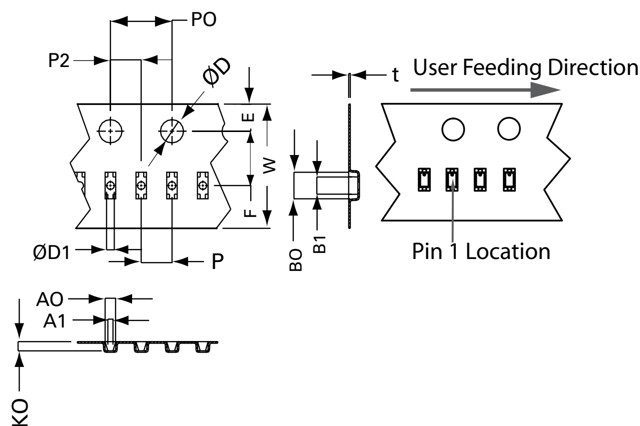
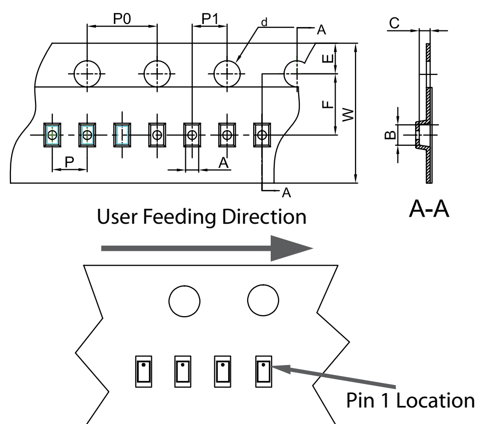
## Embossed Carrier Tape & Reel Specification — SOD723




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.072 |
| **F** | 3.40 | 3.60 | 0.134 | 0.142 |
| **D1** | 0.45 | 0.55 | 0.017 | 0.021 |
| **D** | 1.50 | - - | 0.060 | - - |
| **PO** | 3.90 | 4.10 | 0.153 | 0.161 |
| **10PO** | 40.0± 0.20 | | 1.570±0.010 | |
| **W** | 7.90 | 8.20 | 0.311 | 0.322 |
| **P2/P** | 1.90 | 2.10 | 0.074 | 0.082 |
| **AO** | 0.60 | 0.80 | 0.024 | 0.032 |
| **A1** | 0.33 REF | | 0.010 REF | |
| **BO** | 1.61 | 1.81 | 0.063 | 0.071 |
| **B1** | 1.10 REF | | 0.040 REF | |
| **KO** | 0.54 | 0.78 | 0.021 | 0.031 |
| **t** | - - | 0.21 | - - | 0.008 |

## Embossed Carrier Tape & Reel Specification — SOD882




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **A** | 0.65 | 0.70 | 0.026 | 0.028 |
| **B** | 1.10 | 1.20 | 0.043 | 0.047 |
| **C** | 0.50 | 0.60 | 0.020 | 0.024 |
| **dØ** | 1.40 | 1.60 | 0.055 | 0.063 |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.40 | 3.60 | 0.134 | 0.142 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **P** | 1.90 | 2.10 | 0.075 | 0.083 |
| **P1** | 1.90 | 2.10 | 0.075 | 0.083 |
| **W** | 7.90 | 8.10 | 0.311 | 0.319 |

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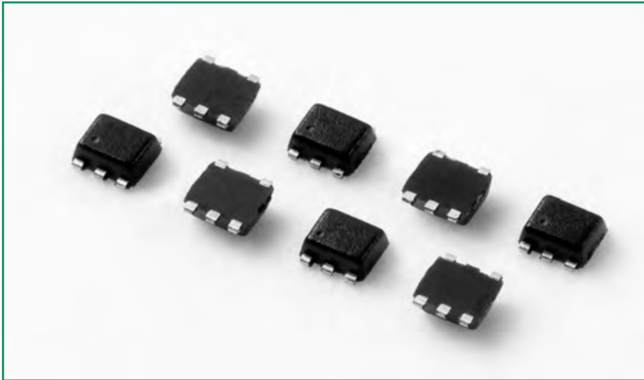
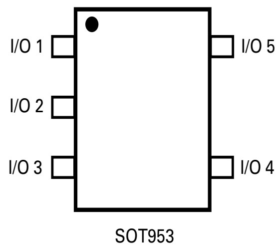
# SP1004 Series 5pF 8kV Bidirectional TVS Array



## Description

Back-to-back zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high-speed signal pins.

## Pinout



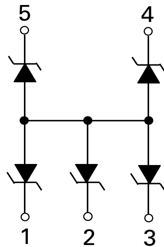

SOT953

Notes:
[1]Any of the 5 I/O pins can be tied to GND to provide 4 channels of bidirectional protection

## Features

- ESD, IEC61000-4-2, ±8kV contact, ±15kV air
- Capable of withstanding >1,000 ±8kV ESD strikes
- Lightning, IEC61000-4-5, 2A ($t_p$=8/20μs)
- Low capacitance of 5pF (TYP) per I/O
- Low leakage current of 1μA (MAX) at 5V
- Small SOT953 package

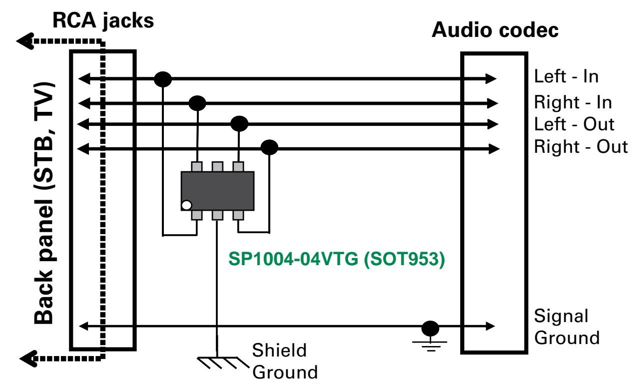
## Functional Block Diagram




## Applications

- MP3-PMPs
- DVD players
- Desktops
- Mobile phones
- Digital cameras
- Set top boxes
- Notebooks

## Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Pulse Current ($t_p$=8/20μs) | 2.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

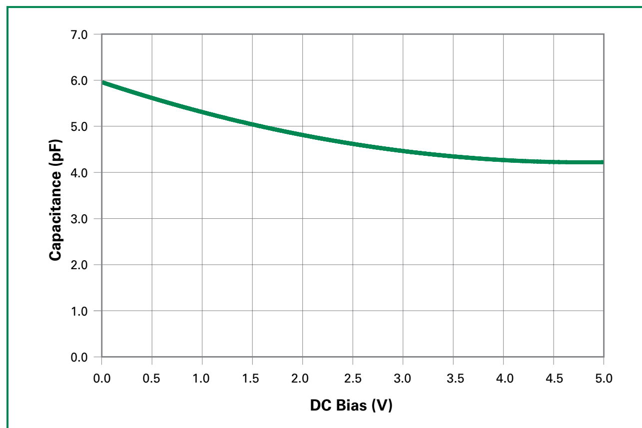
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

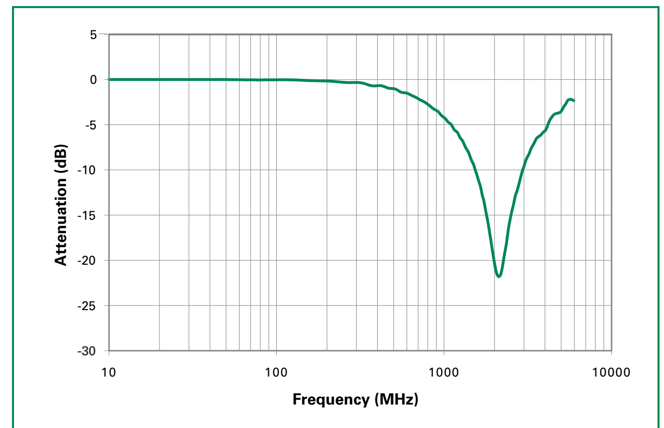
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Voltage Drop[1] | $V_R$ | $I_R$=1mA | 6.0 | | 9.5 | V |
| Reverse Standoff Voltage[1] | $V_{RWM}$ | $I_R$≤1μA | | | 6.0 | V |
| Reverse Leakage Current[1] | $I_{LEAK}$ | $V_R$=5V | | | 0.1 | μA |
| Clamp Voltage[2] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs | | 10 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs | | 12 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 2.0 | | Ω |
| ESD Withstand Voltage[1,2] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge)[3] | ±8 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±15 | | | kV |
| Diode Capacitance[1,2] | $C_D$ | Reverse Bias=0V | | 6 | 7 | pF |
| | | Reverse Bias=1.5V | | 5 | 6 | pF |

Note: [1] Parameter specified with pin 2 grounded externally.
[2] Parameter is guaranteed by design and/or device characterization.
[3] Capable of withstanding >1,000 pulses at 1s intervals.

## Capacitance vs. Reverse Bias




## Insertion Loss (S21)

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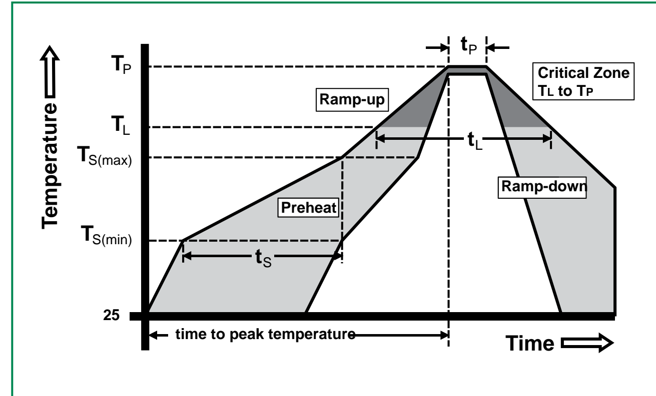
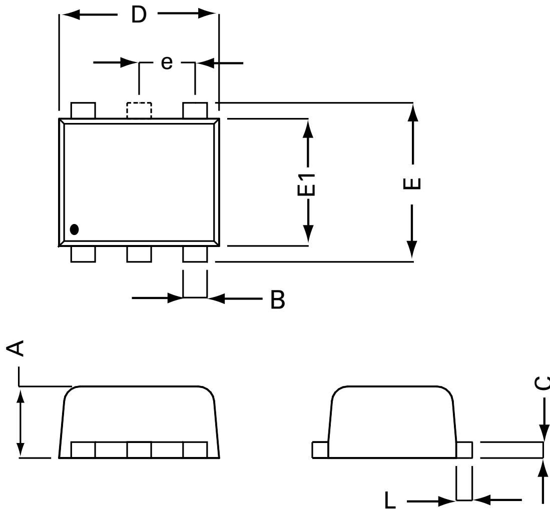
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — SOT953




| Symbol | SOT953 | | | |
|---|---|---|---|---|
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.44 | 0.5 | 0.170 | 0.020 |
| **B** | 0.10 | 0.20 | 0.004 | 0.008 |
| **c** | 0.05 | 0.15 | 0.002 | 0.006 |
| **D** | 0.95 | 1.05 | 0.037 | 0.041 |
| **E** | 0.95 | 1.05 | 0.037 | 0.041 |
| **E1** | 0.75 | 0.85 | 0.029 | 0.033 |
| **e** | 0.35 BSC | | 0.014 BSC | |
| **L** | 0.05 | 0.15 | 0.002 | 0.006 |

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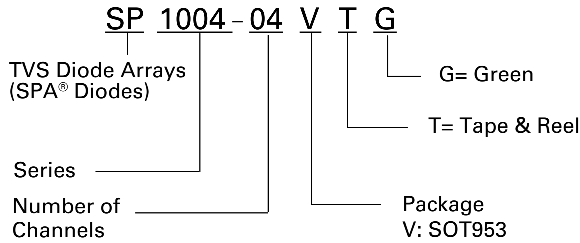
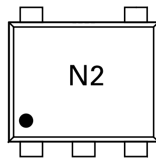
## Part Numbering System




## Part Marking System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

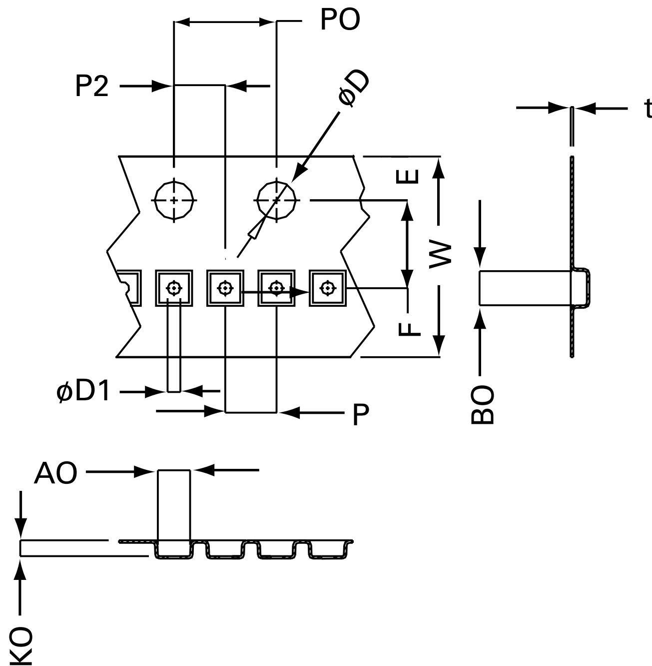
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1004-04VTG | SOT953 | N2 | 8000 |

## Embossed Carrier Tape & Reel Specification – SOT953




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.136 | 0.140 |
| **D1** | 0.45 | 0.55 | 0.018 | 0.022 |
| **D** | 1.50 min | | 0.059 min | |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.575 ± 0.008 | |
| **P** | 1.95 | 2.05 | 0.077 | 0.081 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **W** | 7.90 | 8.20 | 0.311 | 0.323 |
| **A0** | 1.11 | 1.21 | 0.044 | 0.048 |
| **B0** | 1.11 | 1.21 | 0.044 | 0.048 |
| **K0** | 0.58 | 0.68 | 0.023 | 0.027 |
| **t** | 0.22 max | | 0.009 max | |

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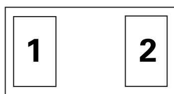
# SP1005 Series 30pF 30kV Bidirectional Discrete TVS

## Description

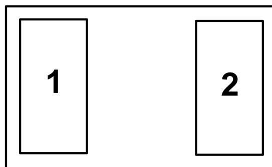
The SP1005 includes back-to-back Zener diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

## Pinout

0201 Flipchip




SOD882




(AEC-Q101 qualified)

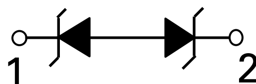
## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 10A ($t_P$=8/20μs)
- Low capacitance of 30pF (@ $V_R$=0V)
- Low leakage current of 0.1μA at 5V
- Space efficient 0201 and 0402 footprint
- AEC-Q101 qualified (SOD882 package)

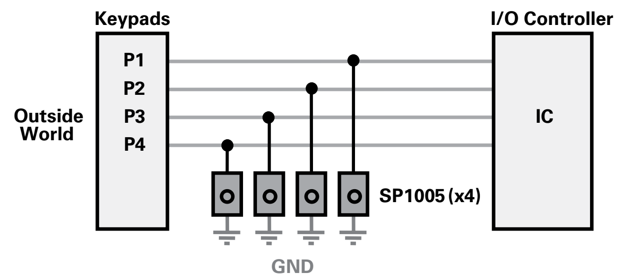
## Applications

- Mobile Phones
- Smart Phones
- Camcorders
- Portable Medical
- Digital Cameras
- MP3/PMP
- Portable Navigation Devices
- Tablets
- Point of Sale Terminals

## Functional Block Diagram




## Application Example




## Additional Information

**Datasheet**

**Resources**

**Samples**

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 10.0 [1] | A |
| | | 8.0 [2] | |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

Notes:
1. *"1 " indicates SP1005-01WTG , while "2" indicates SP1005-01ETG*
2. *CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

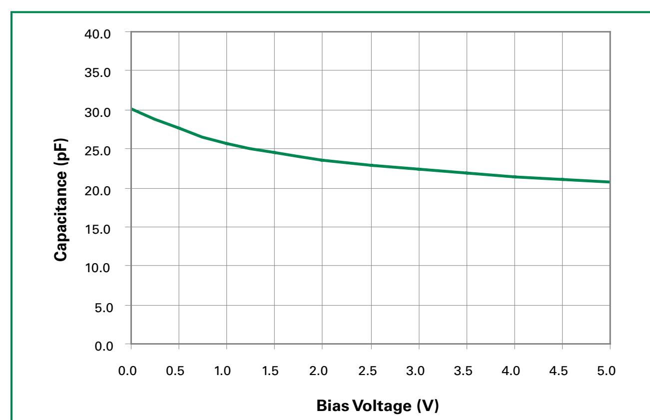
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

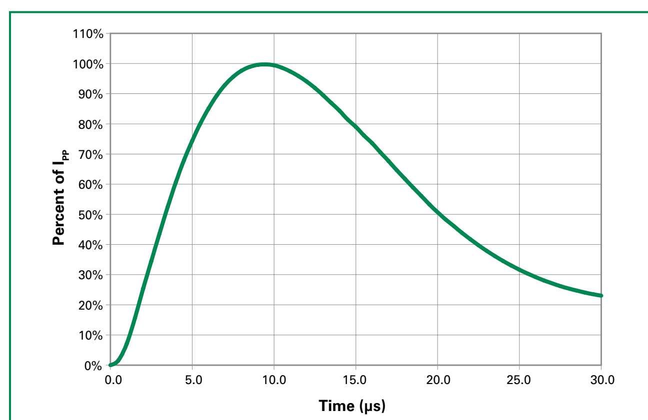
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 6.0 | V |
| Breakdown Voltage | $V_{BR}$ | $I_R$=1mA | | 8.5 | 9.5 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V with 1 pin at GND | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.3 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.0 | | V |
| | | $I_{PP}$=10A, $t_P$=8/20μs, Fwd | | 15.6 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.7 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 30 | | pF |
| | | Reverse Bias=2.5V | | 23 | | pF |

Note:
[1]Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Pulse Waveform

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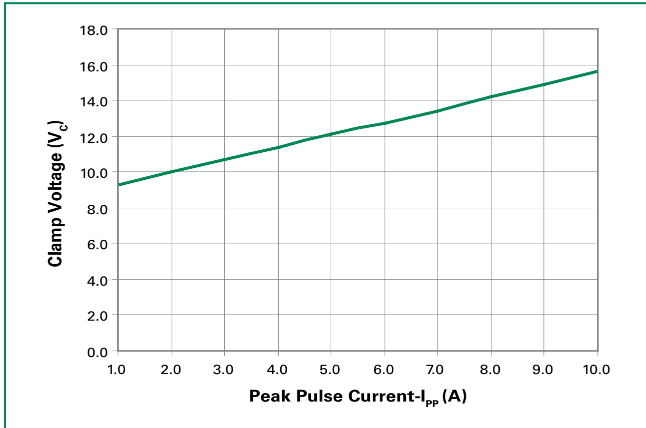
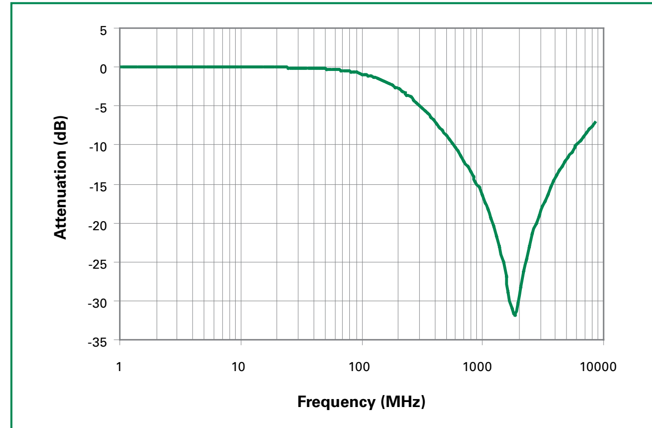
## Clamping Voltage vs. $I_{PP}$

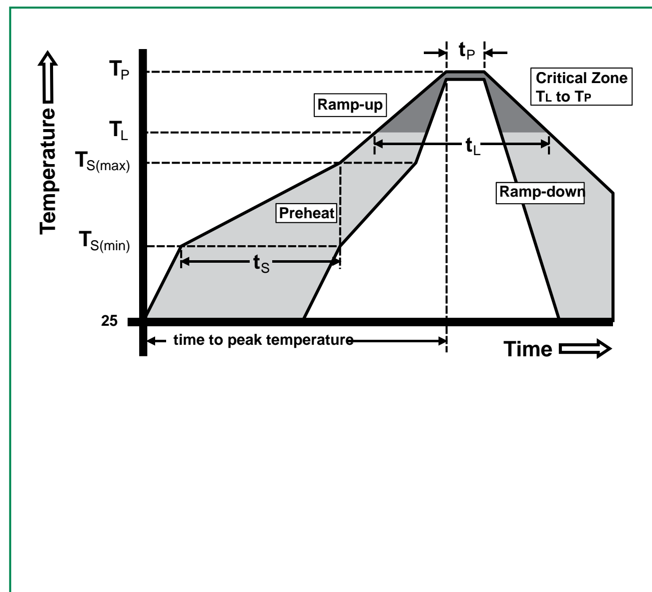



## Insertion Loss (S21) I/O to GND




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Product Characteristics of SOD-882 Package

| **Lead Plating** | Pre-Plated Frame |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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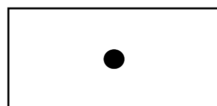
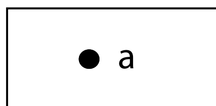
## Part Marking System

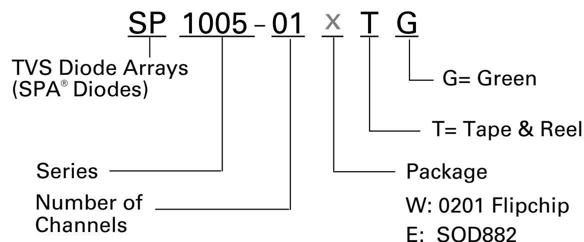


SP1005-01WTG




SP1005-01ETG

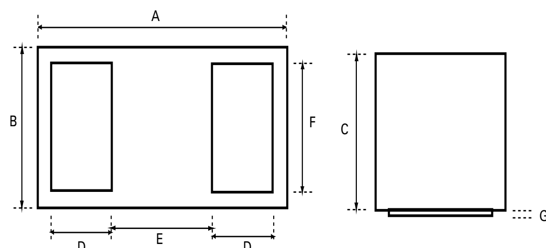
## Part Numbering System




## Ordering Information

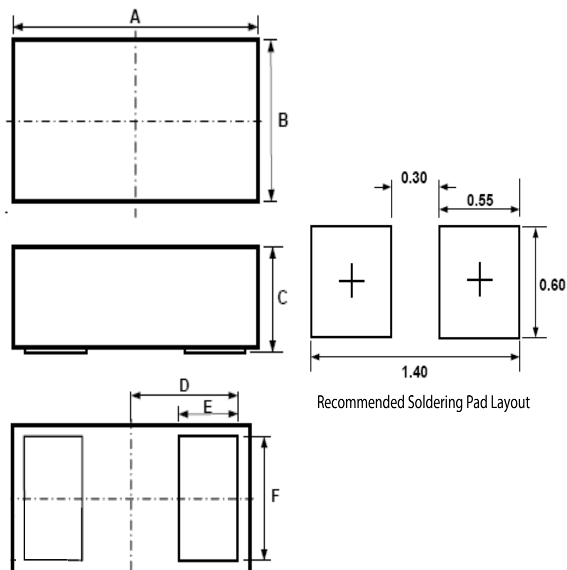
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1005-01WTG | 0201 Flipchip | • | 10,000 |
| SP1005-01ETG | SOD882 | •a | 10,000 |

## Package Dimensions — 0201 Flipchip




| Symbol | 0201 Flipchip | | | | | |
|---|---|---|---|---|---|---|
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.595 | 0.620 | 0.645 | 0.0234 | 0.0244 | 0.0254 |
| **B** | 0.295 | 0.320 | 0.345 | 0.0116 | 0.0126 | 0.0136 |
| **C** | 0.245 | 0.275 | 0.305 | 0.0096 | 0.0108 | 0.0120 |
| **D** | 0.145 | 0.150 | 0.155 | 0.0057 | 0.0059 | 0.0061 |
| **E** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **F** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **G** | 0.005 | 0.010 | 0.015 | 0.0002 | 0.0004 | 0.0006 |

## Package Dimensions — SOD882

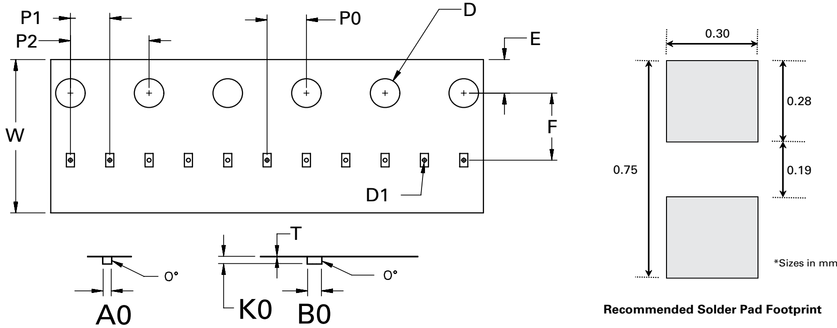



Recommended Soldering Pad Layout

| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **B** | 0.50 | 0.60 | 0.70 | 0.020 | 0.024 | 0.028 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | | 0.45 | | | 0.018 | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

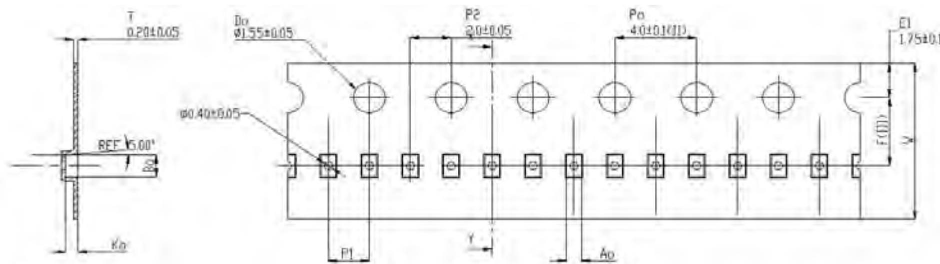
© 2

## Embossed Carrier Tape & Reel Specification — 0201 Flipchip

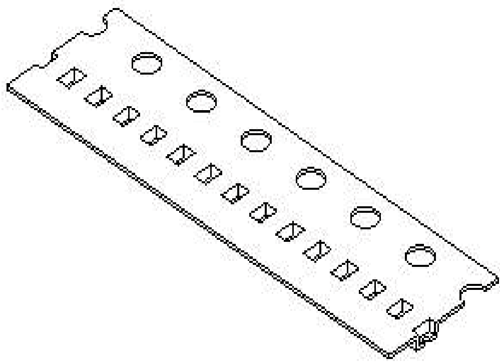



| Symbol | Millimeters |
|---|---|
| A0 | 0.41±0.03 |
| B0 | 0.70±0.03 |
| D | ø 1.50 + 0.10 |
| D1 | ø 0.20 ± 0.05 |
| E | 1.75±0.10 |
| F | 3.50±0.05 |
| K0 | 0.38±0.03 |
| P0 | 2.00±0.05 |
| P1 | 2.00±0.05 |
| P2 | 4.00±0.10 |
| W | 8.00 + 0.30 -0.10 |
| T | 0.23±0.02 |

## Embossed Carrier Tape & Reel Specification — SOD882



| Symbol | Millimeters |
|---|---|
| A0 | 0.70±0.045 |
| B0 | 1.10±0.045 |
| K0 | 0.65±0.045 |
| F | 3.50±0.05 |
| P1 | 2.00±0.10 |
| W | 8.00 + 0.30 -0.10 |



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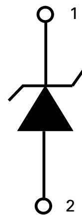
# SP1006 Series 25pF 30kV Unidirectional Discrete TVS

RoHS Pb GREEN

## Pinout

## Functional Block Diagram




## Additional Information

**Datasheet**

**Resources**

**Samples**

## Description

Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at ±30kV (contact discharge, IEC 61000-4-2) without performance degradation. Additionally, each diode can safely dissipate 5A of 8/20μs surge current (IEC61000-4-5) with very low clamping voltages.

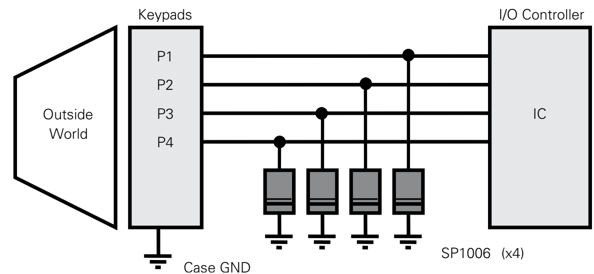
## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 5A (8/20μs)
- Low leakage current of 0.5μA (MAX) at 5V
- Space efficient 0201 footprint)

## Applications

- Mobile phones
- Smart phones
- PDAs
- Digital cameras
- Portable navigation devices
- Portable medical devices

## Application Example




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Pulse Current ($t_p$=8/20μs) | 5 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

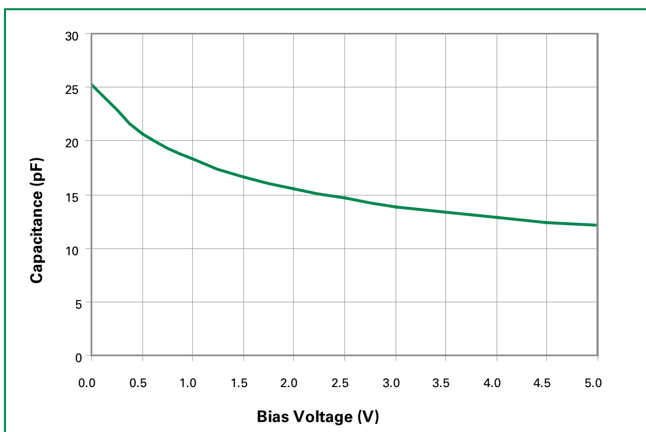
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 30s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

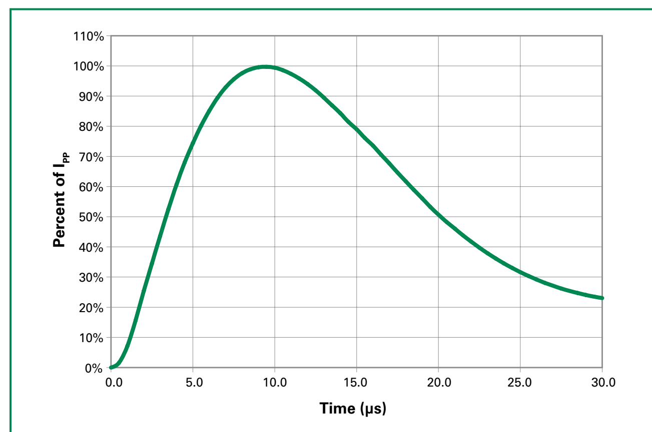
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 6.0 | V |
| Breakdown Voltage | $V_{BR}$ | $I_R$=1mA (Pin 1 to 2) | | 7.8 | | V |
| Forward Voltage Drop | $V_F$ | $I_R$=1mA (Pin 2 to 1) | | 0.8 | | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{pp}$=1A, $t_p$=8/20μs (Pin 1 to 2) | | 8.3 | | V |
| | | $I_{pp}$=2A, $t_p$=8/20μs (Pin 1 to 2) | | 9.2 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.9 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 25 | | pF |
| | | Reverse Bias=2.5V | | 15 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Pulse Waveform

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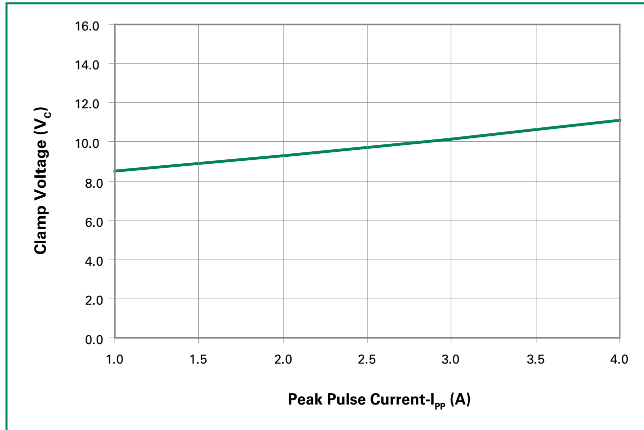
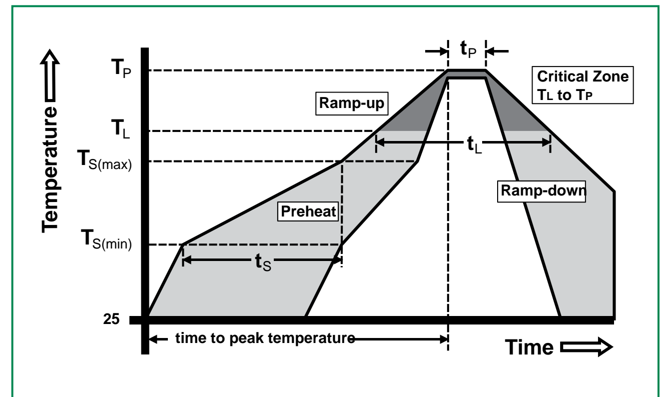
## Clamping Voltage vs. $I_{PP}$

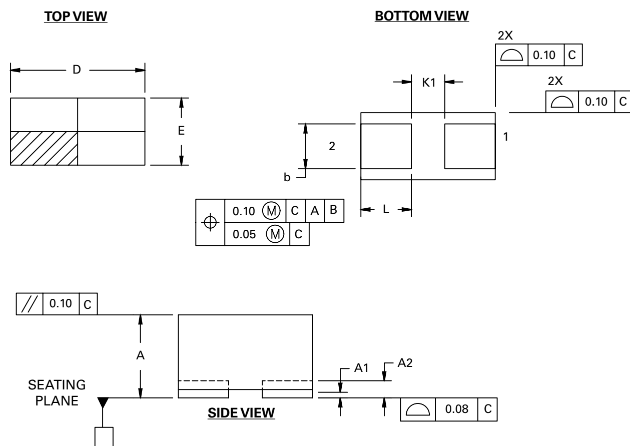



## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |




## Package Dimensions — μDFN-2 (0201)




| Package | μDFN-2 (0201) | | | |
|---|---|---|---|---|
| JEDEC | MO-236 | | | |
| Symbol | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.34 | 0.40 | 0.014 | 0.016 |
| **A1** | 0.00 | 0.05 | 0.000 | 0.002 |
| **A2** | 0.075 REF | | 0.003 REF | |
| **b** | 0.20 REF | | 0.008 REF | |
| **D** | 0.55 | 0.65 | 0.022 | 0.026 |
| **E** | 0.25 | 0.35 | 0.010 | 0.014 |
| **L** | 0.175 | 0.275 | 0.007 | 0.011 |
| **K1** | 0.15 REF | | 0.006 REF | |

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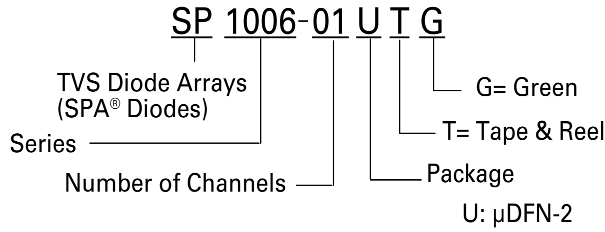
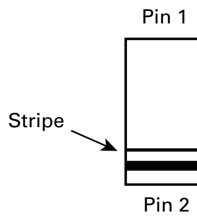
## Part Numbering System




## Part Marking System




## Ordering Information

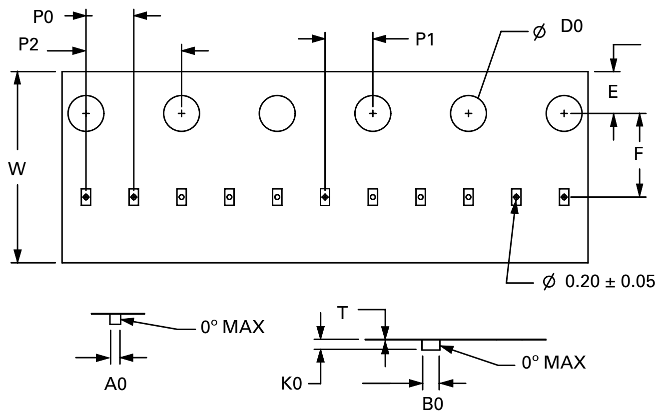
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1006-01UTG | µDFN-2 | ‖ | 10000 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Embossed Carrier Tape & Reel Specification — µDFN-2




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **A0** | 0.36 | 0.42 | 0.014 | 0.017 |
| **B0** | 0.66 | 0.72 | 0.026 | 0.028 |
| **D0** | 1.40 | 1.60 | 0.055 | 0.063 |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.136 | 0.140 |
| **K0** | 0.39 | 0.45 | 0.015 | 0.018 |
| **P0** | 1.95 | 2.05 | 0.077 | 0.081 |
| **P1** | 1.95 | 2.05 | 0.077 | 0.081 |
| **P2** | 3.90 | 4.10 | 0.154 | 0.161 |
| **T** | 0.18 | 0.22 | 0.007 | 0.009 |
| **W** | 7.90 | 8.30 | 0.311 | 0.327 |

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# SP1007 Series 3.5pF 8kV Bidirectional Discrete TVS

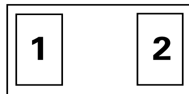
HF RoHS Pb GREEN

## Description

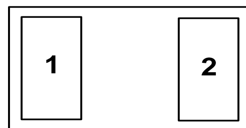
The SP1007 includes back-to-back Zener diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level specified in the IEC61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

## Pinout

0201 Flipchip




SOD882



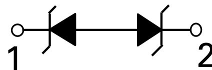

## Features

- ESD, IEC61000-4-2, ±8kV contact, ±15kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 2A ($t_P$=8/20μs)
- Low capacitance of 5pF (TYP @ $V_R$=5V)
- Low leakage current of 0.1μA at 5V
- Space efficient 0201 and 0402 footprint

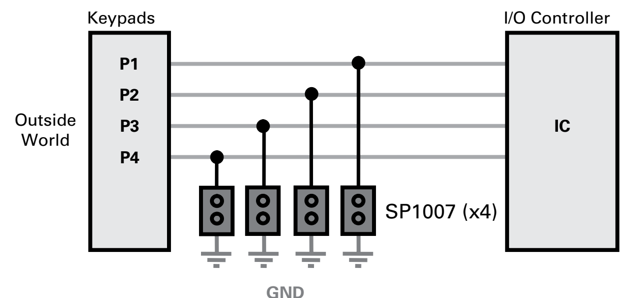
## Applications

- Mobile Phones
- Smart Phones
- Camcorders
- Portable Medical
- Digital Cameras
- MP3/PMP
- Portable Navigation Devices
- Tablets
- Point of Sale Terminals

## Functional Block Diagram




## Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 6.0 | V |
| Breakdown Voltage | $V_{BR}$ | $I_R$=1mA | | 8.5 | 9.5 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V with 1 pin at GND | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 11.2 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 13.1 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.9 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±8 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±15 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 5 | 6 | pF |

Note:
[1]Parameter is guaranteed by design and/or device characterization.

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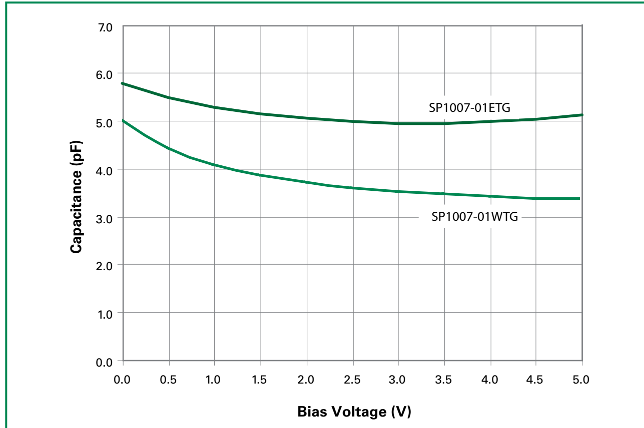
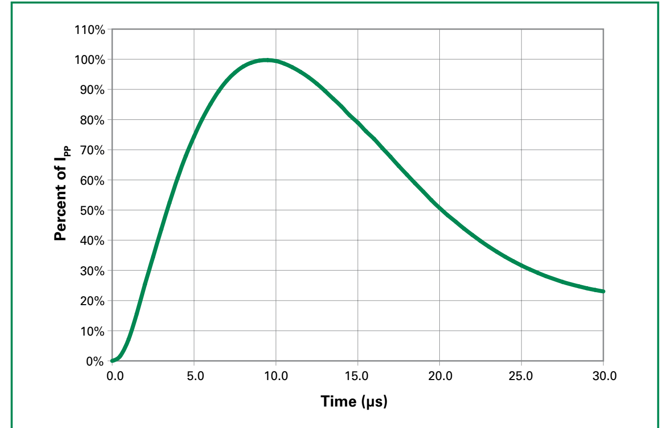
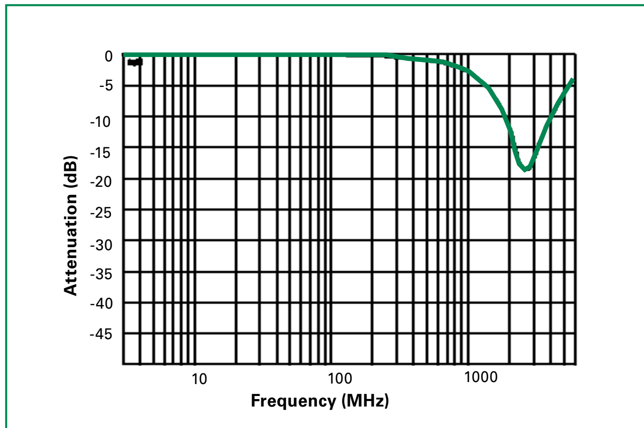
## Capacitance vs. Reverse Bias




## Pulse Waveform




## Insertion Loss (S21) I/O to GND



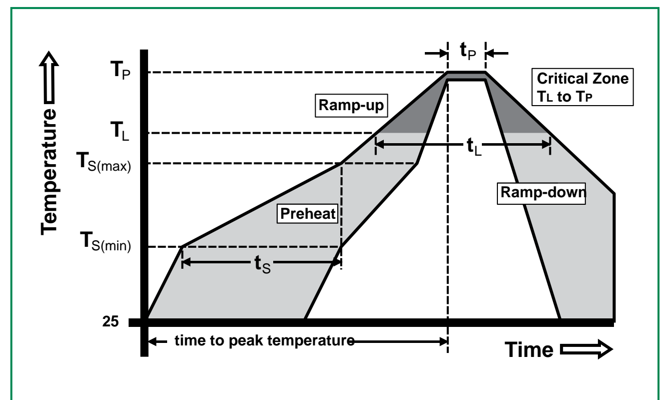

## Product Characteristics of SOD-882 Package

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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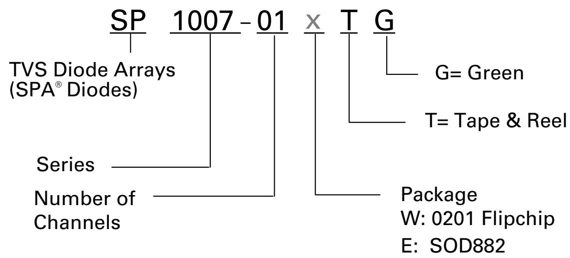
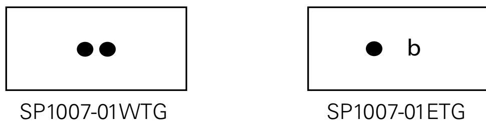
## Part Numbering System



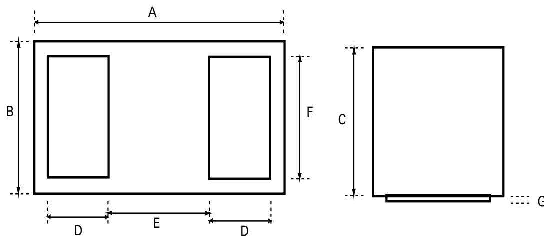

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1007-01WTG | 0201 Flipchip | • • | 10,000 |
| SP1007-01ETG | SOD882 | •b | 10,000 |

## Part Marking System

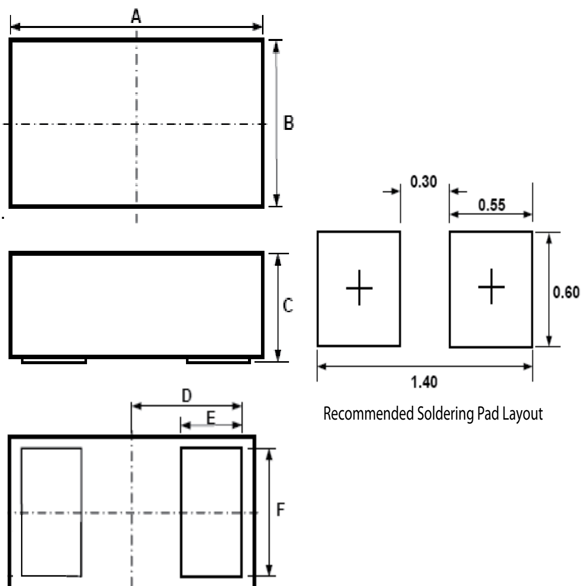



## Package Dimensions — 0201 Flip Chip




| Symbol | 0201 Flipchip | | | | | |
|---|---|---|---|---|---|---|
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.595 | 0.620 | 0.645 | 0.0234 | 0.0244 | 0.0254 |
| **B** | 0.295 | 0.320 | 0.345 | 0.0116 | 0.0126 | 0.0136 |
| **C** | 0.245 | 0.275 | 0.305 | 0.0096 | 0.0108 | 0.0120 |
| **D** | 0.145 | 0.150 | 0.155 | 0.0057 | 0.0059 | 0.0061 |
| **E** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **F** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **G** | 0.005 | 0.010 | 0.015 | 0.0002 | 0.0004 | 0.0006 |

## Package Dimensions — SOD882




Recommended Soldering Pad Layout

| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **B** | 0.50 | 0.60 | 0.70 | 0.020 | 0.024 | 0.028 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | | 0.45 | | | 0.018 | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

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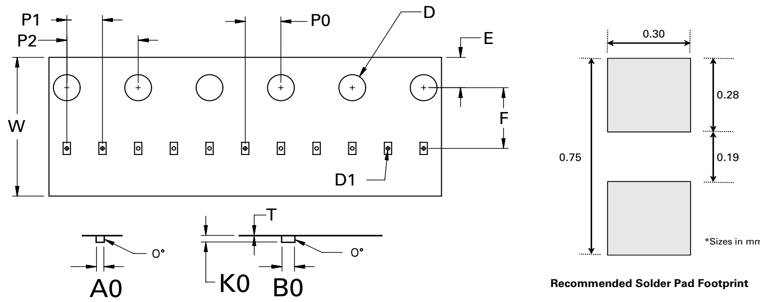
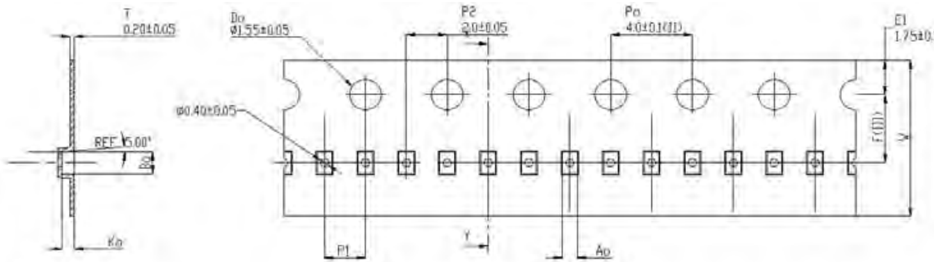
## Embossed Carrier Tape & Reel Specification — 0201 Flipchip




| Symbol | Millimeters |
|---|---|
| **A0** | 0.41±0.03 |
| **B0** | 0.70±0.03 |
| **D** | ø 1.50 + 0.10 |
| **D1** | ø 0.20 ± 0.05 |
| **E** | 1.75±0.10 |
| **F** | 3.50±0.05 |
| **K0** | 0.38±0.03 |
| **P0** | 2.00±0.05 |
| **P1** | 2.00±0.05 |
| **P2** | 4.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |
| **T** | 0.23±0.02 |

## Embossed Carrier Tape & Reel Specification — SOD882




| Symbol | Millimeters |
|---|---|
| **A0** | 0.70±0.045 |
| **B0** | 1.10±0.045 |
| **K0** | 0.65±0.045 |
| **F** | 3.50±0.05 |
| **P1** | 2.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |

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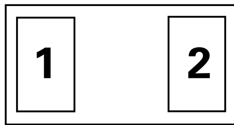
Revised: 12/20/13

# SP1008 Series 6pF 15kV Bidirectional Discrete TVS Protection

## Description

The SP1008 includes back-to-back TVS diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (±15kV contact discharge) without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

## Pinout

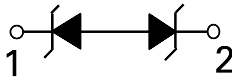



Note: Drawing not to scale

## Features

- ESD, IEC61000-4-2, ±15kV contact, ±15kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 3A ($t_P$=8/20μs)
- Low capacitance of 6pF (@ $V_R$=5V)
- Low leakage current of 0.1μA at 5V
- Space efficient 0201 footprint

## Functional Block Diagram




## Applications

- Mobile phones
- MP3/PMP
- PDA
- Camcorders
- Smart phones
- External storage
- Tablets
- Digital cameras

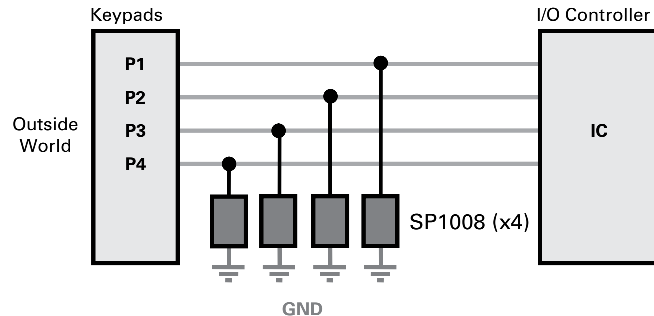
## Additional Information

Datasheet

Resources

Samples

## Application Example




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 3.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 6.0 | V |
| Breakdown Voltage | $V_{BR}$ | $I_R$=1mA | | 7.0 | 8.5 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V with 1 pin at GND | | 0.1 | | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 10.7 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 12.0 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.3 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±15 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±15 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=5.0V | | 6 | 9 | pF |

Note:
[1]Parameter is guaranteed by design and/or device characterization.

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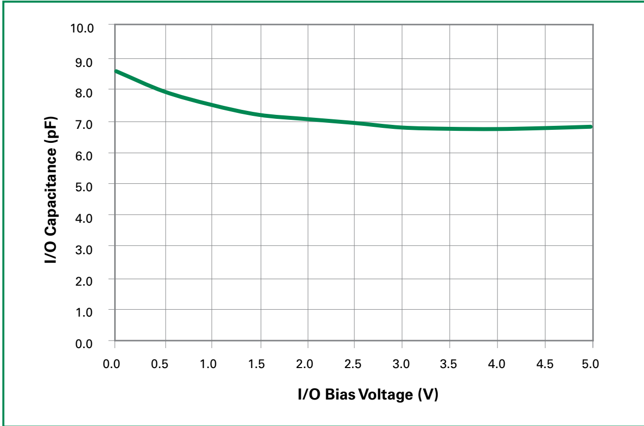
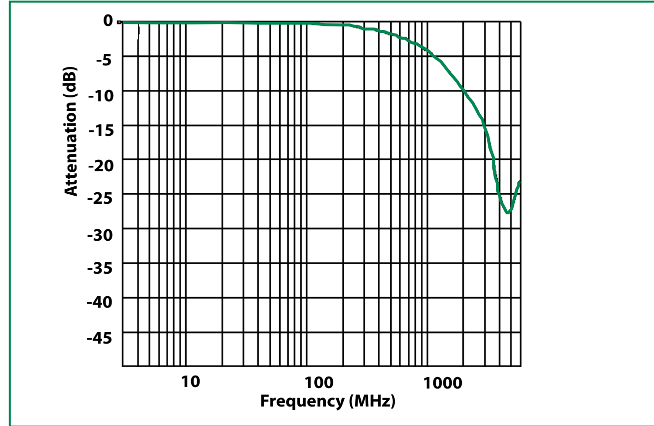
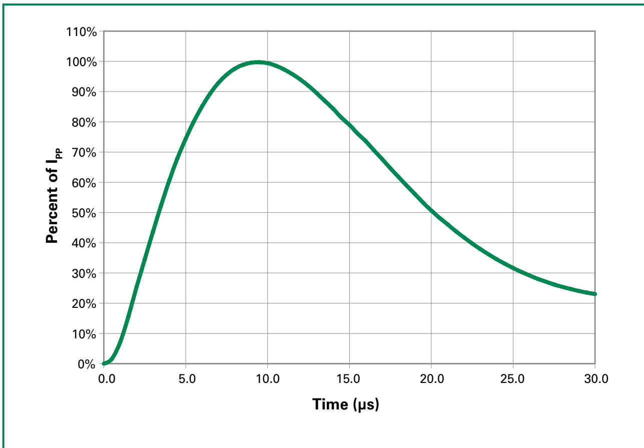
## Capacitance vs. Reverse Bias



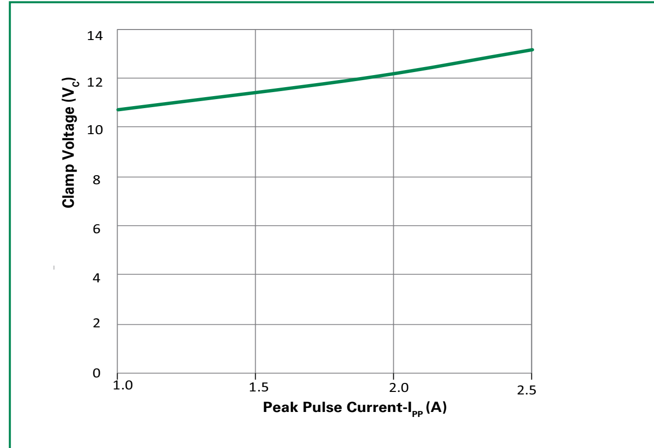

## Insertion Loss (S21) I/O to GND




## Pulse Waveform

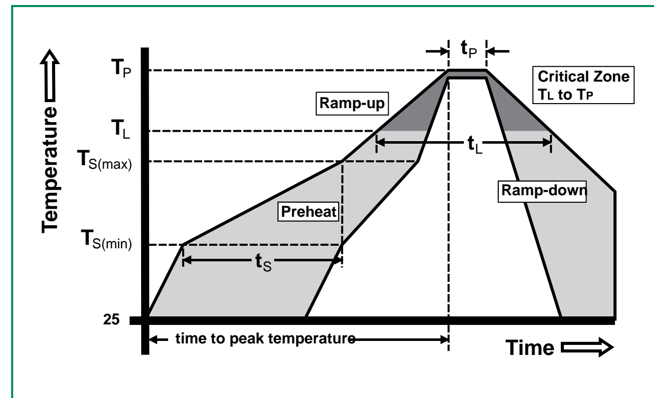



## Clamping Voltage vs. $I_{PP}$




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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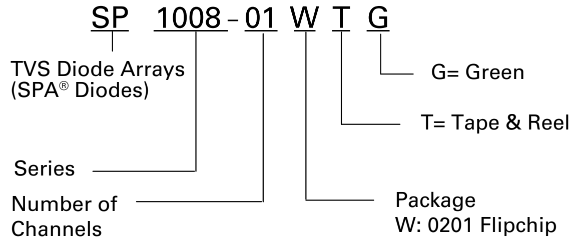
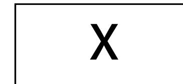
## Part Numbering System



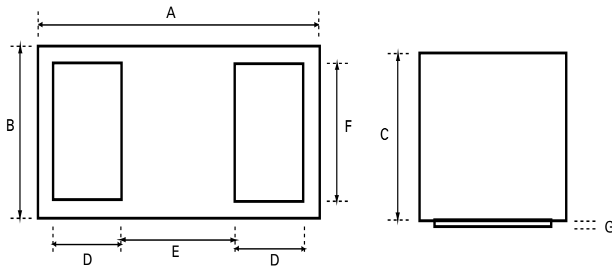

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1008-01WTG | 0201 Flipchip | X | 10000 |

## Part Marking System

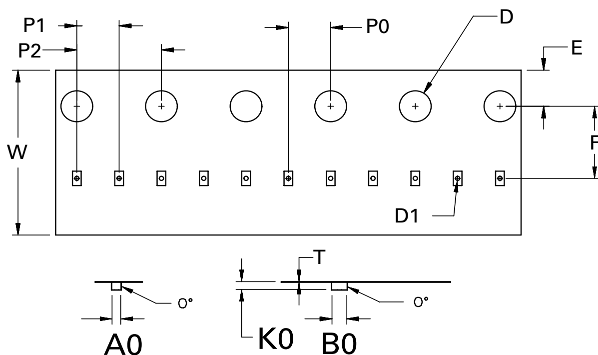


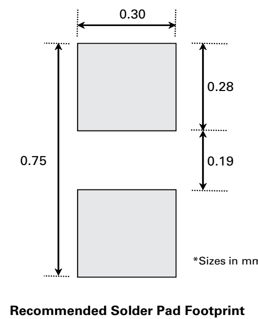

## Package Dimensions — 0201 Flip Chip




| Symbol | 0201 Flipchip | | | | | |
|---|---|---|---|---|---|---|
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.595 | 0.620 | 0.645 | 0.0234 | 0.0244 | 0.0254 |
| **B** | 0.295 | 0.320 | 0.345 | 0.0116 | 0.0126 | 0.0136 |
| **C** | 0.245 | 0.275 | 0.305 | 0.0096 | 0.0108 | 0.0120 |
| **D** | 0.145 | 0.150 | 0.155 | 0.0057 | 0.0059 | 0.0061 |
| **E** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **F** | 0.245 | 0.250 | 0.255 | 0.0096 | 0.0098 | 0.0100 |
| **G** | 0.005 | 0.010 | 0.015 | 0.0002 | 0.0004 | 0.0006 |

## Embossed Carrier Tape & Reel Specification — 0201 Flipchip




Recommended Solder Pad Footprint

| Symbol | Millimeters |
|---|---|
| **A0** | 0.41±0.03 |
| **B0** | 0.70±0.03 |
| **D** | ø 1.50 + 0.10 |
| **D1** | ø 0.20 ± 0.05 |
| **E** | 1.75±0.10 |
| **F** | 3.50±0.05 |
| **K0** | 0.38±0.03 |
| **P0** | 2.00±0.05 |
| **P1** | 2.00±0.05 |
| **P2** | 4.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |
| **T** | 0.23±0.02 |

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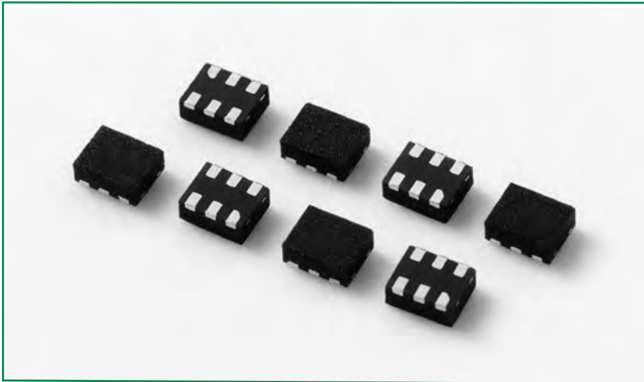
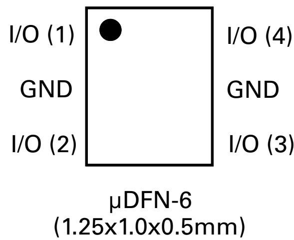
# SP1011 Series 7pF 15kV Unidirectional TVS Array



## Description

Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protection high-speed signal pins.

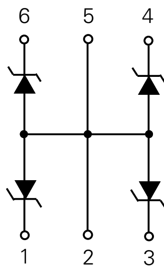
## Pinout




## Features

- ESD, IEC61000-4-2, ±15kV contact, ±30kV air
- Lightning, IEC61000-4-5, 2A ($t_p$=8/20µs)
- Low capacitance of 7 pF (TYP) per I/O @ 2.5V
- Low leakage current of 1µA (MAX) at 5V
- Tiny µDFN( JEDEC MO-229) package (1.25mm x 1.0mm x 0.5mm)
- EFT protection IEC61000-4-4, 40A (5/50ns)

## Functional Block Diagram




## Applications

- LCD/PDP TV
- DVD Player
- Desktop
- Set Top Box
- Mobile Phone
- Notebook
- MP3/PMP
- Digital camera

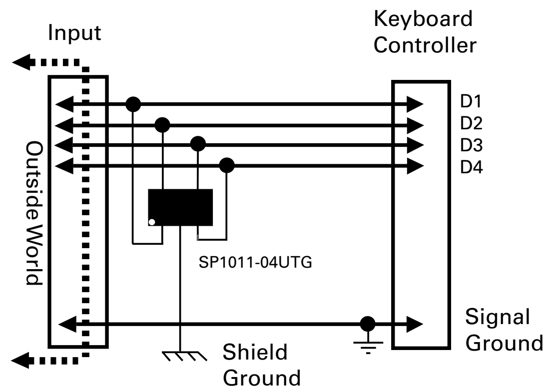
## Additional Information

Datasheet

Resources

Samples

## Application Example




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Pulse Current ($t_p$=8/20μs) | 2 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

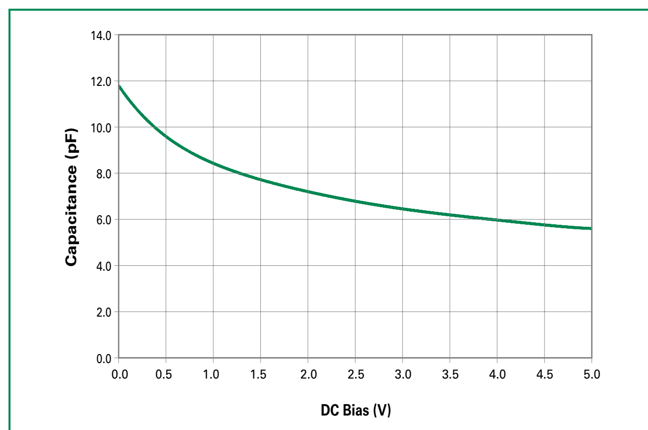
## Electrical Characteristics ($T_{OP}$=25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Voltage Drop | $V_R$ | $I_R$ = 1mA | 6.0 | | 8.5 | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 6 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$ = 5V | | 0.1 | 1 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 8.7 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.2 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.5 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±15 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias = 0V | | 12 | 15 | pF |
| | | Reverse Bias = 2.5V | | 7 | | pF |

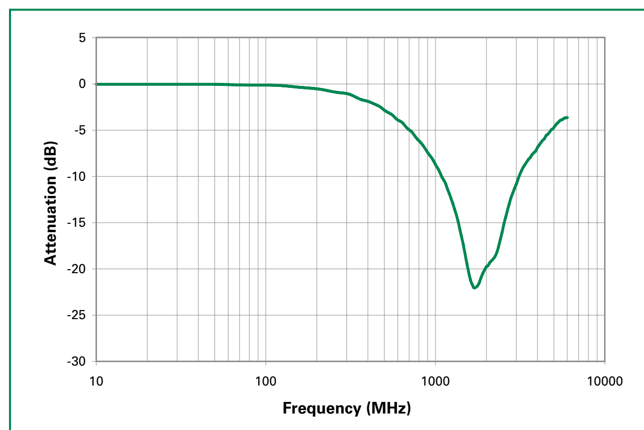
Note:

1. Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Insertion Loss (S21) I/O to GND

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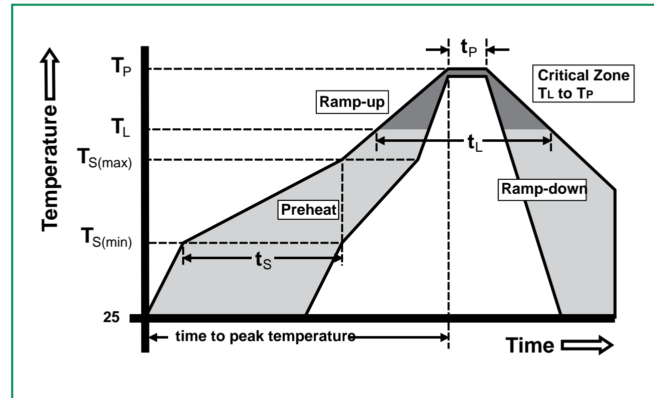
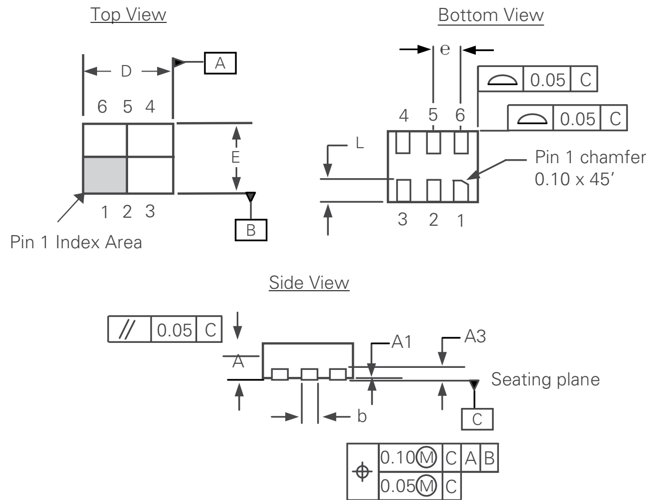
## Soldering Parameters

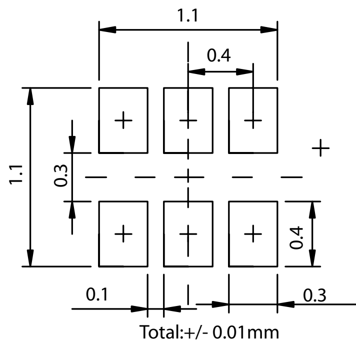
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — μDFN-6 (1.25x1.0x0.5mm)




Recommanded Soldering Pad for μDFN-6L 1.25 x1.0x0.5 mm




| Package | μDFN-6 (1.25x1.0x0.5mm) | | | |
|---|---|---|---|---|
| JEDEC | MO-229 | | | |
| Symbol | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.45 | 0.55 | 0.018 | 0.022 |
| **A1** | 0.00 | 0.05 | 0.000 | 0.002 |
| **A3** | 0.127 REF | | 0.005 REF | |
| **b** | 0.15 | 0.25 | 0.006 | 0.010 |
| **D** | 1.20 | 1.30 | 0.047 | 0.051 |
| **D2** | - | - | - | - |
| **E** | 0.95 | 1.05 | 0.037 | 0.041 |
| **E2** | - | - | - | - |
| **e** | 0.4 REF | | 0.016 REF | |
| **L** | 0.25 | 0.35 | 0.010 | 0.014 |

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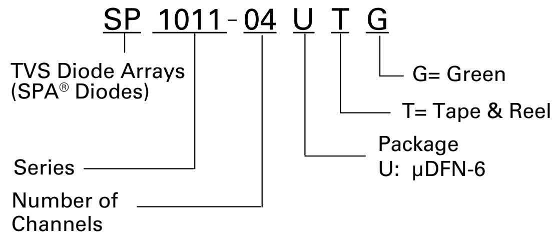
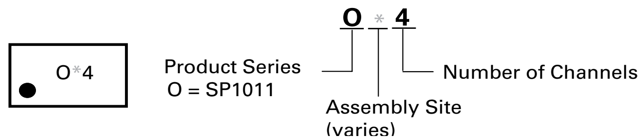
## Part Numbering System




## Part Marking System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

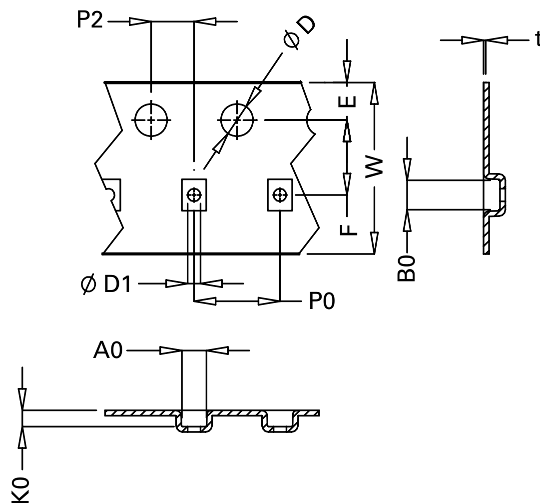
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP1011-04UTG | μDFN-6 (1.25x1.0x0.5mm) | O4 | 3000 |

## Embossed Carrier Tape & Reel Specification —μDFN-6 (1.25x1.0x0.5mm)




| Symbol | Millimeters | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.06 | 0.07 |
| **F** | 3.45 | 3.55 | 0.14 | 0.14 |
| **D1** | 0.50 | 0.65 | 0.02 | 0.03 |
| **D** | 1.50 MIN | | 0.06 MIN | |
| **P0** | 3.90 | 4.10 | 0.15 | 0.16 |
| **10P0** | 40.0 ± 0.20 | | 1.57 ± 0.01 | |
| **W** | 7.90 | 8.30 | 0.31 | 0.33 |
| **P2** | 1.95 | 2.05 | 0.08 | 0.08 |
| **A0** | 1.09 | 1.19 | 0.04 | 0.05 |
| **B0** | 1.42 | 1.52 | 0.06 | 0.06 |
| **K0** | 0.71 | 0.81 | 0.03 | 0.03 |
| **t** | 0.25 TYP | | 0.01 TYP | |

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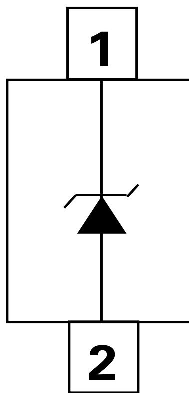
# SD05 Series 450W Discrete Unidirectional TVS Diode

## Description

The SD05 TVS diode is designed to replace multilayer varistors (MLVs) in electronic equipment for low speed and DC applications. It will protect any sensitive equipment from damage due to electrostatic discharge (ESD) and other transient events.

The SD05 can safely absorb repetitive ESD strikes at ±30kV (contact discharge, IEC 61000-4-2) without performance degradation and safely dissipate 30A of 8/20μs induced surge current (IEC61000-4-5) with very low clamping voltages.

## Pinout and Functional Block Diagram




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 30A ($t_P$=8/20μs)
- Low clamping voltage
- Low leakage current
- Small SOD323 package fits 0805 footprints

## Applications

- Switches / Buttons
- Test Equipment / Instrumentation
- Point-of-Sale Terminals
- Medical Equipment
- Notebooks / Desktops / Servers
- Computer Peripherals

## Additional Information

Datasheet

Resources

Samples

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 30 | A |
| $P_{pk}$ | Peak Pulse Power ($t_p$=8/20μs) | 450 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

Notes:
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

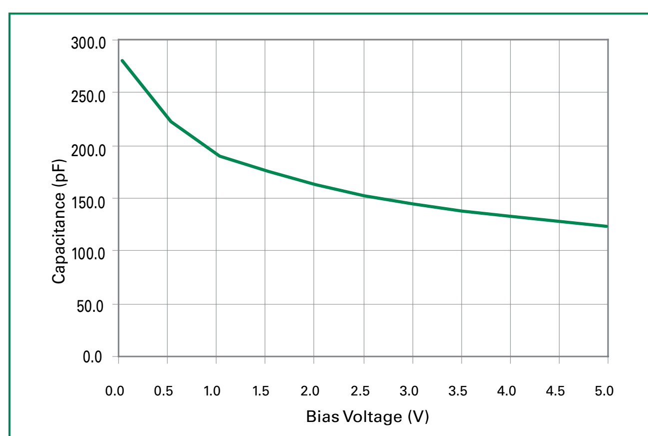
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

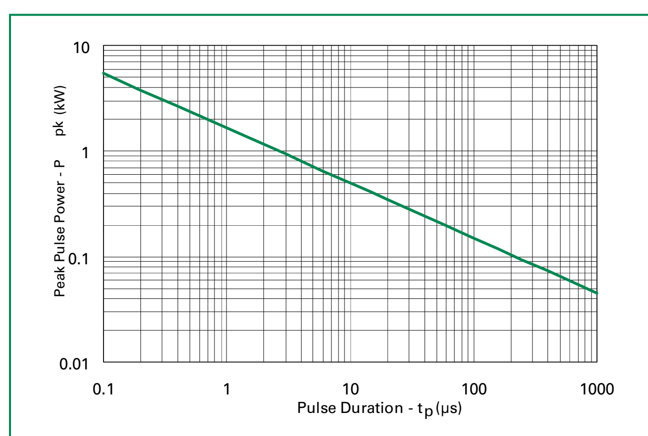
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Voltage Drop | $V_R$ | $I_R$=1mA | 6 | | | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 5.0 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 1.0 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 8.0 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 8.5 | | V |
| | | $I_{PP}$=10A, $t_P$=8/20μs, Fwd | | 11.8 | | V |
| | | $I_{PP}$=24A, $t_P$=8/20μs, Fwd | | 16.8 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.5 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V, f=1MHz | | | 350 | pF |

Note:
[1]Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Non-Repetitive Peak Pulse Power vs. Pulse Time

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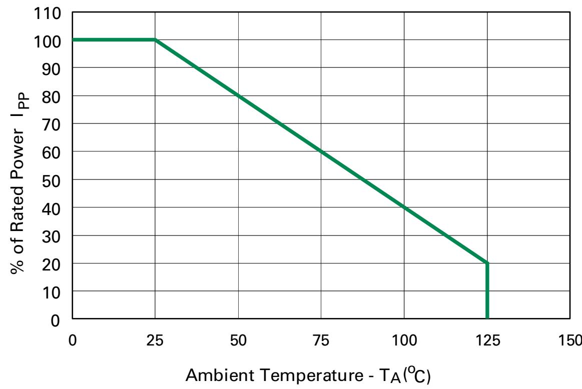
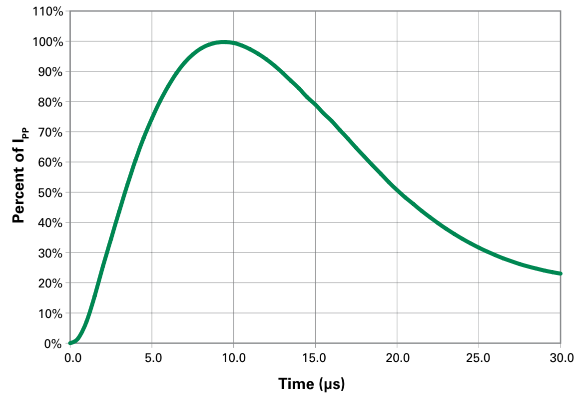
## Power Derating Curve

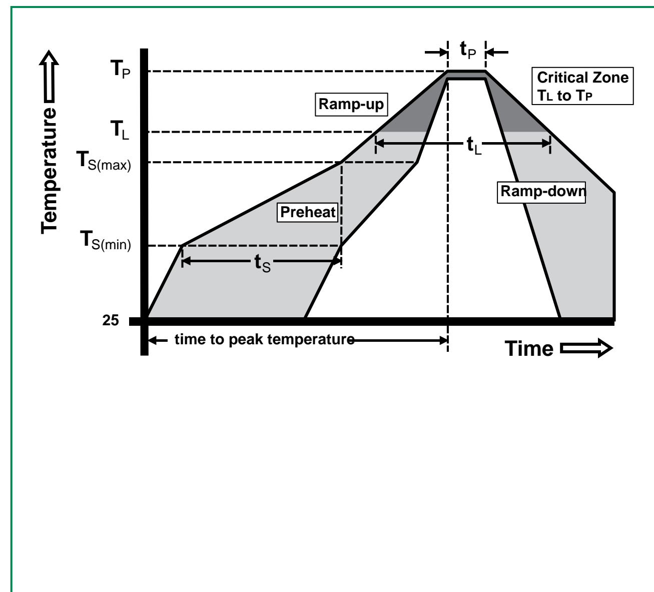



## Pulse Waveform




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Product Characteristics

| Lead Plating | Matte Tin |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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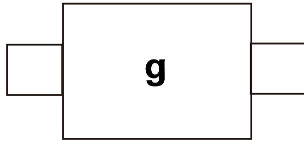
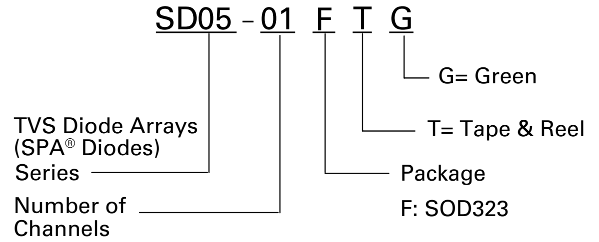
## Part Marking System



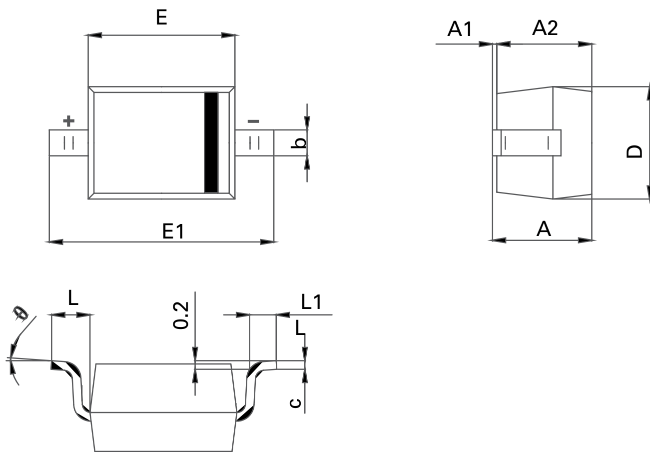

## Part Numbering System




## Ordering Information

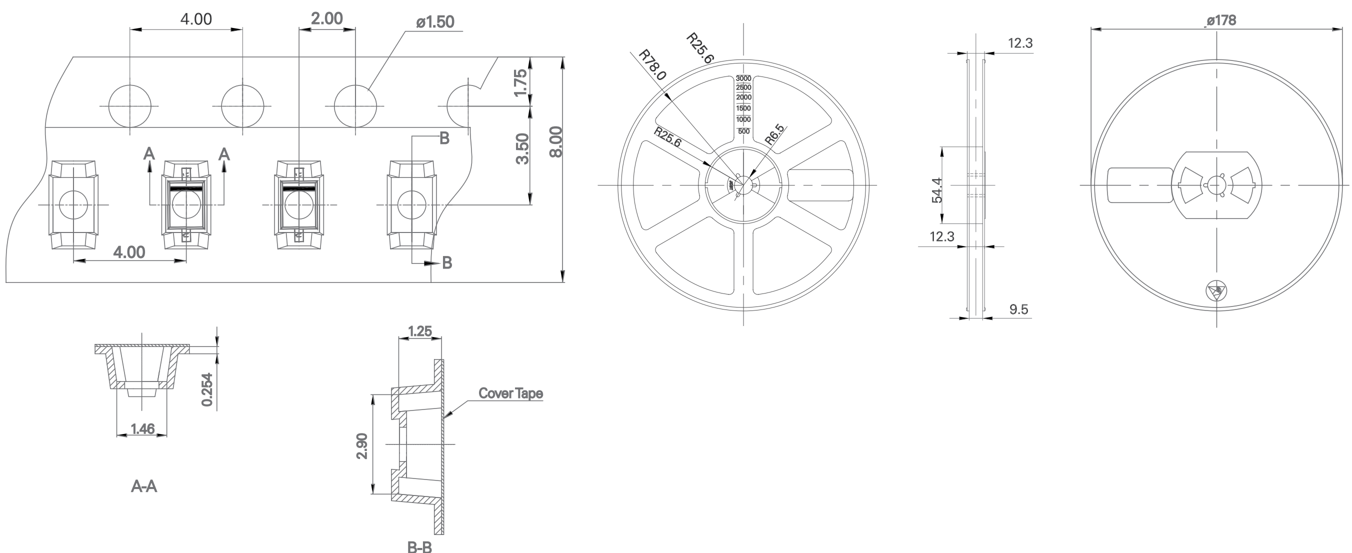
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SD05-01FTG | SOD323 | g | 3000 |

## Package Dimensions -SOD323




| Symbol | SOD323 | | | |
|---|---|---|---|---|
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| A | | 1.00 | | 0.039 |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 |
| A2 | 0.80 | 0.90 | 0.031 | 0.035 |
| b | 0.25 | 0.35 | 0.010 | 0.014 |
| c | 0.08 | 0.15 | 0.003 | 0.006 |
| D | 1.20 | 1.40 | 0.047 | 0.055 |
| E | 1.60 | 1.80 | 0.063 | 0.071 |
| E1 | 2.50 | 2.70 | 0.098 | 0.106 |
| L | 0.475 REF | | 0.019 REF | |
| L1 | 0.25 | 0.40 | 0.010 | 0.016 |
| Ø | 0° | 8° | 0° | 8° |

## Embossed Carrier Tape & Reel Specification — SOD323

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Revised: 12/20/13

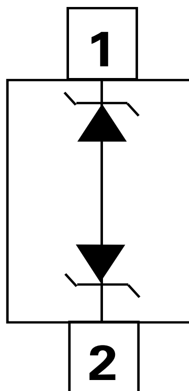
# SD05C Series 450W Discrete Bidirectional TVS Diode

## Description

The bidirectional SD05C TVS diode is designed to replace multilayer varistors (MLVs) in electronic equipment for low speed and DC applications. It will protect any sensitive equipment from damage due to electrostatic discharge (ESD) and other transient events.

The SD05C can safely absorb repetitive ESD strikes at ±30kV (contact discharge, IEC 61000-4-2) without performance degradation and safely dissipate 30A of 8/20μs induced surge current (IEC61000-4-5) with very low clamping voltages.

## Pinout and Functional Block Diagram




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 50A (5/50ns)
- Lightning, IEC61000-4-5, 30A ($t_P$=8/20μs)
- Low clamping voltage
- Low leakage current
- Small SOD323 package fits 0805 footprints

## Applications

- Switches / Buttons
- Test Equipment / Instrumentation
- Point-of-Sale Terminals
- Medical Equipment
- Notebooks / Desktops / Servers
- Computer Peripherals

## Additional Information

Datasheet

Resources

Samples

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 30 | A |
| $P_{pk}$ | Peak Pulse Power ($t_p$=8/20μs) | 450 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

Notes:
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

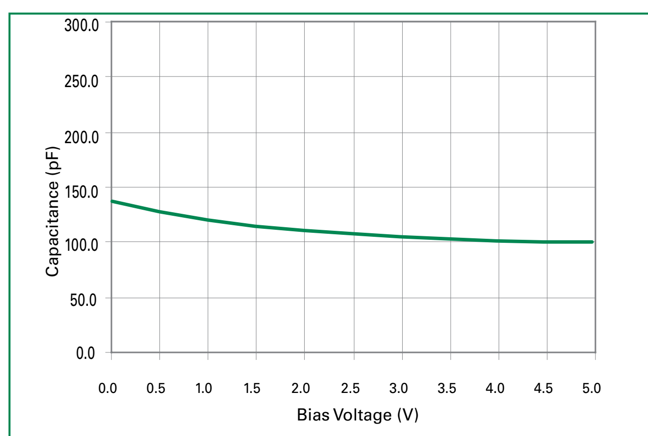
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

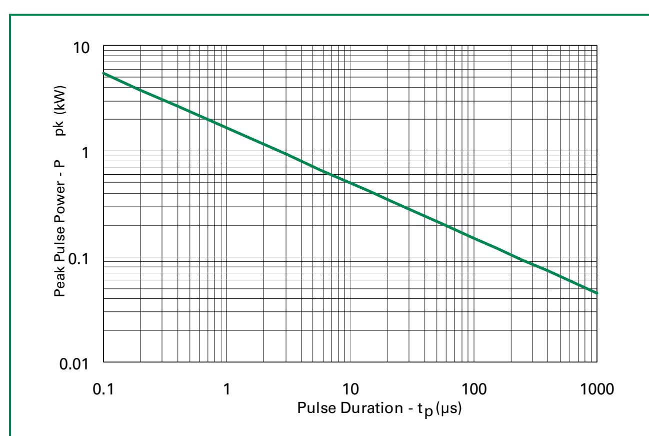
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Voltage Drop | $V_R$ | $I_R$=1mA | 6 | | | V |
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 5.0 | V |
| Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 1.0 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.7 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.3 | | V |
| | | $I_{PP}$=10A, $t_P$=8/20μs, Fwd | | 13.5 | | V |
| | | $I_{PP}$=24A, $t_P$=8/20μs, Fwd | | 18.0 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.6 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | | | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V, f=1MHz | | | 200 | pF |

Note:
[1]Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Non-Repetitive Peak Pulse Power vs. Pulse Time

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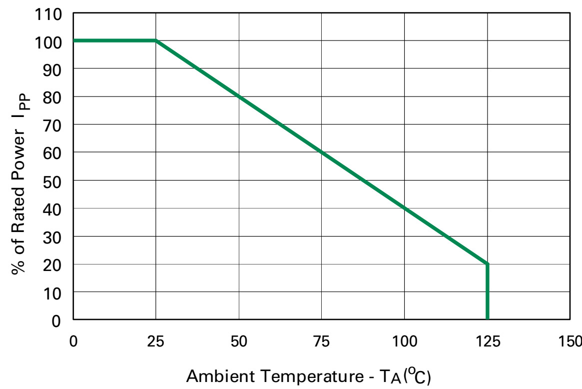
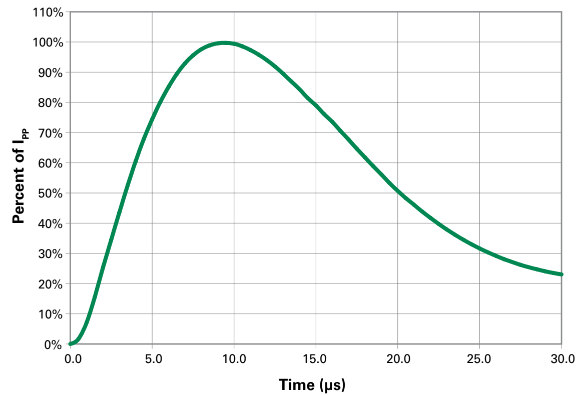
## Power Derating Curve

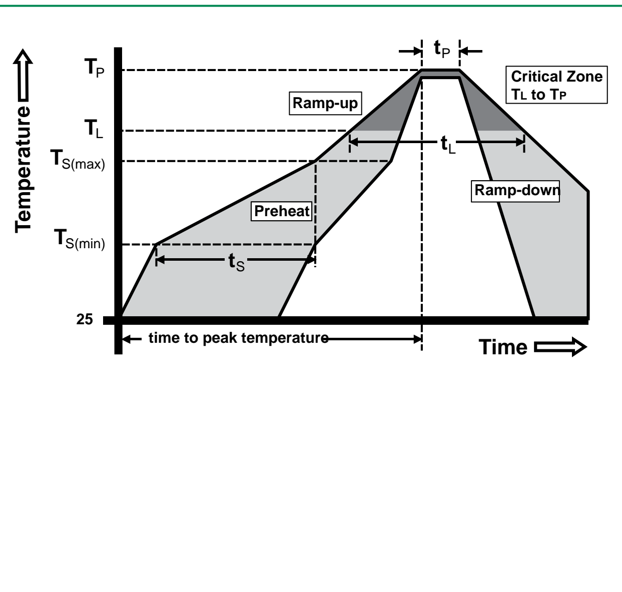



## Pulse Waveform




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Product Characteristics

| **Lead Plating** | Matte Tin |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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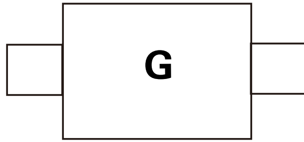
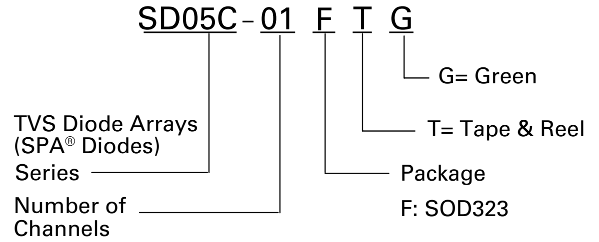
## Part Marking System



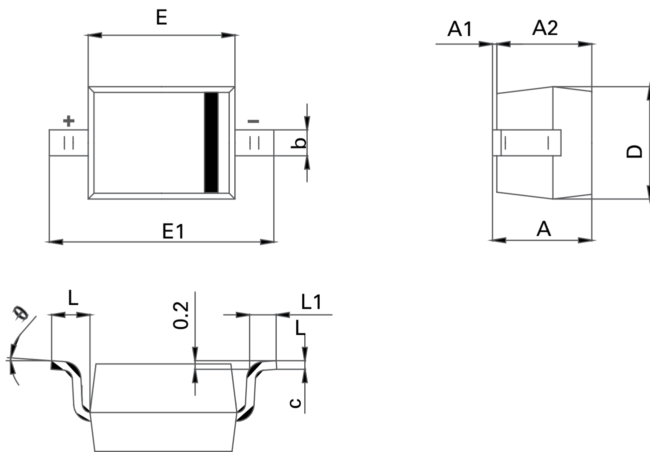

## Part Numbering System




## Ordering Information

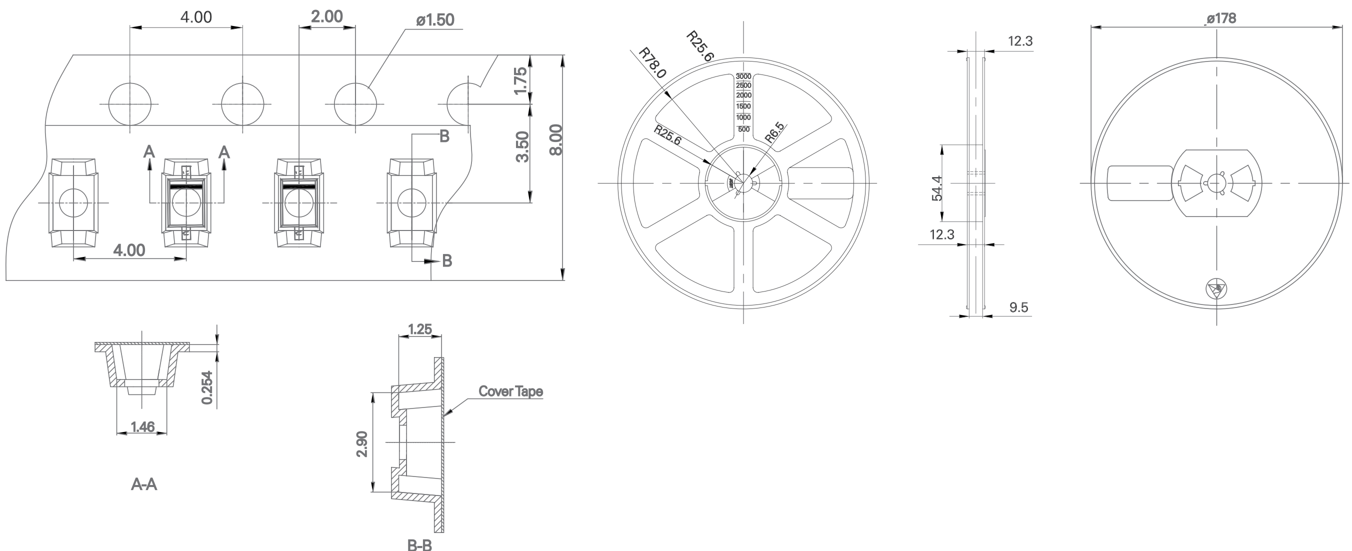
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SD05C-01FTG | SOD323 | G | 3000 |

## Package Dimensions -SOD323




| Symbol | SOD323 | | | |
|---|---|---|---|---|
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | | 1.00 | | 0.039 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.80 | 0.90 | 0.031 | 0.035 |
| **b** | 0.25 | 0.35 | 0.010 | 0.014 |
| **c** | 0.08 | 0.15 | 0.003 | 0.006 |
| **D** | 1.20 | 1.40 | 0.047 | 0.055 |
| **E** | 1.60 | 1.80 | 0.063 | 0.071 |
| **E1** | 2.50 | 2.70 | 0.098 | 0.106 |
| **L** | 0.475 REF | | 0.019 REF | |
| **L1** | 0.25 | 0.40 | 0.010 | 0.016 |
| **Ø** | 0° | 8° | 0° | 8° |

## Embossed Carrier Tape & Reel Specification — SOD323

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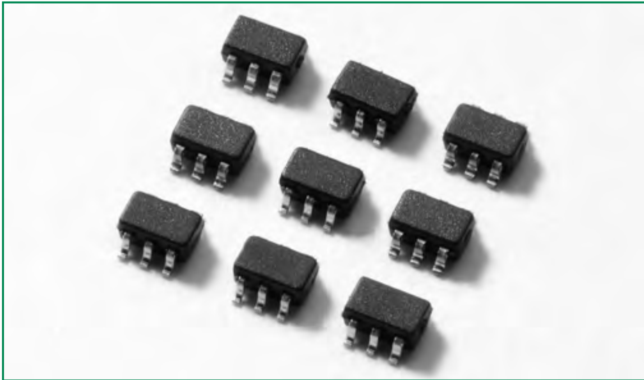
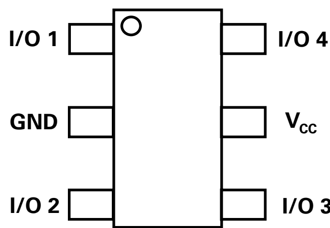
# SP3001 Series 0.65pF Diode Array



## Description

The SP3001 has ultra low capacitance rail-to rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

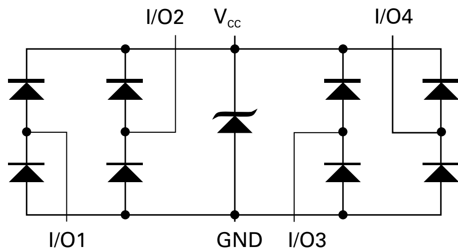
## Pinout




## Features

- Low capacitance of 0.65pF (TYP) per I/O
- ESD protection of ±8kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5μA (MAX) at 5V
- Small SC70 ( JEDEC MO-203) package saves board space
- Lightning Protection, IEC61000-4-5, 2.5A (8/20μs)

## Functional Block Diagram




## Applications

- Computer Peripherals
- Mobile Phones
- PDA's
- Digital Cameras
- Network Hardware/Ports
- Test Equipment
- Medical Equipment

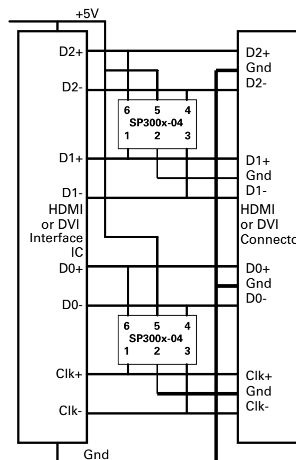
## Additional Information

Datasheet

Resources

Samples

## Application Example




A single 4 channel SP300x-04 device can be used to protect four of the data lines in a HDMI/DVI interface. Two (2) SP300x-04 devices provide protection for the main data lines. Low voltage ASIC HDMI/DVI drivers can also be protected with the SP300x-04, the $+V_{CC}$ pins on the SP300x-04 can be substituted with a suitable bypass capacitor or in some backdrive applications the $+V_{CC}$ of the SP300x-04 can be floated or NC.

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2.5 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

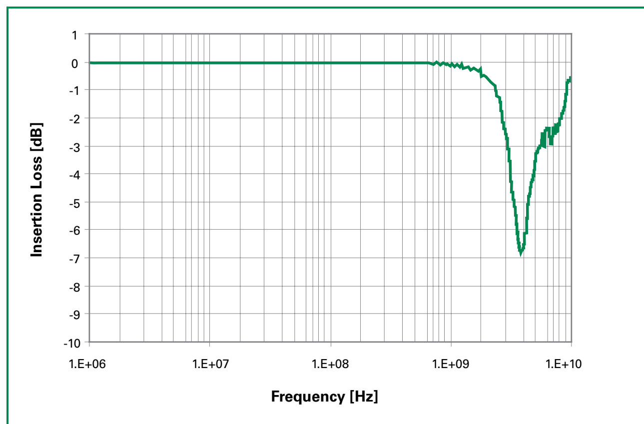
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

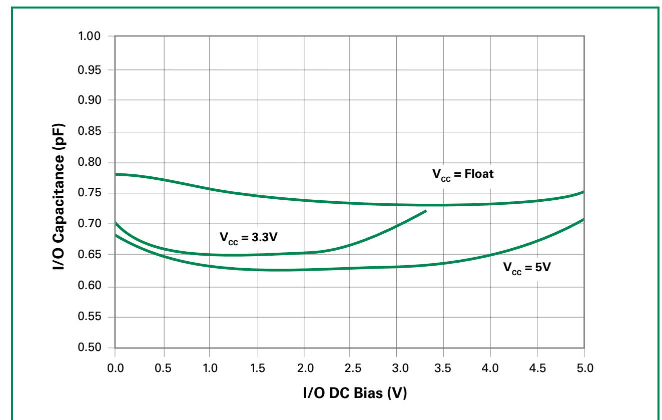
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$ ≤ 1μA | | | 6 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.5 | 11.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.6 | 13.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | 0.7 | 0.8 | 0.9 | pF |
| | | Reverse Bias=1.65V | 0.55 | 0.65 | 0.75 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.35 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Insertion Loss (S21) I/O to GND




## Capacitance vs. Bias Voltage

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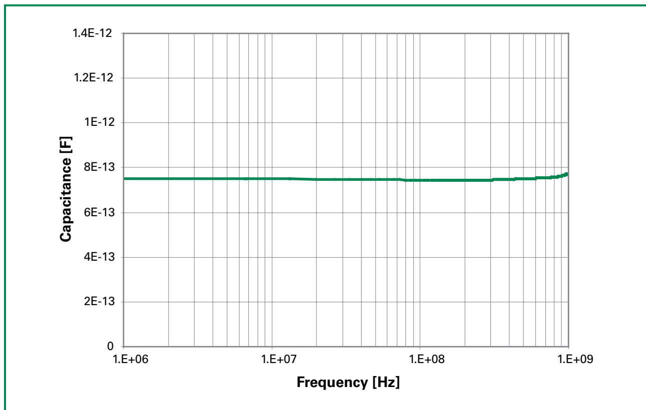
## Capacitance vs. Frequency



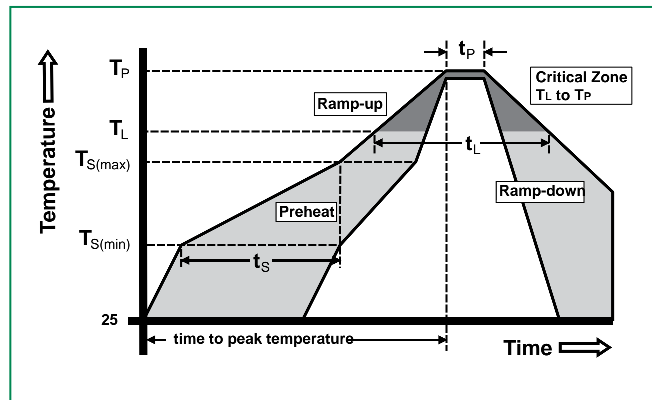

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_P$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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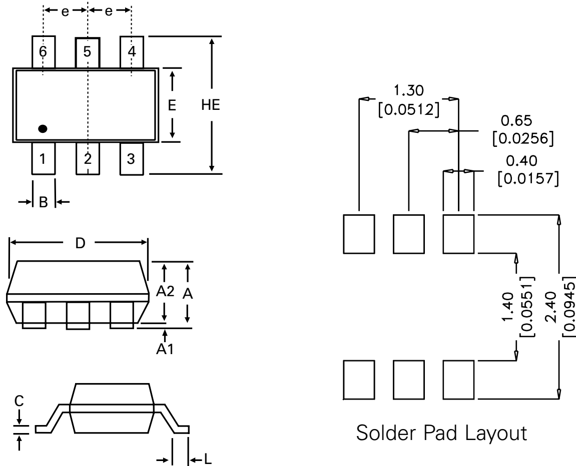
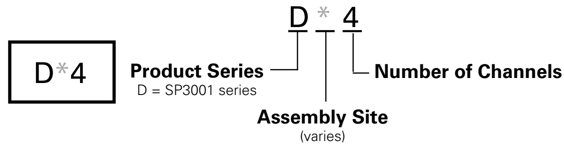
## Package Dimensions — SC70-6

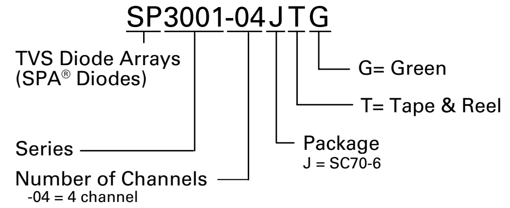



| Package | SC70-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Part Marking System



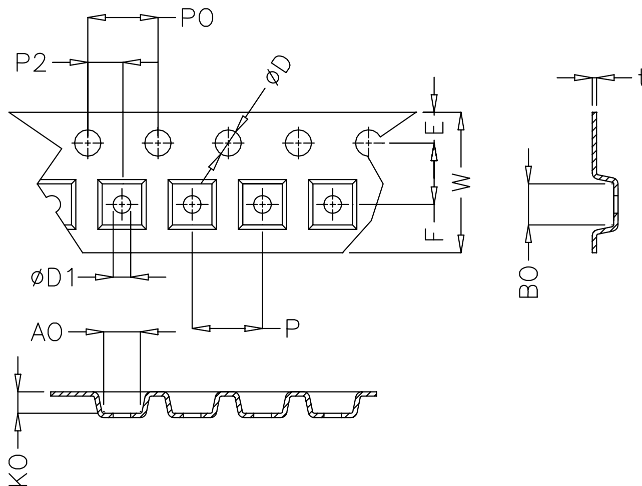

## Part Numbering System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3001-04JTG | SC70-6 | D*4 | 3000 |

## Embossed Carrier Tape & Reel Specification — SC70-6




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.072 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.076 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.062 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.153 | 0.161 |
| **10P0** | 40.0± 0.20 | | 1.574±0.007 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.14 | 2.34 | 0.084 | 0.092 |
| **B0** | 2.24 | 2.44 | 0.088 | 0.960 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.27 max | | 0.010 max | |

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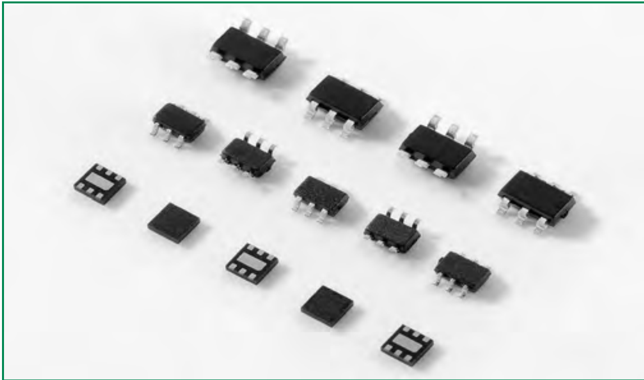
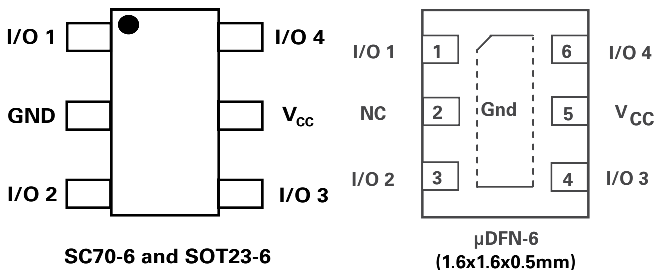
# SP3002 Series 0.85pF Diode Array



## Description

The SP3002 has ultra low capacitance rail-to-rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

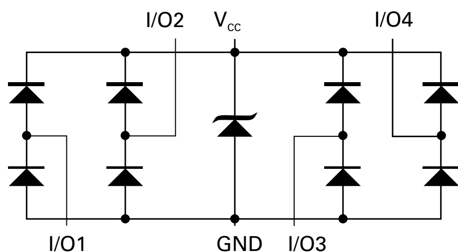
## Pinout




## Features

- Low capacitance of 0.85 pF (TYP) per I/O
- ESD protection of ±12kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5μA (MAX) at 5V
- Small packaging options saves board space
- Lightning Protection, IEC61000-4-5, 4.5A (8/20μs)

## Functional Block Diagram




## Applications

- Computer Peripherals
- Mobile Phones
- PDA's
- Digital Cameras
- Network Hardware/Ports
- Test Equipment
- Medical Equipment

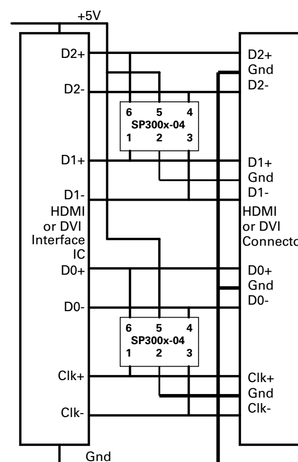
## Additional Information

Datasheet

Resources

Samples

## Application Example




A single 4 channel SP300x-04 device can be used to protect four of the data lines in a HDMI/DVI interface. Two (2) SP300x-04 devices provide protection for the main data lines. Low voltage ASIC HDMI/DVI drivers can also be protected with the SP300x-04, the $+V_{CC}$ pins on the SP300x-04 can be substituted with a suitable bypass capacitor or in some backdrive applications the $+V_{CC}$ of the SP300x-04 can be floated or NC.

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 4.5 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

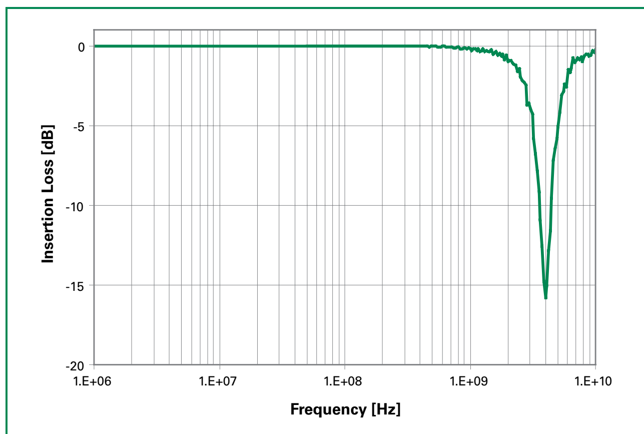
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

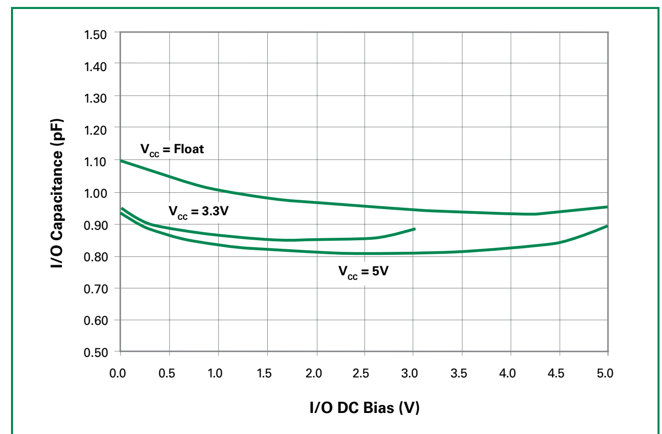
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \leq 1\mu A$ | | | 6.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.5 | 11.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.6 | 13.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±12 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | 0.95 | 1.1 | 1.25 | pF |
| | | Reverse Bias=1.65V | 0.7 | 0.85 | 1.0 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.5 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Insertion Loss (S21) I/O to GND




## Capacitance vs. Bias Voltage

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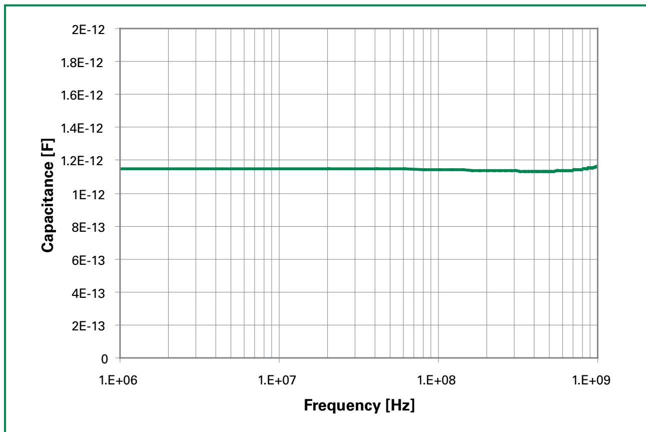
## Capacitance vs. Frequency



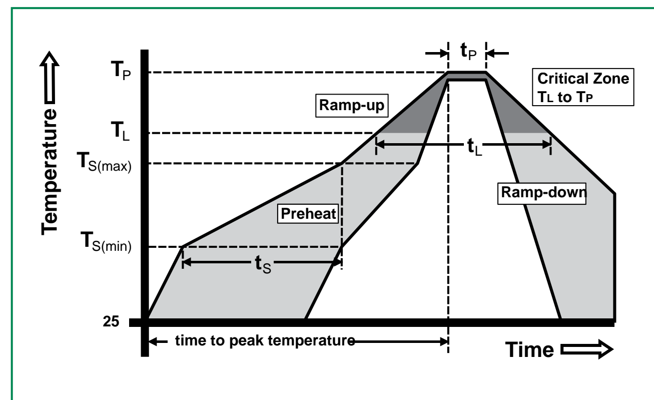

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | SC70 & SOT23: Matte Tin<br>µDFN: Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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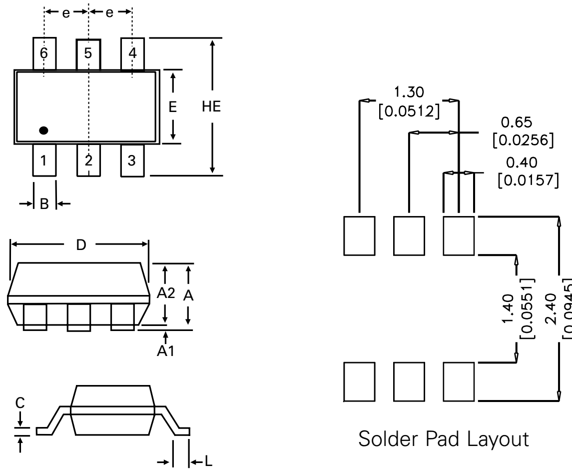
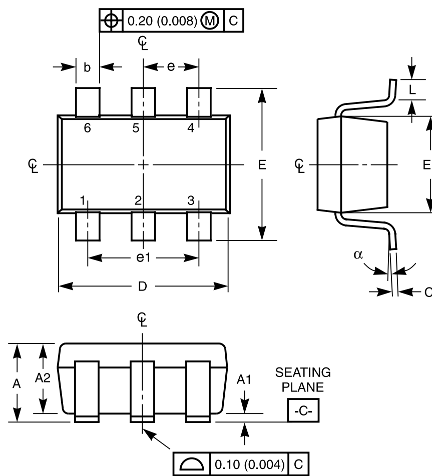
## Package Dimensions — SC70-6



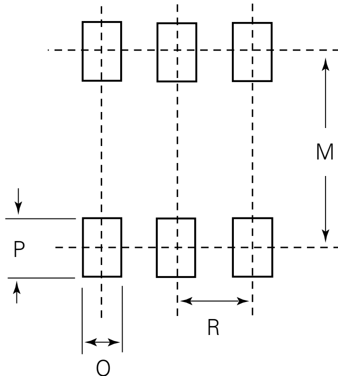

Solder Pad Layout

| Package | SC70-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Package Dimensions — SOT23-6




**Recommended Solder Pad Layout**




| Package | SOT23-6 | | | | |
|---|---|---|---|---|---|
| Pins | 6 | | | | |
| JEDEC | MO-178 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 0.900 | 1.450 | 0.035 | 0.057 | - |
| **A1** | 0.000 | 0.150 | 0.000 | 0.006 | - |
| **A2** | 0.900 | 1.300 | 0.035 | 0.051 | - |
| **b** | 0.350 | 0.500 | 0.0138 | 0.0196 | - |
| **C** | 0.080 | 0.220 | 0.0031 | 0.009 | - |
| **D** | 2.800 | 3.000 | 0.11 | 0.118 | 3 |
| **E** | 2.600 | 3.000 | 0.102 | 0.118 | - |
| **E1** | 1.500 | 1.750 | 0.06 | 0.069 | 3 |
| **e** | 0.95 Ref | | 0.0374 Ref | | - |
| **e1** | 1.9 Ref | | 0.0748 Ref | | - |
| **L** | 0.100 | 0.600 | 0.004 | 0.023 | 4,5 |
| **N** | 6 | | 6 | | 6 |
| **a** | 0° | 10° | 0° | 10° | - |
| **M** | | 2.590 | | 0.102 | - |
| **O** | | 0.690 | | .027 TYP | - |
| **P** | | 0.990 | | .039 TYP | - |
| **R** | | 0.950 | | 0.038 | - |

Notes:
1. Dimensioning and tolerances per ANSI 14.5M-1982.
2. Package conforms to EIAJ SC-74 (1992).
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Footlenth L measured at reference to seating plane.
5. "L" is the length of flat foot surface for soldering to substrate.
6. "N" is the number of terminal positions.
7. Controling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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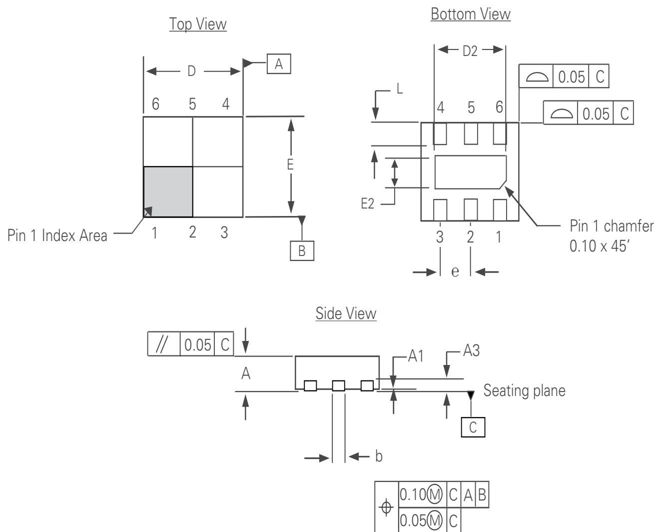
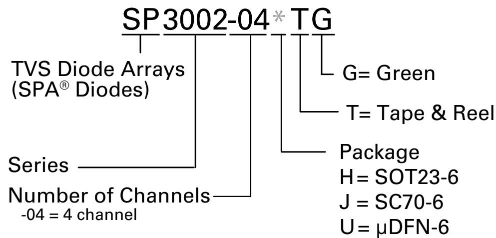
## Package Dimensions — µDFN-6 (1.6x1.6x0.5mm)




| Package | µDFN-6 (1.6x1.6x0.5mm) | | | |
|---|---|---|---|---|
| JEDEC | MO-229 | | | |
| Symbol | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.45 | 0.55 | 0.018 | 0.022 |
| **A1** | 0.00 | 0.05 | 0.000 | 0.002 |
| **A3** | 0.127 Ref | | 0.005 Ref | |
| **b** | 0.20 | 0.30 | 0.008 | 0.012 |
| **D** | 1.50 | 1.70 | 0.060 | 0.067 |
| **D2** | 1.05 | 1.30 | 0.042 | 0.052 |
| **E** | 1.50 | 1.70 | 0.060 | 0.067 |
| **E2** | 0.40 | 0.65 | 0.016 | 0.026 |
| **e** | 0.50 Ref | | 0.020 Ref | |
| **L** | 0.25 | 0.40 | 0.010 | 0.016 |

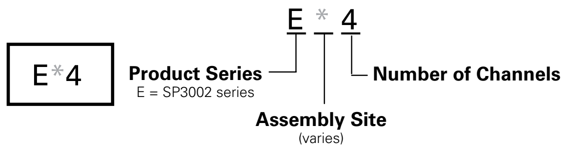
## Part Numbering System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3002-04HTG | SOT23-6 | E*4 | 3000 |
| SP3002-04JTG | SC70-6 | E*4 | 3000 |
| SP3002-04UTG | µDFN-6 (1.6x1.6x0.5mm) | E*4 | 3000 |

## Part Marking System

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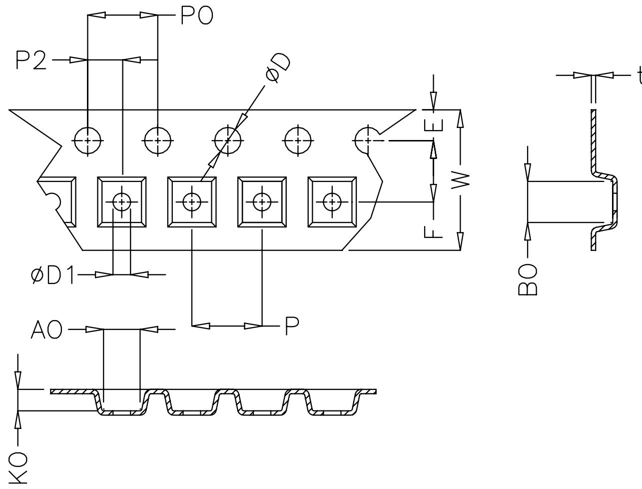
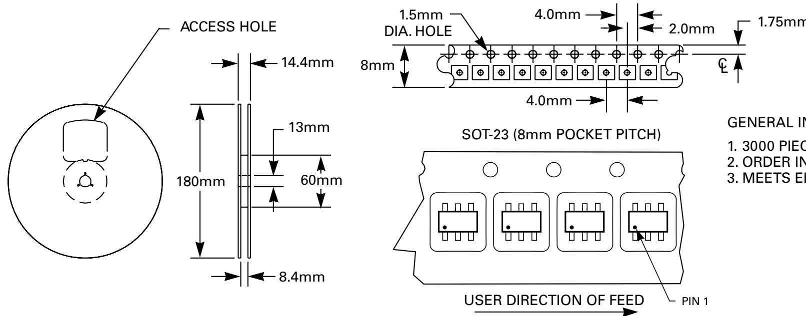
## Embossed Carrier Tape & Reel Specification — SC70-6




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 1.00 | 1.25 | 0.039 | 0.049 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0± 0.20 | | 1.574±0.008 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 2.14 | 2.34 | 0.084 | 0.092 |
| **B0** | 2.24 | 2.44 | 0.088 | 0.096 |
| **K0** | 1.12 | 1.32 | 0.044 | 0.052 |
| **t** | 0.27 Max | | 0.010 Max | |

## Embossed Carrier Tape & Reel Specification — SOT23-6

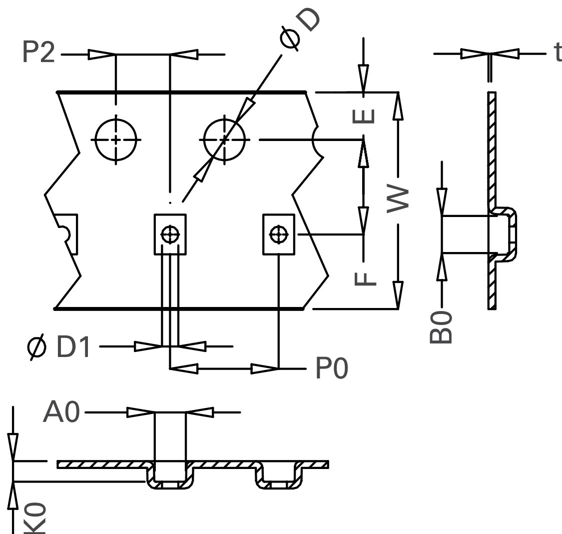
8mm TAPE AND REEL




GENERAL INFORMATION

1. 3000 PIECES PER REEL.
2. ORDER IN MULTIPLES OF FULL REELS ONLY.
3. MEETS EIA-481 REVISION "A" SPECIFICATIONS.

## Embossed Carrier Tape & Reel Specification — µDFN-6 (1.6x1.6x0.5mm)




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.06 | 0.07 |
| **F** | 3.45 | 3.55 | 0.14 | 0.14 |
| **D1** | 1.00 | 1.25 | 0.04 | 0.05 |
| **D** | 1.50 MIN | | 0.06 MIN | |
| **P0** | 3.90 | 4.10 | 0.15 | 0.16 |
| **10P0** | 40.0± 0.20 | | 1.57±0.01 | |
| **W** | 7.90 | 8.30 | 0.31 | 0.33 |
| **P2** | 1.95 | 2.05 | 0.08 | 0.08 |
| **A0** | 1.78 | 1.88 | 0.07 | 0.07 |
| **B0** | 1.78 | 1.88 | 0.07 | 0.07 |
| **K0** | 0.84 | 0.94 | 0.03 | 0.04 |
| **t** | 0.25 TYP | | 0.01 TYP | |

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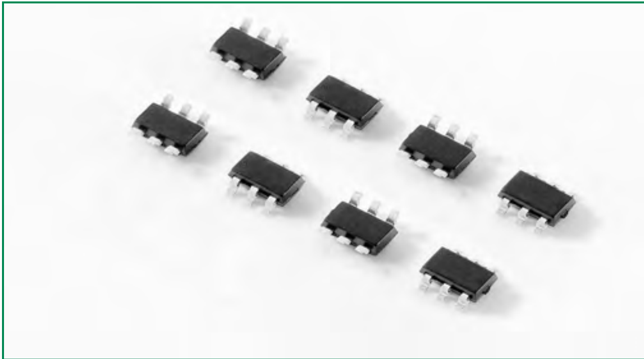
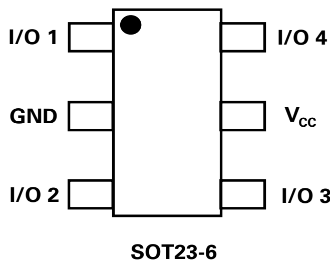
# SP0504S Series 0.85pF Diode Array



## Description

The SP0504S has ultra low capacitance rail-to-rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

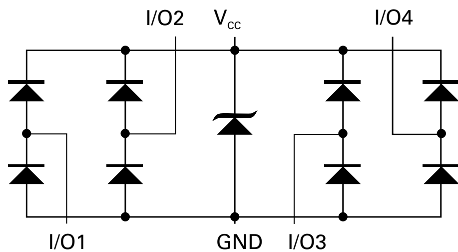
## Pinout




## Features

- Low capacitance of 0.85 pF (TYP) per I/O
- ESD protection of ±12kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5μA (MAX) at 5V
- Small packaging options saves board space
- Lightning Protection, IEC61000-4-5, 4.5A (8/20μs)

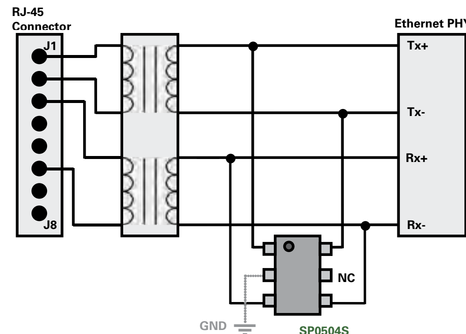
## Functional Block Diagram




## Applications

- Computer Peripherals
- Mobile Phones
- PDA's
- Digital Cameras
- Network Hardware/Ports
- Test Equipment
- Medical Equipment

## Application Example




A single 4 channel SP0504S device can be used to protect four of the data lines in a HDMI/DVI interface. Two (2) SP0504S devices provide protection for the main data lines. Low voltage ASIC HDMI/DVI drivers can also be protected with the SP0504S, the $+V_{CC}$ pins on the SP0504S can be substituted with a suitable bypass capacitor or in some backdrive applications the $+V_{CC}$ of the SP0504S can be floated or NC.

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 4.5 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

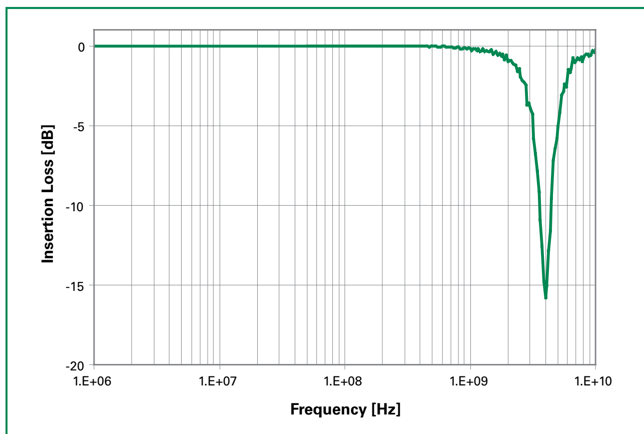
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

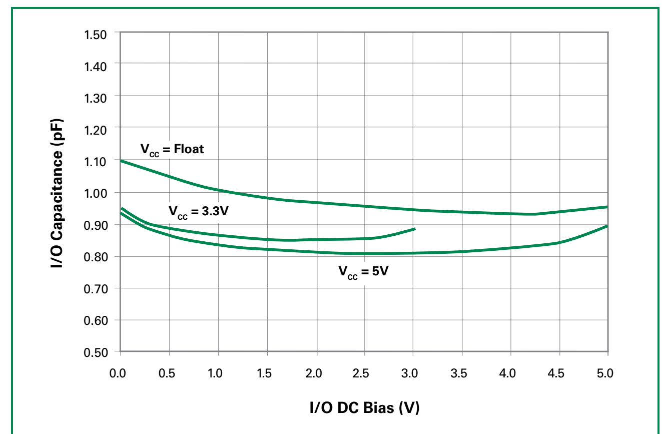
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \leq 1\mu A$ | | | 6.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.5 | 11.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.6 | 13.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±12 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | 0.95 | 1.1 | 1.25 | pF |
| | | Reverse Bias=1.65V | 0.7 | 0.85 | 1.0 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.5 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Insertion Loss (S21) I/O to GND




## Capacitance vs. Bias Voltage

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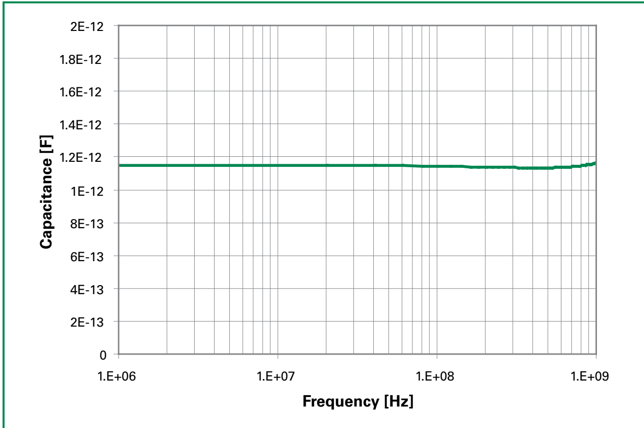
## Capacitance vs. Frequency



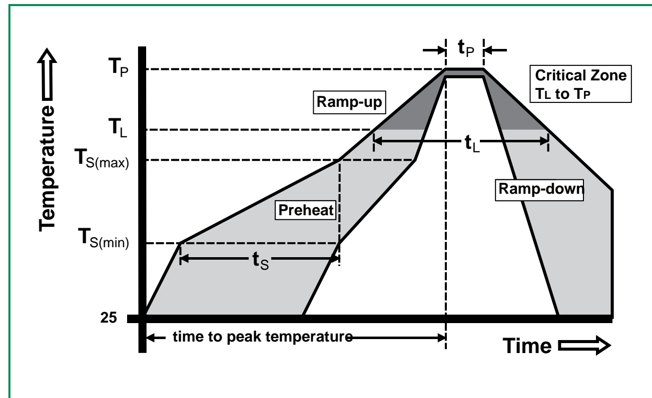

## Product Characteristics

| Lead Plating | Matte Tin |
|---|---|
| Lead Material | Copper Alloy |
| Lead Coplanarity | 0.0004 inches (0.102mm) |
| Substitute Material | Silicon |
| Body Material | Molded Epoxy |
| Flammability | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

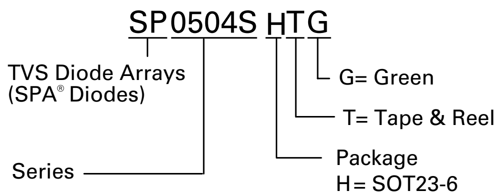
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |



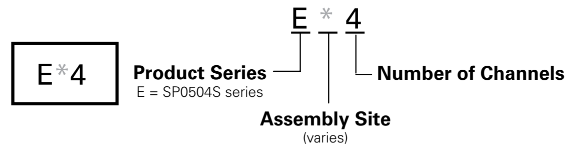

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP0504SHTG | SOT23-6 | E*4 | 3000 |

## Part Numbering System




## Part Marking System

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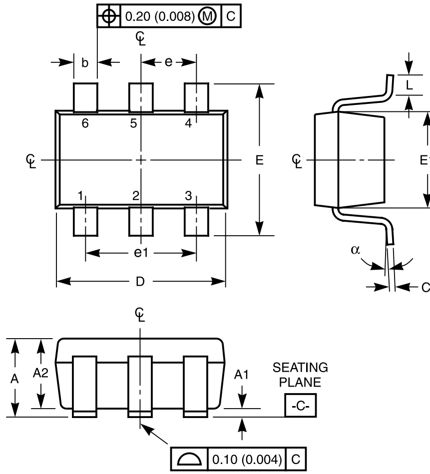
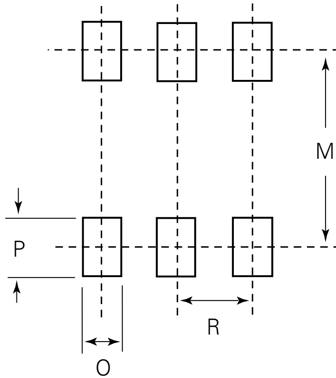
## Package Dimensions — SOT23-6




| Package | SOT23 | | | | |
|---|---|---|---|---|---|
| Pins | 6 | | | | |
| JEDEC | MO-178AB | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 0.900 | 1.450 | 0.035 | 0.057 | - |
| **A1** | 0.000 | 0.150 | 0.000 | 0.006 | - |
| **A2** | 0.900 | 1.300 | 0.035 | 0.051 | - |
| **b** | 0.350 | 0.500 | 0.0138 | 0.0196 | - |
| **C** | 0.080 | 0.220 | 0.0031 | 0.009 | - |
| **D** | 2.800 | 3.000 | 0.11 | 0.118 | 3 |
| **E** | 2.600 | 3.000 | 0.102 | 0.118 | - |
| **E1** | 1.500 | 1.750 | 0.06 | 0.069 | 3 |
| **e** | 0.95 Ref | | 0.0374 ref | | - |
| **e1** | 1.9 Ref | | 0.0748 Ref | | - |
| **L** | 0.30 | 0.600 | 0.012 | 0.023 | 4,5 |
| **N** | 6 | | 6 | | 6 |
| α | 0° | 8° | 0° | 8° | - |
| **M** | | 2.590 | | 0.102 | - |
| **O** | | 0.690 | | .027 TYP | - |
| **P** | | 0.990 | | .039 TYP | - |
| **R** | | 0.950 | | 0.038 | - |

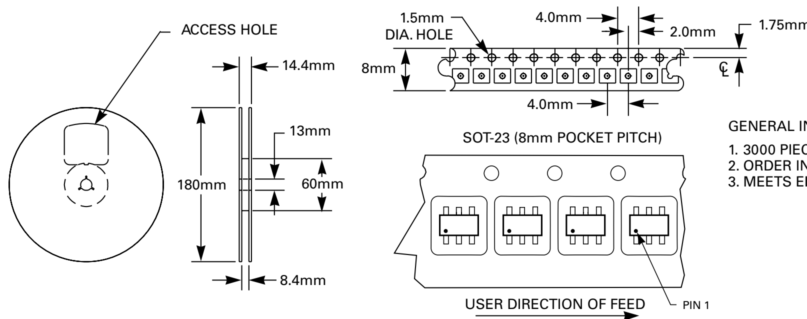
Notes:
1. Dimensioning and tolerancing Per ASME Y14.5M-1994.
2. Package conforms to EIAJ SC-74 (1992).
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Foot length L measured at reference to seating plane.
5. "L" is the length of flat foot surface for soldering to substrate.
6. "N" is the number of terminal positions.
7. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

### Recommended Solder Pad Layout




## Embossed Carrier Tape & Reel Specification — SOT23-6

8mm TAPE AND REEL




GENERAL INFORMATION
1. 3000 PIECES PER REEL.
2. ORDER IN MULTIPLES OF FULL REELS ONLY.
3. MEETS EIA-481 REVISION "A" SPECIFICATIONS.

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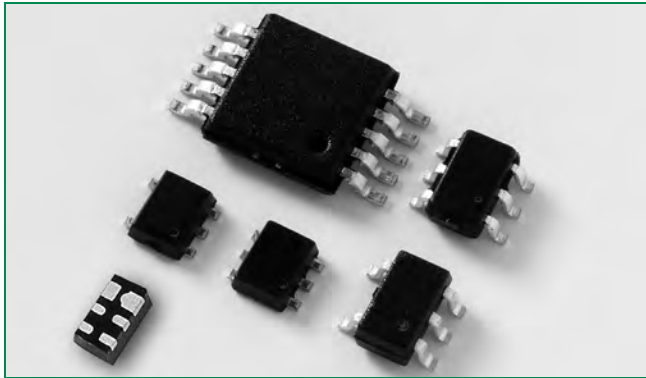
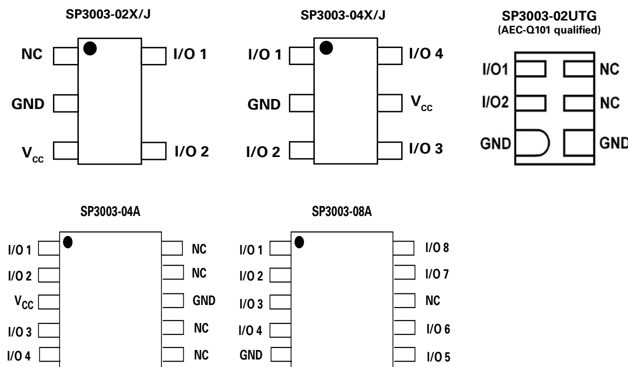
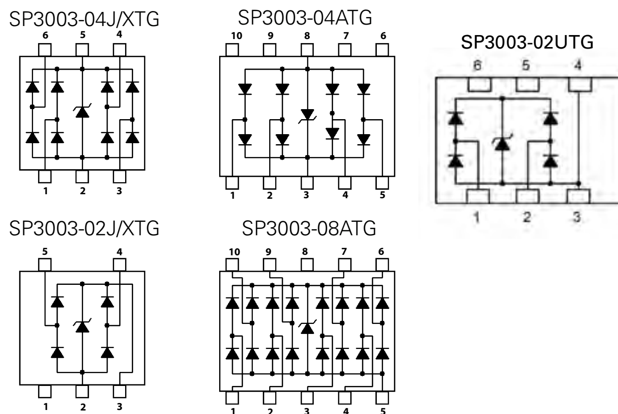
# SP3003 Series 0.65pF Diode Array



## Pinout




## Functional Block Diagram




## Additional Information

**Datasheet**

**Resources**

**Samples**

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## Description

The SP3003 has ultra low capacitance rail-to-rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level specified in the IEC 61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

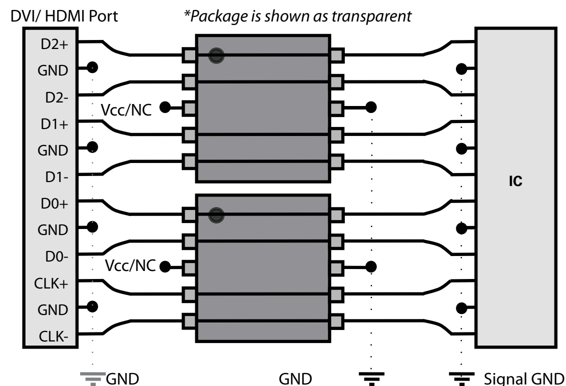
## Features

- ESD protection of ±8kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Lightning Protection, IEC61000-4-5, 2.5A (8/20μs)
- Low capacitance of 0.65pF (TYP) per I/O
- Low leakage current of 0.5μA (MAX) at 5V
- Complete line of small packaging helps save board space (SC70, SOT553, SOT563, MSOP10, **μ**DFN-6L)
- AEC-Q101 qualified (μDFN package)

## Applications

- LCD/ PDP TVs
- DVD Players
- Desktops
- MP3/ PMP
- Digital Cameras
- Set Top Boxes
- Mobile Phones
- Notebooks
- Computer Peripherals

## Application Example




A single, 4 channel SP3003-04 device can be used to protect four (4) of the data lines in a HDMI/DVI interface so two (2) SP3003-04 devices provide protection for all eight (8) TMDS lines.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2.5 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

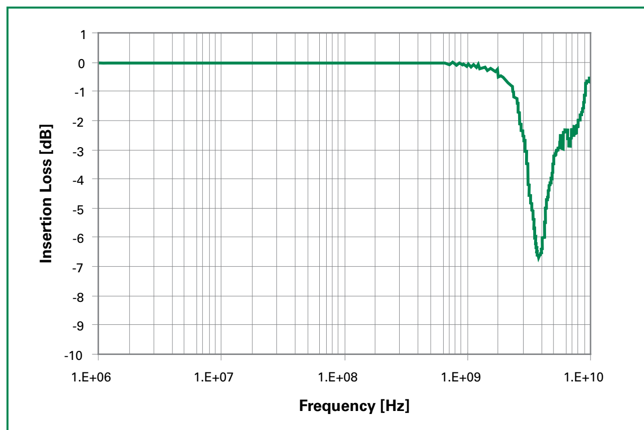
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

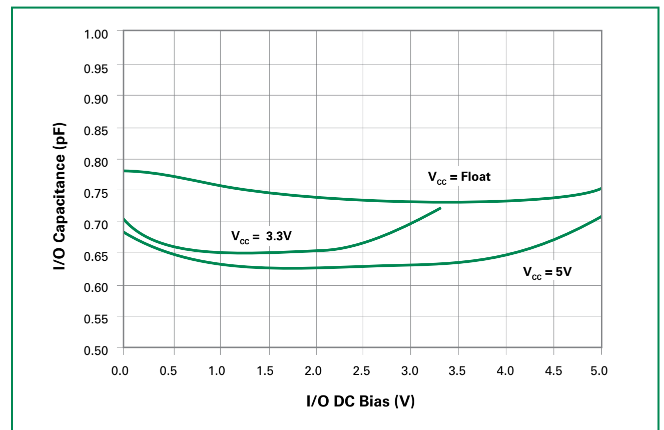
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$ ≤ 1μA | | | 6 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 10.0 | 12.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 11.8 | 15.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | 0.7 | 0.8 | 0.95 | pF |
| | | Reverse Bias=1.65V | 0.55 | 0.65 | 0.8 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.35 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Insertion Loss (S21) I/O to GND




## Capacitance vs. Bias Voltage

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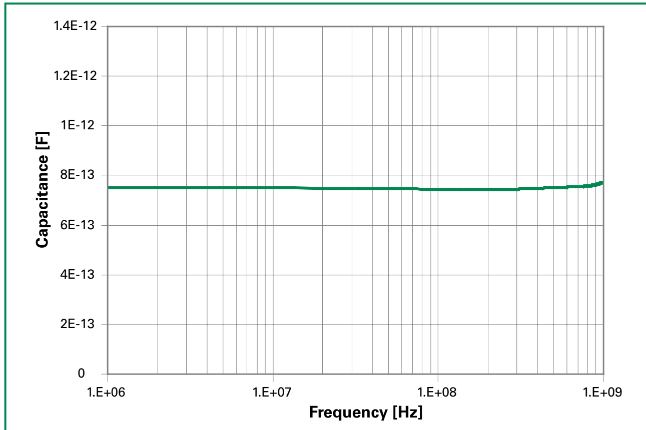
## Capacitance vs. Frequency



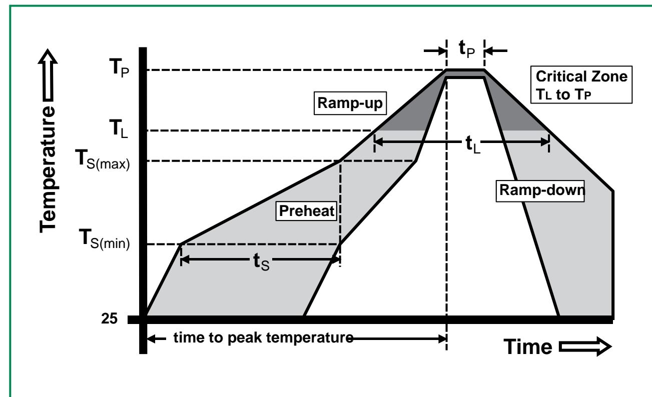

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin (SC70-x, MSOP-10) Pre-Plated Frame (SOT5x3, µDFN-6) |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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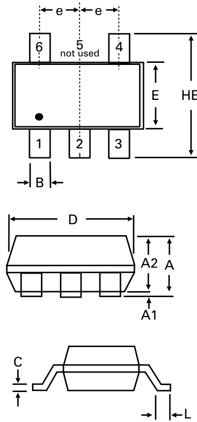
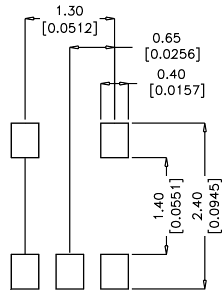
## Package Dimensions — SC70-5

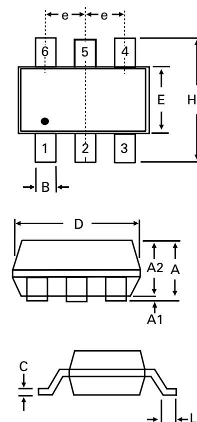



Recommended Solder Pad Layout

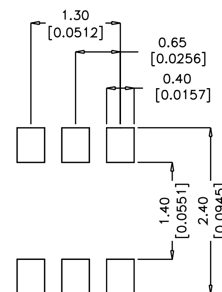



| Package | SC70-5 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Package Dimensions — SC70-6

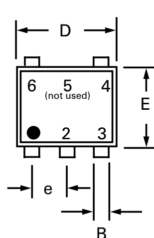



Recommended Solder Pad Layout



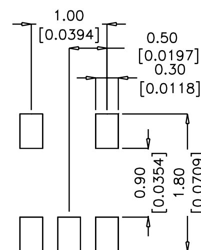

| Package | SC70-6 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| JEDEC | MO-203 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.80 | 1.10 | 0.031 | 0.043 |
| **A1** | 0.00 | 0.10 | 0.000 | 0.004 |
| **A2** | 0.70 | 1.00 | 0.028 | 0.039 |
| **B** | 0.15 | 0.30 | 0.006 | 0.012 |
| **c** | 0.08 | 0.25 | 0.003 | 0.010 |
| **D** | 1.85 | 2.25 | 0.073 | 0.089 |
| **E** | 1.15 | 1.35 | 0.045 | 0.053 |
| **e** | 0.65 BSC | | 0.026 BSC | |
| **HE** | 2.00 | 2.40 | 0.079 | 0.094 |
| **L** | 0.26 | 0.46 | 0.010 | 0.018 |

## Package Dimensions — SOT553




A
L
HE
c

Recommended Solder Pad Layout




| Package | SOT 553 | | | |
|---|---|---|---|---|
| Pins | 5 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.50 | 0.60 | 0.020 | 0.024 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.18 | 0.003 | 0.007 |
| **D** | 1.50 | 1.70 | 0.059 | 0.067 |
| **E** | 1.10 | 1.30 | 0.043 | 0.051 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **L** | 0.10 | 0.30 | 0.004 | 0.012 |
| **HE** | 1.50 | 1.70 | 0.059 | 0.067 |

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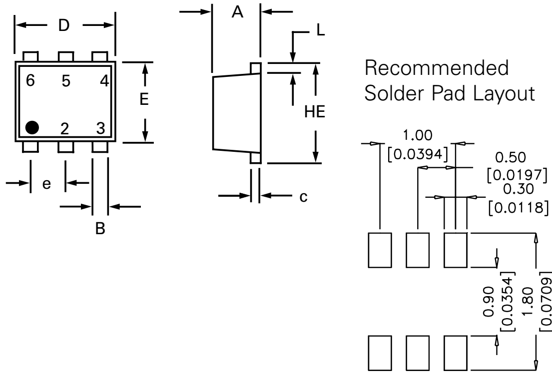
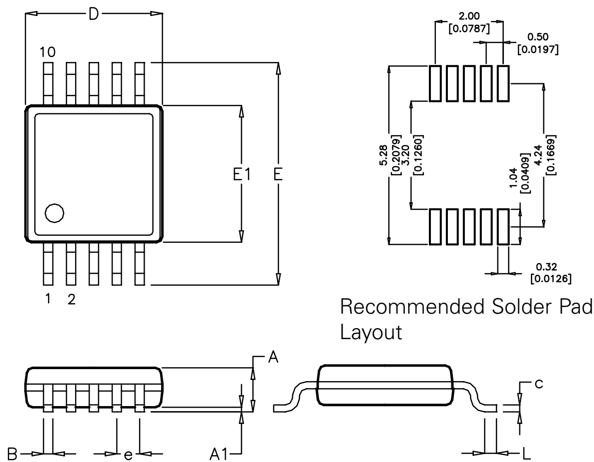
## Package Dimensions — SOT563



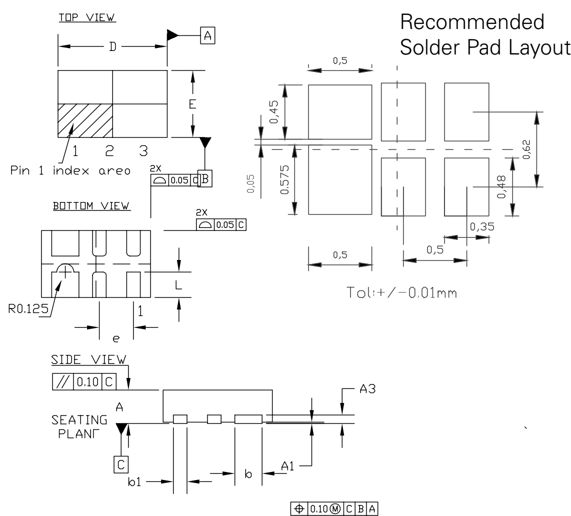

| Package | SOT 563 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.50 | 0.60 | 0.020 | 0.024 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.18 | 0.003 | 0.007 |
| **D** | 1.50 | 1.70 | 0.059 | 0.067 |
| **E** | 1.10 | 1.30 | 0.043 | 0.051 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **L** | 0.10 | 0.30 | 0.004 | 0.012 |
| **HE** | 1.50 | 1.70 | 0.059 | 0.067 |

## Package Dimensions — MSOP10




| Package | MSOP10 | | | |
|---|---|---|---|---|
| JEDEC | MO-187 | | | |
| Pins | 10 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | - | 1.10 | - | 0.043 |
| **A1** | 0.00 | 0.15 | 0.000 | 0.006 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.23 | 0.003 | 0.009 |
| **D** | 2.90 | 3.10 | 0.114 | 0.122 |
| **E** | 4.67 | 5.10 | 0.184 | 0.200 |
| **E1** | 2.90 | 3.10 | 0.114 | 0.122 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **HE** | 0.40 | 0.80 | 0.016 | 0.031 |

## Package Dimensions —μDFN-6L




| Package | μDFN-6L | | | |
|---|---|---|---|---|
| JEDEC | MO-229 | | | |
| Pins | 6 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.45 | 0.55 | 0.018 | 0.022 |
| **A1** | 0.00 | 0.05 | 0.000 | 0.002 |
| **A3** | 0.125REF | | 0.005REF | |
| **b** | 0.35 | 0.45 | 0.014 | 0.018 |
| **b1** | 0.15 | 0.25 | 0.006 | 0.010 |
| **D** | 1.55 | 1.65 | 0.062 | 0.065 |
| **D2** | - | - | - | - |
| **E** | 0.95 | 1.05 | 0.038 | 0.042 |
| **E2** | - | - | - | - |
| **e** | 0.50REF | | 0.020REF | |
| **L** | 0.33 | 0.43 | 0.013 | 0.017 |

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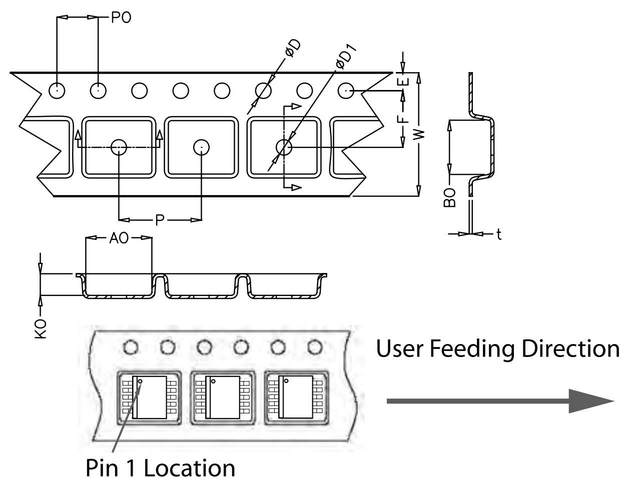
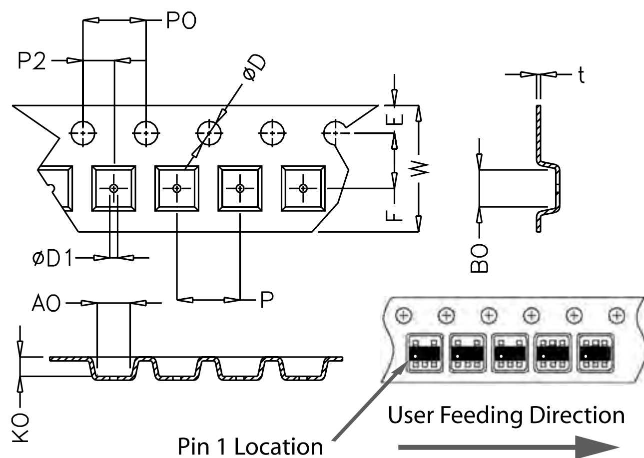
## Embossed Carrier Tape & Reel Specification — MSOP-10



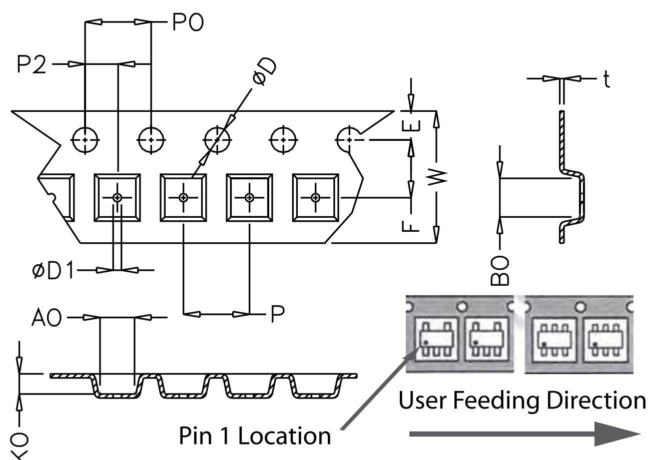

| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 5.40 | 5.60 | 0.213 | 0.220 |
| D | 1.50 | 1.60 | 0.059 | 0.063 |
| D1 | 1.50 Min | | 0.059 Min | |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| 10P0 | 40.0± 0.20 | | 1.574±0.008 | |
| W | 11.90 | 12.10 | 0.469 | 0.476 |
| P | 7.90 | 8.10 | 0.311 | 0.319 |
| A0 | 5.20 | 5.40 | 0.205 | 0.213 |
| B0 | 3.20 | 3.40 | 0.126 | 0.134 |
| K0 | 1.20 | 1.40 | 0.047 | 0.055 |
| t | 0.30 ± 0.05 | | 0.012± 0.002 | |

## Embossed Carrier Tape & Reel Specifications — SC70-5 and SC70-6




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.064 | 0.073 |
| F | 3.45 | 3.55 | 0.135 | 0.139 |
| P2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 1.40 | 1.60 | 0.055 | 0.063 |
| D1 | 1.00 | 1.25 | 0.039 | 0.049 |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| 10P0 | 40.0± 0.20 | | 1.574±0.008 | |
| W | 7.70 | 8.10 | 0.303 | 0.318 |
| P | 3.90 | 4.10 | 0.153 | 0.161 |
| A0 | 2.14 | 2.34 | 0.084 | 0.092 |
| B0 | 2.24 | 2.44 | 0.088 | 0.960 |
| K0 | 1.12 | 1.32 | 0.044 | 0.052 |
| t | 0.27 max | | 0.010 max | |

## Embossed Carrier Tape & Reel Specifications — SOT553 and SOT563




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.064 | 0.073 |
| F | 3.45 | 3.55 | 0.135 | 0.139 |
| P2 | 1.95 | 2.05 | 0.076 | 0.081 |
| D | 1.40 | 1.60 | 0.055 | 0.063 |
| D1 | 0.45 | 0.55 | 0.017 | 0.021 |
| P0 | 3.90 | 4.10 | 0.154 | 0.161 |
| 10P0 | 40.0± 0.20 | | 1.574±0.008 | |
| W | 7.70 | 8.10 | 0.303 | 0.318 |
| P | 3.90 | 4.10 | 0.153 | 0.161 |
| A0 | 1.73 | 1.83 | 0.068 | 0.072 |
| B0 | 1.73 | 1.83 | 0.068 | 0.072 |
| K0 | 0.64 | 0.74 | 0.025 | 0.029 |
| t | 0.22 max | | 0.009 max | |

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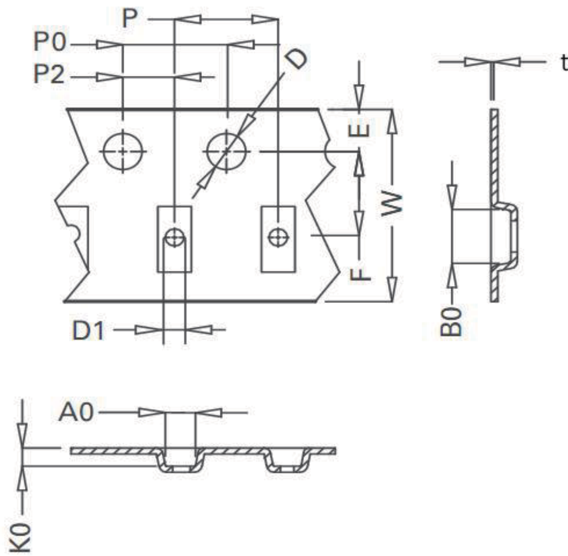
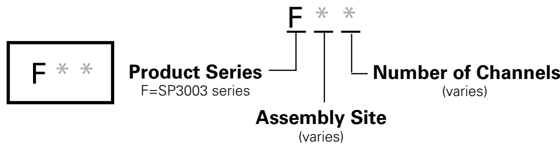
## Embossed Carrier Tape & Reel Specification — μDFN-6L




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.064 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.076 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 0.45 | 0.55 | 0.017 | 0.021 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0±0.20 | | 1.574±0.008 | |
| **W** | 7.90 | 8.30 | 0.311 | 0.319 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **A0** | 1.15 | 1.25 | 0.045 | 0.049 |
| **B0** | 1.75 | 1.85 | 0.069 | 0.073 |
| **K0** | 0.65 | 0.75 | 0.026 | 0.03 |
| **t** | 0.22 max | | 0.009 max | |

## Part Marking System

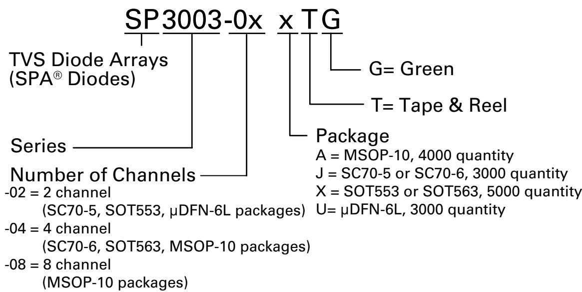
F * *

F * *
**Product Series**
F=SP3003 series
**Assembly Site**
(varies)
**Number of Channels**
(varies)

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3003-02JTG | SC70-5 | F*2 | 3000 |
| SP3003-02UTG | μDFN-6L | FH2 | 3000 |
| SP3003-02XTG | SOT553 | F*2 | 3000 |
| SP3003-04ATG | MSOP-10 | F*4 | 4000 |
| SP3003-04JTG | SC70-6 | F*4 | 3000 |
| SP3003-04XTG | SOT563 | F*4 | 3000 |
| SP3003-08ATG | MSOP-10 | F*8 | 4000 |

## Part Numbering System

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Revised: 12/20/13

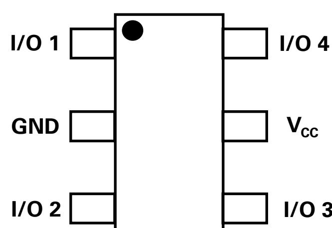
# SP3004 Series 0.85pF Diode Array

RoHS Pb GREEN

## Description

The SP3004 has ultra low capacitance rail-to rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

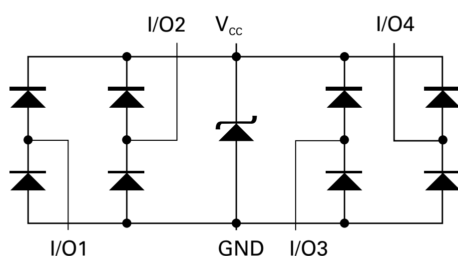
## Pinout




## Features

- Low capacitance of 0.85pF (TYP) per I/O
- ESD protection of ±12kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage of 1nA MAX with $V_R$=3.3V
- Small SOT563 package saves board space
- Lightning Protection, IEC61000-4-5, 4A (8/20μs)

## Functional Block Diagram




## Applications

- Computer Peripherals
- Mobile Phones
- PDA's
- Digital Cameras
- Network Hardware/Ports
- Test Equipment
- Medical Equipment

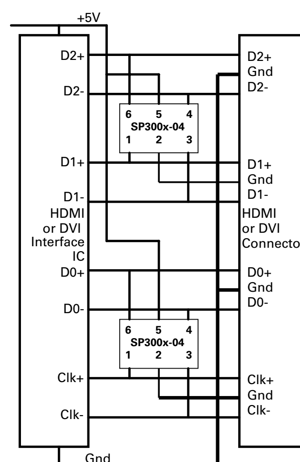
## Additional Information

**Datasheet**

**Resources**

**Samples**

## Application Example




A single 4 channel SP300x-04 device can be used to protect four of the data lines in a HDMI/DVI interface. Two (2) SP300x-04 devices provide protection for the main data lines. Low voltage ASIC HDMI/DVI drivers can also be protected with the SP300x-04, the $+V_{CC}$ pins on the SP300x-04 can be substituted with a suitable bypass capacitor or in some backdrive applications the $+V_{CC}$ of the SP300x-04 can be floated or NC.

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 4 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

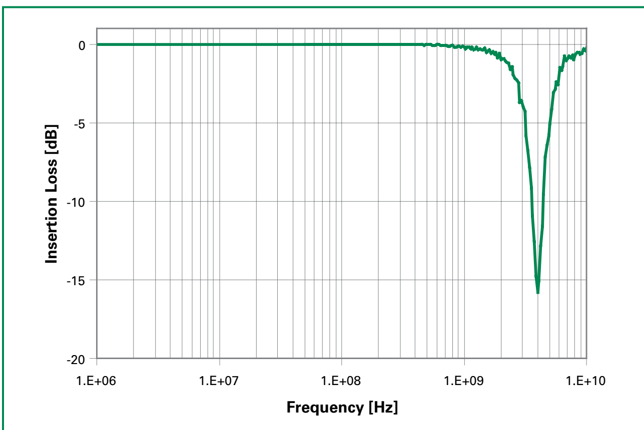
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

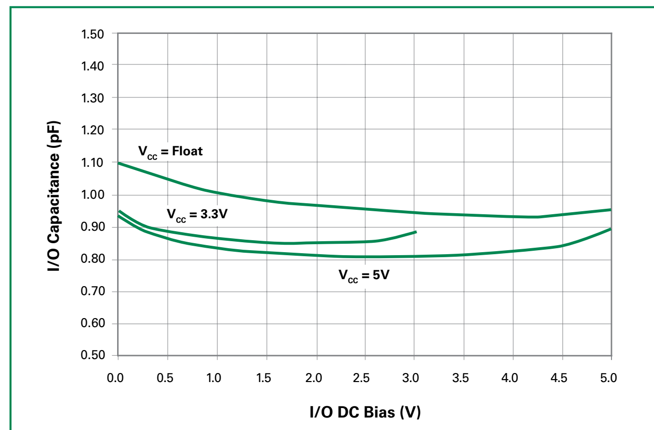
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \leq 1\mu A$ | | | 6 | V |
| Reverse Leakage Current[1] | $I_{LEAK}$ | $V_R$=3.3V | | | 1 | nA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 10.0 | 12.0 | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 11.8 | 15.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±12 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.8 | | Ω |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | 0.95 | 1.1 | 1.25 | pF |
| | | Reverse Bias=1.65V | 0.7 | 0.85 | 1 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.5 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

## Insertion Loss (S21) I/O to GND




## Capacitance vs. Bias Voltage

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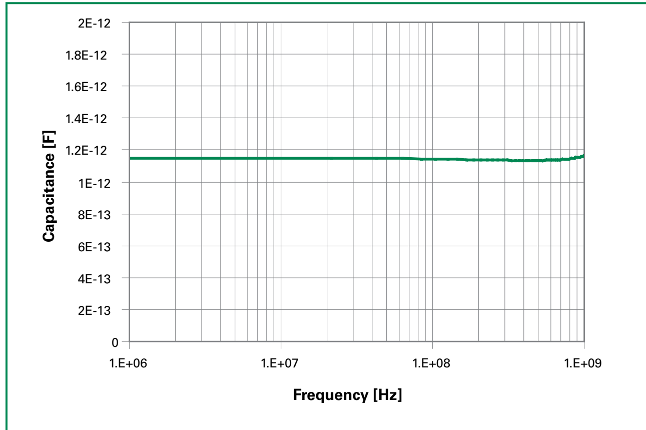
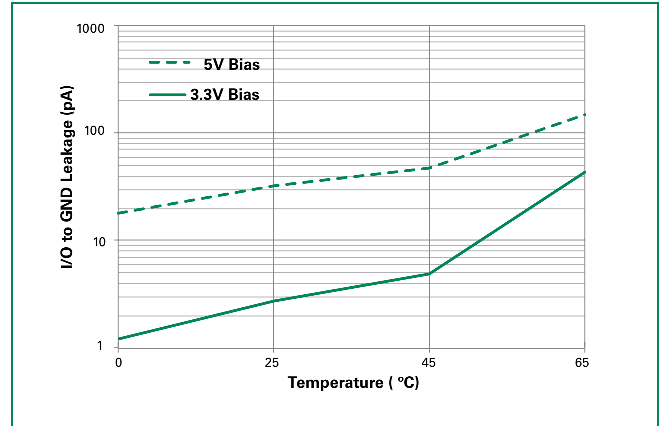
## Capacitance vs. Frequency

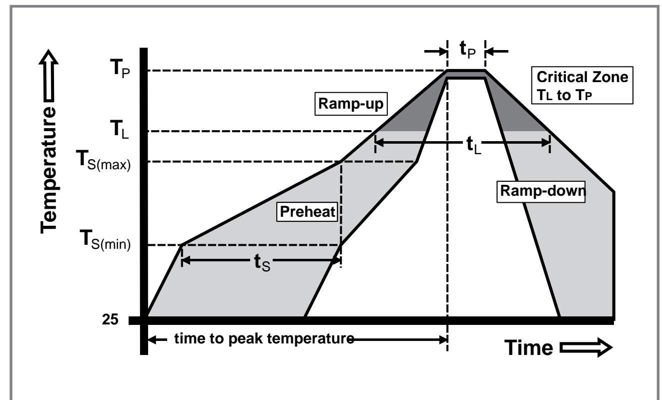



## Leakage Current vs Temperature




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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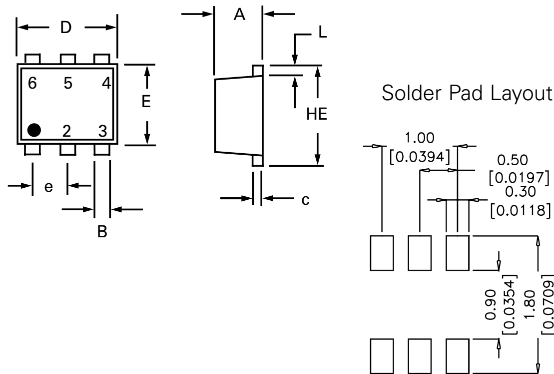
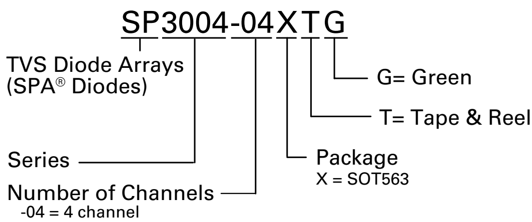
## Package Dimensions — SOT563

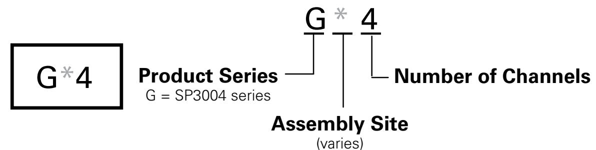



| Package | SOT 563 | | | |
|---|---|---|---|---|
| Pins | 6 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.50 | 0.60 | 0.020 | 0.024 |
| **B** | 0.17 | 0.27 | 0.007 | 0.011 |
| **c** | 0.08 | 0.18 | 0.003 | 0.007 |
| **D** | 1.50 | 1.70 | 0.059 | 0.067 |
| **E** | 1.10 | 1.30 | 0.043 | 0.051 |
| **e** | 0.50 BSC | | 0.020 BSC | |
| **L** | 0.10 | 0.30 | 0.004 | 0.012 |
| **HE** | 1.50 | 1.70 | 0.059 | 0.067 |

## Part Numbering System



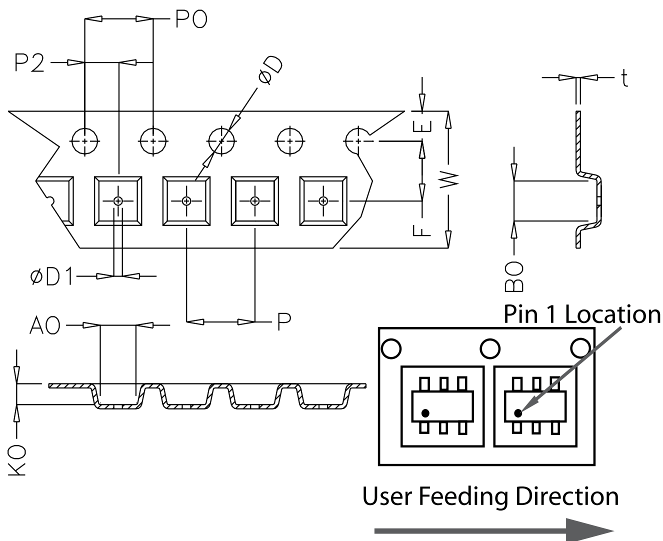

## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3004-04XTG | SOT563 | G*4 | 3000 |

## Embossed Carrier Tape & Reel Specification — SOT563




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.135 | 0.139 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.40 | 1.60 | 0.055 | 0.063 |
| **D1** | 0.45 | 0.55 | 0.017 | 0.021 |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0± 0.20 | | 1.574±0.008 | |
| **W** | 7.70 | 8.10 | 0.303 | 0.318 |
| **P** | 3.90 | 4.10 | 0.153 | 0.161 |
| **A0** | 1.73 | 1.83 | 0.068 | 0.072 |
| **B0** | 1.73 | 1.83 | 0.068 | 0.072 |
| **K0** | 0.64 | 0.74 | 0.025 | 0.029 |
| **t** | 0.22 max | | 0.009 max | |

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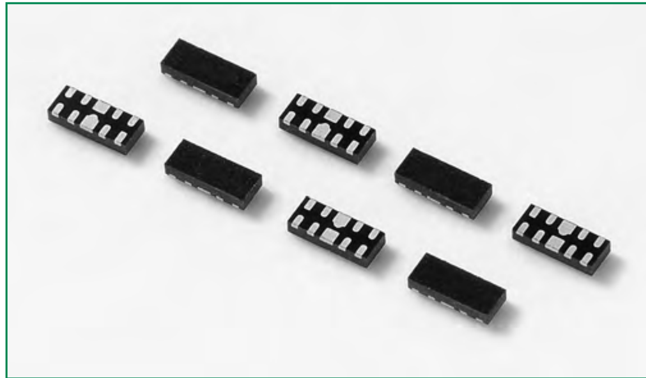
# SP3010 Series 0.45pF Diode Array

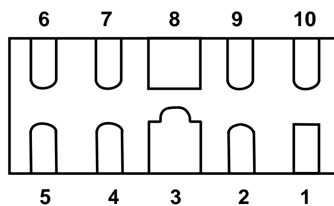
RoHS Pb GREEN



## Description

The SP3010 integrates 4 channels of ultra-low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust device can safely absorb repetitive ESD strikes at the maximum level specified in the IEC61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as HDMI, USB3.0, USB2.0, and IEEE 1394.

## Pinout

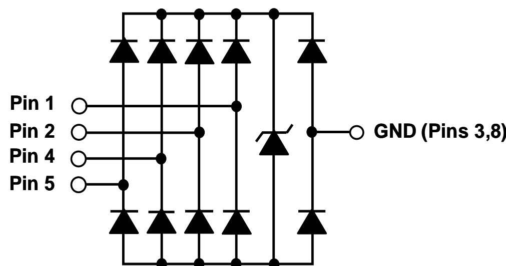



*Pins 6, 7, 9, 10 are not internally connected but should be connected to the trace.

## Features

- ESD, IEC61000-4-2, ±8kV contact, ±15kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 3A ($t_P$=8/20μs)
- Low capacitance of 0.45pF (TYP) per I/O
- Low leakage current of 0.1μA (TYP) at 5V
- Small form factor μDFN( JEDEC MO-229) package saves board space

## Functional Block Diagram




## Applications

- LCD/PDP TVs
- DVD Players
- Desktops
- MP3/PMP
- Set Top Boxes
- Mobile Phones
- Notebooks
- Digital Cameras

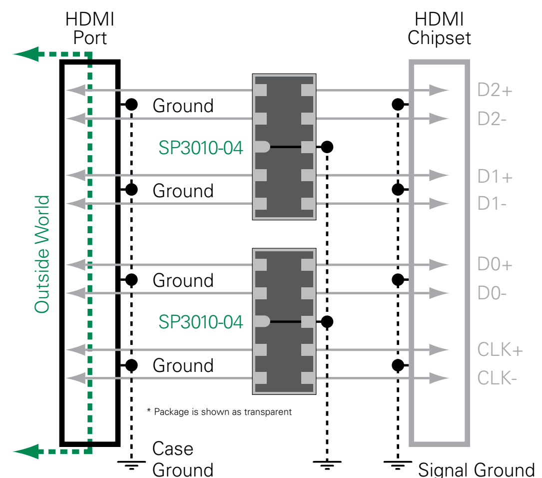
## Additional Information

Datasheet

Resources

Samples

## Application Example




Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 3.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

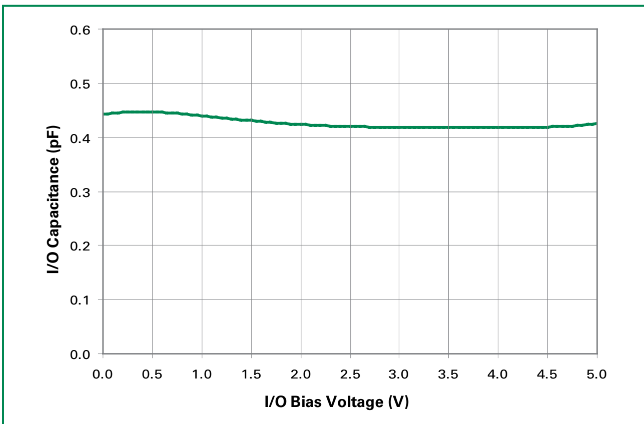
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Electrical Characteristics ($T_{OP}$=25°C)

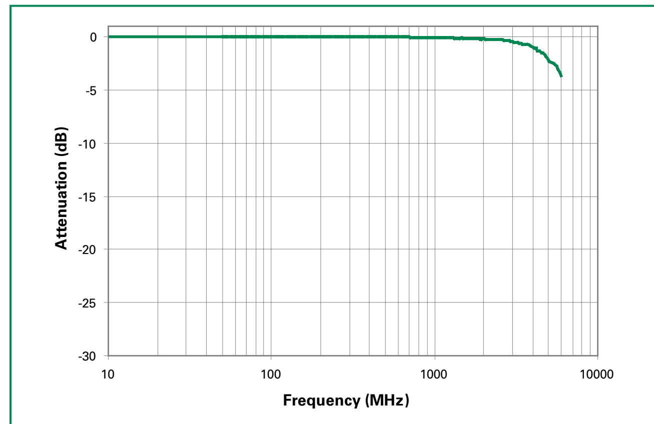
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$ ≤ 1μA | | | 6.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V, Any I/O to GND | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 10.8 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 12.3 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 1.5 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 0.45 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

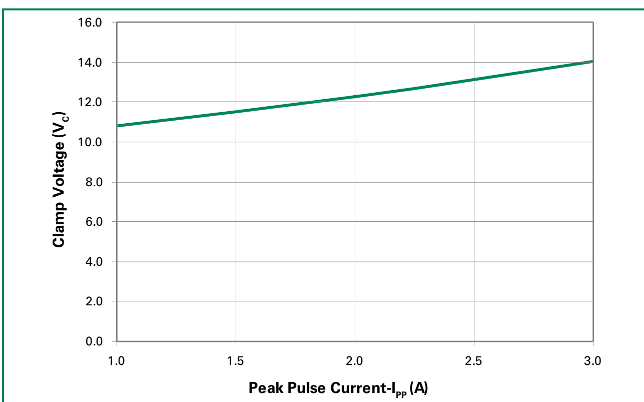
## Capacitance vs. Bias Voltage



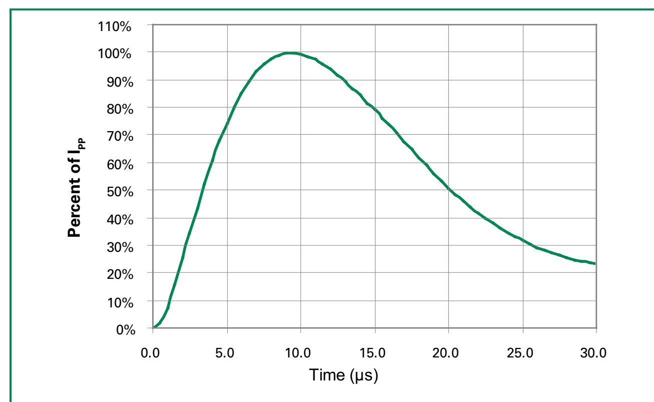

## Insertion Loss (S21) I/O to GND




## Clamping Voltage vs. $I_{PP}$




## Pulse Waveform

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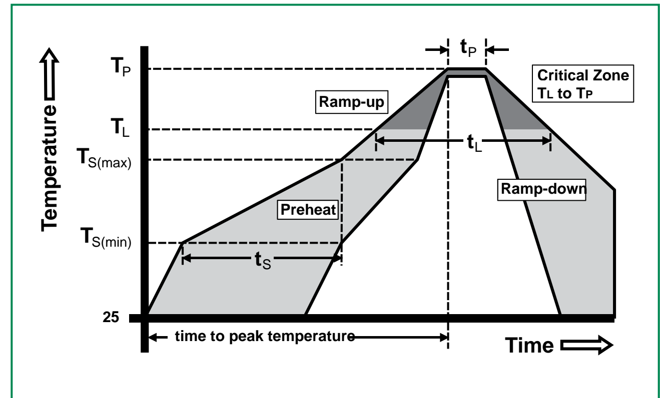
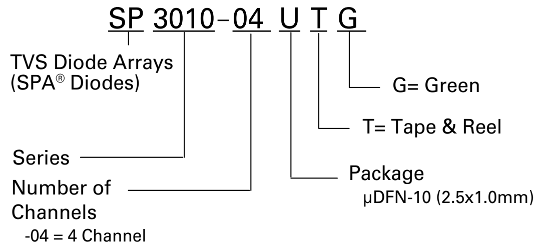
## Soldering Parameters

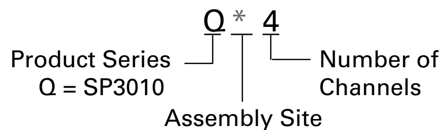
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Part Marking System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3010-04UTG | μDFN-10 | Q*4 | 3000 |

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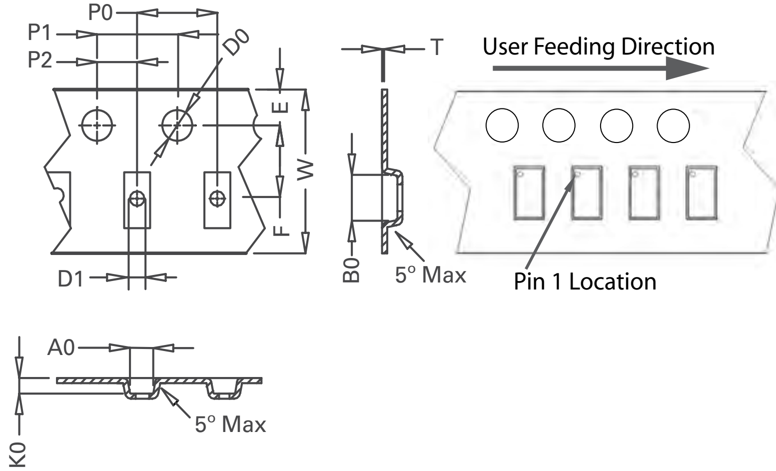
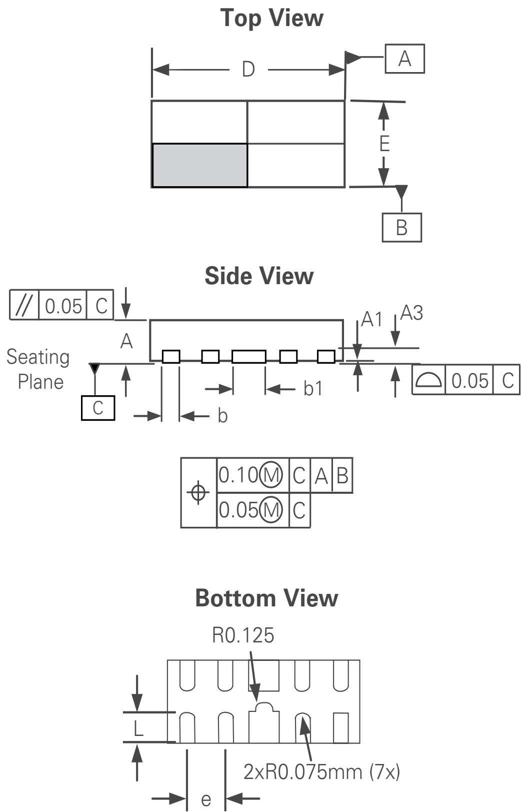
## Embossed Carrier Tape & Reel Specification — μDFN-10



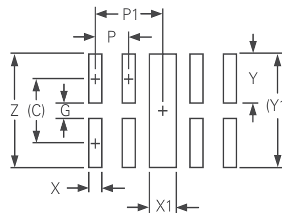

| Package | μDFN-10 (2.5x1.0x0.5mm) |
|---|---|
| Symbol | Millimeters |
| A0 | 1.30 ± 0.10 |
| B0 | 2.83 ± 0.10 |
| D0 | Ø 1.50 + 0.10 |
| D1 | Ø 1.00 + 0.25 |
| E | 1.75 ± 0.10 |
| F | 3.50 ± 0.05 |
| K0 | 0.65 ± 0.10 |
| P0 | 4.00 ± 0.10 |
| P1 | 4.00 ± 0.10 |
| P2 | 2.00 ± 0.05 |
| T | 0.254 ± 0.02 |
| W | 8.00 + 0.30 /- 0.10 |

## Package Dimensions — μDFN-10 (2.5x1.0x0.5mm)

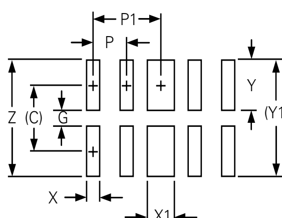



| Package | μDFN-10 (2.5x1.0x0.5mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.48 | 0.515 | 0.55 | 0.019 | 0.020 | 0.021 |
| A1 | 0.00 | -- | 0.05 | 0.000 | | 0.022 |
| A3 | 0.125 Ref | | | 0.005 Ref | | |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.012 |
| b1 | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |
| D | 2.40 | 2.50 | 2.60 | 0.094 | 0.098 | 0.102 |
| E | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| e | 0.50 BSC | | | 0.020 BSC | | |
| L | 0.30 | 0.365 | 0.43 | 0.012 | 0.014 | 0.016 |

**Recomended Soldering Pad Layout**




**Alternative Soldering Pad Layout**




| Soldering Pad Layout Dimensions | | |
|---|---|---|
| | Inch | Millimeter |
| C | (0.034) | (0.875) |
| G | 0.008 | 0.20 |
| P | 0.020 | 0.50 |
| P1 | 0.039 | 1.00 |
| X | 0.008 | 0.20 |
| X1 | 0.016 | 0.40 |
| Y | 0.027 | 0.675 |
| Y1 | (0.061) | (1.55) |
| Z | 0.061 | 1.55 |

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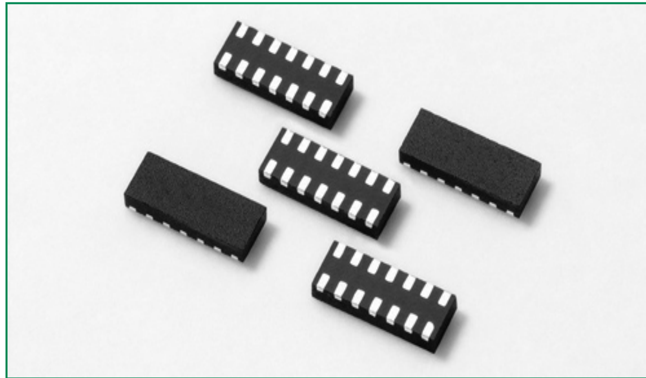
# SP3011 Series 0.40pF Diode Array for USB 3.0

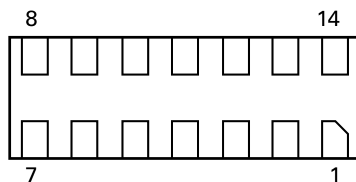
RoHS Pb GREEN



## Description

The SP3011 integrates six channels of ultra-low capacitance rail-to-rail diodes and an additional zener diode to provide protection for USB 3.0 ports that may experience destructive electrostatic discharges (ESD). This high density array can safely absorb repetitive ESD strikes at the maximum level specified in the IEC61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. It's extremely low loading capacitance makes it ideal for protecting any high-speed signal pins.

## Pinout

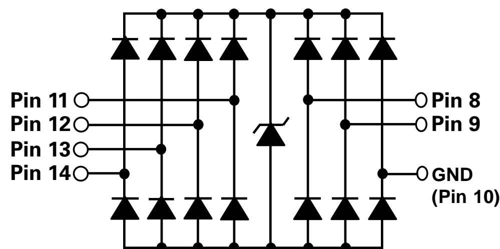



*Pins 1, 2, 3, 4, 5, 6, 7 are not internally connected but should be connected to the opposite pin with the PCB trace.

## Features

- ESD, IEC61000-4-2, ±8kV contact, ±15kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 3A (8/20μs)
- Low capacitance of 0.4pF (TYP) per I/O
- Low leakage current of 0.1μA (TYP) at 5V
- Small form factor μDFN (JEDEC MO-229) package saves board space

## Functional Block Diagram




## Applications

- Notebooks
- External Storage
- Digital Camcorder
- MP3/PMP Player
- Desktops
- Ultramobile PC
- Smartphone
- Set Top Box (DVR/PVR)

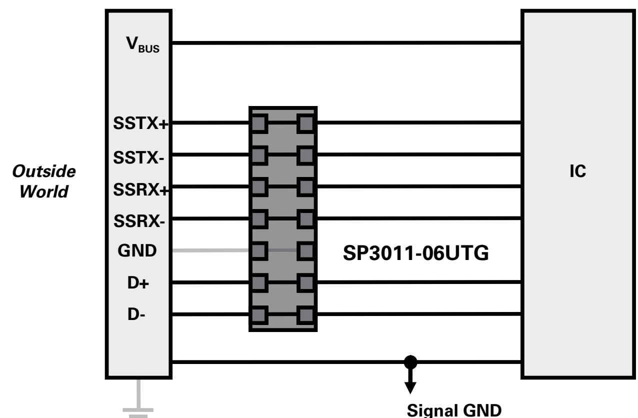
## Additional Information

Datasheet

Resources

Samples

## Application Example




Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 3.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

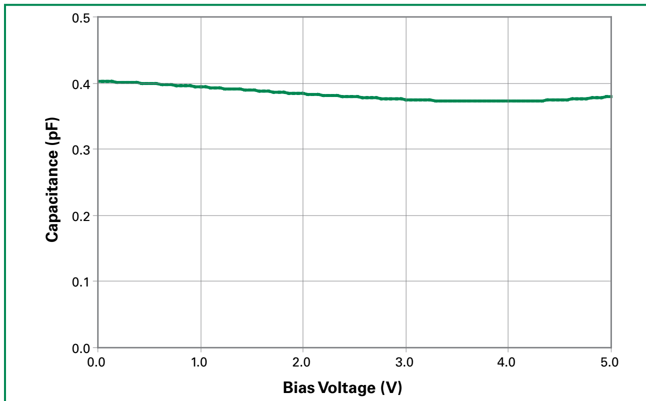
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Electrical Characteristics ($T_{OP}$=25°C)

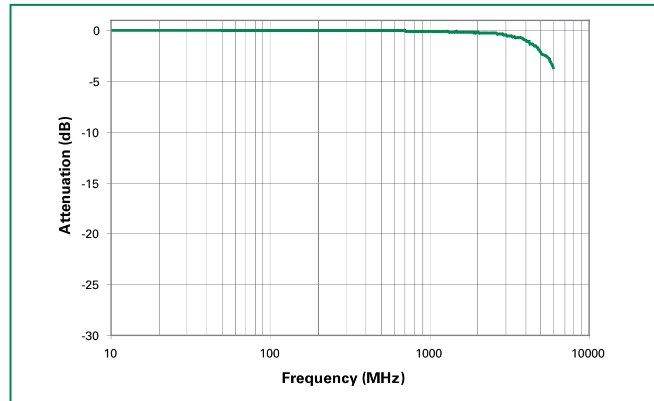
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \le 1\mu A$ | | | 6.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V, Any I/O to GND | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 11.0 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 12.5 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1}) / (I_{PP2}-I_{PP1})$ | | 1.5 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 0.4 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

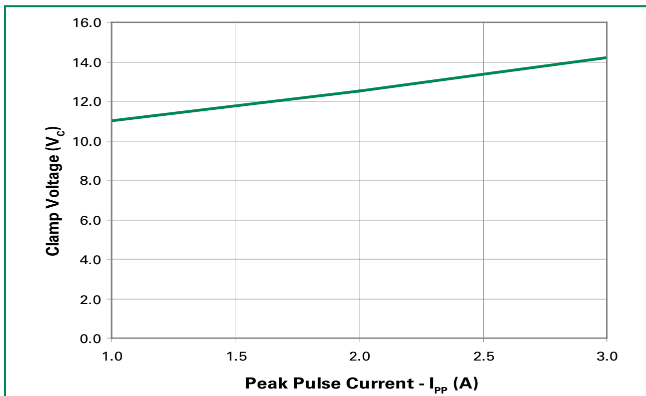
## Capacitance vs. Bias Voltage



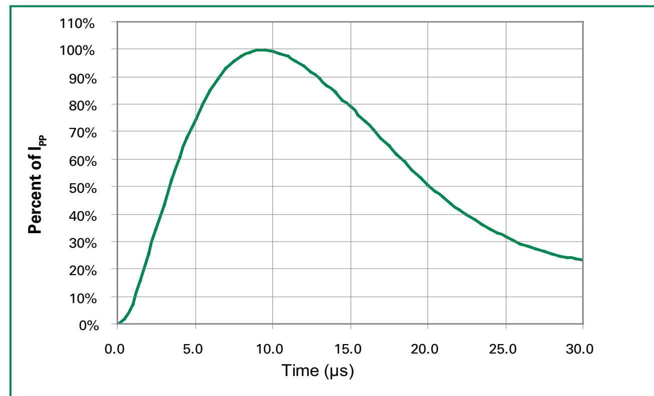

## Insertion Loss (S21) I/O to GND




## Clamping Voltage vs. $I_{PP}$




## Pulse Waveform

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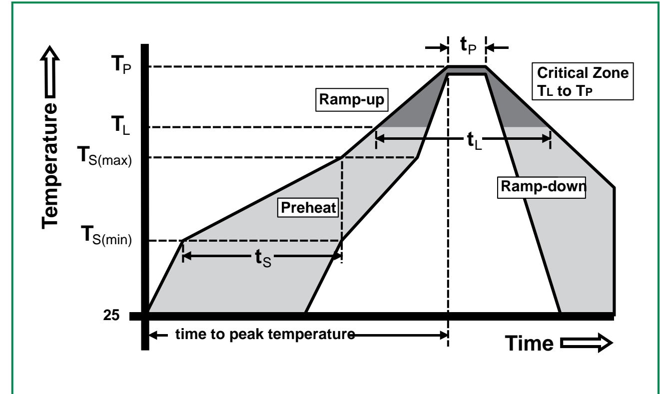
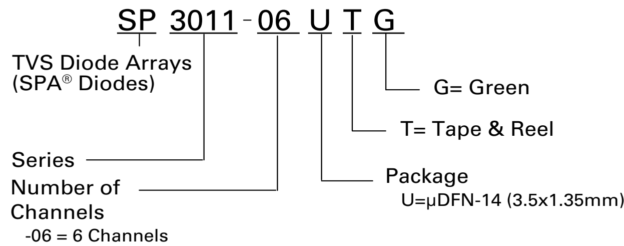
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System



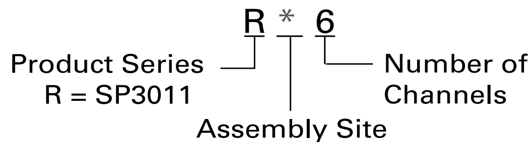

## Product Characteristics

| Lead Plating | Pre-Plated Frame |
|---|---|
| Lead Material | Copper Alloy |
| Lead Coplanarity | 0.0004 inches (0.102mm) |
| Substitute Material | Silicon |
| Body Material | Molded Epoxy |
| Flammability | UL 94 V-0 |

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3011-06UTG | μDFN-14 | R*6 | 3000 |

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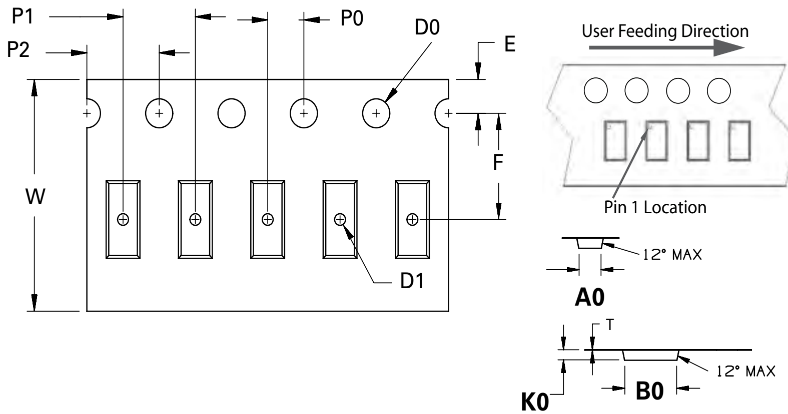
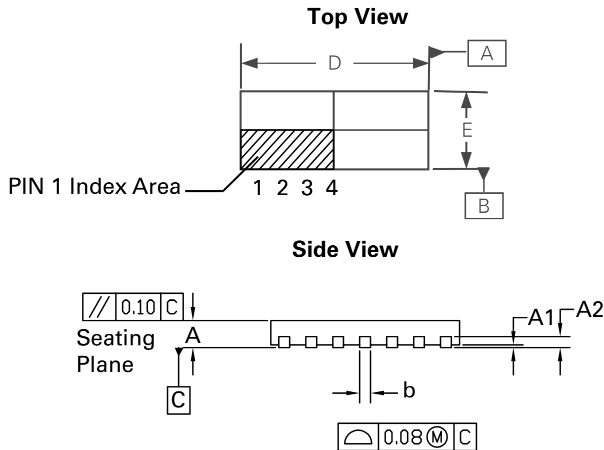
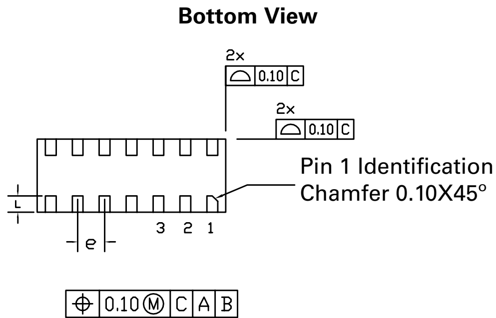
## Embossed Carrier Tape & Reel Specification — μDFN-14




| Symbol | Millimeters |
|---|---|
| A0 | 1.58 ± 0.10 |
| B0 | 3.73 ± 0.10 |
| D0 | 0.60 + 0.05 |
| D1 | Ø 0.60 + 0.05 |
| E | 1.75 ± 0.10 |
| F | 5.50 ± 0.05 |
| K0 | 0.68 ± 0.10 |
| P0 | 2.00 ± 0.05 |
| P1 | 4.00 ± 0.10 |
| P2 | 4.00 ± 0.10 |
| T | 0.28 ± 0.02 |
| W | 12.00 + 0.30 /- 0.10 |

## Package Dimensions — μDFN-14 (3.5x1.35x0.5mm)



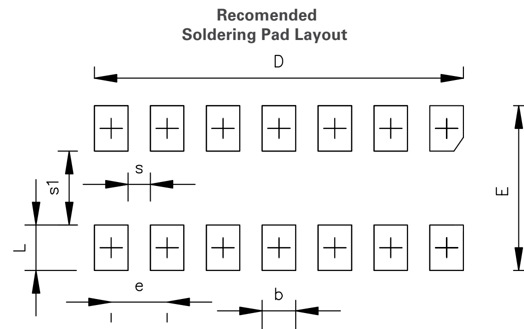




| Package | μDFN-14 (3.5x1.35x0.5mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |
| A1 | 0.00 | 0.02 | 0.05 | 0.000 | 0.001 | 0.002 |
| A2 | 0.203 Ref | | | 0.008 Ref | | |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.012 |
| D | 3.40 | 3.50 | 3.60 | 0.134 | 0.138 | 0.142 |
| D2 | - | - | - | - | - | - |
| E | 1.25 | 1.35 | 1.45 | 0.050 | 0.054 | 0.058 |
| E1 | - | - | - | - | - | - |
| e | 0.500 BSC | | | 0.020 BSC | | |
| L | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 |

Notes:

1. Dimension and tolerancing comform to ASME Y14.5M-1994.
2. Controlling dimensions: Millimeter. Converted Inch dimensions are not necessarily exact.

**Recomended Soldering Pad Layout**




| Symbol | Millimeter | | | Inches | | |
|---|---|---|---|---|---|---|
| D | 3.29 | 3.30 | 3.31 | 0.1295 | 0.1299 | 0.1303 |
| E | 1.44 | 1.45 | 1.46 | 0.0567 | 0.0571 | 0.0575 |
| b | 0.29 | 0.30 | 0.31 | 0.0114 | 0.0118 | 0.0122 |
| L | 0.39 | 0.40 | 0.41 | 0.0154 | 0.0158 | 0.0161 |
| e | 0.50typ | | | 0.020typ | | |
| s | 0.19 | 0.20 | 0.21 | 0.0075 | 0.0078 | 0.0083 |
| s1 | 0.64 | 0.65 | 0.66 | 0.0252 | 0.0256 | 0.0260 |

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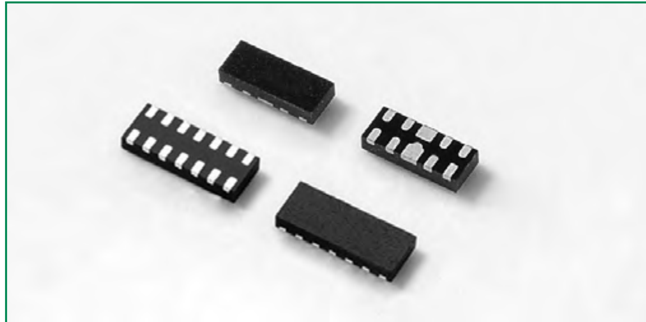
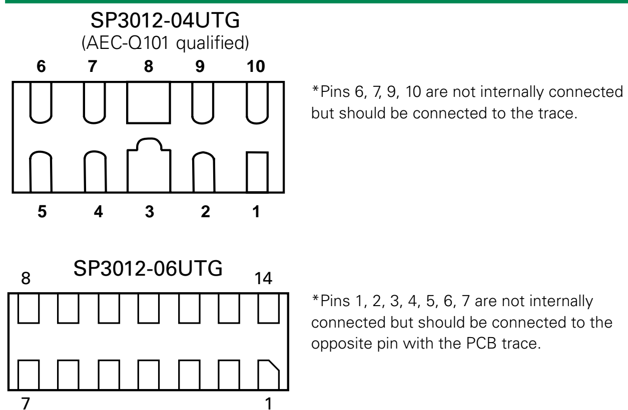
# SP3012 Series 0.5pF Diode Array



## Description

The SP3012 integrates either 4 or 6 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust devices can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (±8kV contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal lines such as USB3.0, HDMI, USB2.0, and eSATA.

## Pinout




*Pins 6, 7, 9, 10 are not internally connected but should be connected to the trace.

*Pins 1, 2, 3, 4, 5, 6, 7 are not internally connected but should be connected to the opposite pin with the PCB trace.

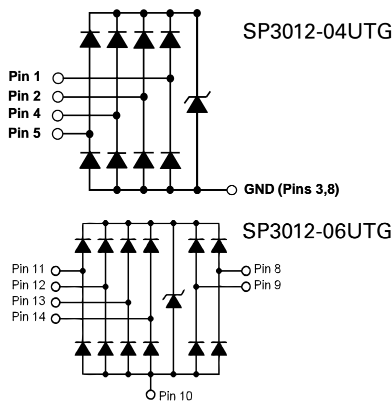
## Features

- ESD, IEC61000-4-2, ±12kV contact, ±25kV air
- EFT, IEC61000-4-4, 40A ($t_P$=5/50ns)
- Lightning, IEC61000-4-5, 4A ($t_P$=8/20μs)
- Low capacitance of 0.5pF (TYP) per I/O
- Low leakage current of 1.5μA (MAX) at 5V
- Small form factor μDFN (JEDEC MO-229) package provides flow through routing to simplify PCB layout
- AEC-Q101 qualified (μDFN-10 package)

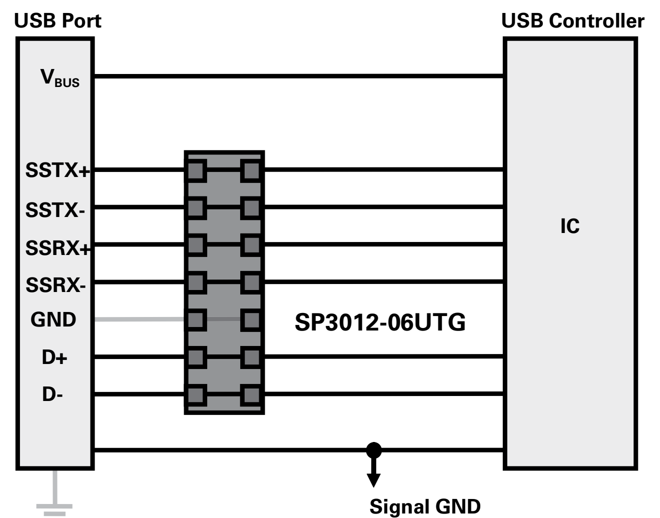
## Applications

- LCD/PDP TVs
- External Storages
- DVD/Blu-ray Players
- Desktops
- MP3/PMP
- Set Top Boxes
- Smartphones
- Ultrabooks/Notebooks
- Digital Cameras

## Functional Block Diagram




## Application Example for USB3.0




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 4.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

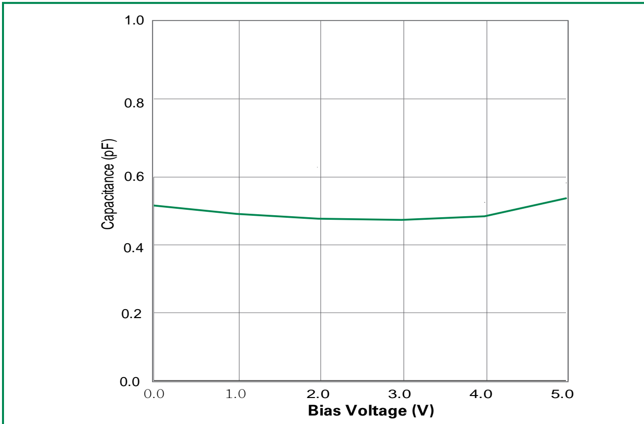
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Electrical Characteristics ($T_{OP}$=25°C)

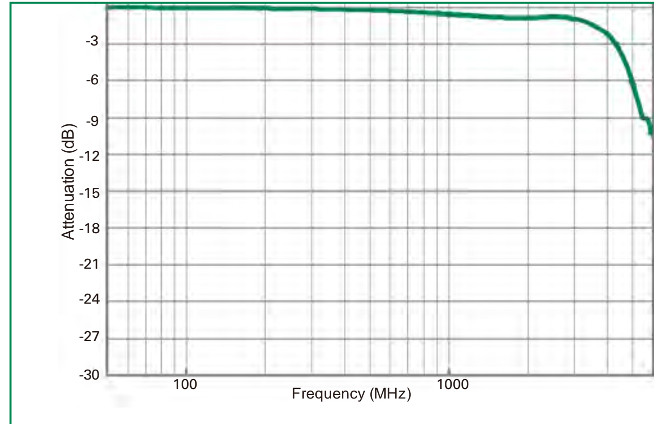
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \leq 1\mu A$ | | | 5.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V, Any I/O to GND | | | 1.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 6.6 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 7.0 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.4 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±12 | | | kV |
| | | IEC61000-4-2 (Air) | ±25 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V, f=1 MHz | | 0.5 | | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V, f=1 MHz | | 0.3 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

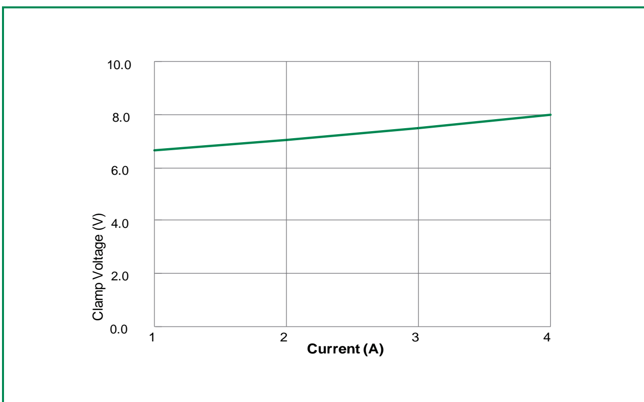
## Capacitance vs. Bias Voltage



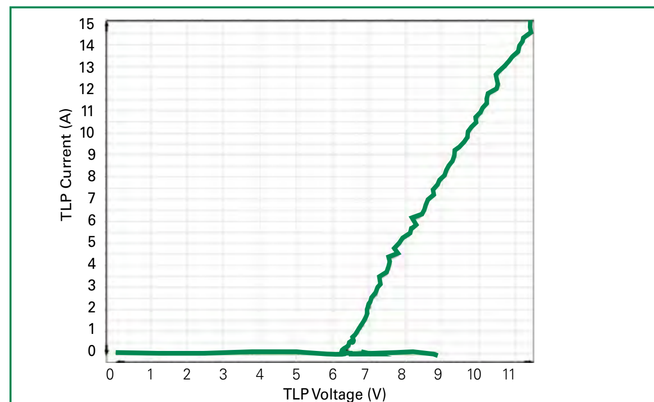

## Insertion Loss (S21) I/O to GND




## Clamping Voltage vs. $I_{PP}$




## Transmission Line Pulsing(TLP) Plot

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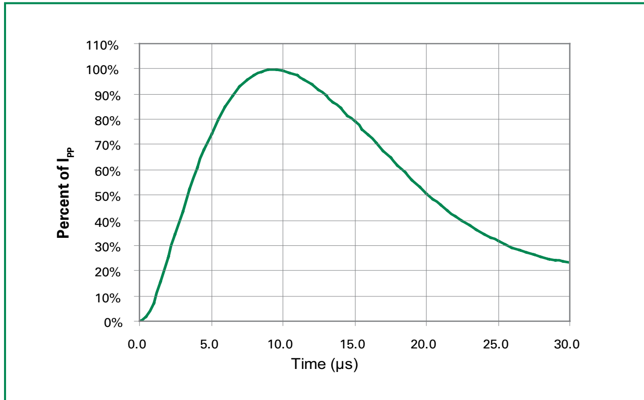
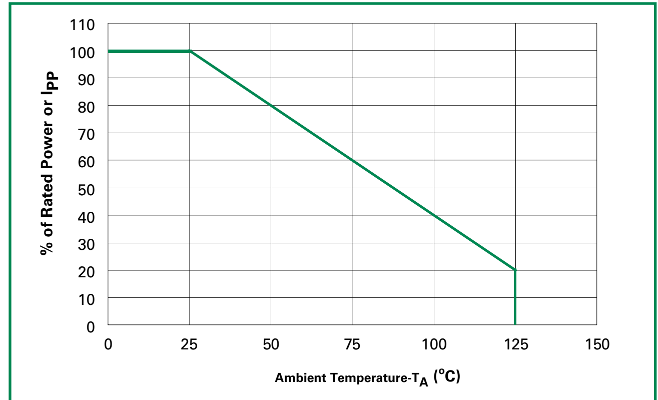
## Pulse Waveform

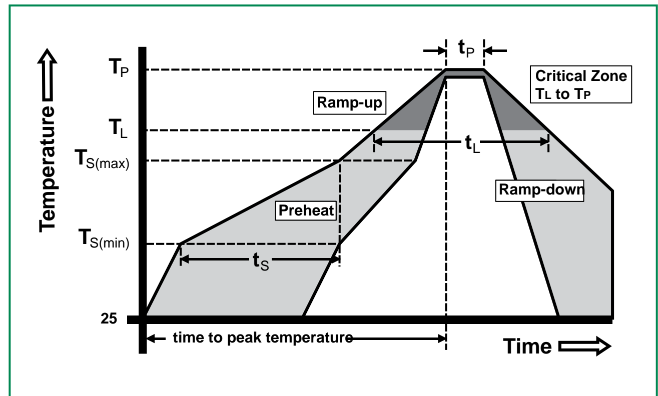



## Power Derating Curve




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Ordering Information

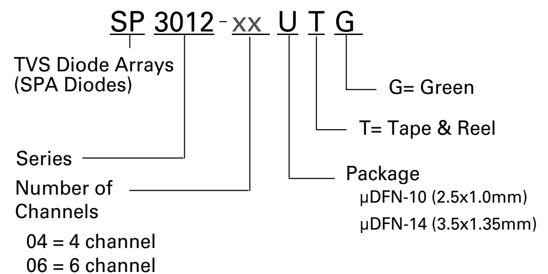
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3012-04UTG | μDFN-10 | V*4 | 3000 |
| SP3012-06UTG | μDFN-14 | V*6 | 3000 |

## Product Characteristics

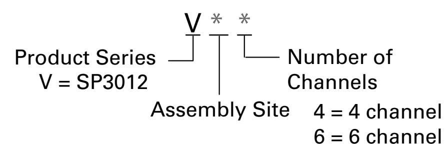
| **Lead Plating** | Pre-Plated Frame |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Numbering System




## Part Marking System

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## Application Information

### Signal Integrity of High-Speed Data Interfaces

Adding external ESD protection to a high-speed data port is not trivial for a variety of reasons.

1. ESD protection devices will add parasitic capacitance to each data line from line to GND and line to line causing impedance mismatches between the differential pairs. This ultimately affects the signal eye-diagram and whether or not the transceiver can distinguish a "1" from a "0".

2. ESD devices should be placed as close as possible to the port being protected to maximize their effect (i.e. clamping capability) and minimize the effect that PCB trace inductance can have during an ESD transient. Depending on the package size and pinout this could be challenging and the bigger the package, the larger the land pattern must be, which adds more parasitic capacitance.

3. Stub traces can add another element of discontinuity adversely affecting signal integrity so ESD protection is best employed when it's "overlaid" on the data lines or when the signals can simply pass underneath the device.

Taking all of this into account Littelfuse developed the SP3012 Series which was designed specifically for protection of high-speed data ports such as HDMI 1.3/1.4 and USB 3.0. They present less than 0.5pF from line to GND and only 0.3pF from line to line minimizing impedance mismatch between the differential pairs.

Furthermore, the SP3012 is rated up to ±12kV (contact discharge) which far exceeds the maximum requirement of the IEC 61000-4-2 standard.

There are two options available (4 channel and 6 channel) and both are housed in leadless µDFN packages so the data lines can pass directly underneath the device to reduce discontinuities and maintain signal integrity.

### USB 3.0 Eye Diagram Data

Figure 1 shows the layout used for the SP3012-06UTG in a USB 3.0 application. The traces routed toward the top are the two legacy USB 2.0 lines (D+/D-) that run at the slower speed of 480Mbps and therefore are not as critical as the 5Gbps Super-Speed traces.

Figure 1: PCB Layout of the SP3012-06UTG for USB 3.0

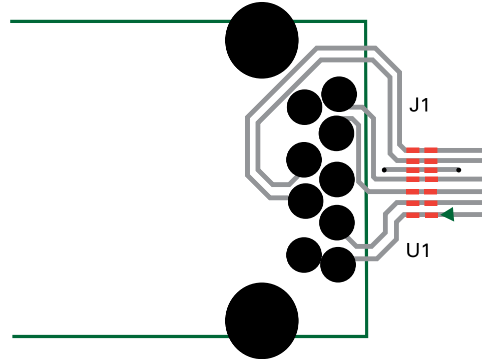


Figure 2 shows the USB 3.0 eye diagram that resulted from the PCB layout above with the SP3012-06UTG soldered on the landing pattern.

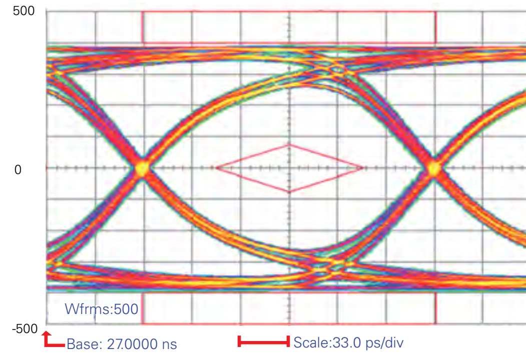


Figure 2: USB 3.0 Eye Diagram with the SP3012-06UTG

Using a similar layout as above, Figure 3 shows the eye diagram that resulted using the SP3012-04UTG to protect the Super-Speed data lines and the SP3003-02UTG to protect the legacy data pair.

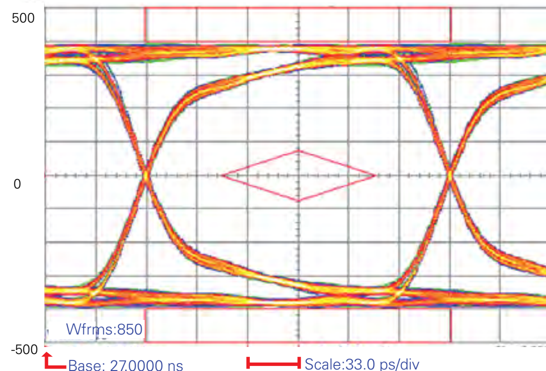


Figure 3: USB 3.0 Eye Diagram with the SP3012-04UTG

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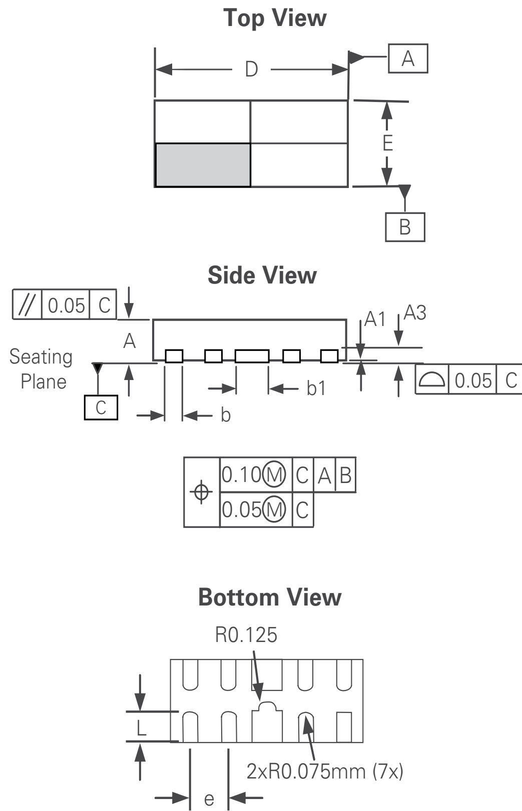
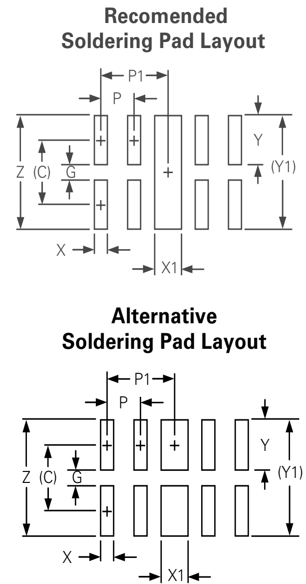
## Package Dimensions — μDFN-10 (2.5x1.0x0.5mm)

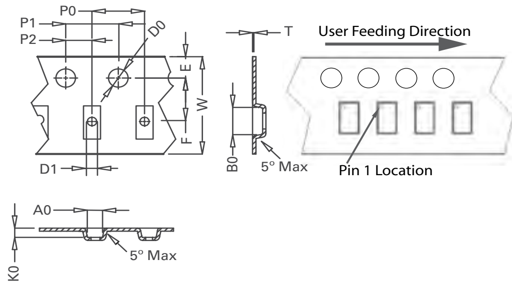



| Package | μDFN-10 (2.5x1.0x0.5mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| **A** | 0.48 | 0.515 | 0.55 | 0.019 | 0.020 | 0.021 |
| **A1** | 0.00 | -- | 0.05 | 0.000 | | 0.022 |
| **A3** | 0.125 Ref | | | 0.005 Ref | | |
| **b** | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.012 |
| **b1** | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |
| **D** | 2.40 | 2.50 | 2.60 | 0.094 | 0.098 | 0.102 |
| **E** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **e** | 0.50 BSC | | | 0.020 BSC | | |
| **L** | 0.30 | 0.365 | 0.43 | 0.012 | 0.014 | 0.016 |

| Soldering Pad Layout Dimensions | | |
|---|---|---|
| | Inch | Millimeter |
| **C** | (0.034) | (0.875) |
| **G** | 0.008 | 0.20 |
| **P** | 0.020 | 0.50 |
| **P1** | 0.039 | 1.00 |
| **X** | 0.008 | 0.20 |
| **X1** | 0.016 | 0.40 |
| **Y** | 0.027 | 0.675 |
| **Y1** | (0.061) | (1.55) |
| **Z** | 0.061 | 1.55 |




## Embossed Carrier Tape & Reel Specification — μDFN-10




| Package | μDFN-10 (2.5x1.0x0.5mm) |
|---|---|
| Symbol | Millimeters |
| **A0** | 1.30 ± 0.10 |
| **B0** | 2.83 ± 0.10 |
| **D0** | Ø 1.50 + 0.10 |
| **D1** | Ø 1.00 + 0.25 |
| **E** | 1.75 ± 0.10 |
| **F** | 3.50 ± 0.05 |
| **K0** | 0.65 ± 0.10 |
| **P0** | 4.00 ± 0.10 |
| **P1** | 4.00 ± 0.10 |
| **P2** | 2.00 ± 0.05 |
| **T** | 0.254 ± 0.02 |
| **W** | 8.00 + 0.30 /- 0.10 |

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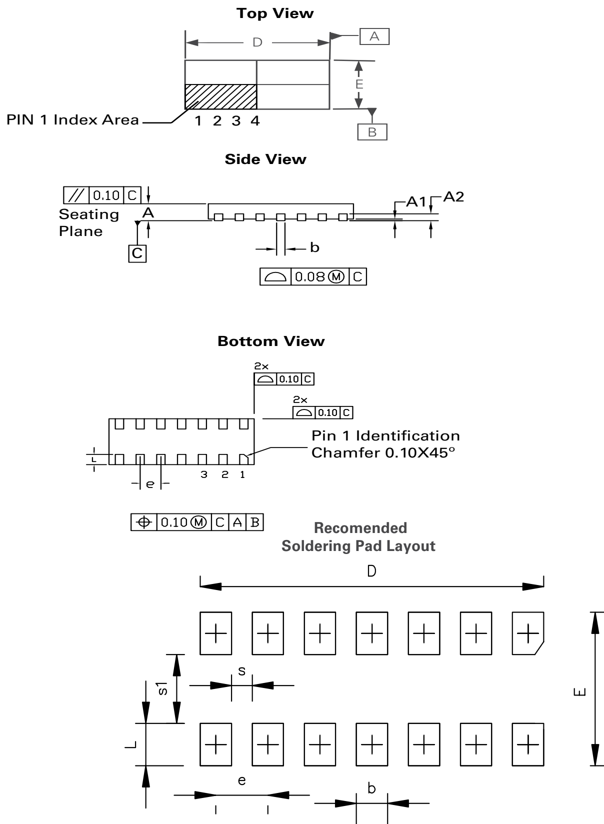
## Package Dimensions — µDFN-14 (3.5x1.35x0.5mm)



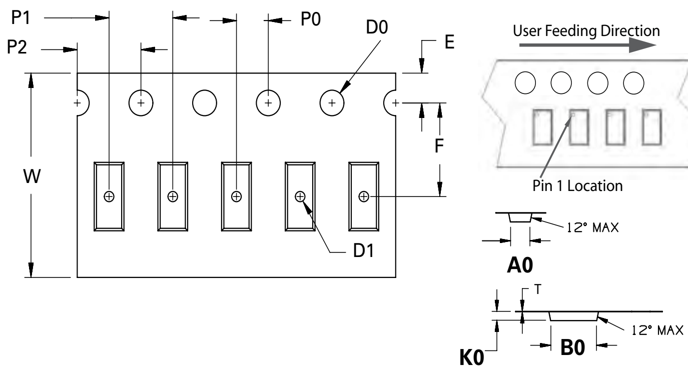

| Symbol | µDFN-14 (3.5x1.35x0.5mm) JEDEC MO-229 | | | | | |
|---|---|---|---|---|---|---|
| | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |
| A1 | 0.00 | 0.02 | 0.05 | 0.000 | 0.001 | 0.002 |
| A2 | 0.203 Ref | | | 0.008 Ref | | |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.012 |
| D | 3.40 | 3.50 | 3.60 | 0.134 | 0.138 | 0.142 |
| D2 | - | - | - | - | - | - |
| E | 1.25 | 1.35 | 1.45 | 0.050 | 0.054 | 0.058 |
| E1 | - | - | - | - | - | - |
| e | 0.500 BSC | | | 0.020 BSC | | |
| L | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 |

Notes:

1. Dimension and tolerancing comform to ASME Y14.5M-1994.
2. Controlling dimensions: Millimeter. Converted Inch dimensions are not necessarily exact.

| Symbol | Soldering Pad Layout Dimensions | | | | | |
|---|---|---|---|---|---|---|
| | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| D | 3.29 | 3.30 | 3.31 | 0.1295 | 0.1299 | 0.1303 |
| E | 1.44 | 1.45 | 1.46 | 0.0567 | 0.0571 | 0.0575 |
| b | 0.29 | 0.30 | 0.31 | 0.0114 | 0.0118 | 0.0122 |
| L | 0.39 | 0.40 | 0.41 | 0.0154 | 0.0158 | 0.0161 |
| e | 0.50 typ | | | 0.020 typ | | |
| s | 0.19 | 0.20 | 0.21 | 0.0075 | 0.0078 | 0.0083 |
| s1 | 0.64 | 0.65 | 0.66 | 0.0252 | 0.0256 | 0.0260 |

## Embossed Carrier Tape & Reel Specification — µDFN-14




| Symbol | Millimeters |
|---|---|
| A0 | 1.58 ± 0.10 |
| B0 | 3.73 ± 0.10 |
| D0 | 0.60 + 0.05 |
| D1 | Ø 0.60 + 0.05 |
| E | 1.75 ± 0.10 |
| F | 5.50 ± 0.05 |
| K0 | 0.68 ± 0.10 |
| P0 | 2.00 ± 0.05 |
| P1 | 4.00 ± 0.10 |
| P2 | 4.00 ± 0.10 |
| T | 0.28 ± 0.02 |
| W | 12.00 + 0.30 /- 0.10 |

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# SP0524P Series 0.5pF Diode Array

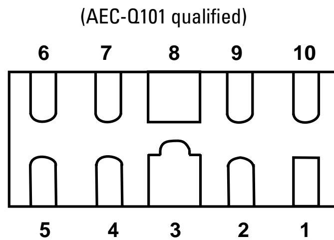
RoHS Pb GREEN

## Description

The SP0524P integrates 4 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust device can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (±8kV contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as HDMI, USB3.0, USB2.0, and IEEE 1394.

## Pinout

(AEC-Q101 qualified)

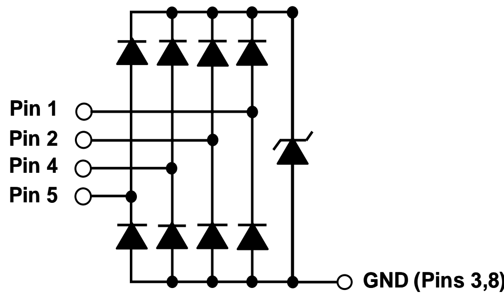



*Pins 6, 7, 9, 10 are not internally connected but should be connected to the trace.

## Features

- ESD, IEC61000-4-2, ±12kV contact, ±25kV air
- EFT, IEC61000-4-4, 40A ($t_P$=5/50ns)
- Lightning, IEC61000-4-5, 4A ($t_P$=8/20μs)
- Low capacitance of 0.5pF (TYP) per I/O
- Low leakage current of 1.5μA (MAX) at 5V
- Small form factor μDFN (JEDEC MO-229) package saves board space
- AEC-Q101 qualified (μDFN-10 package)

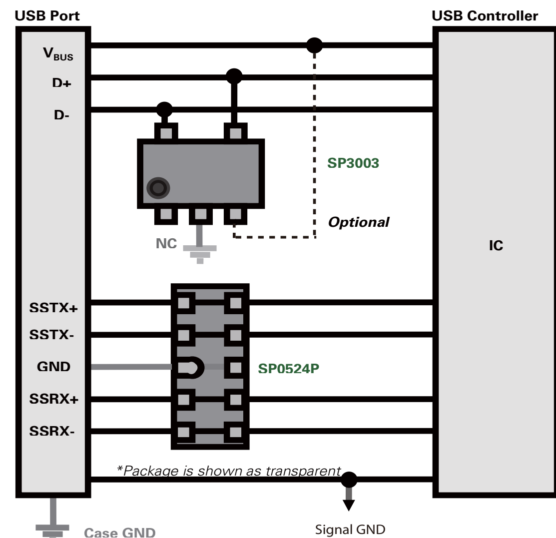
## Functional Block Diagram




## Applications

- LCD/PDP TVs
- External Storages
- DVD/ Blue-Ray Players
- Desktops
- MP3/PMP
- Set Top Boxes
- Mobile Phones
- Notebooks
- Digital Cameras

## Application Example for USB3.0




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 4.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

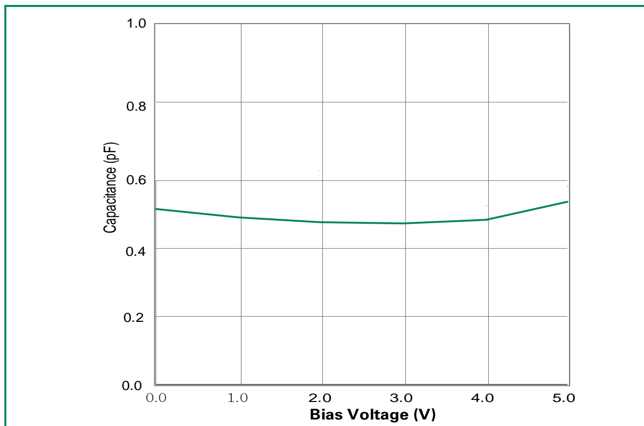
*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Electrical Characteristics ($T_{OP}$=25°C)

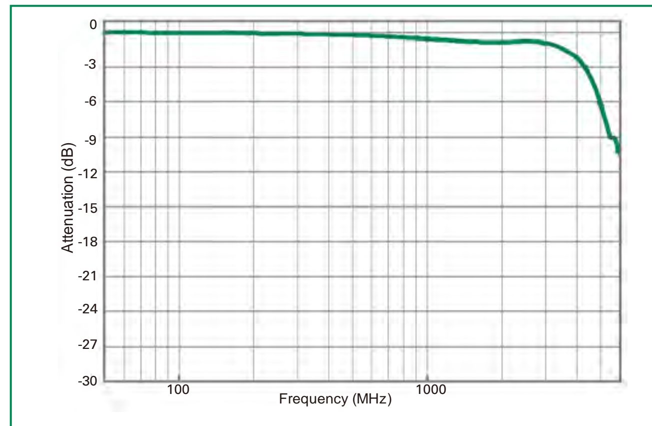
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$ ≤ 1μA | | | 5.0 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V, Any I/O to GND | | | 1.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 6.6 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 7.0 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.4 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±12 | | | kV |
| | | IEC61000-4-2 (Air) | ±25 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V, f=1 MHz | | 0.5 | | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V, f=1 MHz | | 0.3 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

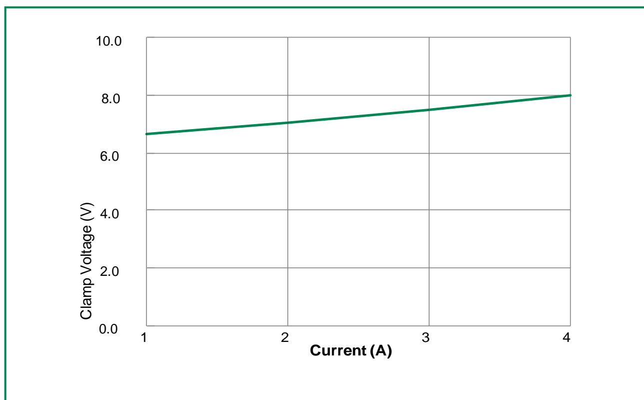
## Capacitance vs. Bias Voltage



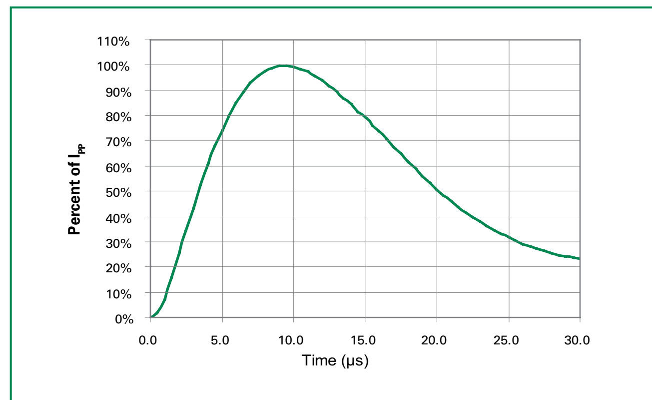

## Insertion Loss (S21) I/O to GND




## Clamping Voltage vs. $I_{PP}$




## Pulse Waveform

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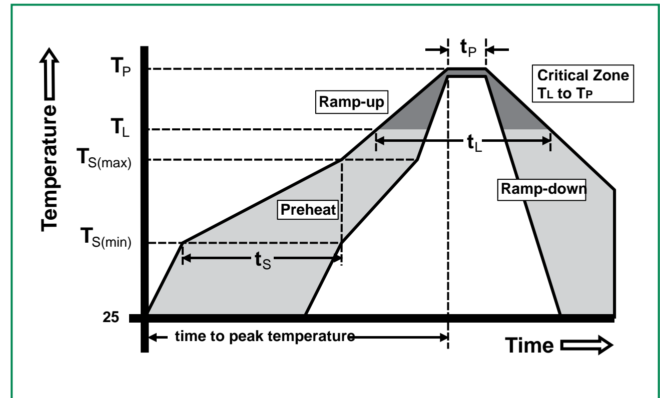
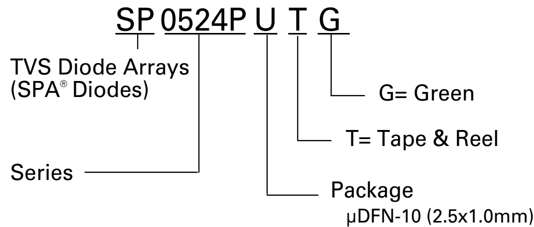
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System

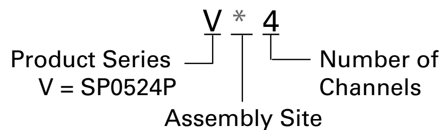



## Product Characteristics

| **Lead Plating** | Pre-Plated Frame |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP0524PUTG | μDFN-10 | V*4 | 3000 |

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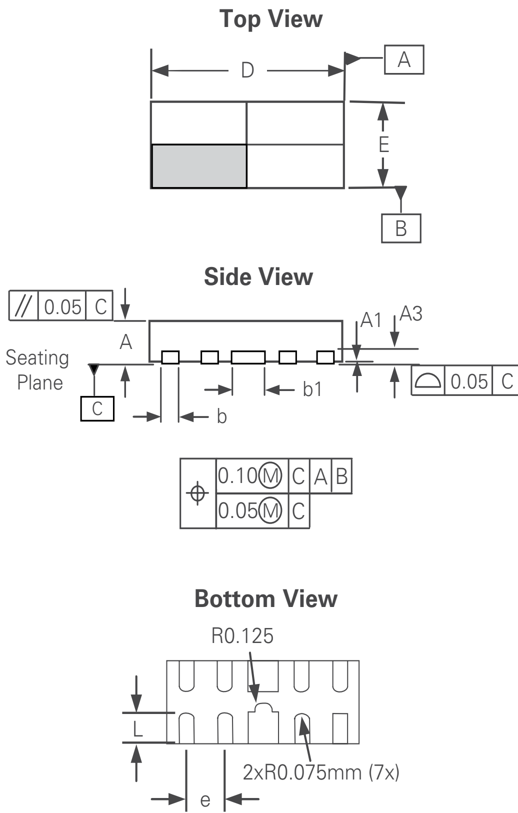
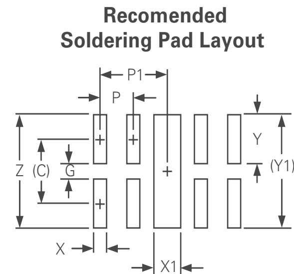
## Package Dimensions — µDFN-10 (2.5x1.0x0.5mm)



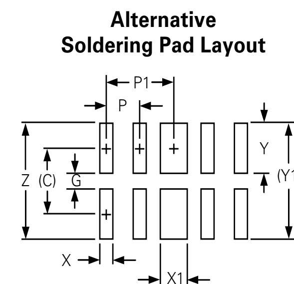

| Package | µDFN-10 (2.5x1.0x0.5mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| **A** | 0.48 | 0.515 | 0.55 | 0.019 | 0.020 | 0.021 |
| **A1** | 0.00 | -- | 0.05 | 0.000 | | 0.022 |
| **A3** | 0.125 Ref | | | 0.005 Ref | | |
| **b** | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.012 |
| **b1** | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |
| **D** | 2.40 | 2.50 | 2.60 | 0.094 | 0.098 | 0.102 |
| **E** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **e** | 0.50 BSC | | | 0.020 BSC | | |
| **L** | 0.30 | 0.365 | 0.43 | 0.012 | 0.014 | 0.016 |

| Soldering Pad Layout Dimensions | | |
|---|---|---|
| | Inch | Millimeter |
| **C** | (0.034) | (0.875) |
| **G** | 0.008 | 0.20 |
| **P** | 0.020 | 0.50 |
| **P1** | 0.039 | 1.00 |
| **X** | 0.008 | 0.20 |
| **X1** | 0.016 | 0.40 |
| **Y** | 0.027 | 0.675 |
| **Y1** | (0.061) | (1.55) |
| **Z** | 0.061 | 1.55 |

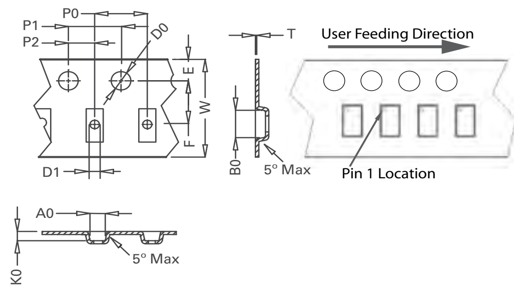
**Recomended Soldering Pad Layout**




**Alternative Soldering Pad Layout**




## Embossed Carrier Tape & Reel Specification — µDFN-10




| Package | µDFN-10 (2.5x1.0x0.5mm) |
|---|---|
| Symbol | Millimeters |
| **A0** | 1.30 ± 0.10 |
| **B0** | 2.83 ± 0.10 |
| **D0** | Ø 1.50 + 0.10 |
| **D1** | Ø 1.00 + 0.25 |
| **E** | 1.75 ± 0.10 |
| **F** | 3.50 ± 0.05 |
| **K0** | 0.65 ± 0.10 |
| **P0** | 4.00 ± 0.10 |
| **P1** | 4.00 ± 0.10 |
| **P2** | 2.00 ± 0.05 |
| **T** | 0.254 ± 0.02 |
| **W** | 8.00 + 0.30 /- 0.10 |

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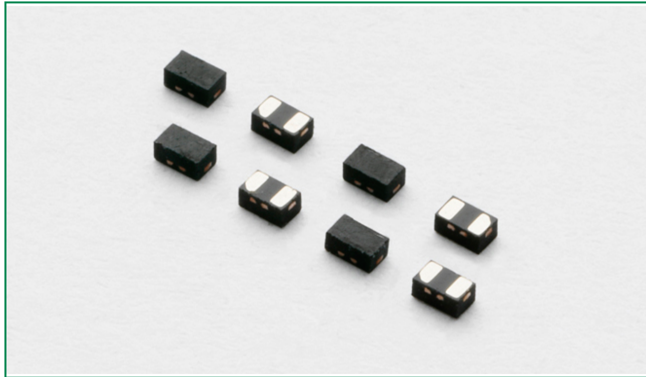
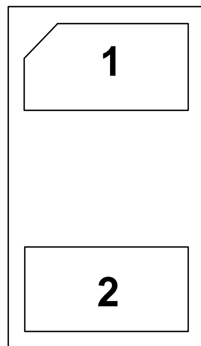
# SP3021 Series 0.5pF 8kV Bidirectional Discrete TVS



## Description

The SP3021 includes back-to-back TVS diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes up to the maximum level specified in the IEC61000-4-2 international standard without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

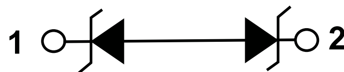
## Pinout




## Features

- ESD protection of ±8kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning protection, IEC61000-4-5, 2A ($t_p$=8/20μs)
- Low capacitance of 0.5pF @ $V_R$=0V
- Low leakage current of 1μA at 5V
- 0402 small footprint available

## Functional Block Diagram




## Applications

- USB 3.0/USB 2.0
- MHL/MIPI/MDDI
- HDMI, Display Port, eSATA
- Set Top Boxes, Game Consoles
- Smart Phones
- External Storage
- Ultrabooks, Notebooks
- Tablets, eReaders

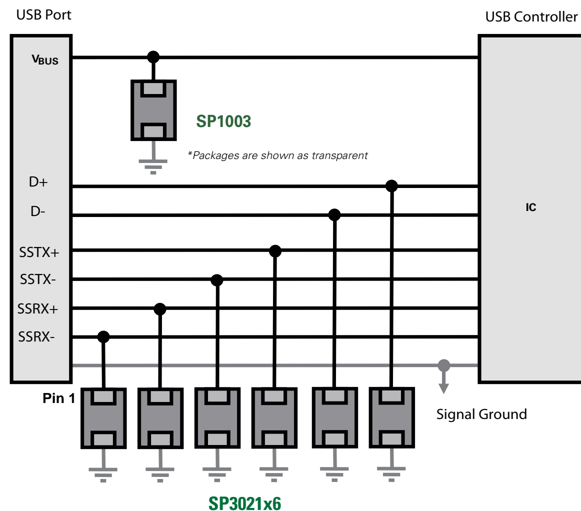
## Additional Information

Datasheet

Resources

Samples

## USB3.0 Application Example




Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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Revised: 12/20/13

## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 2.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

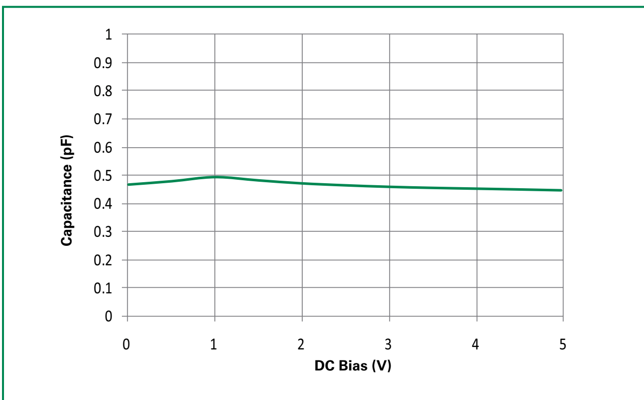
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

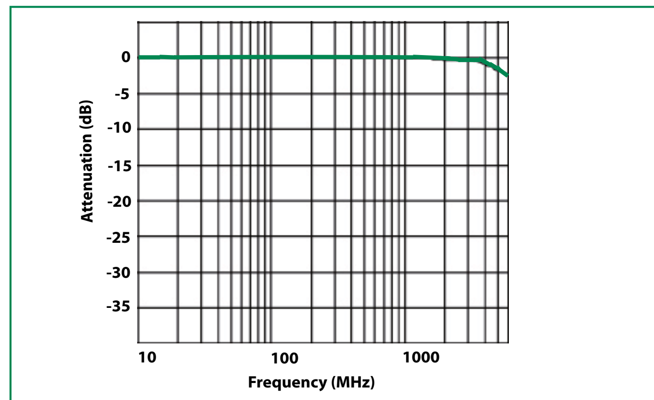
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 5.0 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $1_R$=1mA | 7.0 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | | 1 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 13.1 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 14.7 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 1.6 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±8 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_D$ | Reverse Bias=0V | | 0.5 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

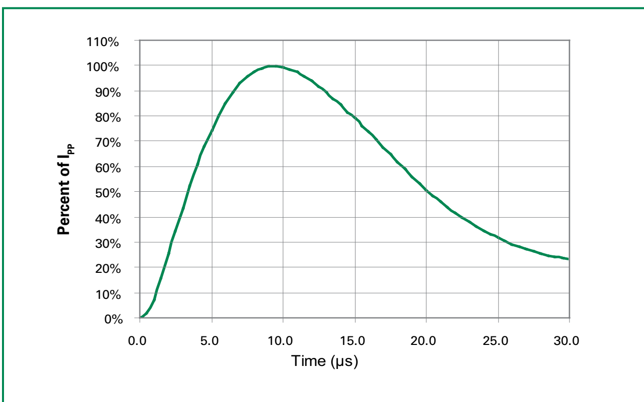
## Capacitance vs. Bias Voltage



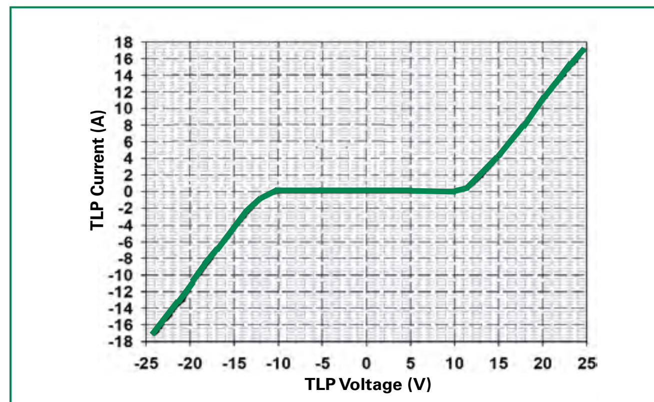

## Insertion Loss (S21) I/O to GND




## Pulse Waveform




## Transmission Line Pulsing(TLP) Plot

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## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame or Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

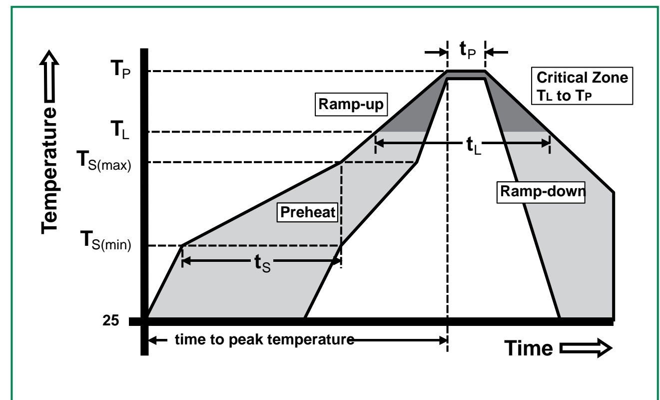
Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

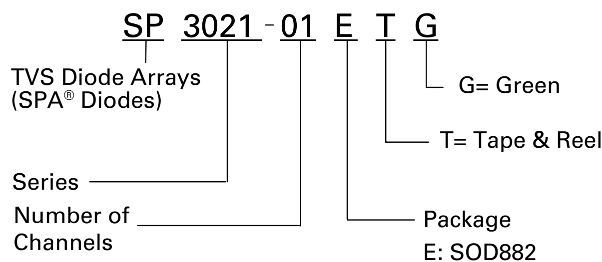
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3021-01ETG | SOD882 | ● ▬ | 12000 |

## Soldering Parameters

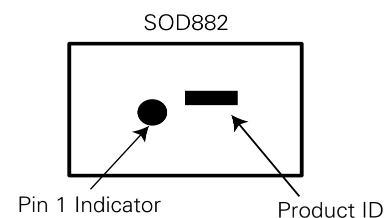
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Part Marking System

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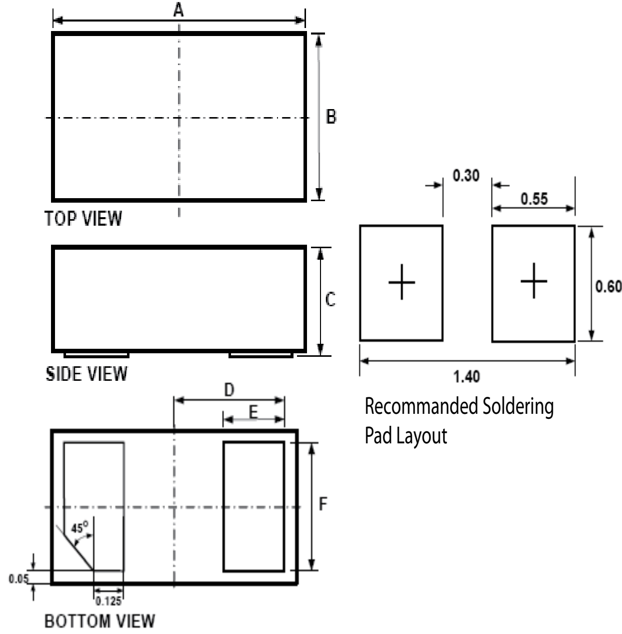
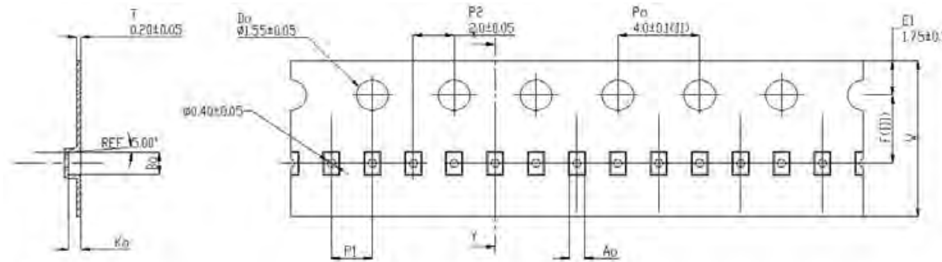
Revised: 12/20/13

## Package Dimensions — SOD882

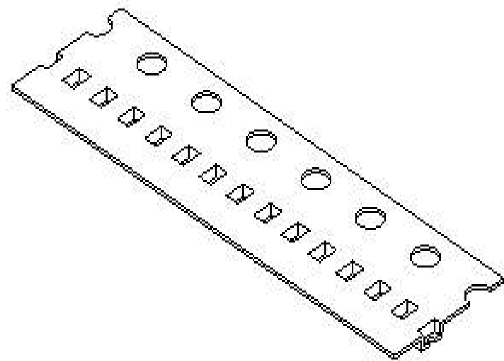



| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **B** | 0.50 | 0.60 | 0.70 | 0.020 | 0.024 | 0.028 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | | 0.45 | | | 0.018 | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

## Embossed Carrier Tape & Reel Specification — SOD882



| Symbol | Millimeters |
|---|---|
| **A0** | 0.70±0.045 |
| **B0** | 1.10±0.045 |
| **K0** | 0.65±0.045 |
| **F** | 3.50±0.05 |
| **P1** | 2.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |



Notes :
1. All dimensions are in millimeters

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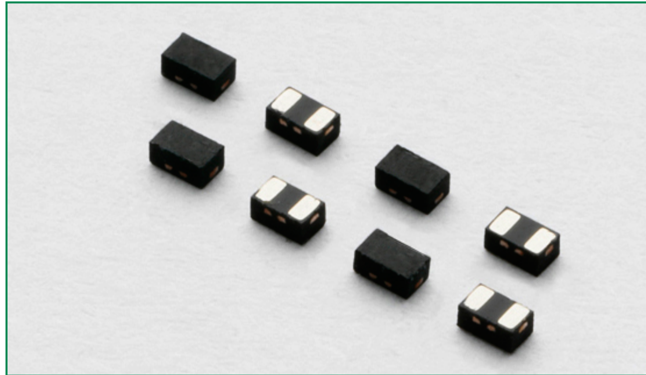
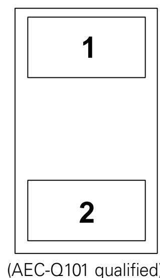
# SP3030 Series 0.5pF 20kV Unidirectional Discrete TVS

RoHS Pb GREEN

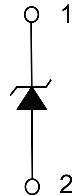


## Pinout




(AEC-Q101 qualified)

## Functional Block Diagram

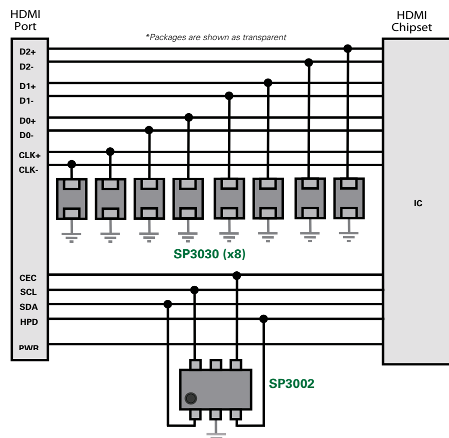



Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## HDMI Application Example




## Description

The SP3030 includes low capacitance rail to rail diodes with an additional Zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (±20kV contact discharge) without performance degradation. The low loading capacitance makes it ideal for protecting high speed data lines such as HDMI, DVI, USB2.0, USB3.0 and eSATA.

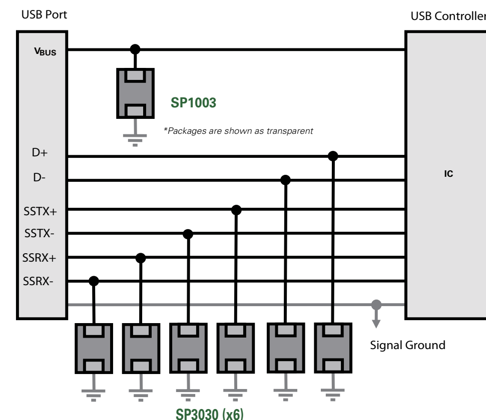
## Features

- ESD protection of ±20kV contact discharge, ±30kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A ($t_p$=5/50ns)
- Lightning Protection, IEC61000-4-5, 3A ($t_p$=8/20μs)
- Low capacitance of 0.5pF @ $V_R$=0V
- Low leakage current of 0.1μA at 5V
- Small SOD882 packaging helps save board space
- AEC-Q101 qualified (SOD882 package)

## Applications

- Tablets
- Ultrabook
- eReader
- Smart Phones
- Digital Cameras
- MP3/ PMP
- Set Top Boxes
- Portable Medical

## USB3.0 Application Example




## Additional Information

**Datasheet**

**Resources**

**Samples**

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 3.0 | A |
| $T_{OP}$ | Operating Temperature | -40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | -55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

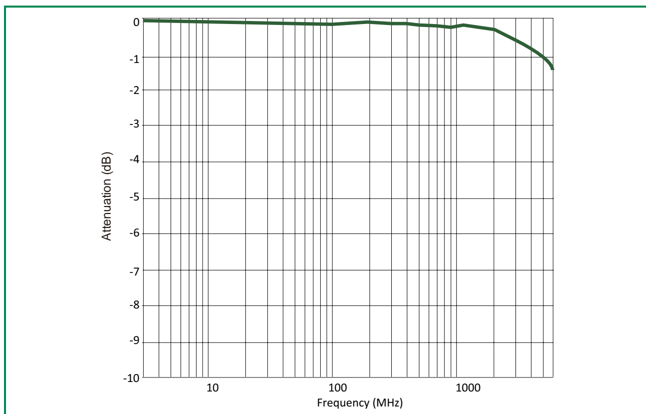
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | -55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

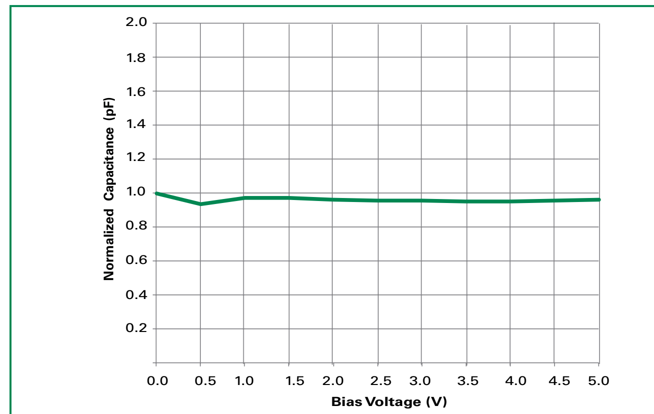
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 5 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V with 1pin at GND | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 9.2 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 10.0 | | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±20 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 0.8 | | Ω |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V, f=1 MHz | | 0.5 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

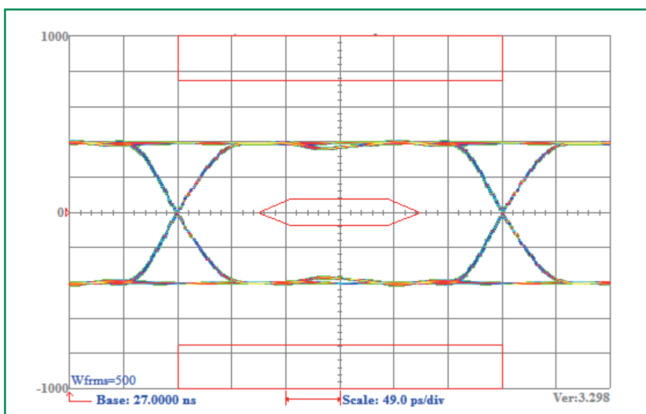
## Insertion Loss (S21) I/O to GND



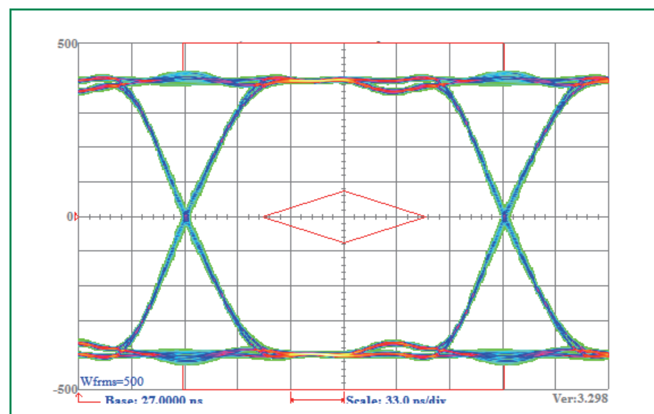

## Normalized Capacitance vs. Reverse Voltage




## HDMI 1.4 Eye Diagram




## USB3.0 Eye Diagram

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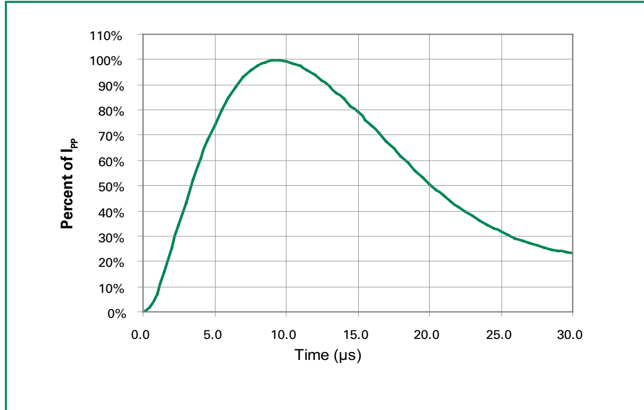
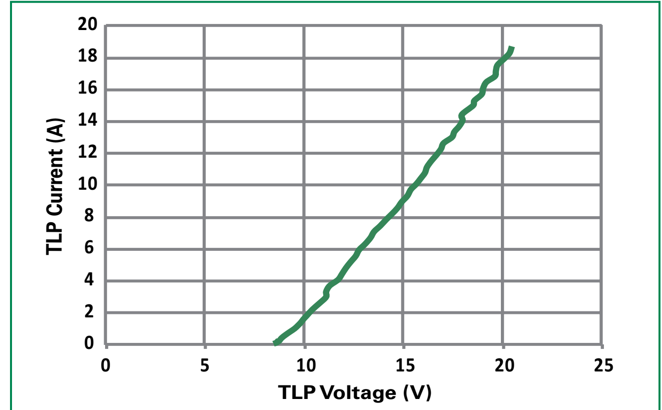
## Pulse Waveform

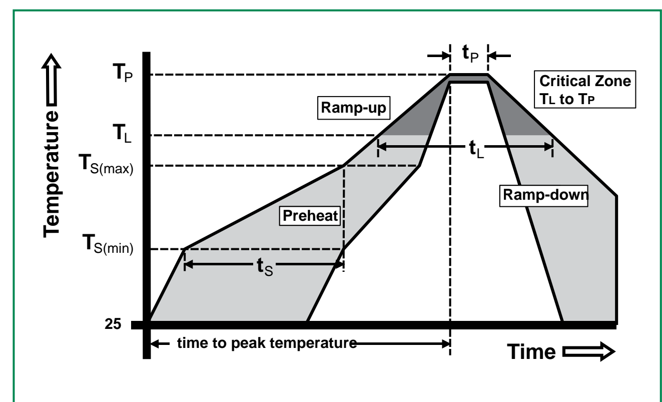



## Transmission Line Pulsing(TLP) Plot

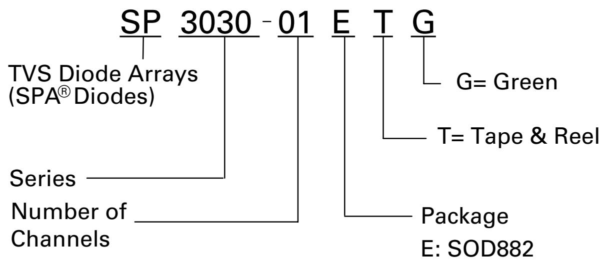



## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Product Characteristics

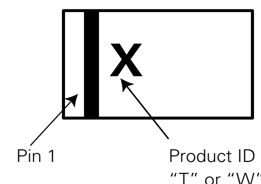
| Lead Plating | Pre-Plated Frame |
|---|---|
| Lead Material | Copper Alloy |
| Lead Coplanarity | 0.0004 inches (0.102mm) |
| Substitute Material | Silicon |
| Body Material | Molded Epoxy |
| Flammability | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3030-01ETG | SOD882 | "T" or "W" | 10,000 |

## Part Marking System

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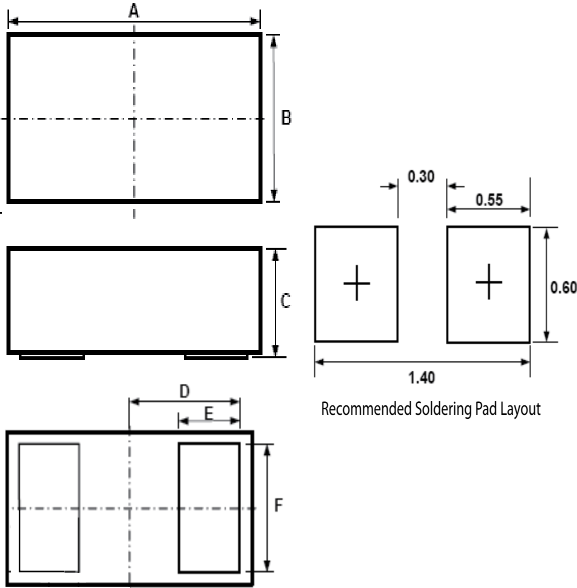
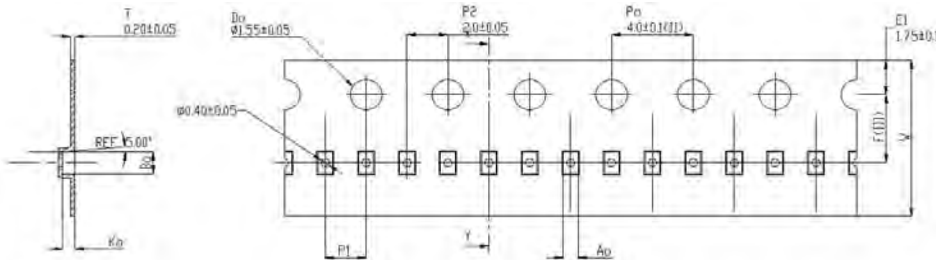
## Package Dimensions — SOD882

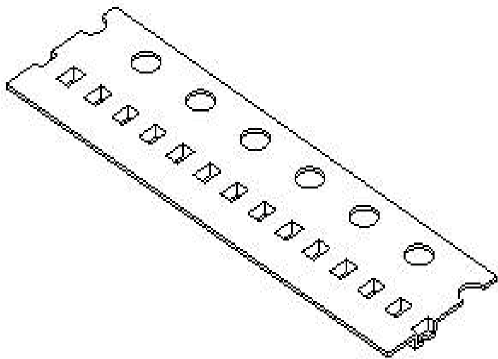



| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.037 | 0.039 | 0.041 |
| **B** | 0.50 | 0.60 | 0.70 | 0.022 | 0.024 | 0.026 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | 0.45 | | | 0.018 | | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

## Embossed Carrier Tape & Reel Specification — SOD882



| Symbol | Millimeters |
|---|---|
| **A0** | 0.70±0.045 |
| **B0** | 1.10±0.045 |
| **K0** | 0.65±0.045 |
| **F** | 3.50±0.05 |
| **P1** | 2.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |



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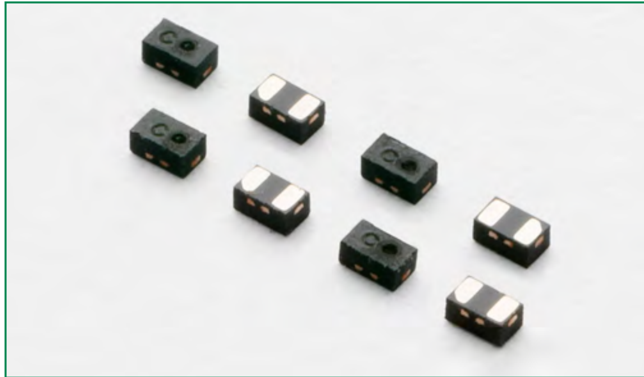
# SP3031 Series 0.8pF 10kV Unidirectional Discrete TVS

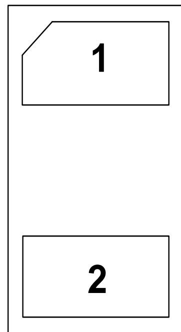
HF RoHS Pb GREEN



## Description

The SP3031 includes low capacitance rail to rail diodes with an additional Zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard without performance degradation. The low loading capacitance makes it ideal for protecting high speed data lines.

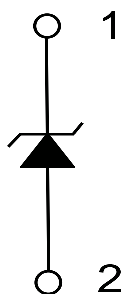
## Pinout




## Features

- ESD protection of ±10kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning protection, IEC61000-4-5, 5A ($t_p$=8/20μs)
- Low capacitance of 0.8pF @ $V_R$=0V
- Low leakage current of 1μA at 5V
- 0402 small footprint available

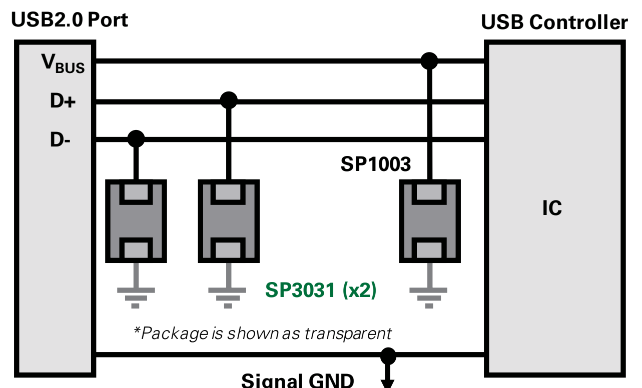
## Functional Block Diagram




## Applications

- USB 2.0, Ethernet
- MHL/MIPI/MDDI
- HDMI, Display Port, eSATA
- Set Top Boxes, Game Consoles
- Smart Phones
- External Storage
- Ultrabooks, Notebooks
- Tablets, eReaders

## USB2.0 Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 5.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

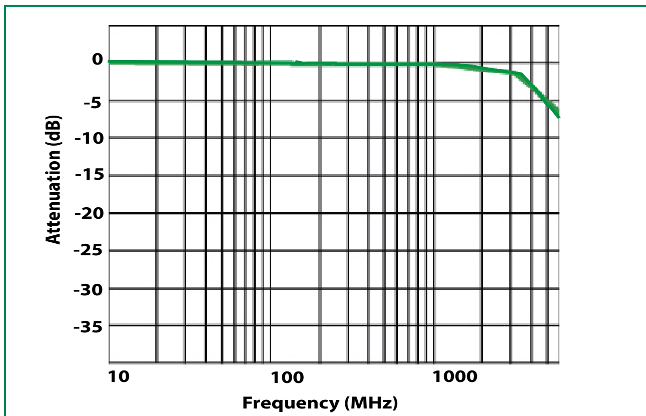
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

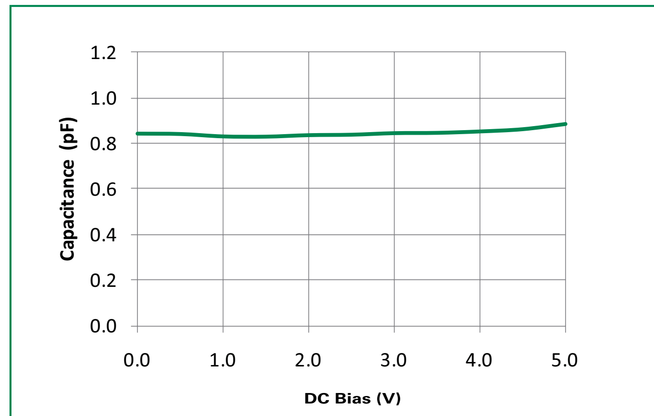
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 5.0 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $1_R$=1mA | 6.0 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V with 1pin at GND | | | 1 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 6.9 | | V |
| | | $I_{PP}$=2A, $t_p$=8/20μs, Fwd | | 7.5 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 0.6 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±10 | | | kV |
| | | IEC61000-4-2 (Air) | ±15 | | | kV |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 0.8 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

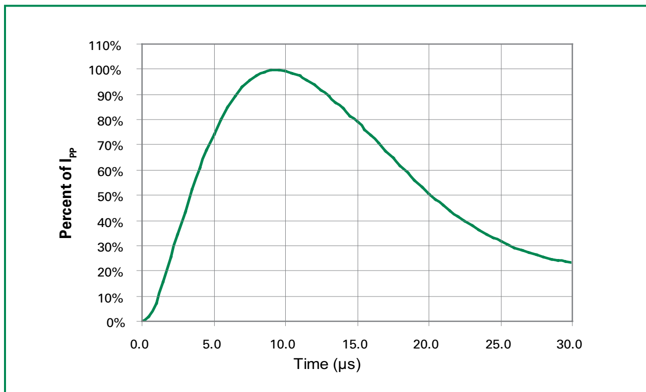
## Insertion Loss (S21) I/O to GND



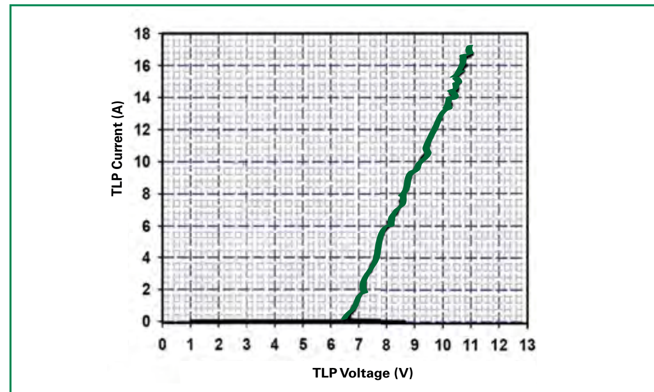

## Capacitance vs. Reverse Voltage




## Pulse Waveform




## Transmission Line Pulsing(TLP) Plot

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## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame or Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

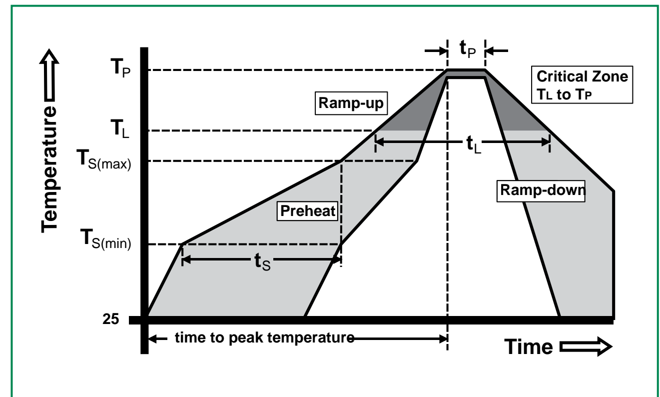
Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

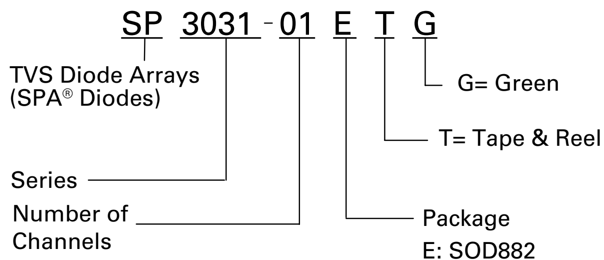
| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3031-01ETG | SOD882 | •f | 12000 |

## Soldering Parameters

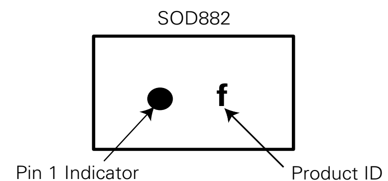
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Part Marking System

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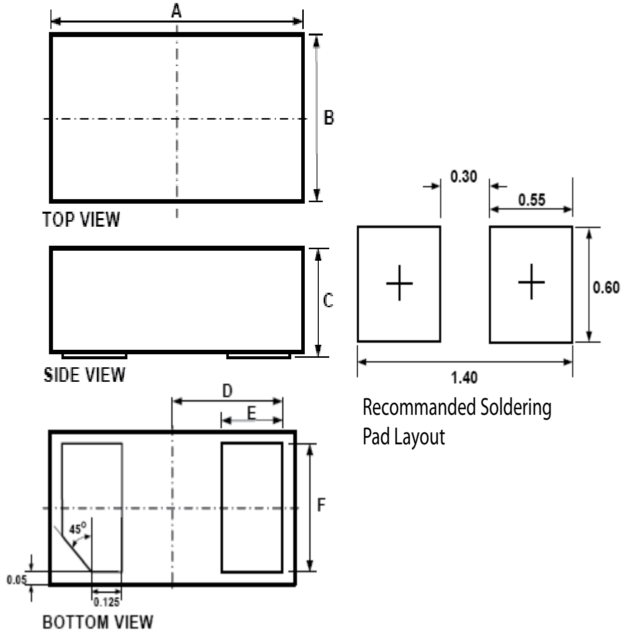
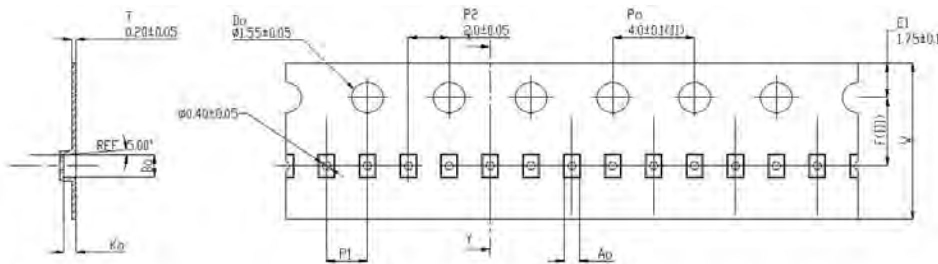
## Package Dimensions — SOD882

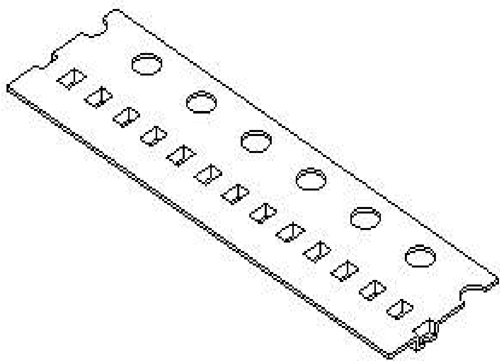



| Symbol | Package | SOD882 | | | | |
|---|---|---|---|---|---|---|
| | JEDEC | MO-236 | | | | |
| | Millimeters | | | Inches | | |
| | Min | Typ | Max | Min | Typ | Max |
| **A** | 0.90 | 1.00 | 1.10 | 0.035 | 0.039 | 0.043 |
| **B** | 0.50 | 0.60 | 0.70 | 0.020 | 0.024 | 0.028 |
| **C** | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 |
| **D** | | 0.45 | | | 0.018 | |
| **E** | 0.20 | 0.25 | 0.35 | 0.008 | 0.010 | 0.012 |
| **F** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |

## Embossed Carrier Tape & Reel Specification — SOD882



| Symbol | Millimeters |
|---|---|
| **A0** | 0.70±0.045 |
| **B0** | 1.10±0.045 |
| **K0** | 0.65±0.045 |
| **F** | 3.50±0.05 |
| **P1** | 2.00±0.10 |
| **W** | 8.00 + 0.30 -0.10 |



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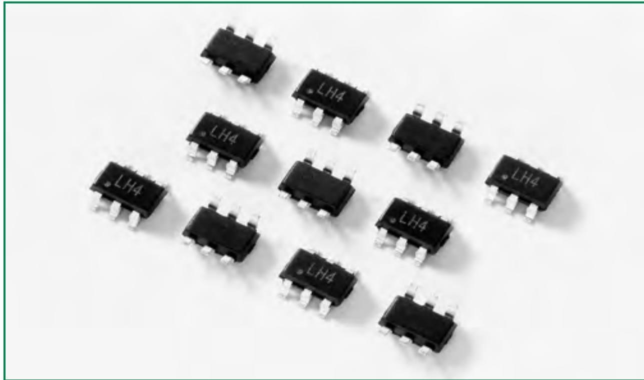
# SRV05 Series 6V 10A Diode Array




## Description

The SRV05 integrates low capacitance rail-to-rail diodes with an additional zener diode to protect each I/O pin against ESD and high surge events. This robust device can safely absorb surge current per IEC61000-4-5 ($t_P$=8/20μs) without performance degradation and a minimum ±20kV ESD per IEC61000-4-2. Their very low loading capacitance also makes them ideal for protecting high speed signal pins.

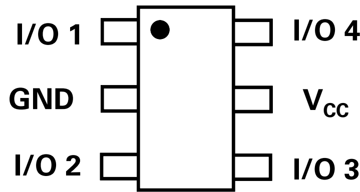
## Features

- ESD, IEC61000-4-2, ±20kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 10A (8/20μs)
- Low capacitance of 2pF (TYP) per I/O
- Low leakage current of 0.5μA (MAX) at 5V
- Small SOT23-6 (JEDEC MO-178) packaging

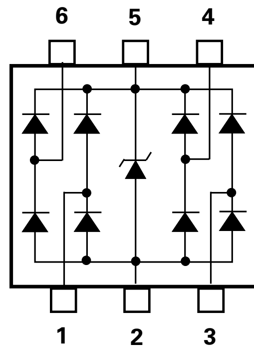
## Applications

- LCD/PDP TVs
- Monitors
- Notebooks
- 10/100/1000 Ethernet
- Firewire
- Set Top Boxes
- Flat Panel Displays
- Portable Medical

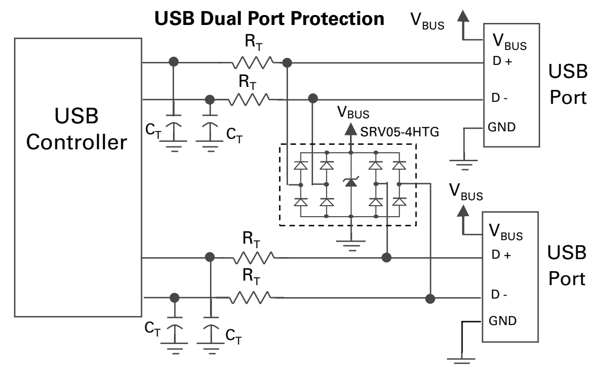
## Pinout

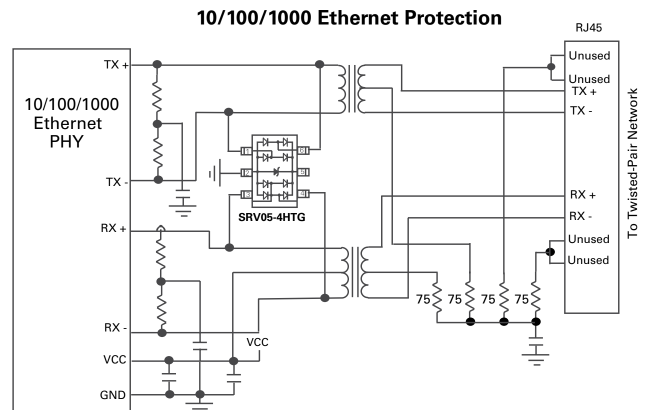



## Functional Block Diagram




## Application Examples




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs)[1] | 10 | A |
| $P_{PK}$ | Peak Pulse Power ($t_p$=8/20μs) | 150 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

[1]Non-repetitive pulse per waveform on page 3

## Thermal Information

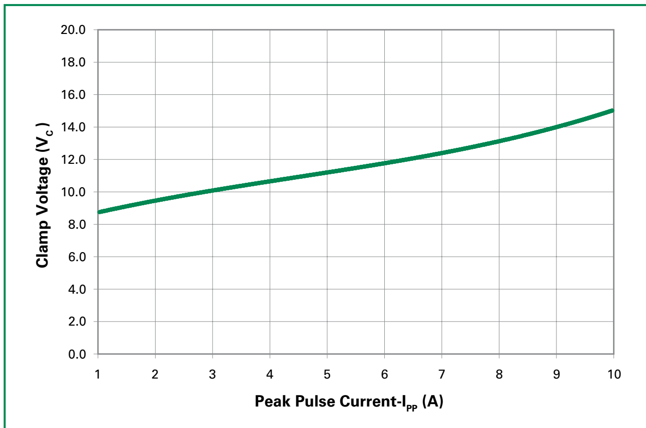
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R \leq 1μA$ | | | 6.0 | V |
| Reverse Voltage Drop | $V_R$ | $I_R$ = 1mA | | 8.0 | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=5V | | 0.1 | 0.5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, I/O to GND[2] | | 8.8 | 10.0 | V |
| | | $I_{PP}$=5A, $t_p$=8/20μs, I/O to GND[2] | | 11.5 | 13.0 | V |
| | | $I_{PP}$=8A, $t_p$=8/20μs, I/O to GND[2] | | 13.2 | 15.0 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ | | 0.7 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±20 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 2.4 | 3.0 | pF |
| | | Reverse Bias=1.65V | | 2.0 | | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 1.2 | | pF |

Notes: [1] Parameter is guaranteed by design and/or device characterization.
[2] Repetitive pulse per waveform on page 3.

## Clamping Voltage vs. $I_{PP}$




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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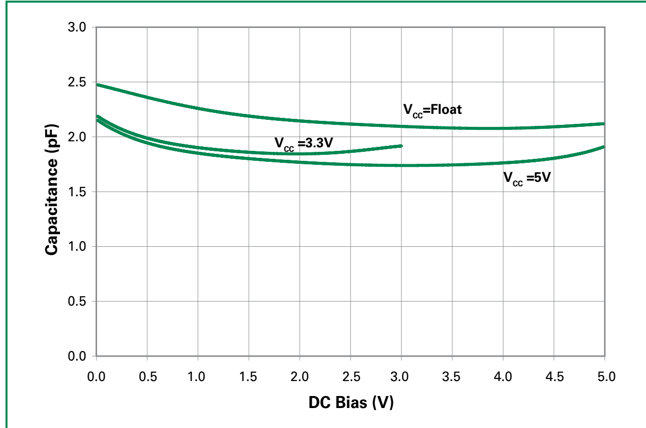
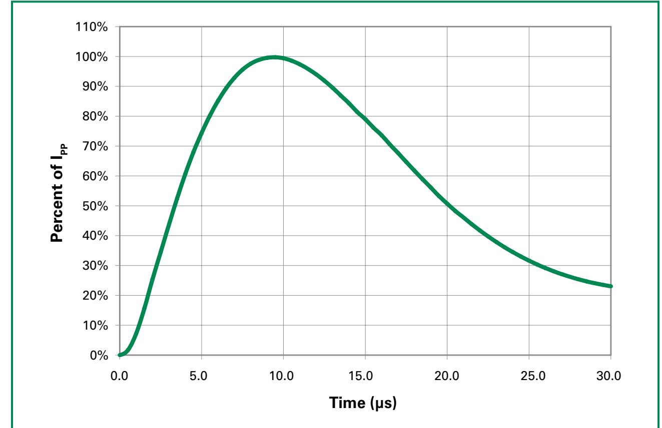
## Capacitance vs. Reverse Bias

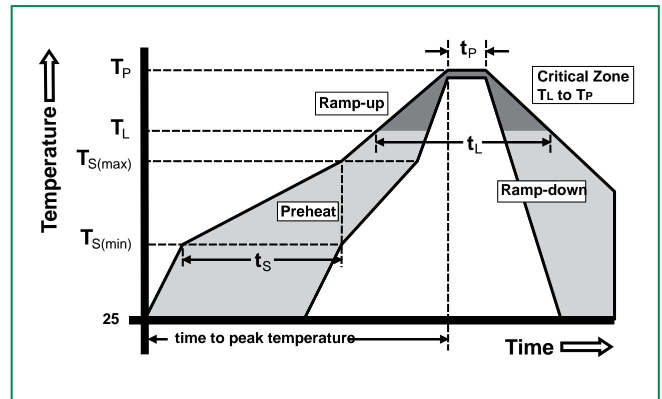



## Pulse Waveform

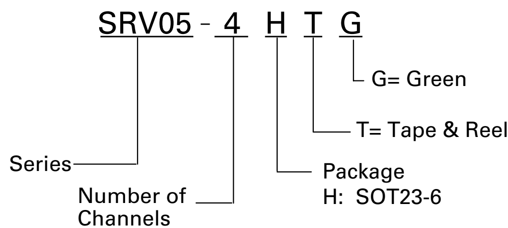



## Soldering Parameters

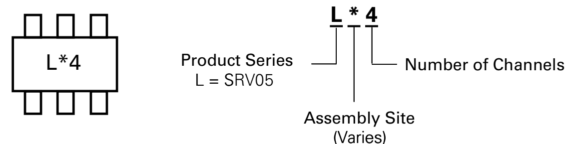
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Numbering System




## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SRV05-4HTG | SOT23-6 | L*4 | 3000 |

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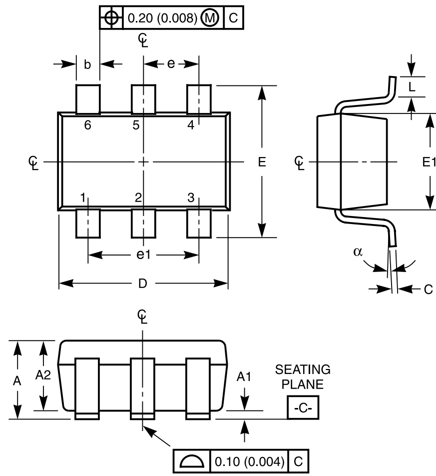
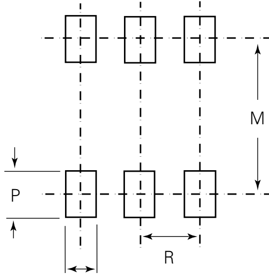
## Package Dimensions — SOT23-6




**Recommended Solder Pad Layout**

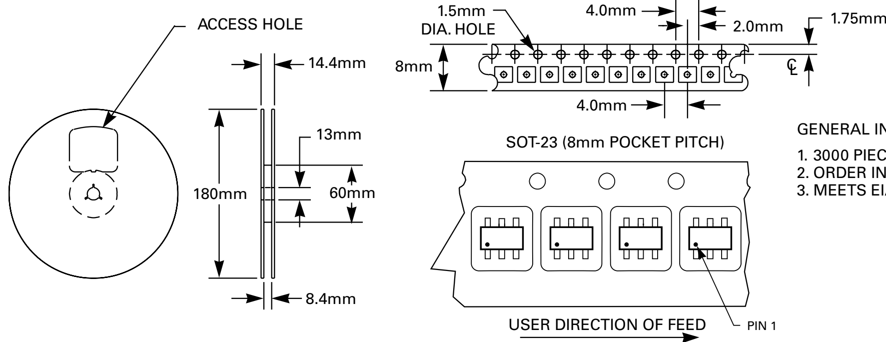



| Package | SOT23-6 | | | | |
|---|---|---|---|---|---|
| Pins | 6 | | | | |
| JEDEC | MO-178 | | | | |
| | Millimeters | | Inches | | Notes |
| | Min | Max | Min | Max | |
| **A** | 0.900 | 1.450 | 0.035 | 0.057 | - |
| **A1** | 0.000 | 0.150 | 0.000 | 0.006 | - |
| **A2** | 0.900 | 1.300 | 0.035 | 0.051 | - |
| **b** | 0.350 | 0.500 | 0.0138 | 0.0196 | - |
| **C** | 0.080 | 0.220 | 0.0031 | 0.009 | - |
| **D** | 2.800 | 3.000 | 0.11 | 0.118 | 3 |
| **E** | 2.600 | 3.000 | 0.102 | 0.118 | - |
| **E1** | 1.500 | 1.750 | 0.06 | 0.069 | 3 |
| **e** | 0.95 Ref | | 0.0374 ref | | - |
| **e1** | 1.9 Ref | | 0.0748 Ref | | - |
| **L** | 0.100 | 0.600 | 0.004 | 0.023 | 4,5 |
| **N** | 6 | | 6 | | 6 |
| **a** | 0° | 10° | 0° | 10° | - |
| **M** | | 2.590 | | 0.102 | - |
| **O** | | 0.690 | | .027 TYP | - |
| **P** | | 0.990 | | .039 TYP | - |
| **R** | | 0.950 | | 0.038 | - |

Notes:
1. Dimensioning and tolerances per ANSI 14.5M-1982.
2. Package conforms to EIAJ SC-74 (1992).
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Footlenth L measured at reference to seating plane.
5. “L” is the length of flat foot surface for soldering to substrate.
6. “N” is the number of terminal positions.
7. Controling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

## Embossed Carrier Tape & Reel Specification — SOT23-6

8mm TAPE AND REEL

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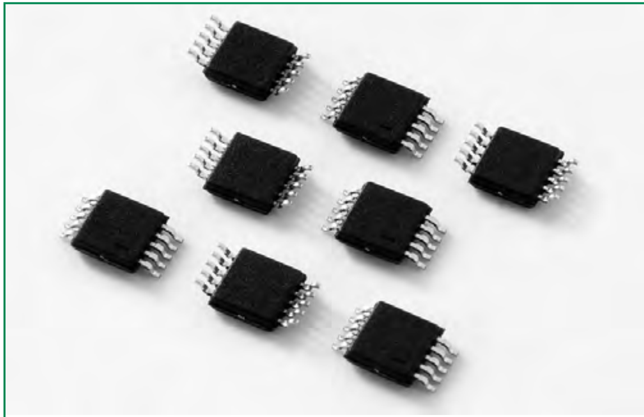
# SP4060 Series 2.5V 20A Diode Array

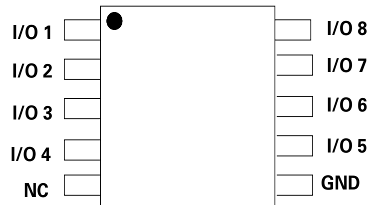
HF RoHS Pb GREEN



## Description

The SP4060 integrates low capacitance diodes with an additional zener diode to protect each I/O pin against ESD and high surge events. This robust device can safely absorb up to 20A per IEC61000-4-5 ($t_p$=8/20μs) without performance degradation and a minimum ±30kV ESD per IEC61000-4-2 International Standard. Their low loading capacitance also makes them ideal for protecting high speed signal pins.

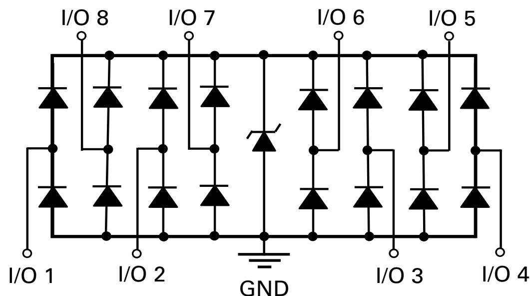
## Pinout




## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 20A (8/20μs)
- Low capacitance of 4.4pF (TYP) per I/O
- Low leakage current of 1μA (MAX) at 2.5V

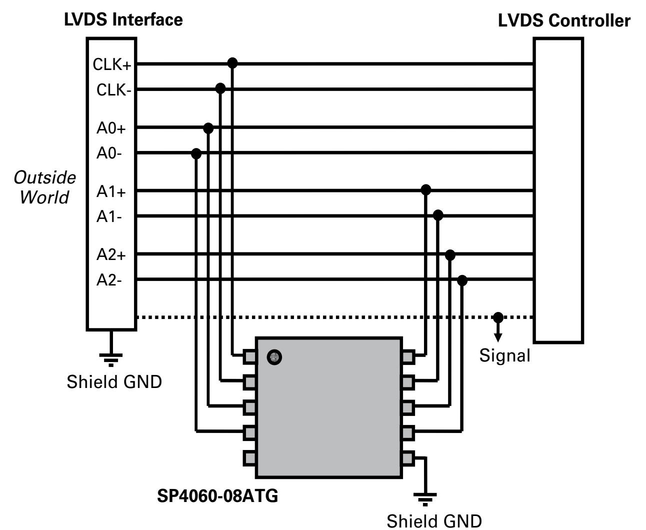
## Functional Block Diagram




## Applications

- LCD/PD TVs
- Desktops
- Game Consoles
- Set Top Boxes
- Notebooks

## Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 20.0 | A |
| $P_{PK}$ | Peak Pulse Power ($t_p$=8/20μs) | 300 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

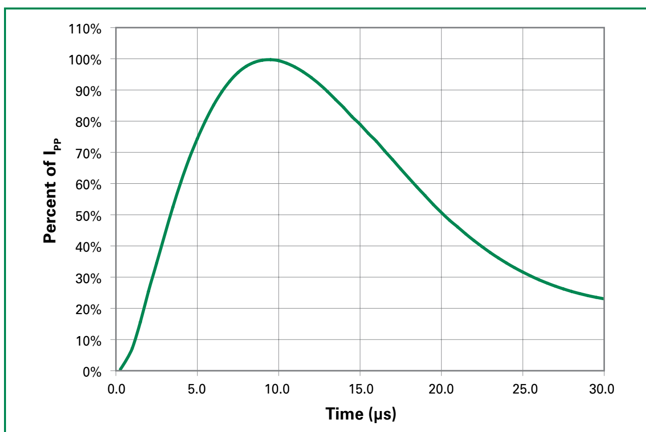
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

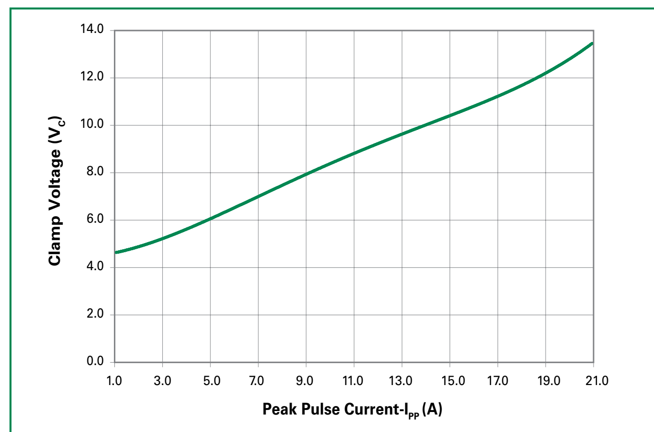
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 2.5 | V |
| Snap Back Voltage | $V_{SB}$ | $I_{SB}$=50mA | 2.0 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=2.5V, I/O to GND | | 0.5 | 1.0 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 4.5 | 5.5 | V |
| | | $I_{PP}$=5A, $t_p$=8/20μs, Fwd | | 6.0 | 7.2 | V |
| | | $I_{PP}$=10A, $t_p$=8/20μs, Fwd | | 8.0 | 9.6 | V |
| | | $I_{PP}$=20A, $t_p$=8/20μs, Fwd | | 12.5 | 15.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 4.4 | 5.0 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 2.2 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

## Pulse Waveform




## Clamping Voltage vs. $I_{PP}$

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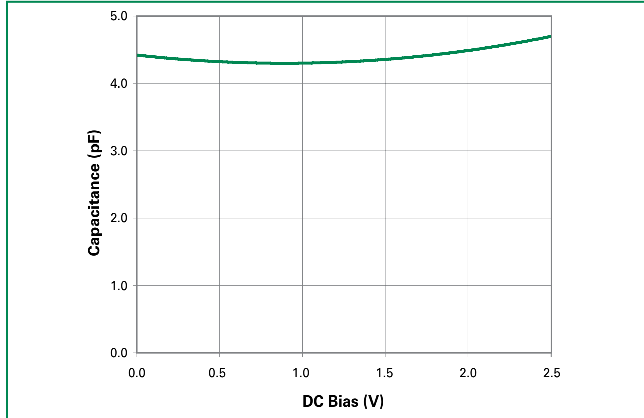
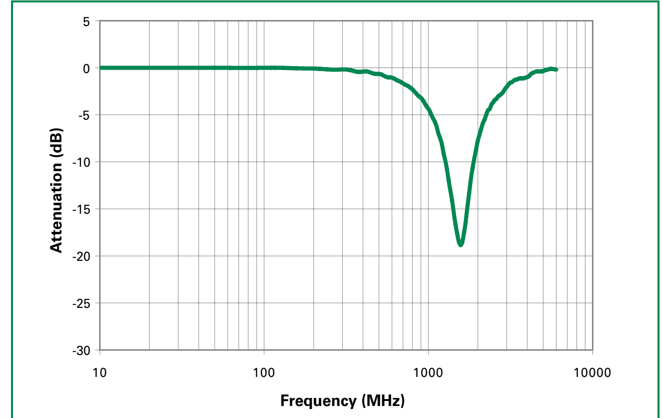
## Capacitance vs. Bias

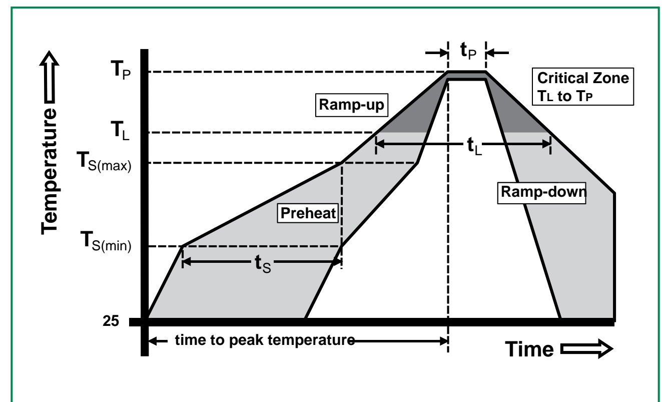



## Insertion Loss (S21) I/O to GND

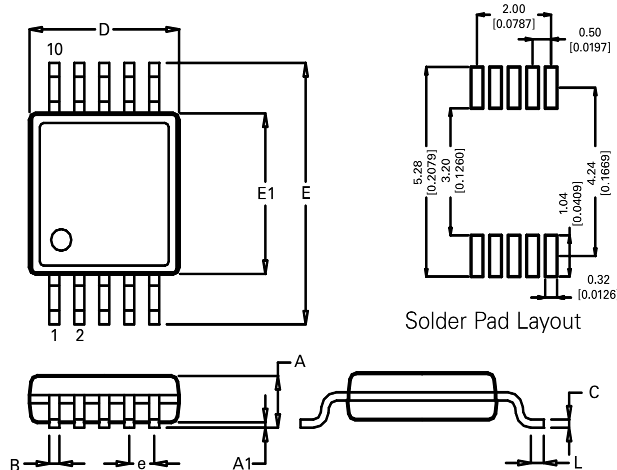



## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — MSOP10




| Package | MSOP | | | |
|---|---|---|---|---|
| Pins | 10 | | | |
| JEDEC | MO-187 | | | |
| | Millimeters | | Inches | |
| DIM | Min | Max | Min | Max |
| A | - | 1.10 | - | 0.043 |
| A1 | 0.00 | 0.15 | 0.000 | 0.006 |
| B | 0.17 | 0.27 | 0.007 | 0.011 |
| c | 0.08 | 0.23 | 0.003 | 0.009 |
| D | 2.90 | 3.10 | 0.114 | 0.122 |
| E | 4.67 | 5.10 | 0.184 | 0.200 |
| E1 | 2.90 | 3.10 | 0.114 | 0.122 |
| e | 0.50 BSC | | 0.020 BSC | |
| L | 0.40 | 0.80 | 0.016 | 0.032 |

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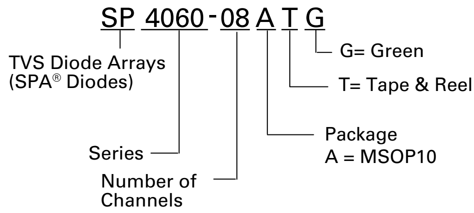
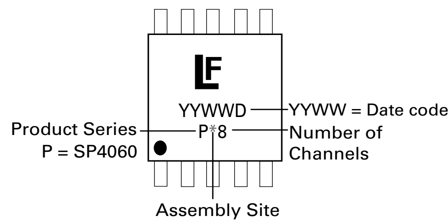
## Part Numbering System




## Part Marking System




## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Pre-Plated Frame |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

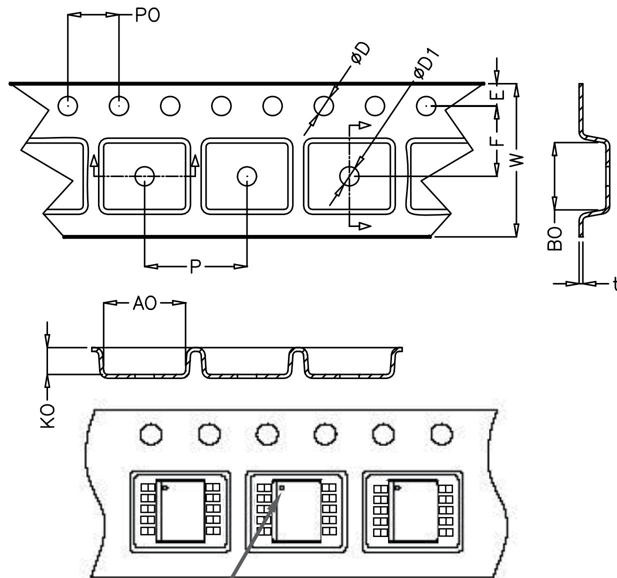
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP4060-08ATG | MSOP10 | P*8 | 4000 |

## Embossed Carrier Tape & Reel Specification — MSOP-10




User Feeding Direction

| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.40 | 5.60 | 0.213 | 0.220 |
| **D** | 1.50 | 1.60 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.90 | 4.10 | 0.154 | 0.161 |
| **10P0** | 40.0± 0.20 | | 1.574±0.008 | |
| **W** | 11.90 | 12.10 | 0.469 | 0.476 |
| **P** | 7.90 | 8.10 | 0.311 | 0.319 |
| **A0** | 5.20 | 5.40 | 0.205 | 0.213 |
| **B0** | 3.20 | 3.40 | 0.126 | 0.134 |
| **K0** | 1.20 | 1.40 | 0.047 | 0.055 |
| **t** | 0.30 ± 0.05 | | 0.012± 0.002 | |

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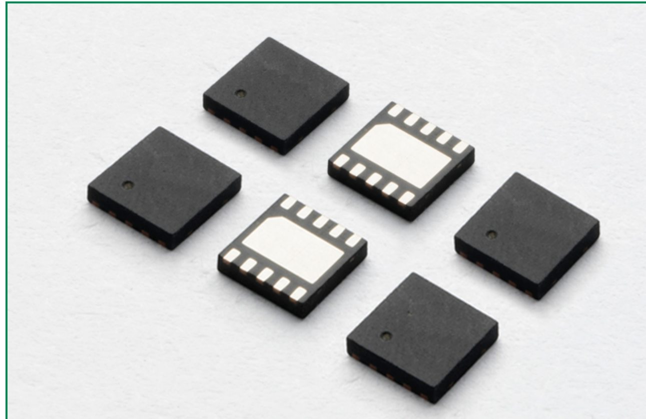
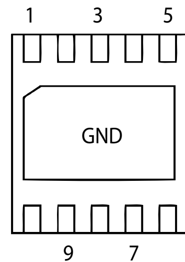
# SP2504N Series 2.5V 20A Diode Array



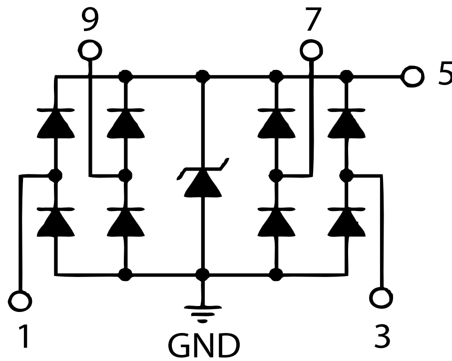
## Description

The SP2504N integrates 4 channels of low capacitance diodes with an additional zener diode to protect sensitive I/O pins against lightning induced surge events and ESD. This robust device can safely absorb up to 20A per IEC61000-4-5 ($t_P$=8/20μs) without performance degradation and a minimum ±30kV ESD per IEC61000-4-2 international standard. The low loading capacitance makes the SP2504N ideal for protecting high-speed signal pins.

## Pinout




## Functional Block Diagram



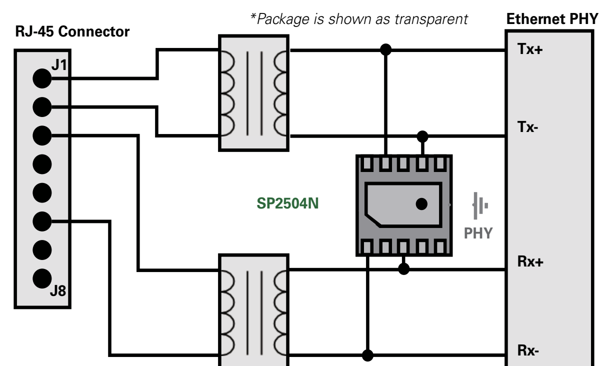

## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A ($t_P$=5/50ns)
- Lightning, IEC61000-4-5, 20A ($t_P$=8/20μs)
- Low capacitance of 3.5pF (TYP) per I/O
- Low leakage current of 1μA (MAX) at 2.5V

## Applications

- 10/100/1000 Ethernet Interfaces
- Customer Premise Equipment (CPE)
- VoIP Phones
- Set Top Boxes
- PBX Systems

## Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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Revised: 12/20/13

## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 20.0 | A |
| $P_{PK}$ | Peak Pulse Power ($t_p$=8/20μs) | 300 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

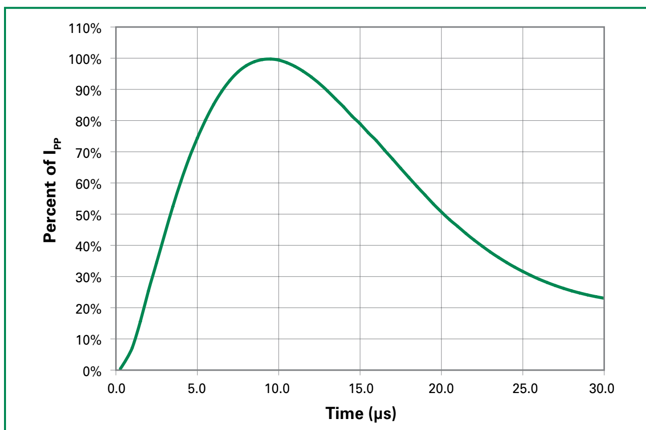
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

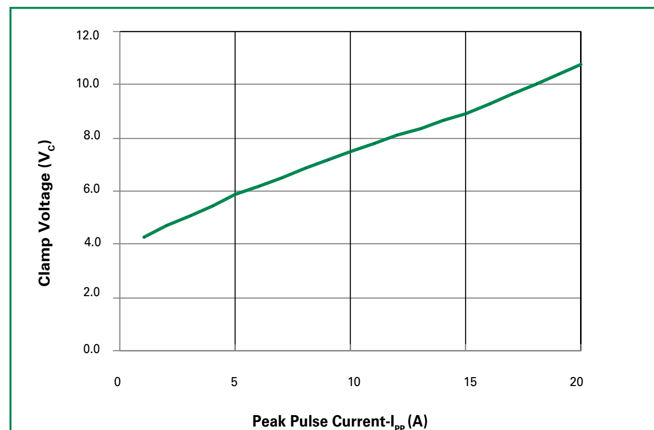
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 2.5 | V |
| Snap Back Voltage | $V_{SB}$ | $I_{SB}$=50mA | 2.0 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=2.5V, I/O to GND | | 0.5 | 1.0 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | | 5.0 | V |
| | | $I_{PP}$=5A, $t_p$=8/20μs, Fwd | | | 6.3 | V |
| | | $I_{PP}$=10A, $t_p$=8/20μs, Fwd | | | 8.0 | V |
| | | $I_{PP}$=20A, $t_p$=8/20μs, Fwd | | | 11.5 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 0.35 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 3.5 | 5.0 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 2.0 | | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Pulse Waveform




## Clamping Voltage vs. $I_{PP}$

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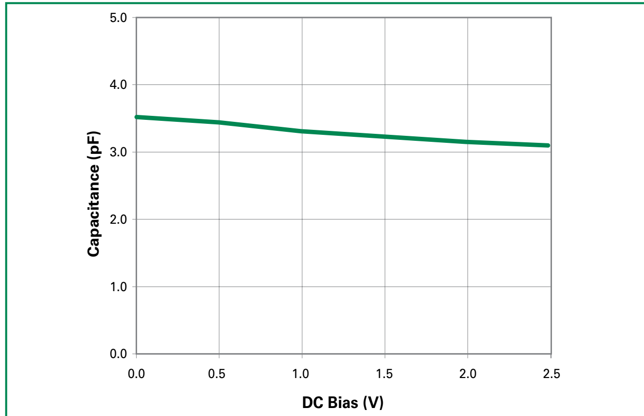
## Capacitance vs. Bias

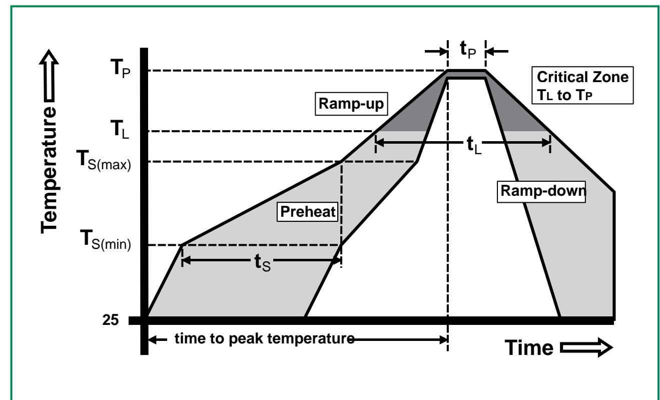



## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP2504NUTG | µDFN-10 | TH4 | 3000 |

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |



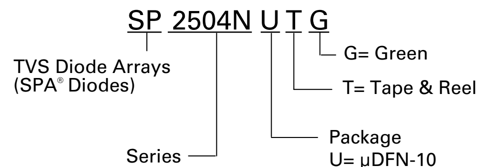

## Product Characteristics

| Lead Plating | Pre-Plated Frame |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

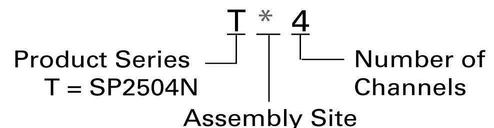
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4.. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Numbering System




## Part Marking System

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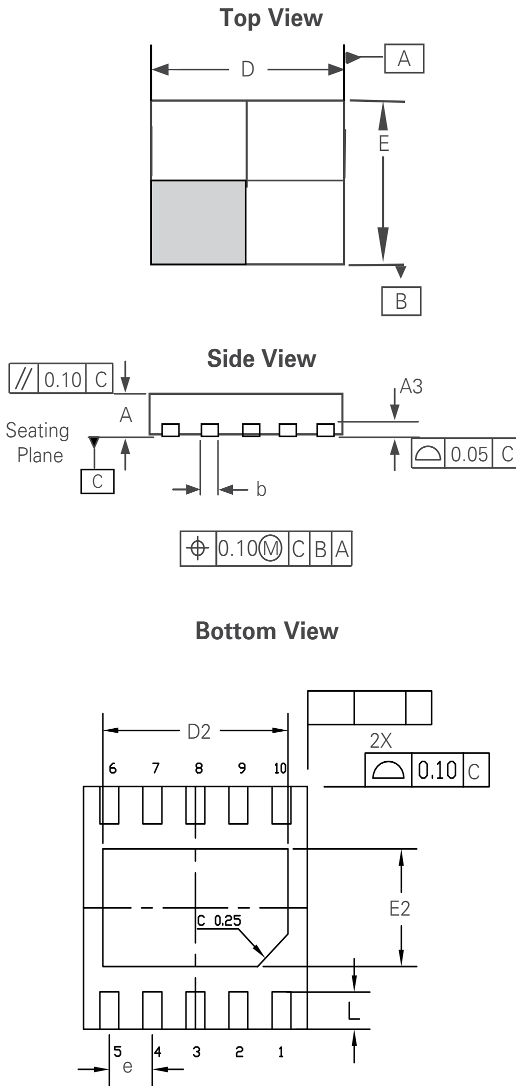
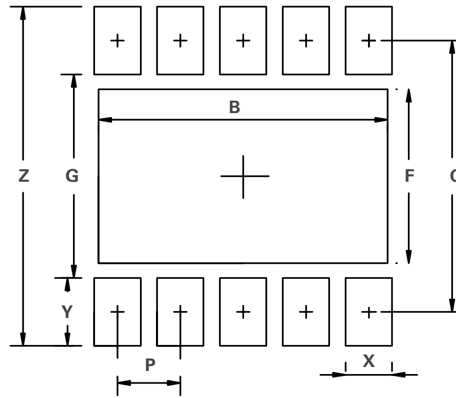
## Package Dimensions — µDFN-10



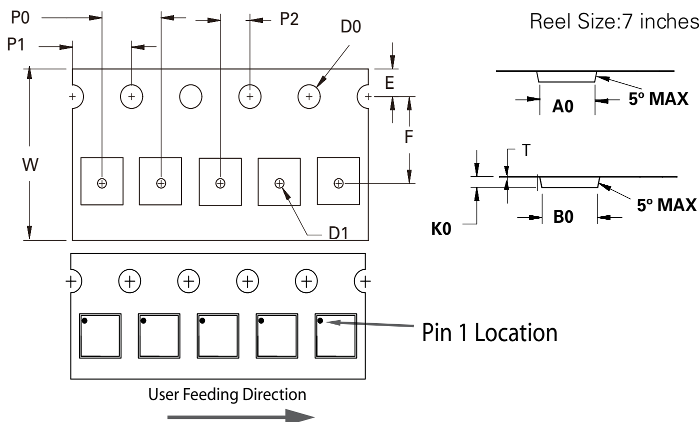

| Package | µDFN-10 (2.6x2.6mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |
| A3 | 0.130 Ref | | | 0.005 Ref | | |
| b | 0.17 | 0.22 | 0.27 | 0.006 | 0.008 | 0.010 |
| D | 2.50 | 2.60 | 2.70 | 0.097 | 0.101 | 0.105 |
| D2 | 2.10 | 2.15 | 2.20 | 0.081 | 0.083 | 0.085 |
| E | 2.50 | 2.60 | 2.70 | 0.097 | 0.101 | 0.105 |
| E2 | 1.21 | 1.26 | 1.31 | 0.046 | 0.049 | 0.051 |
| e | 0.50 BSC | | | 0.020 BSC | | |
| L | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |

**Recommended Solder Pads µDFN-10L 2.6x2.6mm**




| Dimension | | |
|---|---|---|
| Symbol | Millimeters | Inches |
| B | 2.30 | 0.091 |
| C | 2.20 | 0.087 |
| F | 1.41 | 0.056 |
| G | 1.65 | 0.065 |
| P | 0.50 | 0.020 |
| X | 0.37 | 0.015 |
| Y | 0.55 | 0.022 |
| Z | 2.75 | 0.108 |

## Embossed Carrier Tape & Reel Specification — µDFN-10 (2.6x2.6mm)




| Symbol | Millimeters |
|---|---|
| A0 | 2.82 ± 0.05 |
| B0 | 2.82 ± 0.05 |
| D0 | Ø1.50 + 0.10 |
| D1 | Ø 0.50 + 0.05 |
| E | 1.75 ± 0.10 |
| F | 3.50 ± 0.05 |
| K0 | 0.76 ± 0.05 |
| P0 | 4.00 ± 0.10 |
| P1 | 4.00 ± 0.10 |
| P2 | 2.00 ± 0.05 |
| T | 0.25 ± 0.02 |
| W | 8.00 + 0.30 /- 0.10 |

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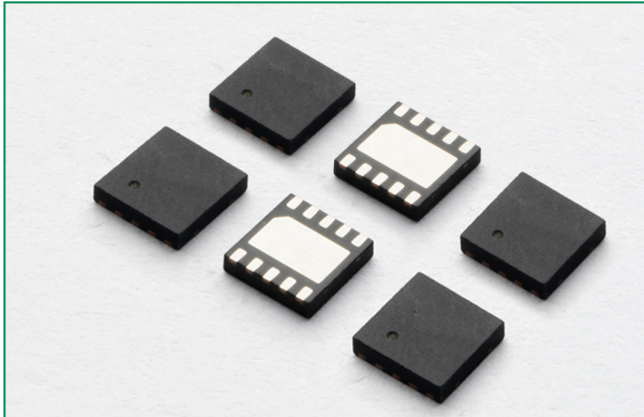
# SP3304N Series 3.3V 20A Diode Array

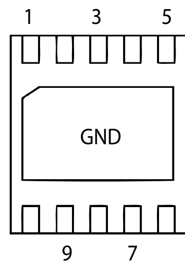
HF RoHS Pb GREEN



## Description

The SP3304N integrates 4 channels of low capacitance diodes with an additional zener diode to protect sensitive I/O pins against lightning induced surge events and ESD. This robust device can safely absorb up to 20A per IEC61000-4-5 ($t_P$=8/20μs) without performance degradation and a minimum ±30kV ESD per IEC61000-4-2 international standard. The low loading capacitance makes the SP3304N ideal for protecting high-speed signal pins.

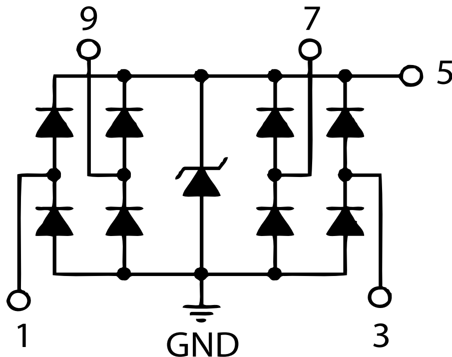
## Pinout




## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A ($t_P$=5/50ns)
- Lightning, IEC61000-4-5, 20A ($t_P$=8/20μs)
- Low capacitance of 3.5pF (TYP) per I/O
- Low leakage current of 1μA (MAX) at 3.3V

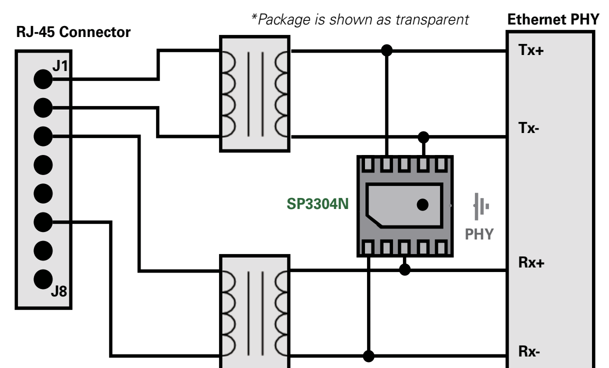
## Functional Block Diagram




## Applications

- 10/100/1000 Ethernet Interfaces
- Customer Premise Equipment (CPE)
- VoIP Phones
- Set Top Boxes
- PBX Systems

## Application Example




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 20.0 | A |
| $P_{PK}$ | Peak Pulse Power ($t_p$=8/20μs) | 300 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

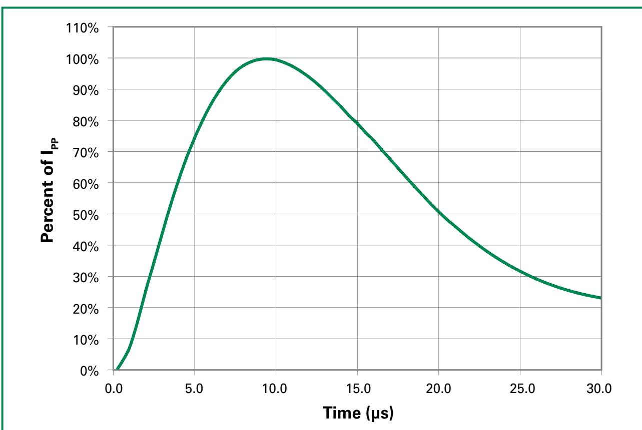
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

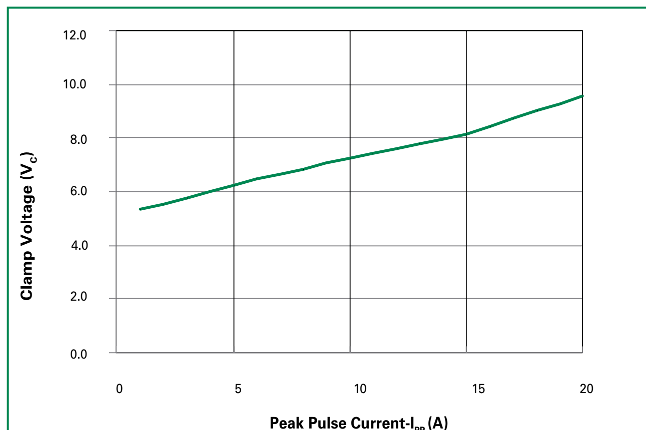
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 3.3 | V |
| Punch Through Voltage | $V_{PT}$ | $I_{PT}$=5μA | 3.5 | | | V |
| Snap Back Voltage | $V_{SB}$ | $I_{SB}$=50mA | 2.8 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=2.5V, I/O to GND | | 0.5 | 1.0 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | | 6.0 | V |
| | | $I_{PP}$=5A, $t_p$=8/20μs, Fwd | | | 7.0 | V |
| | | $I_{PP}$=10A, $t_p$=8/20μs, Fwd | | | 8.0 | V |
| | | $I_{PP}$=20A, $t_p$=8/20μs, Fwd | | | 11.5 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 0.25 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V | | 3.5 | 5.0 | pF |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | | 2.0 | | pF |

Note: [1] Parameter is guaranteed by design and/or device characterization.

## Pulse Waveform




## Clamping Voltage vs. $I_{PP}$

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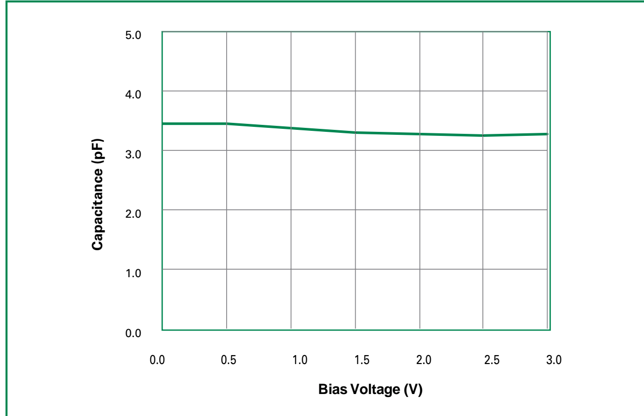
## Capacitance vs. Bias

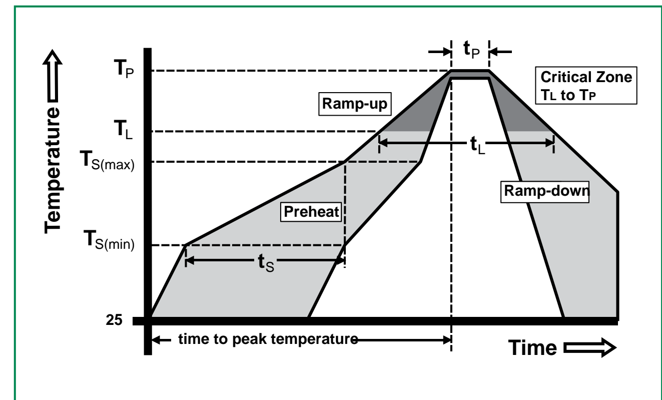



## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP3304NUTG | µDFN-10 | UH4 | 3000 |

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |



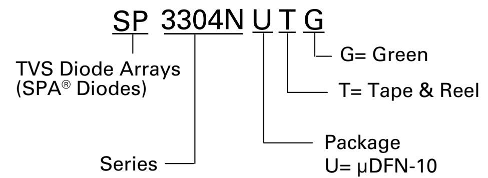

## Product Characteristics

| **Lead Plating** | Pre-Plated Frame |
|---|---|
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

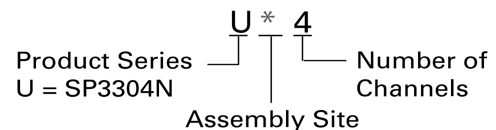
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Numbering System




## Part Marking System

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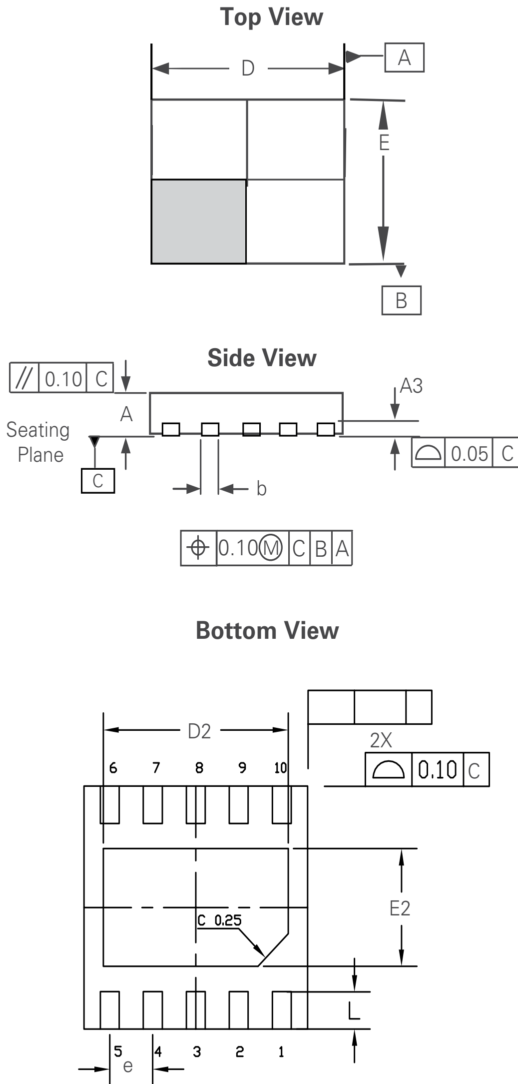
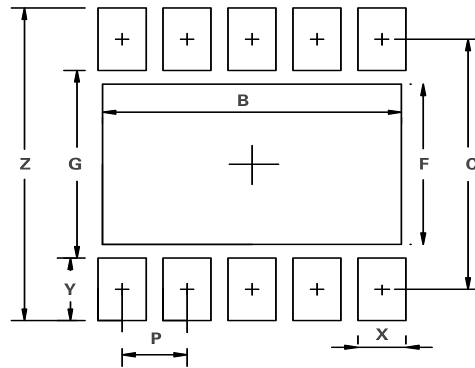
## Package Dimensions — *µDFN-10*



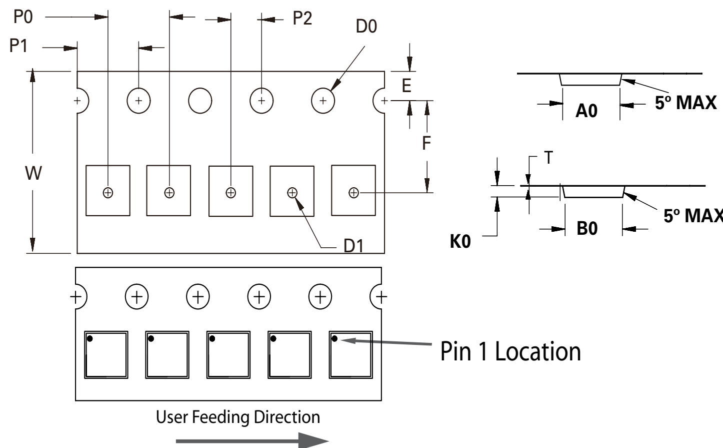

| Package | µDFN-10 (2.6x2.6mm) | | | | | |
|---|---|---|---|---|---|---|
| JEDEC | MO-229 | | | | | |
| Symbol | Millimeters | | | Inches | | |
| | Min | Nom | Max | Min | Nom | Max |
| **A** | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |
| **A3** | 0.130 Ref | | | 0.005 Ref | | |
| **b** | 0.17 | 0.22 | 0.27 | 0.006 | 0.008 | 0.010 |
| **D** | 2.50 | 2.60 | 2.70 | 0.097 | 0.101 | 0.105 |
| **D2** | 2.10 | 2.15 | 2.20 | 0.081 | 0.083 | 0.085 |
| **E** | 2.50 | 2.60 | 2.70 | 0.097 | 0.101 | 0.105 |
| **E2** | 1.21 | 1.26 | 1.31 | 0.046 | 0.049 | 0.051 |
| **e** | 0.50 BSC | | | 0.020 BSC | | |
| **L** | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |

**Recommended Solder Pads µDFN-10L 2.6x2.6mm**




| Dimension | | |
|---|---|---|
| Symbol | Millimeters | Inches |
| **B** | 2.30 | 0.091 |
| **C** | 2.20 | 0.087 |
| **F** | 1.41 | 0.056 |
| **G** | 1.65 | 0.065 |
| **P** | 0.50 | 0.020 |
| **X** | 0.37 | 0.015 |
| **Y** | 0.55 | 0.022 |
| **Z** | 2.75 | 0.108 |

## Embossed Carrier Tape & Reel Specification — µDFN-10 (2.6x2.6mm)




| Symbol | Millimeters |
|---|---|
| **A0** | 2.82 ± 0.05 |
| **B0** | 2.82 ± 0.05 |
| **D0** | Ø1.50 + 0.10 |
| **D1** | Ø 0.50 + 0.05 |
| **E** | 1.75 ± 0.10 |
| **F** | 3.50 ± 0.05 |
| **K0** | 0.76 ± 0.05 |
| **P0** | 4.00 ± 0.10 |
| **P1** | 4.00 ± 0.10 |
| **P2** | 2.00 ± 0.05 |
| **T** | 0.25 ± 0.02 |
| **W** | 8.00 + 0.30 /- 0.10 |

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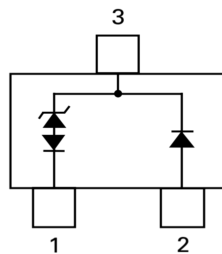
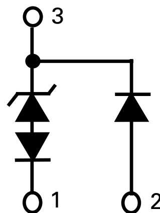
# SLVU2.8 Series 2.8V 40A TVS Array

RoHS Pb GREEN

## Pinout




## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

## Description

The SLVU2.8 series was designed to protect low voltage, CMOS devices from ESD and lightning induced transients. There is a compensating diode in parallel with the low voltage TVS to protect one unidirectional line or a high speed data pair when two devices are paired together. These robust structures can safely absorb repetitive ESD strikes at ±30kV (contact discharge) per the IEC61000-4-2 standard and each structure can safely dissipate up to 40A (IEC61000-4-5, $t_P$=8/20μs) with very low clamping voltages.

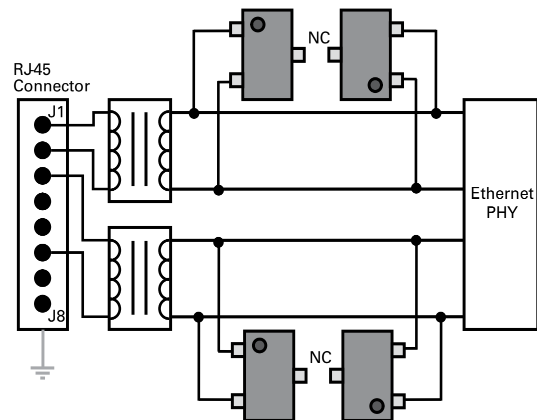
## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 40A (8/20μs)
- Low capacitance of 2pF per line (Pin 2 to 1)
- Low leakage current of 1μA (MAX) at 2.8V
- Small SOT23-3 (JEDEC TO-236) package saves board space

## Applications

- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Switching Systems
- Desktops, Servers, and Notebooks
- Analog Inputs
- Base Stations

## Application Example

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## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 2.8 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$=2μA | 3.0 | | | V |
| Snap Back Voltage | $V_{SB}$ | $I_T$=50mA | 2.8 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=2.8V (Pin 2 or 3 to 1) | | | 1 | μA |
| Clamping Voltage[1] | $V_C$ | $I_{PP}$=5A, $t_P$=8/20μs (Pin 3 to 1) | | 5.7 | 7.0 | V |
| Clamping Voltage[1] | | $I_{PP}$=24A, $t_P$=8/20μs (Pin 3 to 1) | | 8.3 | 12.5 | V |
| Clamping Voltage[1] | | $I_{PP}$=5A, $t_P$=8/20μs (Pin 2 to 1) | | 7.0 | 8.5 | V |
| Clamping Voltage[1] | | $I_{PP}$=24A, $t_P$=8/20μs (Pin 2 to 1) | | 13.9 | 15.0 | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$ (Pin 2 to 1) | | 0.4 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_D$ | $V_R$=0V, f=1MHz (Pin 2 to 1) | | 2.0 | 2.5 | pF |

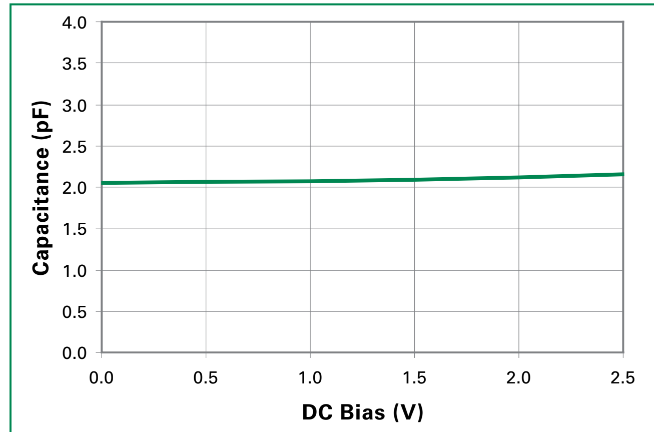
Note: [1]Parameter is guaranteed by design and/or device characterization.

## Absolute Maximum Ratings

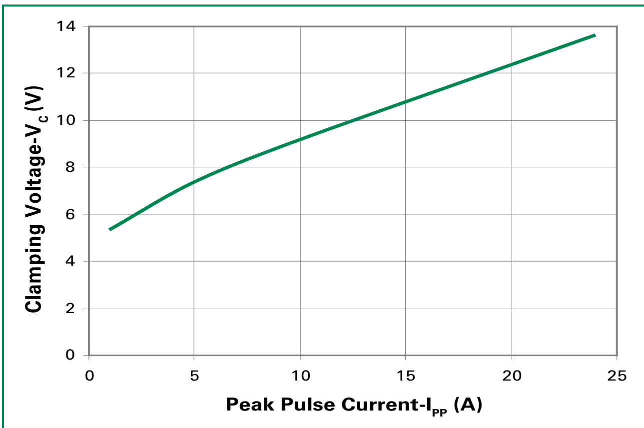
| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Power ($t_P$=8/20μs) | 600 | W |
| Peak Pulse Current ($t_P$=8/20μs) | 40 | A |
| Operating Temperature | –40 to 125 | °C |
| Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

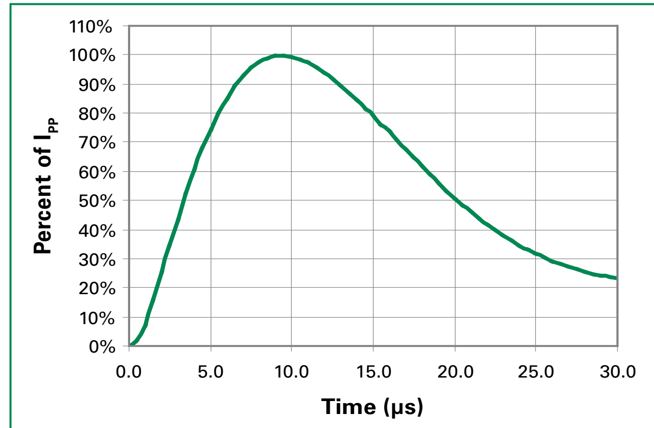
## Figure 1: Capacitance vs. Reverse Voltage




## Figure 2: Clamping Voltage vs. $I_{PP}$




## Figure 3: Pulse Waveform

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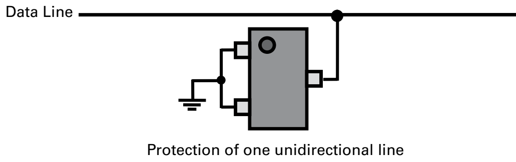
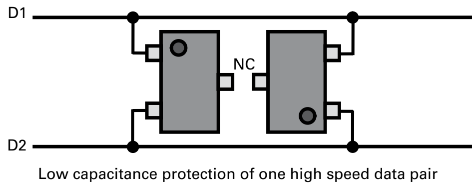
## Application Example Detail



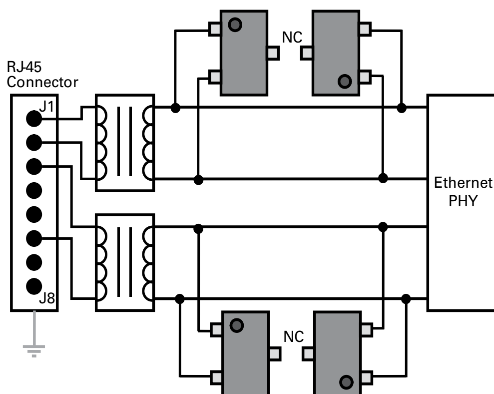
Protection of one unidirectional line

Protection of one unidirectional data line is realized by connecting pin 3 to the protected line, and pins 1 and 2 to GND. In this configuration, the device presents a maximum loading capacitance of tens of picofarads. During positive transients, the internal TVS diode will conduct and steer current from pin 3 to 1 (GND), clamping the data line at or below the specified voltages for the device (see Electrical Characteristics section). For negative transients, the internal compensating diode is forward biased, steering the current from pin 2 (GND) to 3.



Low capacitance protection of one high speed data pair

Low capacitance protection of a high-speed data pair is realized by connecting two devices in antiparallel. As shown, pin 1 of the first device is connected to D1 and pin 2 is connected to D2. Additionally, pin 2 of the second device is connected to D1 and pin 1 is connected to D2. Pin 3 must be NC (or not connected) for both devices. When the potential on D1 exceeds the potential on D2 (by the rated standoff voltage), pin 2 on the second device will steer current into pin 1. The compensating diode will conduct in the forward direction steering current into the avalanching TVS diode which is operating in the reverse direction. For the opposite transient, the first device will behave in the same manner. In this two device arrangement, the total loading capacitance is two times the rated capacitance from pin 2 to pin 1 which will typically be much less than 10pF making it suitable for high-speed data pair such as 10/100/1000 Ethernet.



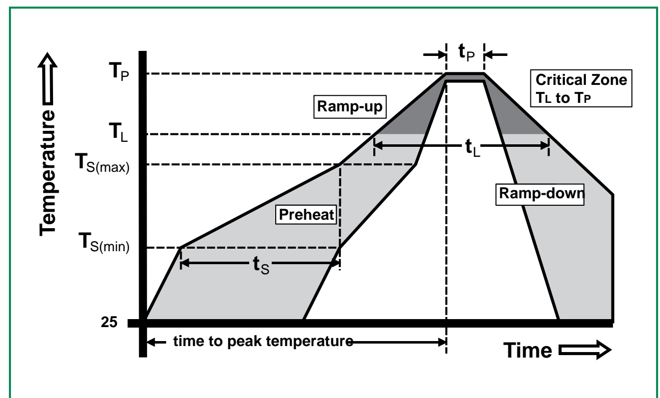

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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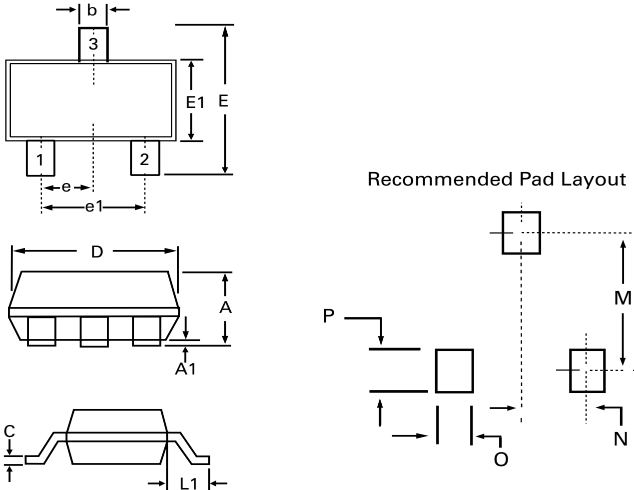
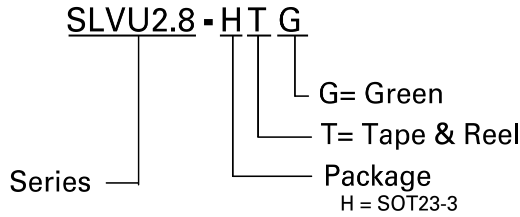
Revised: 12/20/13

## Package Dimensions — SOT-23

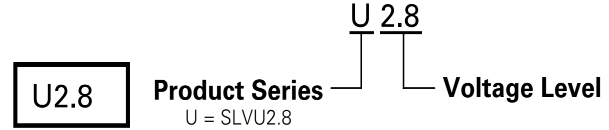



| Package | SOT23-3 | | | |
|---|---|---|---|---|
| Pins | 3 | | | |
| JEDEC | TO-236 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.89 | 1.12 | 0.035 | 0.044 |
| **A1** | 0.01 | 0.1 | 0.0004 | 0.004 |
| **b** | 0.3 | 0.5 | 0.012 | 0.020 |
| **c** | 0.08 | 0.2 | 0.003 | 0.008 |
| **D** | 2.8 | 3.04 | 0.110 | 0.120 |
| **E** | 2.1 | 2.64 | 0.083 | 0.104 |
| **E1** | 1.2 | 1.4 | 0.047 | 0.055 |
| **e** | 0.95 BSC | | 0.038 BSC | |
| **e1** | 1.90 BSC | | 0.075 BSC | |
| **L1** | 0.54 REF | | 0.021 REF | |
| **M** | | 2.29 | | .90 |
| **N** | | 0.95 | | 0.038 |
| **O** | | 0.78 | | 0.30 TYP |
| **P** | | 0.78 | | 0.30 TYP |

## Part Numbering System



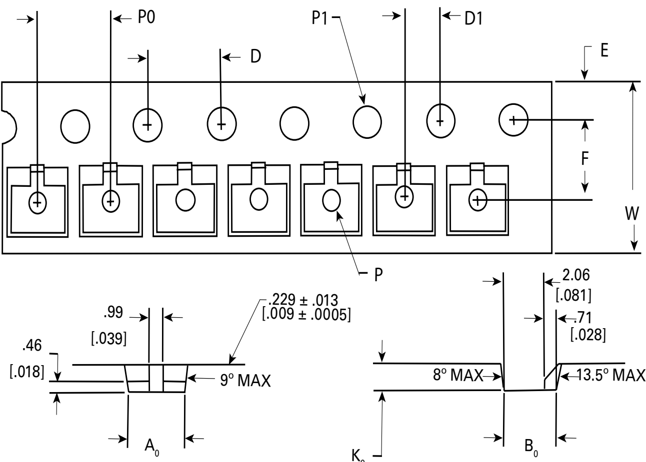

## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SLVU2.8HTG | SOT23-3 | U2.8 | 3000 |

## Embossed Carrier Tape & Reel Specification — SOT23-3 Package




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **A0** | 3.05 | 3.25 | 0.12 | 0.128 |
| **B0** | 2.67 | 2.87 | 0.105 | 0.113 |
| **D** | 3.9 | 4.1 | 0.153 | 0.161 |
| **D1** | 1.95 | 2.05 | 0.788 | 0.792 |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 3.45 | 3.55 | 0.136 | 0.14 |
| **K0** | 1.12 | 1.32 | 0.476 | 0.484 |
| **P** | 0.95 | 1.05 | 0.037 | 0.041 |
| **P0** | 3.9 | 4.1 | 0.153 | 0.161 |
| **P1** | | 1.6 | | 0.063 |
| **W** | 7.9 | 8.3 | 0.311 | 0.327 |

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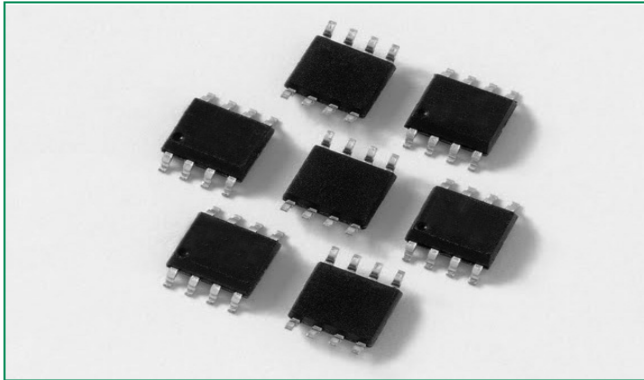
# SLVU2.8-4 Series 2.8V 40A TVS Array

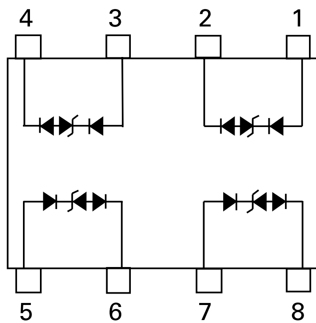
RoHS Pb GREEN



## Description

The SLVU2.8-4 was designed to protect low voltage, CMOS devices from ESD and lightning induced transients. There is a compensating diode in series with each low voltage TVS to present a low loading capacitance to the line being protected. These robust structures can safely absorb repetitive ESD strikes at ±30kV (contact discharge) per IEC61000-4-2 standard and each structure can safely dissipate up to 40A (IEC61000-4-5, $t_P$=8/20μs) with very low clamping voltages.

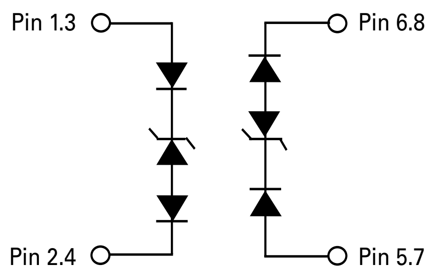
## Pinout




## Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 40A (8/20μs)
- Low capacitance of 2pF per line
- Low leakage current of 1μA (MAX) at 2.8V
- SOIC-8 (JEDEC MO-012) pin configuration allows for simple flow-through layout

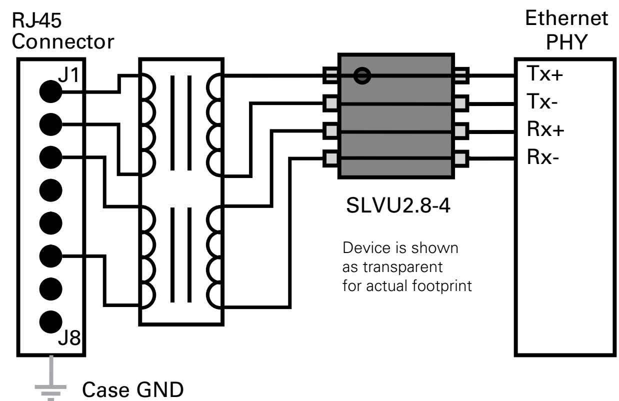
## Functional Block Diagram




## Applications

- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Switching Systems
- Desktops, Servers, and Notebooks
- Analog Inputs
- Base Stations

## Application Example




## Additional Information

Datasheet

Resources

Samples

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## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | $I_R$≤1μA | | | 2.8 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$=2μA | 3.0 | | | V |
| Snap Back Voltage | $V_{SB}$ | $I_T$=50mA | 2.8 | | | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=2.8V (Each Line) | | | 1 | μA |
| Clamping Voltage[1] | $V_C$ | $I_{PP}$=5A, $t_P$=8/20μs (Each Line) | | 7.0 | 8.5 | V |
| Clamping Voltage[1] | $V_C$ | $I_{PP}$=24A, $t_P$=8/20μs (Each Line) | | 13.9 | 15.0 | V |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Dynamic Resistance | $R_{DYN}$ | ($V_{C2}$ - $V_{C1}$) / ($I_{PP2}$ - $I_{PP1}$) (Each Line) | | 0.4 | | Ω |
| Diode Capacitance[1] | $C_D$ | $V_R$=0V, f=1MHz (Each Line) | | 2.0 | 2.5 | pF |

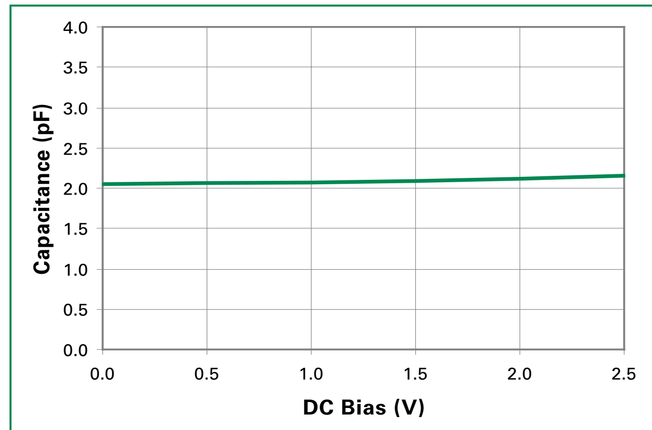
Note: [1]Parameter is guaranteed by design and/or device characterization.

## Absolute Maximum Ratings

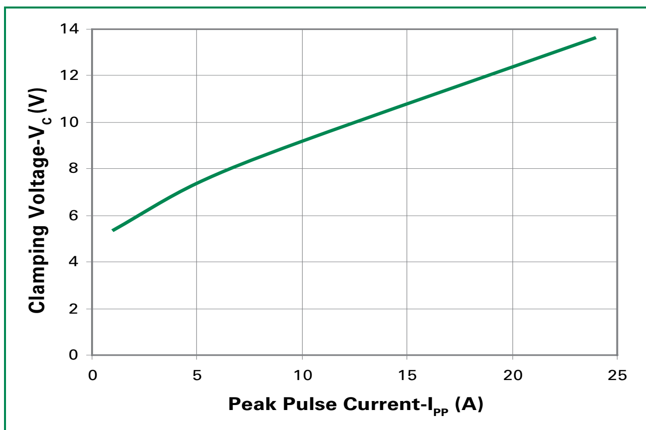
| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Power ($t_P$=8/20μs) | 600 | W |
| Peak Pulse Current ($t_P$=8/20μs) | 40 | A |
| Operating Temperature | –40 to 125 | °C |
| Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

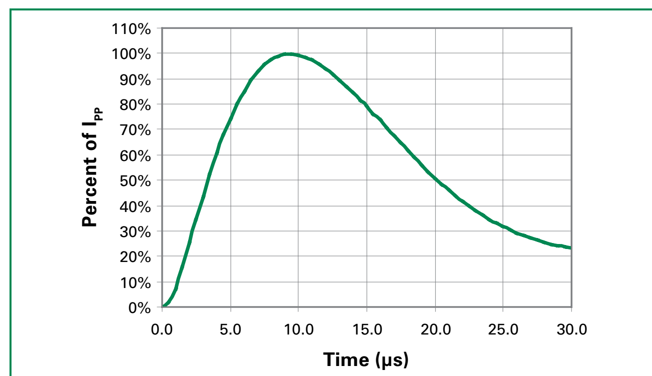
## Figure 1: Capacitance vs. Reverse Voltage




## Figure 2: Clamping Voltage vs. $I_{PP}$




## Figure 3: Pulse Waveform

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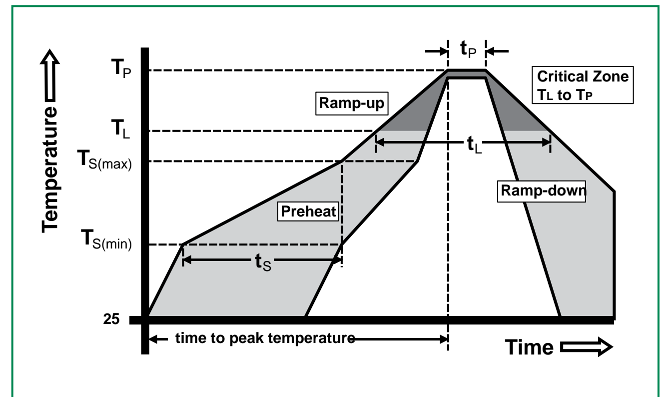
## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

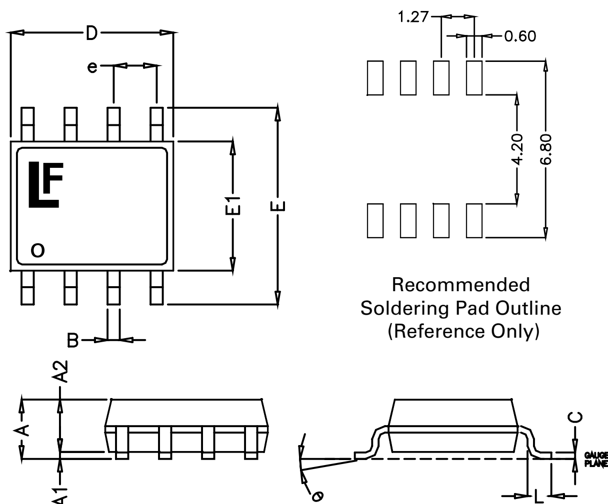
Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. All specifications comply to JEDEC SPEC MO-203 Issue A
5. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
6. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 5°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline



Recommended Soldering Pad Outline (Reference Only)

| Package | SOIC-8 | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| A | 1.35 | 1.75 | 0.053 | 0.069 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| A2 | 1.25 | 1.65 | 0.050 | 0.065 |
| B | 0.31 | 0.51 | 0.012 | 0.020 |
| c | 0.17 | 0.25 | 0.007 | 0.010 |
| D | 4.80 | 5.00 | 0.189 | 0.197 |
| E | 5.80 | 6.20 | 0.228 | 0.244 |
| E1 | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| L | 0.40 | 1.27 | 0.016 | 0.050 |

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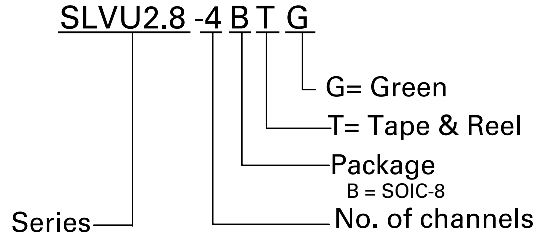
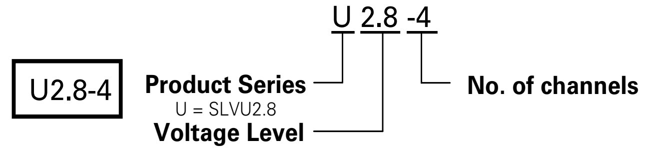
## Part Numbering System



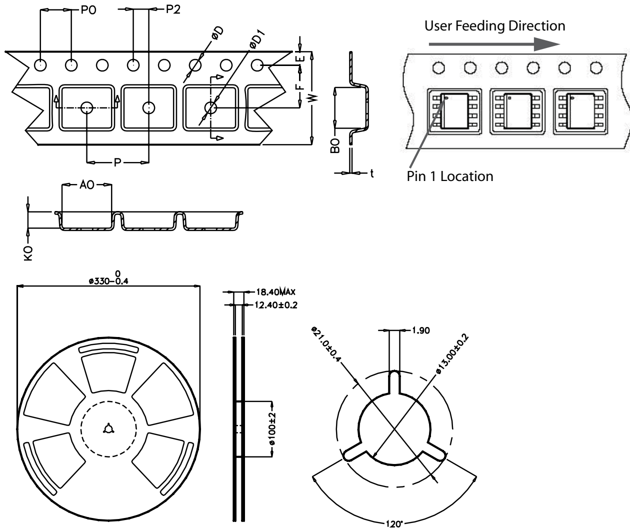

## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SLVU2.8-4BTG | SOIC-8 | U2.8-4 | 2500 |

## Embossed Carrier Tape & Reel Specification — SOIC Package




| Symbol | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

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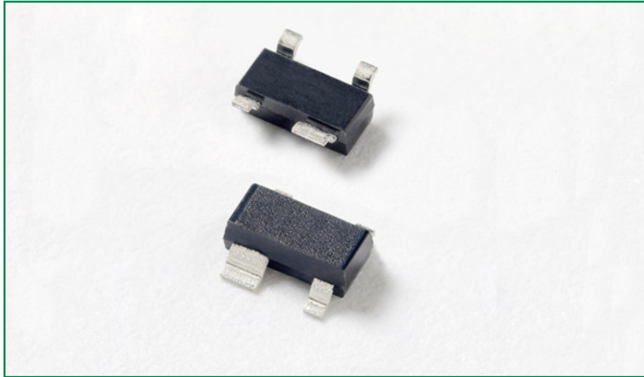
# SR70 Series 70V 40A Diode Array

RoHS Pb GREEN



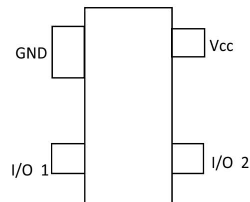
## Description

The SR70 consists of four, low capacitance, rail-to-rail diodes that provide protection against ESD and lightning surge events. These robust diodes can safely absorb up to 40A ($t_P$=8/20μs) and repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation.

Its low loading capacitance makes it ideal for protecting high-speed data lines such as VDSL and VDSL2.

## Pinout

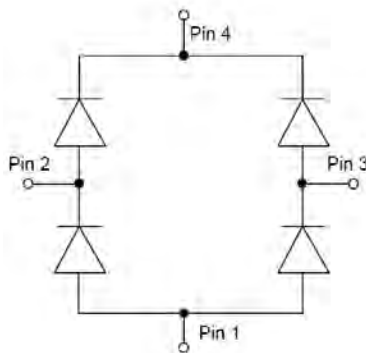
**SOT-143-4**




## Features

- ESD, IEC61000-4-2 , ±30kV contact discharge, ±30kV air discharge
- EFT, IEC61000-4-4, 80A ($t_p$=5/50ns)
- Lightning protection, IEC61000-4-5, 40A ($t_p$=8/20μs)
- Low capacitance of 2.0pF (TYP) per I/O
- Low clamp voltage
- Small SOT143 (JEDEC TO-253) packaging

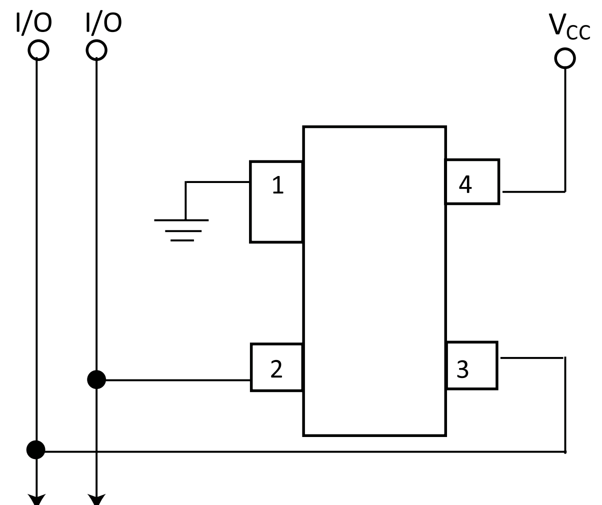
## Functional Block Diagram




## Applications

- xDSL Lines
- Video Lines
- Customer Premises Equipment
- 10/100/1000 Ethernet

## Application Example




## Additional Information

**Datasheet**

**Resources**

**Samples**

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 40.0 | A |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

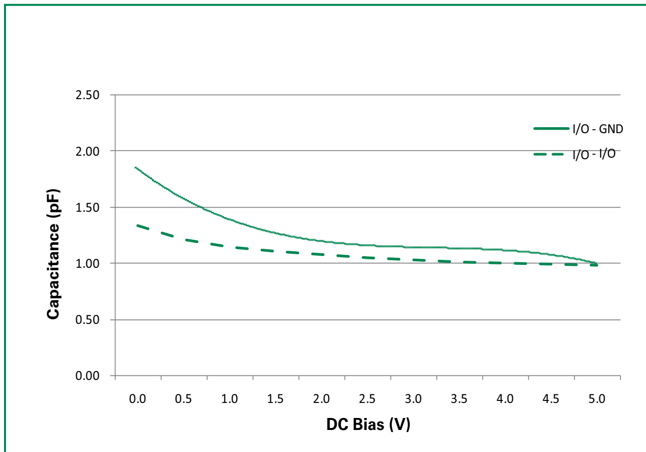
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

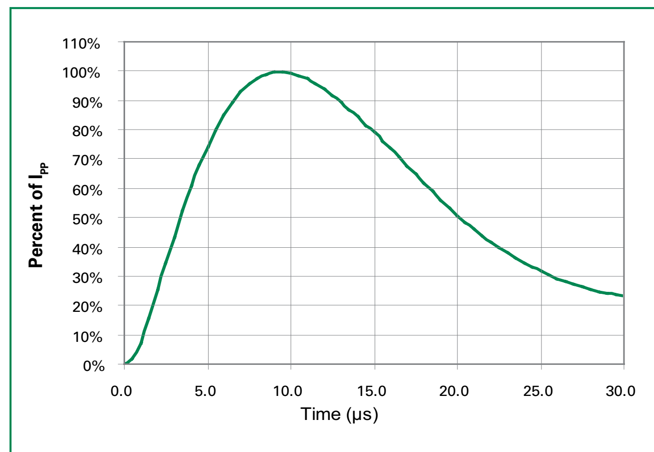
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Standoff Voltage | $V_{RWM}$ | | | | 70 | V |
| Reverse Leakage Current | $I_{LEAK}$ | $V_R$=70V | | | 5 | μA |
| Clamp Voltage[1] | $V_C$ | $I_{PP}$=1A, $t_p$=8/20μs, Fwd | | 1.4 | | V |
| | | $I_{PP}$=10A, $t_p$=8/20μs, Fwd | | 4.7 | | V |
| | | $I_{PP}$=30A, $t_p$=8/20μs, Fwd | | 12 | | V |
| Dynamic Resistance | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | | 0.35 | | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact) | ±30 | | | kV |
| | | IEC61000-4-2 (Air) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-GND}$ | Reverse Bias=0V, f=1MHz | | 2.0 | 3.0 | pF |
| | $C_{I/O-I/O}$ | Reverse Bias=0V, f=1MHz | | 1.3 | 2.0 | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Pulse Waveform

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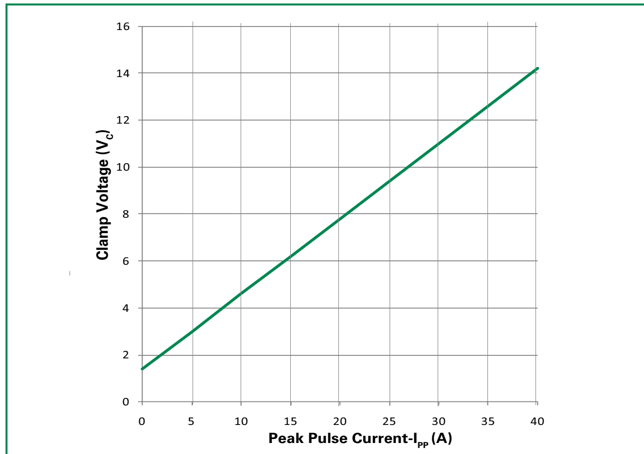
## Clamping Voltage vs. $I_{PP}$



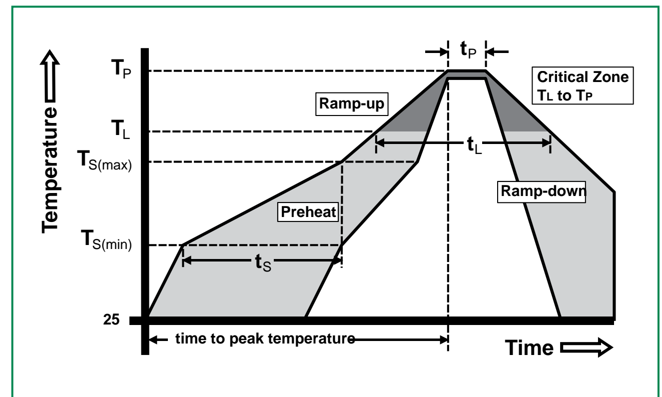

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

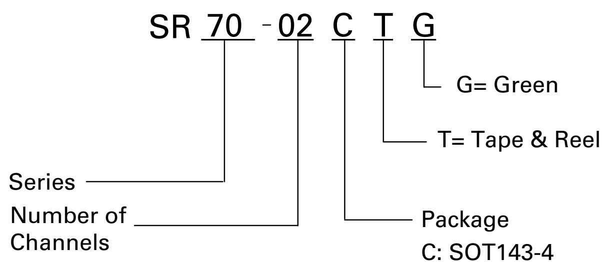
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |



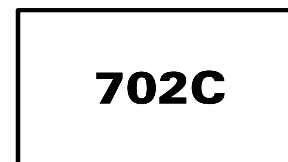

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SR70-02CTG | SOT143 | 702C | 3000 |

## Part Numbering System




## Part Marking System

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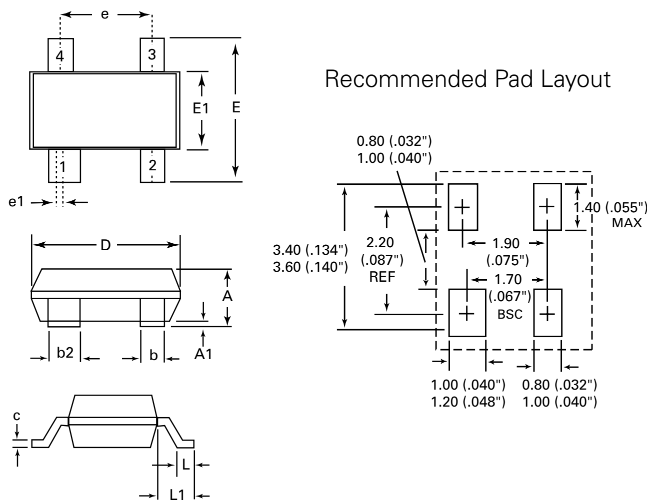
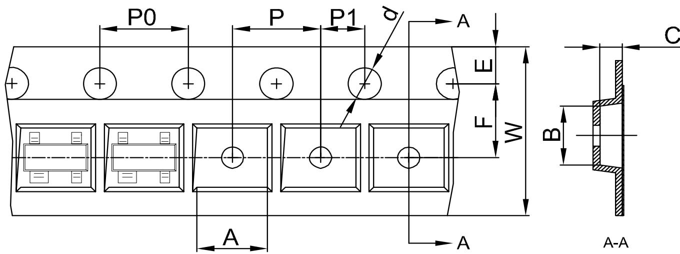
## Package Dimensions—SOT143

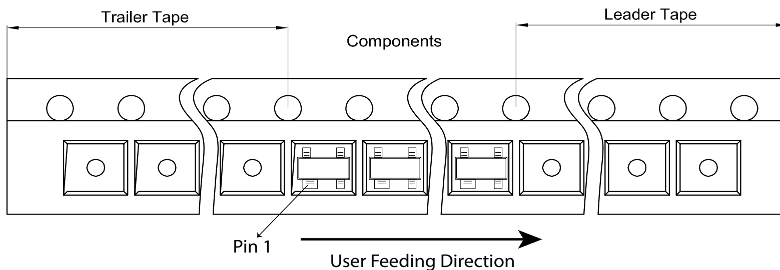



| Package | SOT143 | | | |
|---|---|---|---|---|
| Pins | 4 | | | |
| JEDEC | TO-253 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.8 | 1.22 | 0.03 | 0.048 |
| **A1** | 0.05 | 0.15 | 0.002 | 0.006 |
| **b** | 0.30 | 0.50 | 0.012 | 0.020 |
| **b2** | 0.76 | 0.89 | 0.030 | 0.035 |
| **c** | 0.08 | 0.20 | 0.003 | 0.008 |
| **D** | 2.80 | 3.04 | 0.110 | 0.120 |
| **E** | 2.10 | 2.64 | 0.082 | 0.104 |
| **E1** | 1.20 | 1.40 | 0.047 | 0.055 |
| **e** | 1.92 BSC | | 0.076 BSC | |
| **e1** | 0.20 BSC | | 0.008 BSC | |
| **L** | 0.4 | 0.6 | 0.016 | 0.024 |
| **L1** | 0.550 REF | | 0.022 REF | |

## Embossed Carrier Tape & Reel Specification—SOT143




| Symbol | Millimeters |
|---|---|
| **A** | 3.19±0.10 |
| **B** | 2.8±0.10 |
| **C** | 1.31±0.10 |
| **d** | ⌀ 1.50±0.10 |
| **E** | 1.75±0.10 |
| **F** | 3.50±0.10 |
| **P0** | 4.00±0.10 |
| **P** | 4.00±0.10 |
| **P1** | 2.00±0.10 |
| **W** | 8.00±0.10 |




Notes :
1. All dimensions are in millimeters

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Revised: 12/20/13

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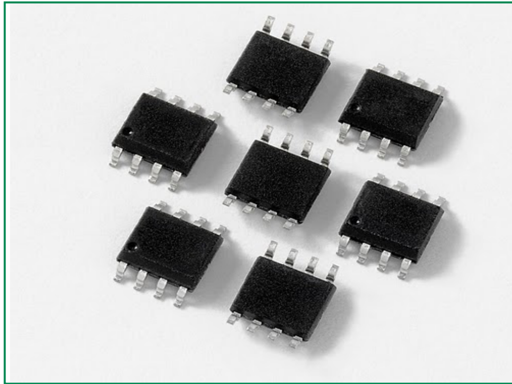
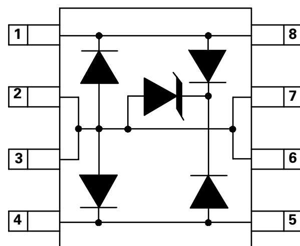
# SP2502L Series 3.3V 75A Diode Array



## Description

The SP2502L provides overvoltage protection for applications such as 10/100/1000 Base-T Ethernet and T3/E3 interfaces. This device has a low capacitance of only 5pF making it suitable for PHY side Ethernet protection and the capability to protect against both longitudinal and differential transients. Furthermore, the SP2502L is rated up to 100A (tp=2/10μs) making it suitable for line side protection as well against lightning transients as defined by GR-1089 (intra-building), ITU, YD/T, etc. The application schematic provides the connection information for a PHY side protection scheme of a single differential pair.

## Pinout



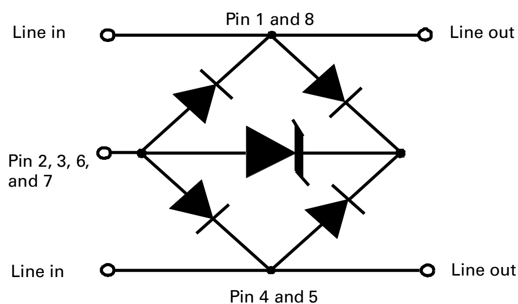

**SOIC-8 (Top View)**

Note: Pinout diagrams above shown as device footprint on circuit board.

## Features

- Lightning protection, IEC61000-4-5, 75A (8/20μs)
- Low clamping voltage
- Low insertion loss, log-linear capacitance
- Combined longitudinal and metallic protection
- Clamping speed of nanoseconds
- SOIC-8 surface mount package (JEDEC MS-012)
- UL 94V-0 epoxy molding
- RoHS compliant

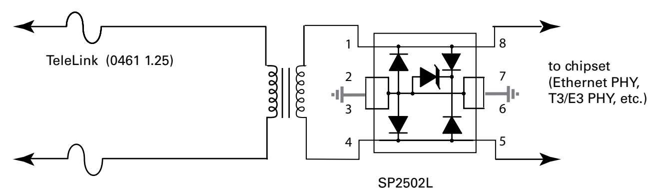
## Functional Block Diagram




## Applications

- T1/E1 Line cards
- 10/100/1000 BaseT Ethernet
- T3/E3 and DS3 Interfaces
- STS-1 Interfaces

## Application Example




The schematic shows protection for a single differential pair as part of a larger high-speed data interface such as Ethernet. The SP2502L provides both metallic (differential) and longitudinal (common mode) protection from lightning induced surge events as specified by regulatory standards such as Telcordia's GR-1089 CORE and ITU K.20 and 21.

The SP2502L protects against both positive and negative induced surge events while the TeleLink fuse provides overcurrent protection for the long term 50/60 Hz power fault events.

## Additional Information

**Datasheet**

**Resources**

**Samples**

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Current (8/20μs) | 75 | A |
| Peak Pulse Power (8/20μs) | 2100 | W |
| IEC 61000-4-2, Direct Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-2, Air Discharge, (Level 4) | 30 | kV |
| Telcordia GR 1089 (Intra-Building) (2/10μs) | 100 | A |
| ITU K.20 (5/310μs) | 20 | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| SOIC Package | 170 | °C/W |
| Operating Temperature Range | –40 to 125 | °C |
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | $I_T \leq 1\mu A$ | - | - | 3.3 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$= 2μA | 3.3 | - | - | V |
| Snap Back Voltage | $V_{SB}$ | $I_T$= 50mA | 3.3 | - | - | V |
| Reverse Leakage Current | $I_R$ | $V_{RWM}$= 3.3V | - | - | 1 | μA |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 40A, $t_p$=8/20 μs | - | - | 14 | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 75A, $t_p$=8/20 μs | - | - | 20 | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 100A, $t_p$=2/10 μs | | | 20 | V |
| Dynamic Resistance, Line-Ground[1] | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.2 | - | Ω |
| Clamping Voltage, Line-Line[1] | $V_C$ | $I_{PP}$= 40A, $t_p$=8/20 μs | - | - | 20 | V |
| Clamping Voltage, Line-Line[1] | $V_C$ | $I_{PP}$= 75A, $t_p$=8/20 μs | - | - | 30 | V |
| Clamping Voltage, Line-Line[1] | $V_C$ | $I_{PP}$= 100A, $t_p$=2/10 μs | | | 30 | V |
| Dynamic Resistance, Line-Line[1] | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.3 | - | Ω |
| Junction Capacitance[1] | $C_j$ | Line to Ground $V_R$=0V, f= 1MHz | - | 5 | 8 | pF |
| | | Line to Line, $V_R$=0V, f= 1MHz | - | 2.5 | 5 | pF |

[1] Parameter is guaranteed by design and/or device characterization.

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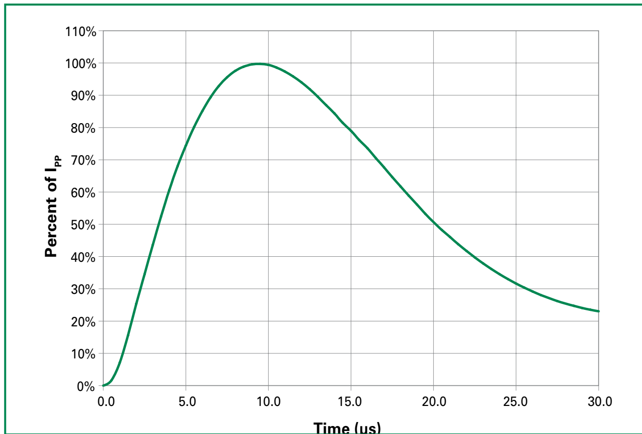
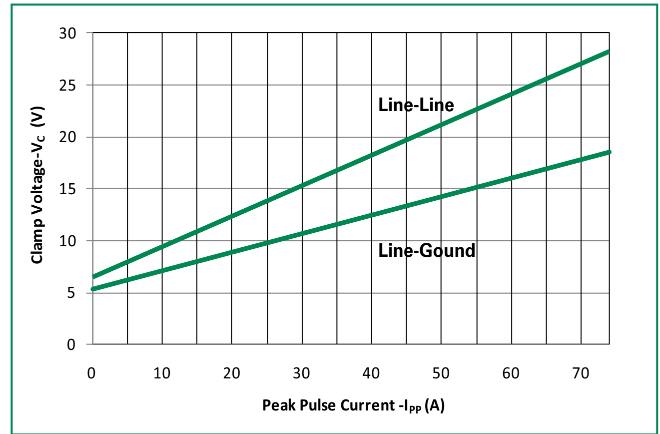
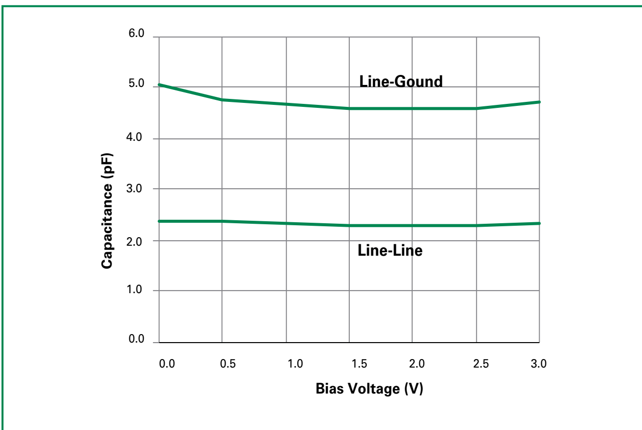
## Pulse Waveform



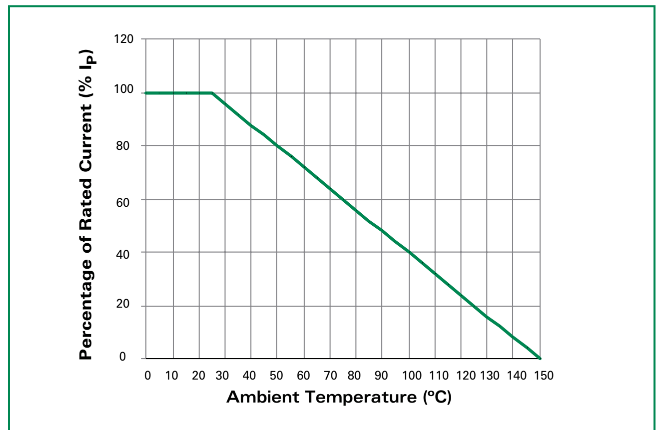

## Clamping Voltage vs. $I_{PP}$



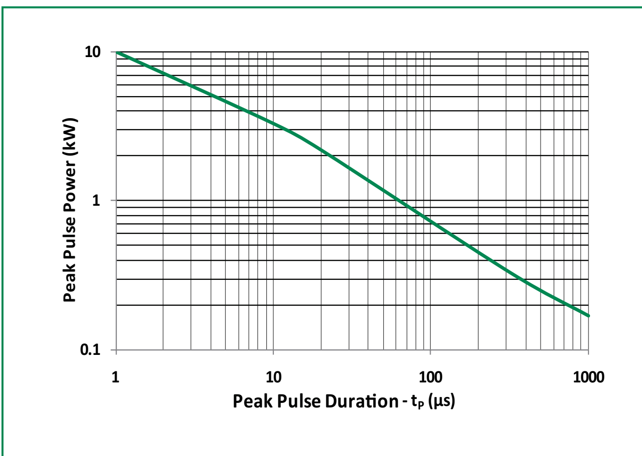

## Capacitance vs. Reverse Bias at 1MHz




## Current Derating Curve




## Non-Repetitive Peak Pulse Power vs. Pulse Time

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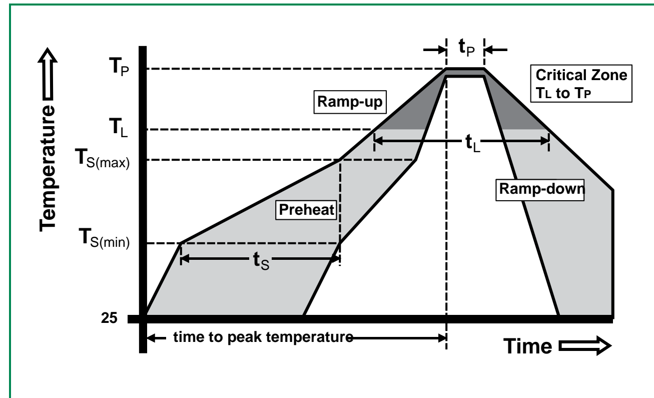
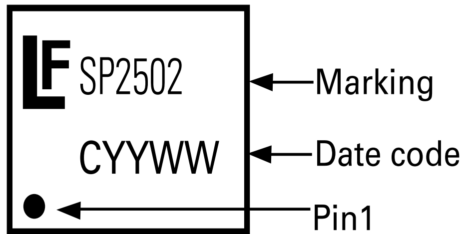
## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Part Marking System

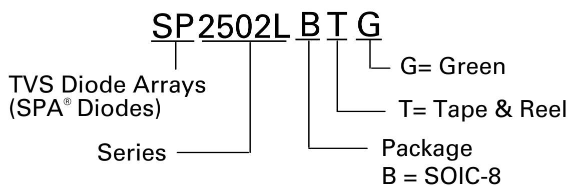



## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Part Numbering System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP2502LBTG | SOIC-8 | SP2502 | 2500 |

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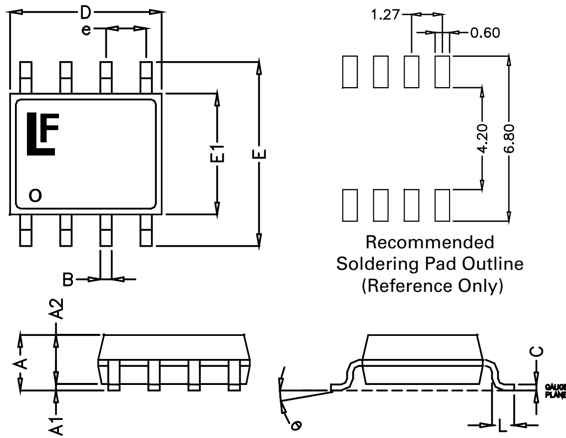
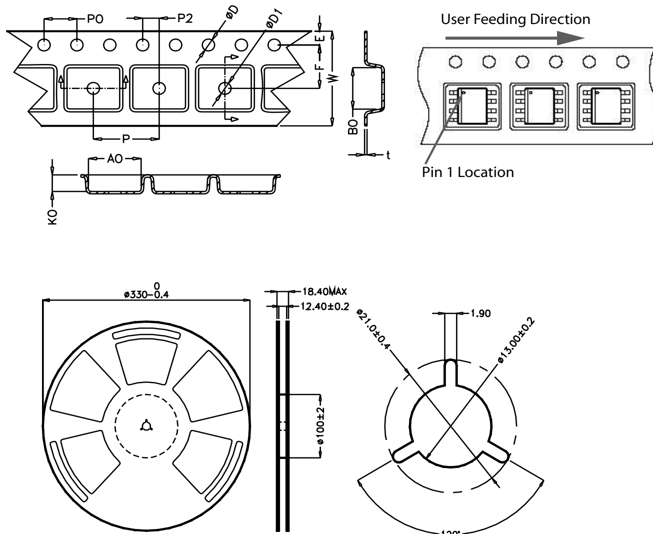
## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline




| Package | SOIC | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| **A** | 1.35 | 1.75 | 0.053 | 0.069 |
| **A1** | 0.10 | 0.25 | 0.004 | 0.010 |
| **A2** | 1.25 | 1.65 | 0.050 | 0.065 |
| **B** | 0.31 | 0.51 | 0.012 | 0.020 |
| **c** | 0.17 | 0.25 | 0.007 | 0.010 |
| **D** | 4.80 | 5.00 | 0.189 | 0.197 |
| **E** | 5.80 | 6.20 | 0.228 | 0.244 |
| **E1** | 3.80 | 4.00 | 0.150 | 0.157 |
| **e** | 1.27 BSC | | 0.050 BSC | |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 |

## Embossed Carrier Tape & Reel Specification — SOIC Package




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

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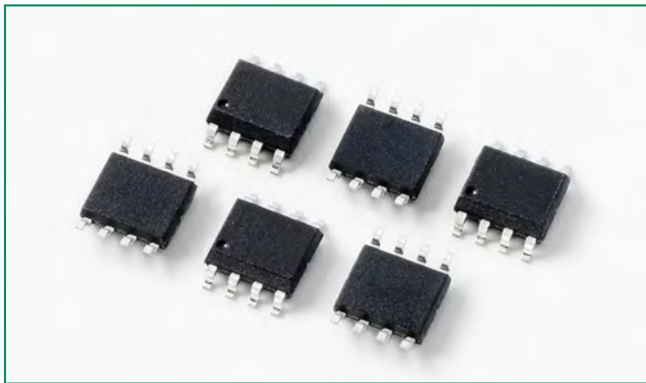
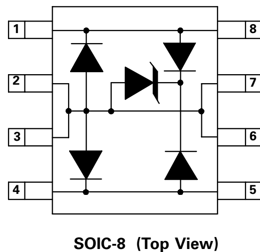
# LC03-3.3 Series 3.3V 150A Diode Array



## Description

This LC03-3.3 series provides overvoltage protection for applications such as 10/100/1000 BaseT Ethernet, and T3/E3 interfaces. This new protector combines the TVS diode element with a diode rectifier bridge to provide both longitudinal and differential protection in one package. This design results in a capacitive loading characteristic that is log-linear with respect to the signal voltage across the device. This reduces intermodulation (IM) distortion caused by a typical solid-state protection solution. The application schematic provides the connection information and the LC03-3.3 is rated for GR-1089, intra-building transient immunity requirements for telecommunication installations.

## Pinout

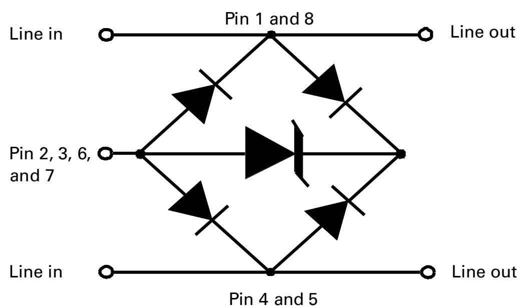



SOIC-8 (Top View)

## Features

- Lightning Protection, IEC61000-4-5, 150A ($t_P$=8/20μs)
- EFT, IEC61000-4-4, 40A ($t_P$=5/50ns)
- Low insertion loss, log-linear capacitance
- Low clamping voltage
- SOIC-8 surface mount package (JEDEC MS-012)
- Combined longitudinal and metallic protection
- Clamping speed of nanoseconds
- UL 94V-0 epoxy molding
- RoHS compliant

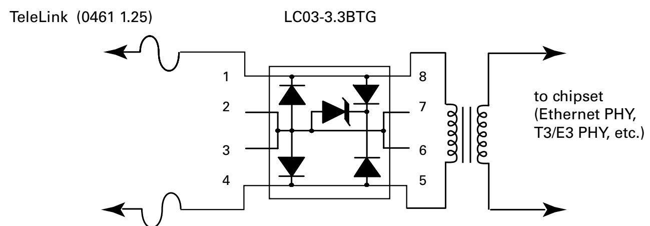
## Functional Block Diagram




## Applications

- T1/E1 Line cards
- T3/E3 and DS3 Interfaces
- STS-1 Interfaces
- 10/100/1000 BaseT Ethernet

## Application Example




This schematic shows a high-speed data interface protection solution. The LC03-3.3BTG is compatible with the intra-building surge requirements of Telcordia's GR-1089-CORE, and the Basic Level Recommendations of ITU K.20 and K.21. The TeleLink fuse provides overcurrent protection for the long term 50/60 Hz power fault events.

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Current (8/20μs) | 150 | A |
| Peak Pulse Power (8/20μs) | 3300 | W |
| IEC 61000-4-2, Direct Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-2, Air Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-5 (8/20μs) | 150 | A |
| Telcordia GR 1089 (Intra-Building) (2/10μs) | 100 | A |
| ITU K.20 (5/310μs) | 40 | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

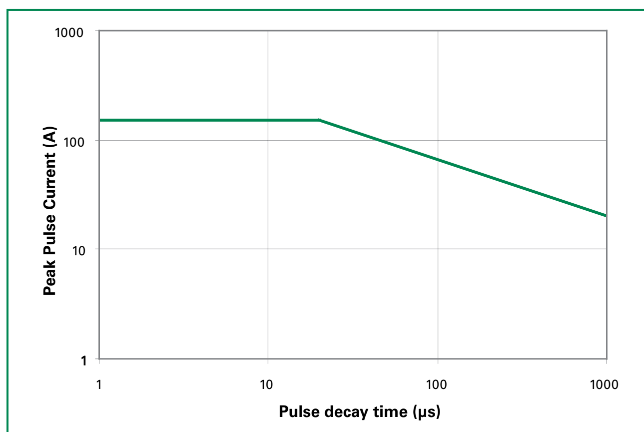
## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| SOIC Package | 170 | °C/W |
| Operating Temperature Range | –40 to 125 | °C |
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

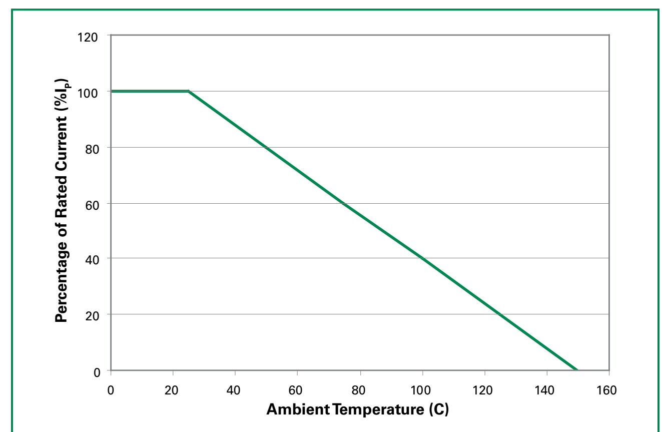
## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | $I_T \leq 1\mu A$ | - | - | 3.3 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$= 2μA | 3.3 | - | - | V |
| Snap Back Voltage | $V_{SB}$ | $I_T$= 50mA | 3.3 | - | - | V |
| Reverse Leakage Current | $I_R$ | $V_{RWM}$= 3.3V, T= 25°C | - | - | 1 | μA |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 50A, $t_p$=8/20 μs | - | - | 13 | V |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 100A, $t_p$=8/20 μs | - | - | 17 | V |
| Dynamic Resistance, Line-Ground | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.15 | - | Ω |
| Clamping Voltage, Line-Line | $V_C$ | $I_{PP}$= 50A, $t_p$=8/20 μs | - | - | 15 | V |
| Clamping Voltage, Line-Line | $V_C$ | $I_{PP}$= 100A, $t_p$=8/20 μs | - | - | 20 | V |
| Dynamic Resistance , Line-Line | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.25 | - | Ω |
| Junction Capacitance | $C_j$ | Between I/O Pins and Ground $V_R$=0V, f= 1MHz | - | 9 | 12 | pF |
| | | Between I/O Pins $V_R$=0V, f= 1MHz | - | 4.5 | 6 | pF |

## Figure 1: Non-repetitive Peak Pulse Current vs. Pulse Time




## Figure 2: Current Derating Curve

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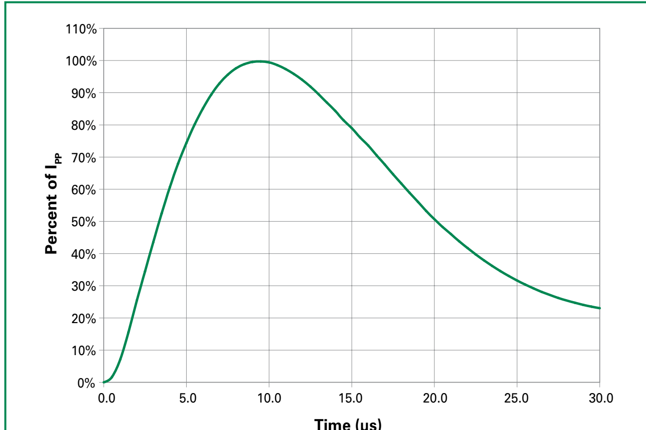
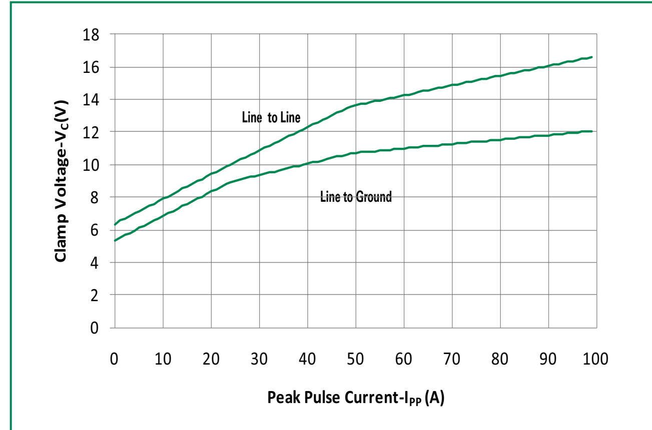
Revised: 12/20/13

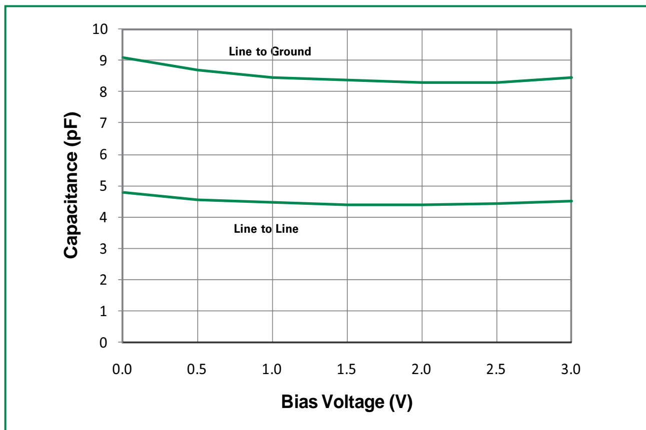
## Figure 3: Pulse Waveform



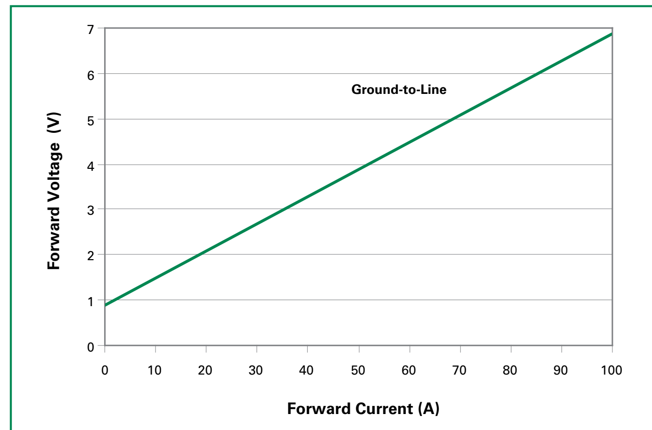

## Figure 4: Clamping Voltage vs. Peak Pulse Current




## Figure 5: Capacitance vs. Reverse Voltage

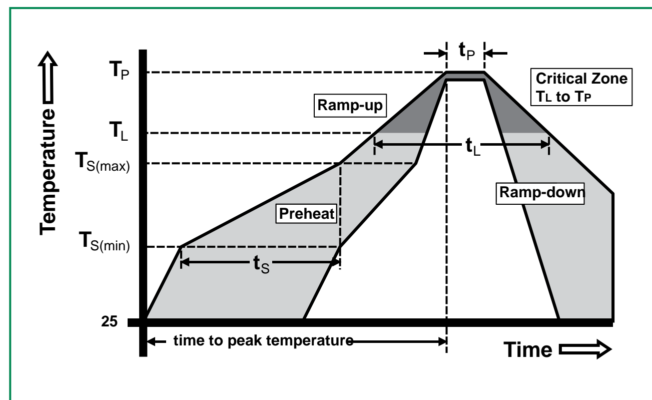



## Figure 6: Forward Voltage vs. Forward Current




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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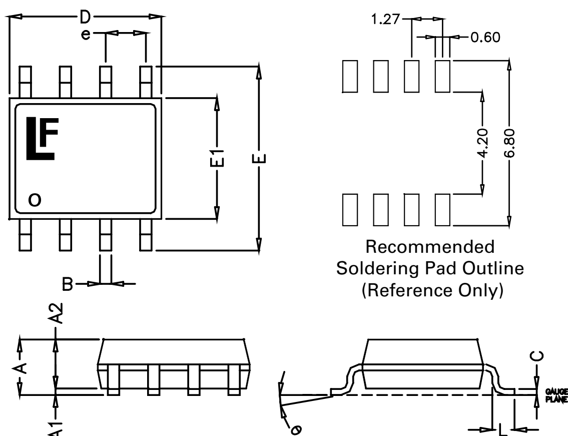
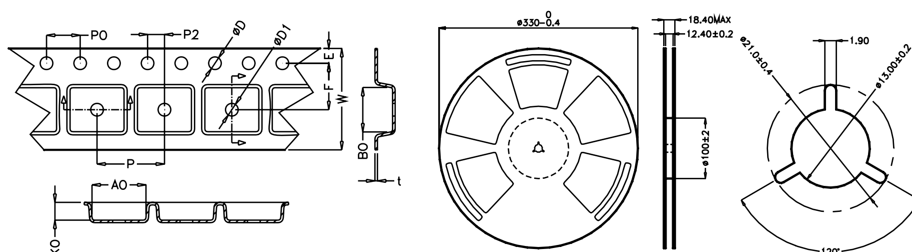
## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline



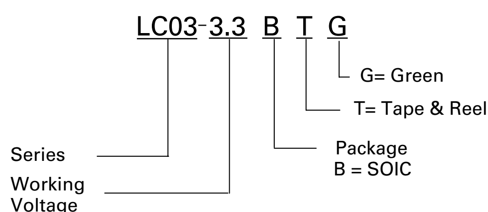

| Package | SOIC-8 | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| **A** | 1.35 | 1.75 | 0.053 | 0.069 |
| **A1** | 0.10 | 0.25 | 0.004 | 0.010 |
| **A2** | 1.25 | 1.65 | 0.050 | 0.065 |
| **B** | 0.31 | 0.51 | 0.012 | 0.020 |
| **c** | 0.17 | 0.25 | 0.007 | 0.010 |
| **D** | 4.80 | 5.00 | 0.189 | 0.197 |
| **E** | 5.80 | 6.20 | 0.228 | 0.244 |
| **E1** | 3.80 | 4.00 | 0.150 | 0.157 |
| **e** | 1.27 BSC | | 0.050 BSC | |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 |

## Embossed Carrier Tape & Reel Specification — SOIC Package

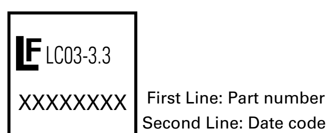



| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

## Part Numbering System




## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| LC03-3.3BTG | SOIC-8 | LC03-3.3 | 2500 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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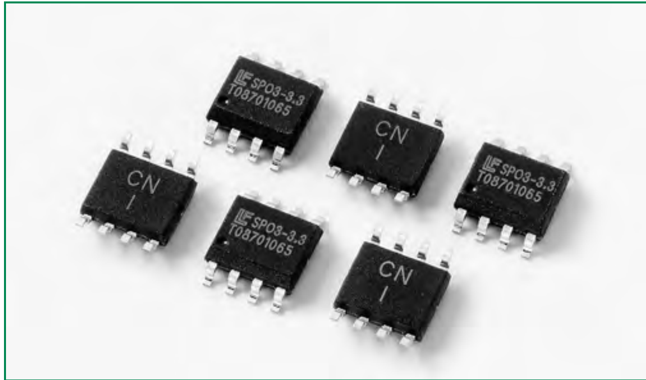
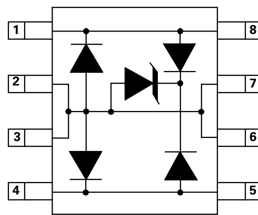
# SP03-3.3 Series 3.3V 150A Diode Array




## Agency Approvals - Pending

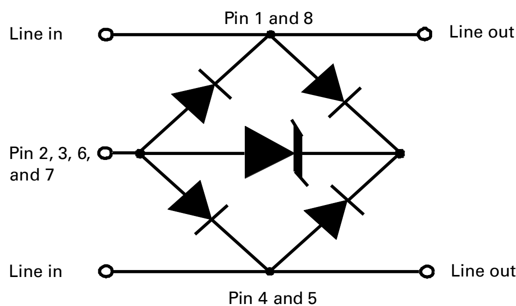
| Agency | Agency File Number |
|---|---|
| UL® | E128662 |

## Pinout




SOIC-8 (Top View)

## Functional Block Diagram




## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

## Description

This new broadband protection device from Littelfuse provides overvoltage protection for applications such as 10/100/1000 BaseT Ethernet, T3/E3 DS3 interfaces, ADSL2+, and VDSL2+. This new protector combines the TVS diode element with a diode rectifier bridge to provide both longitudinal and differential protection in one package. This design innovation results in a capacitive loading characteristic that is log-linear with respect to the signal voltage across the device. This reduces intermodulation (IM) distortion caused by a typical solid-state protection solution. The application schematic provides the connection information.

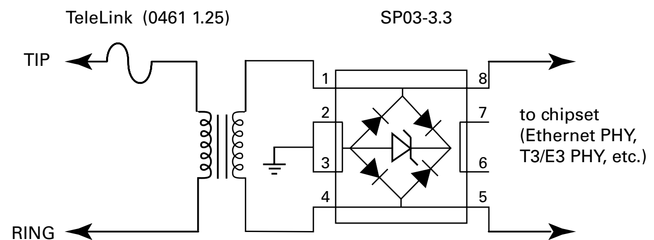
## Features

- RoHS compliant
- SOIC-8 surface mount package (JEDEC MS-012)
- Low insertion loss, log-linear capacitance
- Combined longitudinal and metallic protection
- Lightning Protection, IEC61000-4-5, 100A (8/20μs)
- Clamping speed of nanoseconds
- UL 94V-0 epoxy molding
- Pending UL recognized component
- Low clamping voltage

## Applications

- T1/E1 Line cards
- T3/E3 and DS3 Interfaces
- STS-1 Interfaces
- 10/100/1000 BaseT Ethernet

## Application Example




This schematic shows a high-speed data interface protection solution. The SP03-3.3 provides both metallic (differential) and longitudinal (common mode) protection from lightning induced surge events. Its surge rating is compatible with the intra-building surge requirements of Telcordia's GR-1089-CORE, and the Basic Level Recommendations of ITU K.20 and .21. This device protects against both positive and negative induced surge events. The TeleLink fuse provides overcurrent protection for the long term 50/60 Hz power fault events.

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## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Current (8/20μs) | 150 | A |
| Peak Pulse Power (8/20μs) | 3300 | W |
| IEC 61000-4-2, Direct Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-2, Air Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-5 (8/20μs) | 100 | A |
| Telcordia GR 1089 (Intra-Building) (2/10μs) | 100 | A |
| ITU K.20 (5/310μs) | 40 | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

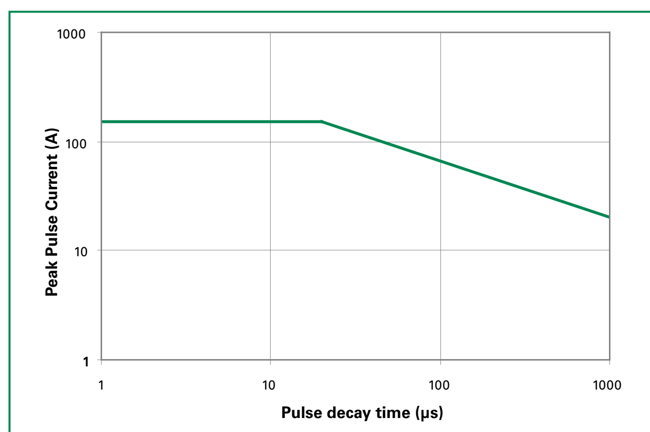
## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| SOIC Package | 170 | °C/W |
| Operating Temperature Range | –40 to 125 | °C |
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

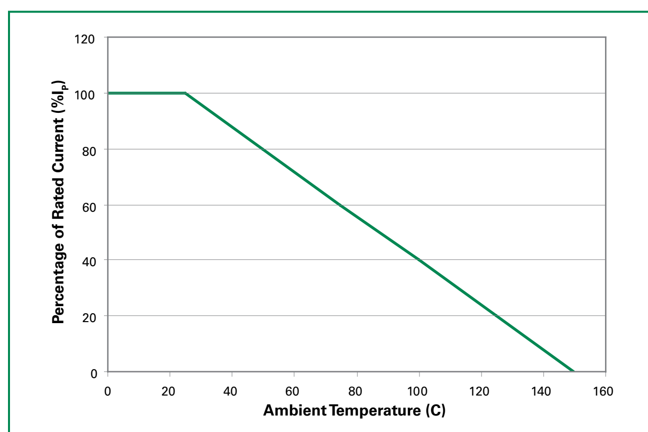
## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | - | - | - | 3.3 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$= 2μA | 3.3 | - | - | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$= 50μA | 3.3 | - | - | V |
| Reverse Leakage Current | $I_R$ | $V_{RWM}$= 3.3V, T= 25°C | - | - | 1 | μA |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 50A, $t_p$=8/20 μs | - | - | 11.5 | V |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 100A, $t_p$=8/20 μs | - | - | 15 | V |
| Clamping Voltage, Line-Line | $V_C$ | $I_{PP}$= 50A, $t_p$=8/20 μs | - | - | 13.5 | V |
| Clamping Voltage, Line-Line | $V_C$ | $I_{PP}$= 100A, $t_p$=8/20 μs | - | - | 18 | V |
| Junction Capacitance | $C_j$ | Between I/O Pins and Ground $V_R$=0V, f= 1MHz | - | 16 | 25 | pF |
| | | Between I/O Pins $V_R$=0V, f= 1MHz | - | 8 | 12 | pF |

## Figure 1: Non-repetitive Peak Pulse Current vs. Pulse Time




## Figure 2: Current Derating Curve

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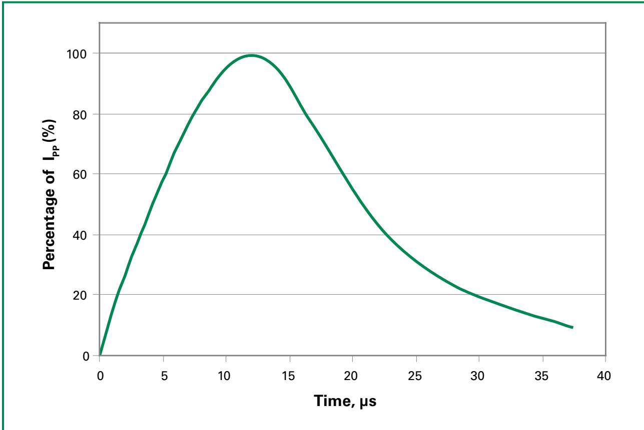
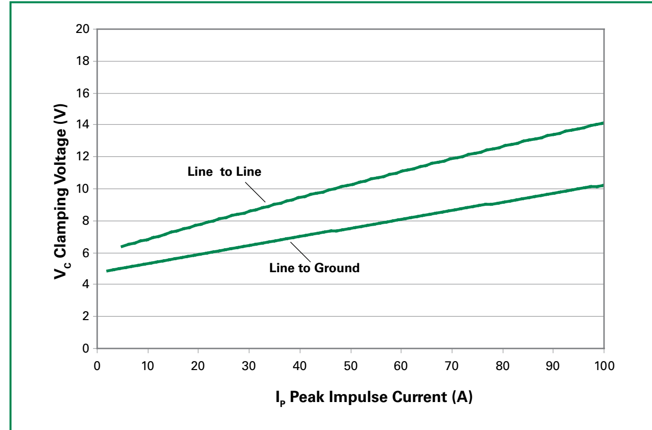
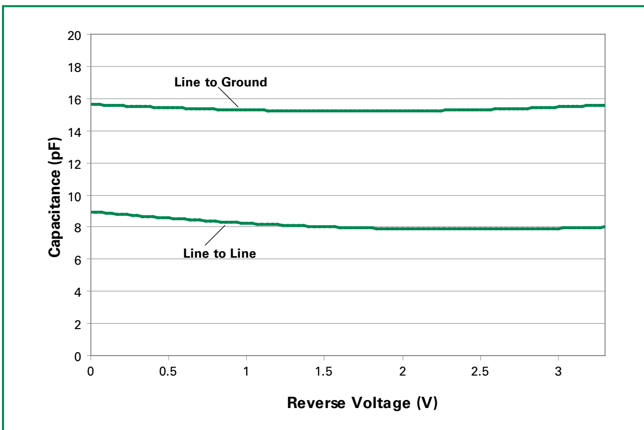
## Figure 3: Pulse Waveform



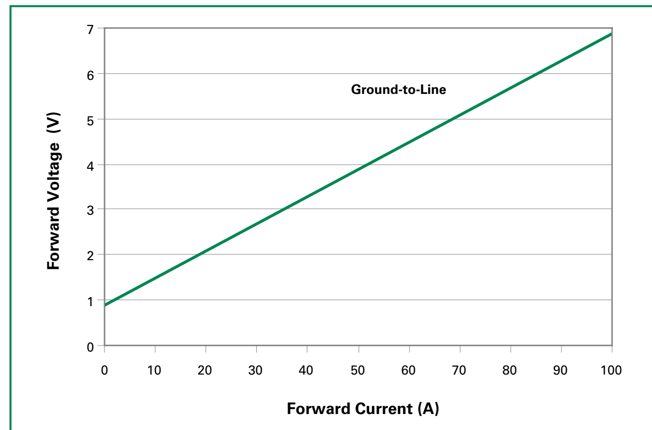

## Figure 4: Clamping Voltage vs. Peak Pulse Current




## Figure 5: Capacitance vs. Reverse Voltage

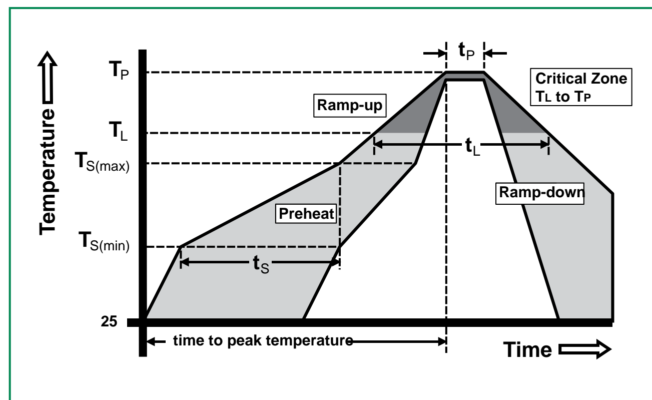



## Figure 6: Forward Voltage vs. Forward Current




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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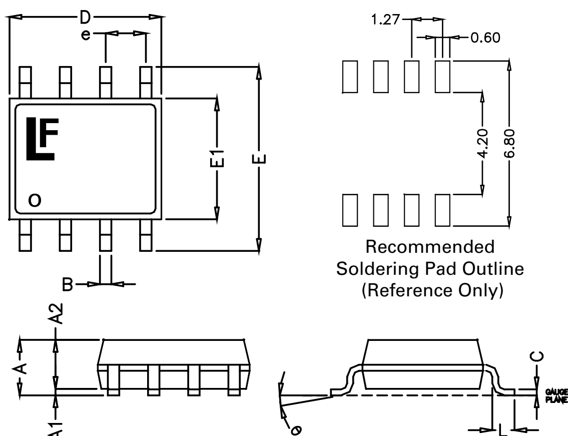
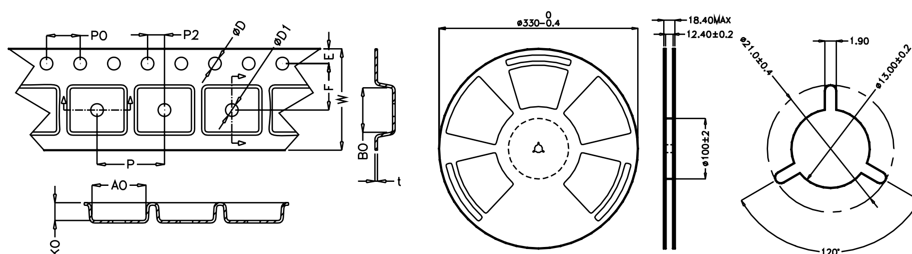
Specifications are subject to change without notice.

## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline



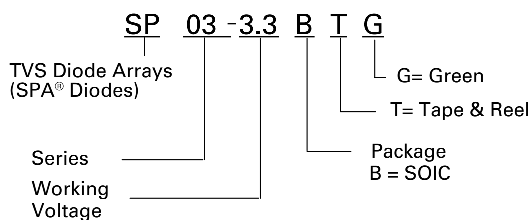

| Package | SOIC-8 | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| **A** | 1.35 | 1.75 | 0.053 | 0.069 |
| **A1** | 0.10 | 0.25 | 0.004 | 0.010 |
| **A2** | 1.25 | 1.65 | 0.050 | 0.065 |
| **B** | 0.31 | 0.51 | 0.012 | 0.020 |
| **c** | 0.17 | 0.25 | 0.007 | 0.010 |
| **D** | 4.80 | 5.00 | 0.189 | 0.197 |
| **E** | 5.80 | 6.20 | 0.228 | 0.244 |
| **E1** | 3.80 | 4.00 | 0.150 | 0.157 |
| **e** | 1.27 BSC | | 0.050 BSC | |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 |

## Embossed Carrier Tape & Reel Specification — SOIC Package

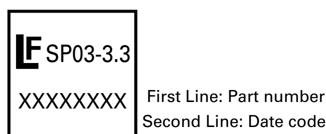



| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

## Part Numbering System




## Part Marking System




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP03-3.3BTG | SOIC Tape & Reel | SP03-3.3 | 2500 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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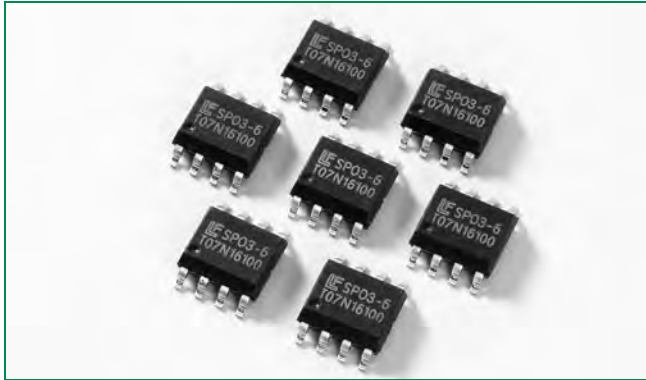
# SP03-6 Series 6V 150A Diode Array




## Description

This new broadband protection device from Littelfuse provides overvoltage protection for applications such as 10/100/1000 BaseT Ethernet, T3/E3 DS3 interfaces, ADSL2+, and VDSL2+. This new protector combines the TVS diode element with a diode rectifier bridge to provide both longitudinal and differential protection in one package. This design innovation results in a capacitive loading characteristic that is log-linear with respect to the signal voltage across the device. This reduces intermodulation (IM) distortion caused by a typical solid-state protection solution. The application schematic provides the connection information.

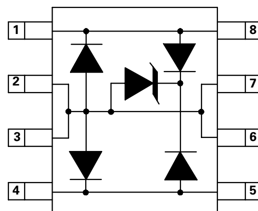
## Agency Approvals - Pending

| Agency | Agency File Number |
|---|---|
| UR | E128662 |

## Features

- RoHS compliant
- SOIC-8 surface mount package (JEDEC MS-012)
- Low insertion loss, log-linear capacitance
- Combined longitudinal and metallic protection
- Clamping speed of nanoseconds
- UL 94V-0 epoxy molding
- Pending UL recognized component
- Low clamping voltage

## Pinout

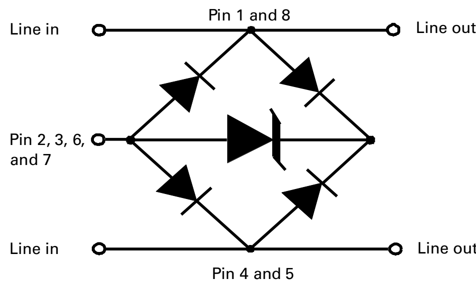



SOIC-8 (Top View)

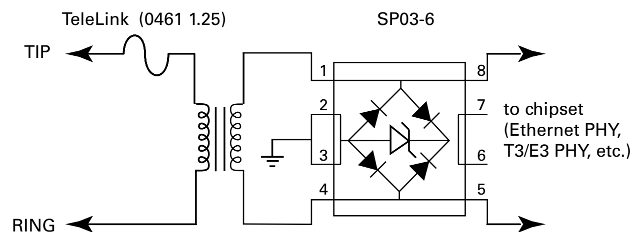
## Applications

- T1/E1 Line cards
- T3/E3 and DS3 Interfaces
- STS-1 Interfaces
- 10/100/1000 BaseT Ethernet

## Functional Block Diagram




## Application Example




This schematic shows a high-speed data interface protection solution. The SP03-6 provides both metallic (differential) and longitudinal (common mode) protection from lightning induced surge events. Its surge rating is compatible with the intra-building surge requirements of Telcordia's GR-1089-CORE, and the Basic Level Recommendations of ITU K.20 and .21. This device protects against both positive and negative induced surge events. The TeleLink fuse provides overcurrent protection for the long term 50/60 Hz power fault events.

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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Expertise Applied | Answers Delivered

## Absolute Maximum Ratings

| Parameter | Rating | Units |
|---|---|---|
| Peak Pulse Current (8/20μs) | 150 | A |
| Peak Pulse Power (8/20μs) | 2800 | W |
| IEC 61000-4-2, Direct Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-2, Air Discharge, (Level 4) | 30 | kV |
| IEC 61000-4-5 (8/20μs) | 100 | A |
| Telcordia GR 1089 (Intra-Building) (2/10μs) | 100 | A |
| ITU K.20 (5/310μs) | 40 | A |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

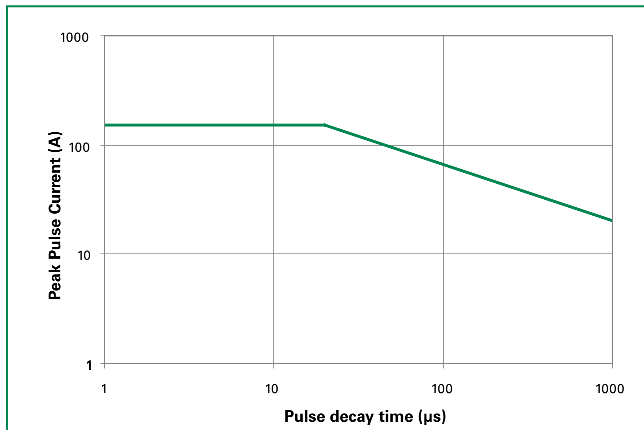
## Thermal Information

| Parameter | Rating | Units |
|---|---|---|
| SOIC Package | 170 | °C/W |
| Operating Temperature Range | –40 to 125 | °C |
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

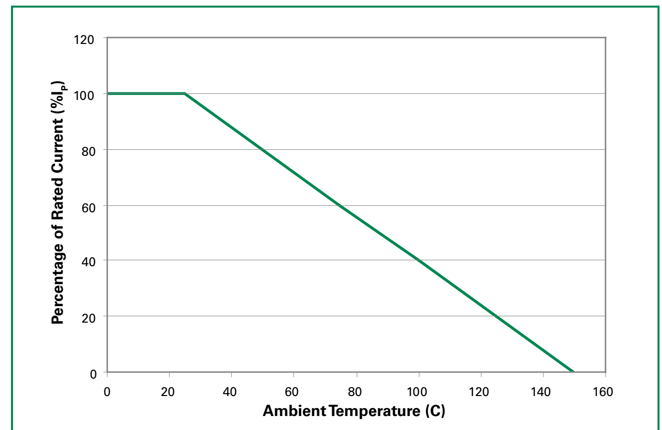
## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | - | - | - | 6 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$= 1mA | 6.8 | - | - | V |
| Reverse Leakage Current | $I_R$ | $V_{RWM}$= 6V, T= 25°C | - | - | 25 | μA |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 50A, $t_p$=8/20 μs | - | - | 15 | V |
| Clamping Voltage, Line-Ground | $V_C$ | $I_{PP}$= 100A, $t_p$=8/20 μs | - | - | 20 | V |
| Junction Capacitance | $C_j$ (Line-Ground) | Between I/O Pins and Ground $V_R$=0V, f= 1MHz | - | 16 | 25 | pF |
| | $C_j$ (Line-Line) | Between I/O Pins $V_R$=0V, f= 1MHz | - | 8 | 12 | pF |

## Figure 1: Non-repetitive Peak Pulse Current vs. Pulse Time




## Figure 2: Current Derating Curve

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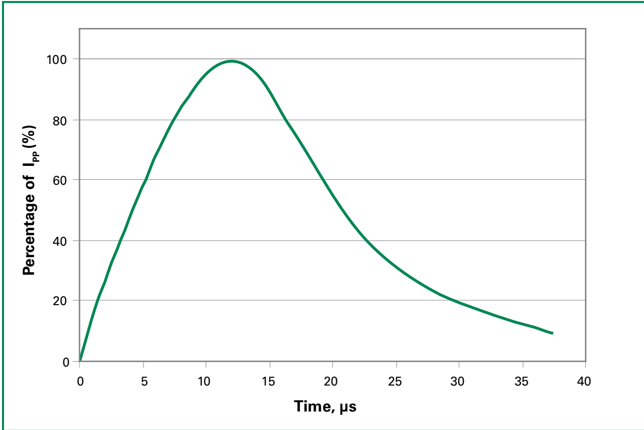
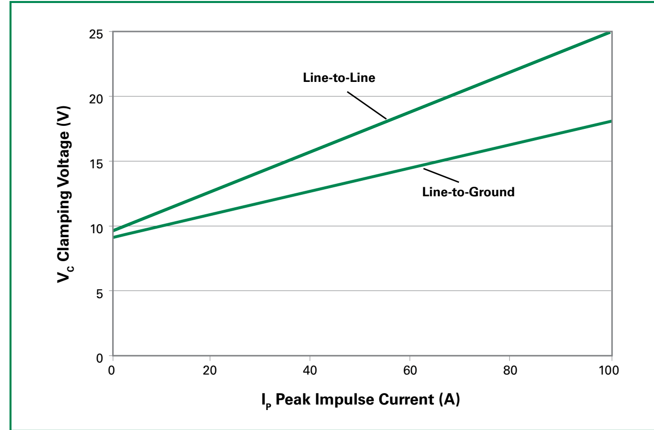
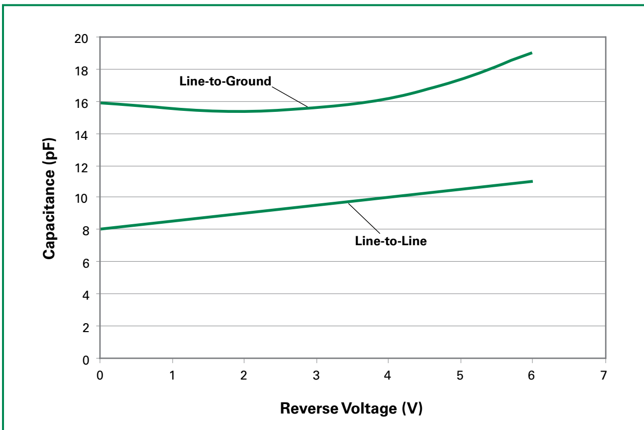
## Figure 3: Pulse Waveform



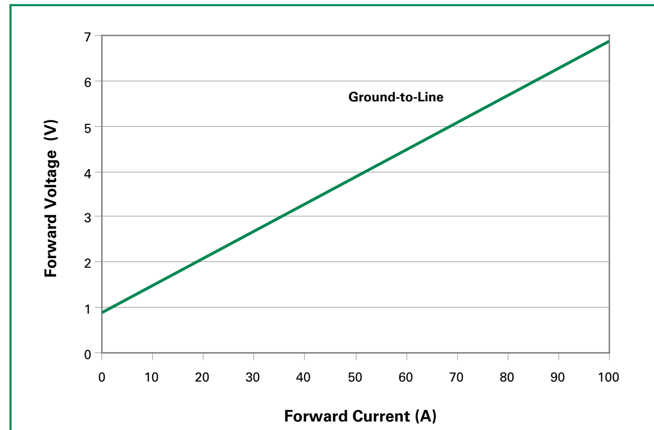

## Figure 4: Clamping Voltage vs. Peak Pulse Current




## Figure 5: Capacitance vs. Reverse Voltage

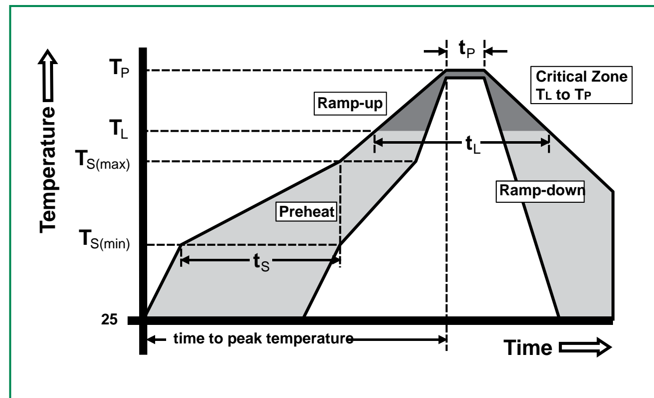



## Figure 6: Forward Voltage vs. Forward Current




## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |

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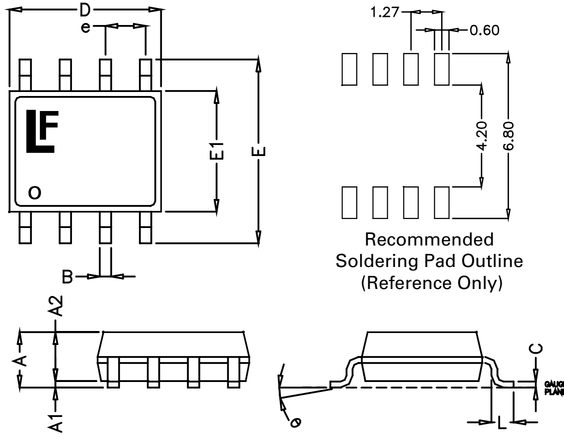
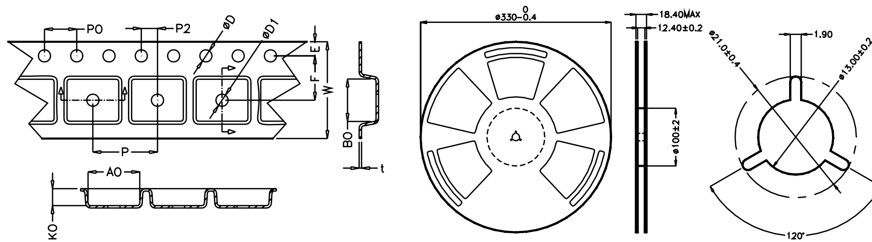
## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline



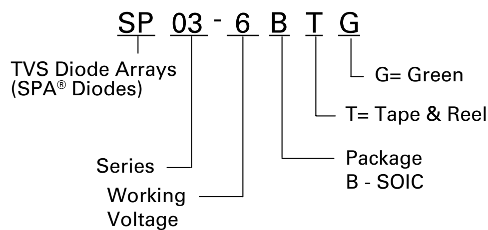

| Package | SOIC | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| **A** | 1.35 | 1.75 | 0.053 | 0.069 |
| **A1** | 0.10 | 0.25 | 0.004 | 0.010 |
| **A2** | 1.25 | 1.65 | 0.049 | 0.065 |
| **B** | 0.31 | 0.51 | 0.012 | 0.020 |
| **c** | 0.17 | 0.25 | 0.007 | 0.010 |
| **D** | 4.80 | 5.00 | 0.189 | 0.197 |
| **E** | 5.80 | 6.20 | 0.228 | 0.244 |
| **E1** | 3.80 | 4.00 | 0.150 | 0.157 |
| **e** | 1.27 BSC | | 0.050 BSC | |
| **L** | 0.40 | 1.27 | 0.016 | 0.050 |

## Embossed Carrier Tape & Reel Specification — SOIC Package

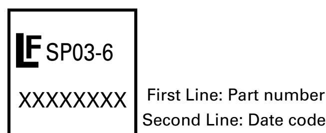



| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **E** | 1.65 | 1.85 | 0.065 | 0.073 |
| **F** | 5.4 | 5.6 | 0.213 | 0.22 |
| **P2** | 1.95 | 2.05 | 0.077 | 0.081 |
| **D** | 1.5 | 1.6 | 0.059 | 0.063 |
| **D1** | 1.50 Min | | 0.059 Min | |
| **P0** | 3.9 | 4.1 | 0.154 | 0.161 |
| **10P0** | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| **W** | 11.9 | 12.1 | 0.468 | 0.476 |
| **P** | 7.9 | 8.1 | 0.311 | 0.319 |
| **A0** | 6.3 | 6.5 | 0.248 | 0.256 |
| **B0** | 5.1 | 5.3 | 0.2 | 0.209 |
| **K0** | 2 | 2.2 | 0.079 | 0.087 |
| **t** | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

## Part Numbering System




## Part Marking System




First Line: Part number
Second Line: Date code

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SP03-6BTG | SOIC Tape & Reel | SP03-6 | 2500 |

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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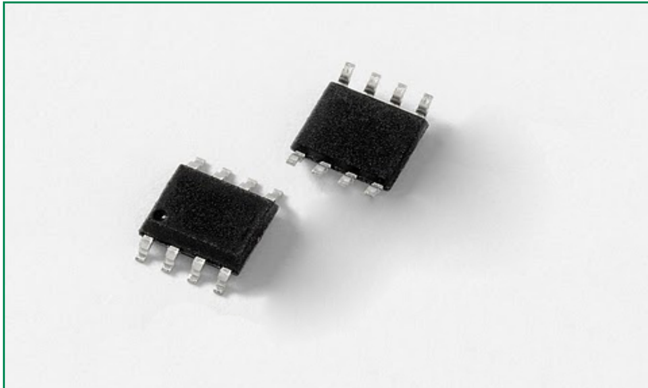
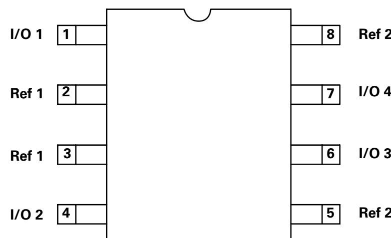
# SRDA05 Series 8pF 30A Diode Array



## Description

The SRDA05 integrates low capacitance rail-to-rail diodes with an additional zener diode to protect I/O pins against ESD and lightning induced surge events. This robust device can safely absorb up to 30A per IEC61000-4-5 (tp=8/20μs) without performance degradation and a minimum ±30kV ESD per IEC61000-4-2 international standard. Its low loading capacitance makes it ideal for high-speed interface protection.

## Pinout



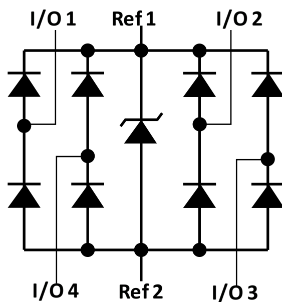

SOIC-8 (Top View)

Note: Pinout diagrams above shown as device footprint on circuit board.

## Features

- Lightning protection, IEC61000-4-5, 30A (8/20μs)
- EFT, IEC61000-4-4, 50A (5/50ns)
- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- Low clamping voltage
- Low leakage current
- SOIC-8 surface mount package (JEDEC MS-012)

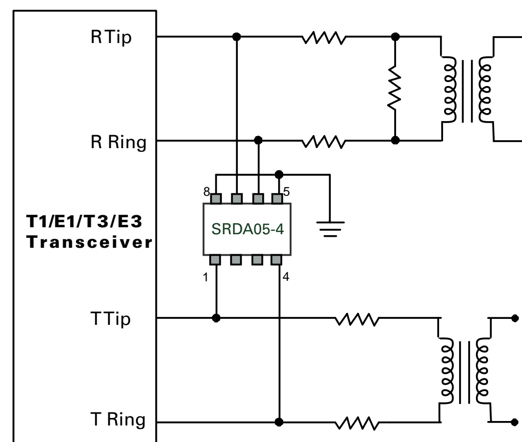
## Functional Block Diagram




## Applications

- Tertiary (IC Side) Protection:
  - T1/E1/T3/E3
  - HDSL/SDSL
  - Ethernet
- RS232, RS485
- Video Line Protection
- Security Cameras
- Storage DVRs
- Network Equipment
- Instrumentation, Medical Equipment

## Application Example




T1/E1/T3/E3 Interface Protection

## Additional Information

Datasheet

Resources

Samples

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $P_{pk}$ | Peak Pulse Power (8/20μs) | 600 | W |
| $I_{pp}$ | Peak Pulse Current (8/20μs) | 30 | A |
| $T_{op}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

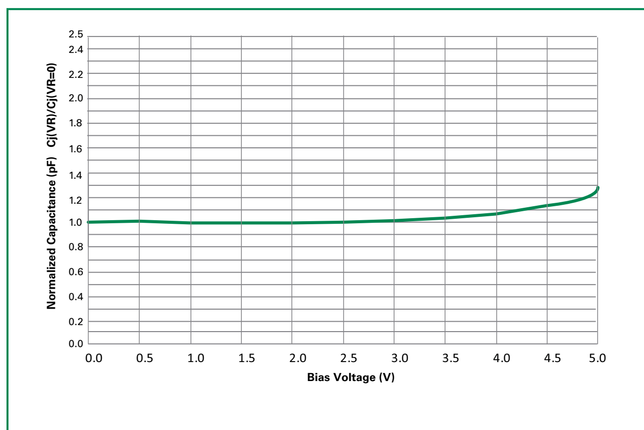
| Parameter | Rating | Units |
|---|---|---|
| SOIC Package | 170 | °C/W |
| Operating Temperature Range | –40 to 125 | °C |
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) (SOIC - Lead Tips Only) | 260 | °C |

## Electrical Characteristics ($T_{OP}$ = 25°C)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | $I_T$≤1μA | - | - | 5.0 | V |
| Reverse Leakage Current | $I_R$ | $V_R$= 5V | - | - | 10 | μA |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_t$ = 1mA | 6 | - | - | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 1A, $t_p$=8/20 μs | - | 9.2 | - | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 2A, $t_p$=8/20 μs | - | 10.0 | - | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 10A, $t_p$=8/20 μs | - | 14.5 | - | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 25A, $t_p$=8/20 μs | - | 21.0 | - | V |
| Dynamic Resistance, Line-Ground[1] | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.8 | - | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | - | - | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | - | 4.0 | - | pF |
| | $C_{I/O-GND}$ | Reverse Bias=0V | - | 8.0 | - | pF |

[1] Parameter is guaranteed by design and/or device characterization.

## Normalized Capacitance vs. Bias Voltage




## Non-Repetitive Peak Pulse Power vs. Pulse Time

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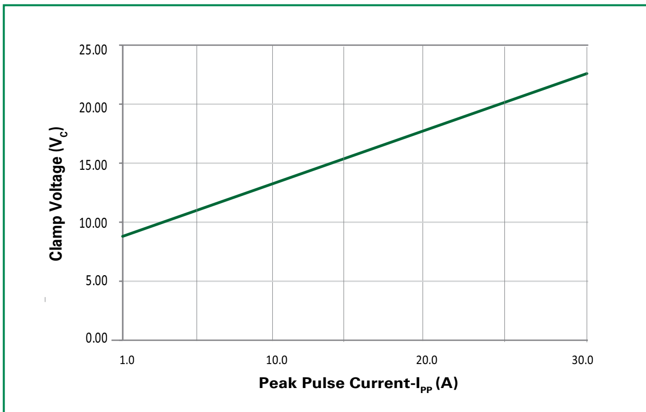
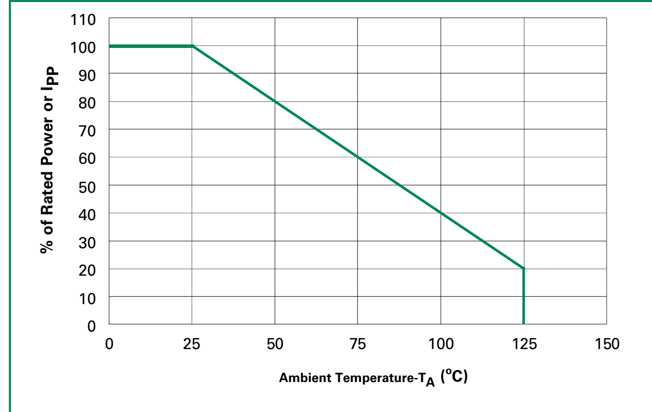
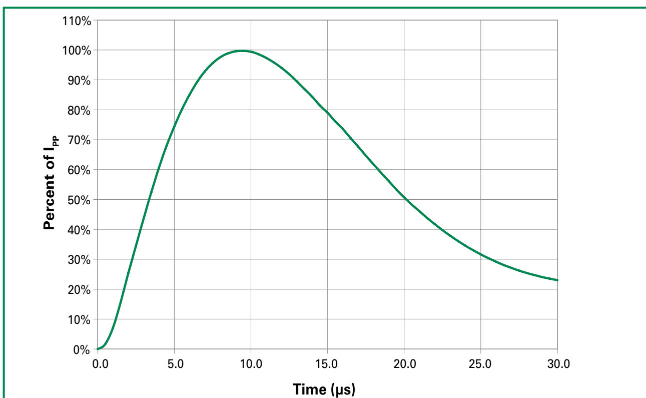
## Clamping Voltage vs. $I_{PP}$




## Power Derating Curve




## Pulse Waveform




## Product Characteristics

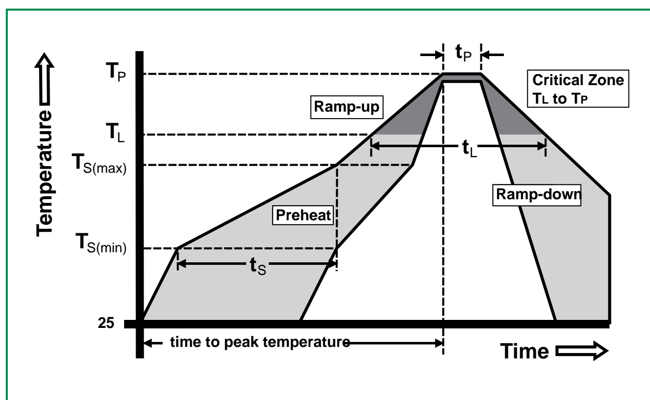
| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | - Temperature ($T_L$) (Liquidus) | 217°C |
| | - Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |




## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SRDA05-4BTG | SOIC-8 | LF SRDA05<br>SYYWW | 2500 |

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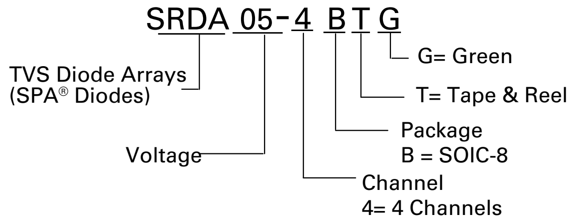
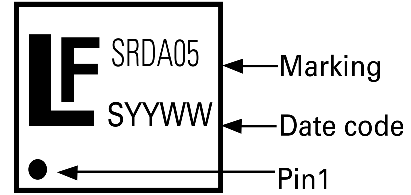
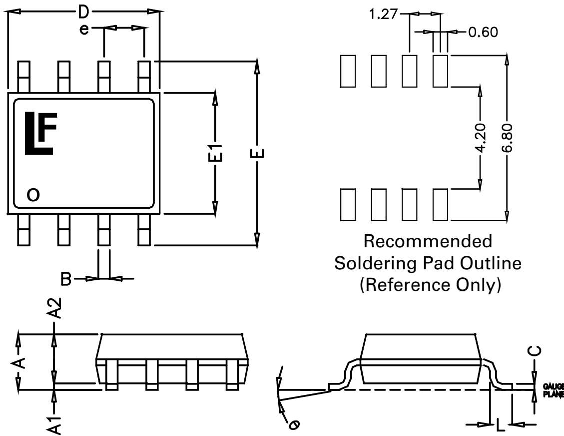
## Part Numbering System




## Part Marking System

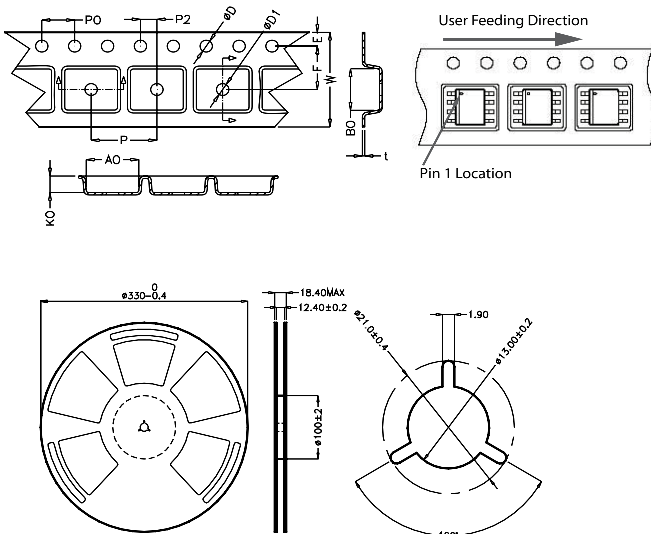



## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline




| Package | SOIC | | | |
|---|---|---|---|---|
| Pins | 8 | | | |
| JEDEC | MS-012 | | | |
| | Millimetres | | Inches | |
| | Min | Max | Min | Max |
| A | 1.35 | 1.75 | 0.053 | 0.069 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| A2 | 1.25 | 1.65 | 0.050 | 0.065 |
| B | 0.31 | 0.51 | 0.012 | 0.020 |
| c | 0.17 | 0.25 | 0.007 | 0.010 |
| D | 4.70 | 5.10 | 0.185 | 0.201 |
| E | 5.80 | 6.20 | 0.228 | 0.244 |
| E1 | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| L | 0.40 | 1.27 | 0.016 | 0.050 |

## Embossed Carrier Tape & Reel Specification — SOIC Package




| | Millimetres | | Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 5.4 | 5.6 | 0.213 | 0.22 |
| P2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 1.5 | 1.6 | 0.059 | 0.063 |
| D1 | 1.50 Min | | 0.059 Min | |
| P0 | 3.9 | 4.1 | 0.154 | 0.161 |
| 10P0 | 40.0 ± 0.20 | | 1.574 ± 0.008 | |
| W | 11.9 | 12.1 | 0.468 | 0.476 |
| P | 7.9 | 8.1 | 0.311 | 0.319 |
| A0 | 6.3 | 6.5 | 0.248 | 0.256 |
| B0 | 5.1 | 5.3 | 0.2 | 0.209 |
| K0 | 2 | 2.2 | 0.079 | 0.087 |
| t | 0.30 ± 0.05 | | 0.012 ± 0.002 | |

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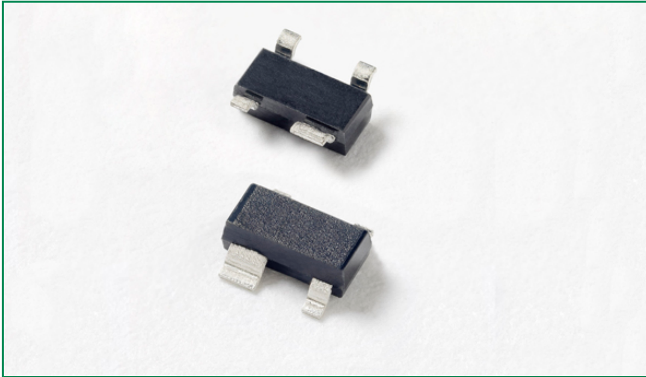
# SR05 Series 5V 25A Diode Array

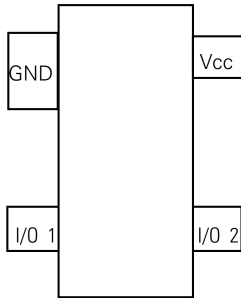


## Description

The SR05 consists of four, low capacitance steering diodes and a low voltage TVS diode that provide protection against ESD and lightning surge events. Each channel or I/O pin can safely absorb up to 25A (tp=8/20μs) and repetitive ESD strikes above the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation.

The low loading capacitance makes it ideal for protecting high-speed telecommunication data lines.

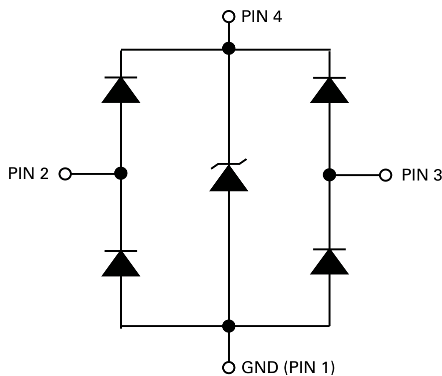
## Pinout




## Features

- ESD, IEC61000-4-2 , ±30kV contact discharge, ±30kV air discharge
- EFT, IEC61000-4-4, 80A ($t_p$=5/50ns)
- Lightning protection, IEC61000-4-5, 25A ($t_p$=8/20μs)
- Low capacitance of 6.0pF (TYP) per I/O
- Low clamp voltage
- Small SOT143 (JEDEC TO-253) packaging

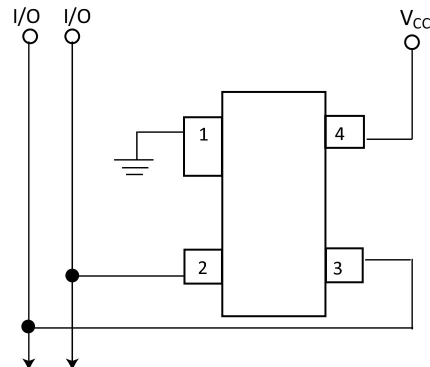
## Functional Block Diagram




## Applications

- T1/E1 IC/Secondary Protection
- Ethernet 10BaseT
- WAN/LAN Equipment
- ISDN S/T Interface
- Video Lines
- Microcontroller Input Protection

## Application Example




The SR05 integrates a TVS Diode between the Vcc and Gnd pins. This allows the array to protect the power supply against ESD and lighting surges when these pins are both connected in the application.

## Additional Information

Datasheet

Resources

Samples

Life Support Note:
**Not Intended for Use in Life Support or Life Saving Applications**
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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## Absolute Maximum Ratings

| Symbol | Parameter | Value | Units |
|---|---|---|---|
| $I_{PP}$ | Peak Current ($t_p$=8/20μs) | 25.0 | A |
| $P_{Pk}$ | Peak Pulse Power ($t_p$=8/20μs) | 450 | W |
| $T_{OP}$ | Operating Temperature | –40 to 125 | °C |
| $T_{STOR}$ | Storage Temperature | –55 to 150 | °C |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Thermal Information

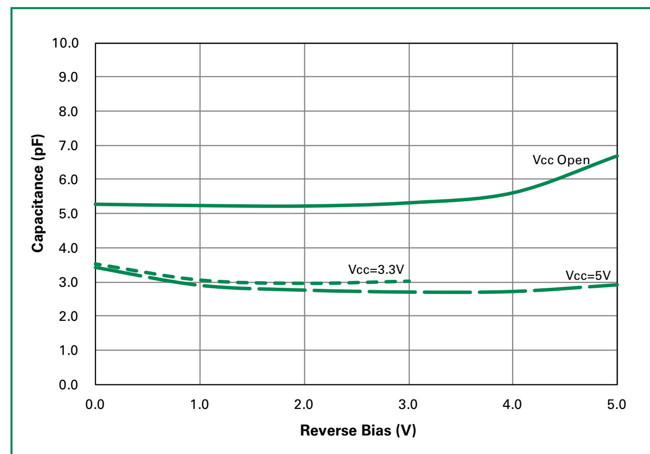
| Parameter | Rating | Units |
|---|---|---|
| Storage Temperature Range | –55 to 150 | °C |
| Maximum Junction Temperature | 150 | °C |
| Maximum Lead Temperature (Soldering 20-40s) | 260 | °C |

## Electrical Characteristics ($T_{OP}$=25°C)

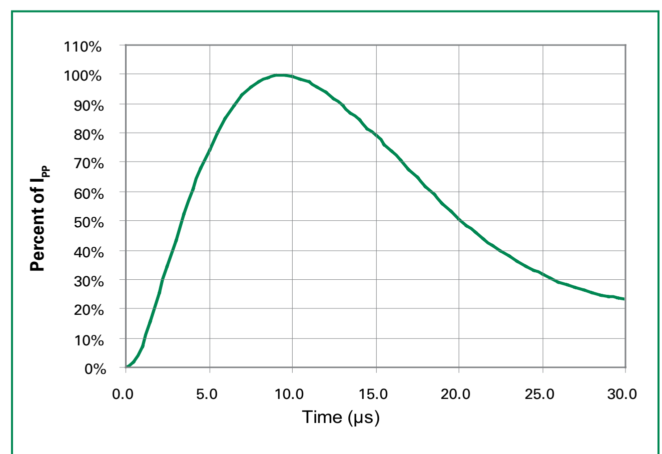
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | | - | - | 5.0 | V |
| Reverse Leakage Current | $I_R$ | $V_R$= 5V, I/O to GND | - | - | 5.0 | μA |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_t$ = 1mA | 6.0 | - | - | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 1A, $t_p$=8/20 μs | - | - | 9.8 | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 10A, $t_p$=8/20 μs | - | - | 12.0 | V |
| Clamping Voltage, Line-Ground[1] | $V_C$ | $I_{PP}$= 25A, $t_p$=8/20 μs | - | - | 18.0 | V |
| Dynamic Resistance, Line-Ground[1] | $R_{DYN}$ | $(V_{C2}-V_{C1})/(I_{PP2}-I_{PP1})$ | - | 0.3 | - | Ω |
| ESD Withstand Voltage[1] | $V_{ESD}$ | IEC61000-4-2 (Contact Discharge) | ±30 | - | - | kV |
| | | IEC61000-4-2 (Air Discharge) | ±30 | | | kV |
| Diode Capacitance[1] | $C_{I/O-I/O}$ | Reverse Bias=0V | - | 3.0 | - | pF |
| | $C_{I/O-GND}$ | Reverse Bias=0V | - | 6.0 | 10.0 | pF |

Note: 1. Parameter is guaranteed by design and/or device characterization.

## Capacitance vs. Reverse Bias




## Pulse Waveform

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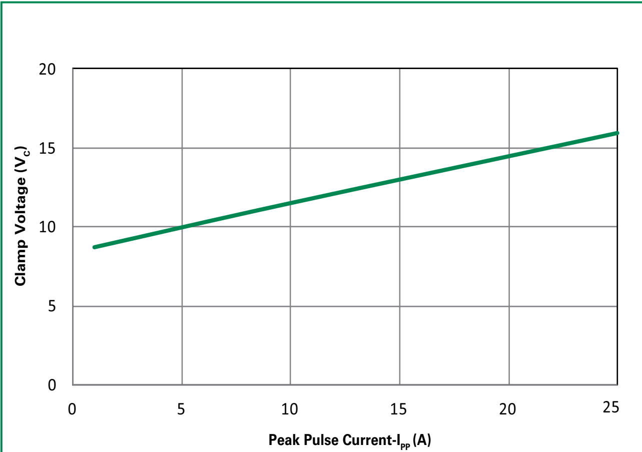
Revised: 12/20/13

## Clamping Voltage vs. $I_{PP}$



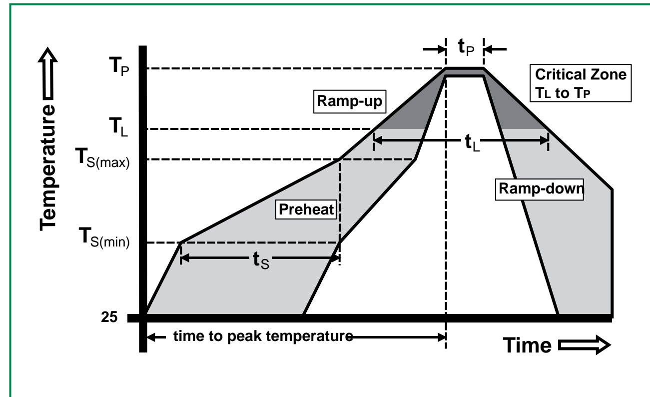

## Product Characteristics

| | |
|---|---|
| **Lead Plating** | Matte Tin |
| **Lead Material** | Copper Alloy |
| **Lead Coplanarity** | 0.0004 inches (0.102mm) |
| **Substitute Material** | Silicon |
| **Body Material** | Molded Epoxy |
| **Flammability** | UL 94 V-0 |

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

## Soldering Parameters

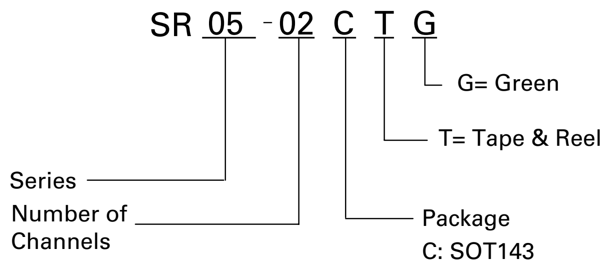
| Reflow Condition | | Pb – Free assembly |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | 150°C |
| | -Temperature Max ($T_{s(max)}$) | 200°C |
| | -Time (min to max) ($t_s$) | 60 – 180 secs |
| Average ramp up rate (Liquidus) Temp ($T_L$) to peak | | 3°C/second max |
| $T_{S(max)}$ to $T_L$ - Ramp-up Rate | | 3°C/second max |
| Reflow | -Temperature ($T_L$) (Liquidus) | 217°C |
| | -Temperature ($t_L$) | 60 – 150 seconds |
| Peak Temperature ($T_P$) | | $260^{+0/-5}$ °C |
| Time within 5°C of actual peak Temperature ($t_p$) | | 20 – 40 seconds |
| Ramp-down Rate | | 6°C/second max |
| Time 25°C to peak Temperature ($T_P$) | | 8 minutes Max. |
| Do not exceed | | 260°C |



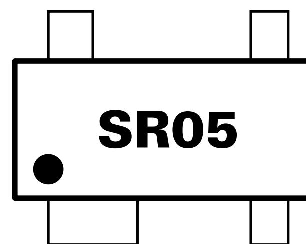

## Ordering Information

| Part Number | Package | Marking | Min. Order Qty. |
|---|---|---|---|
| SR05-02CTG | SOT143 | SR05 | 3000 |

## Part Numbering System




## Part Marking System

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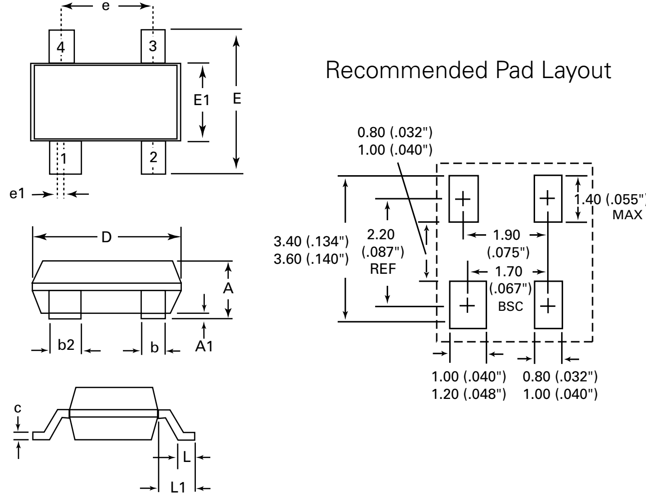
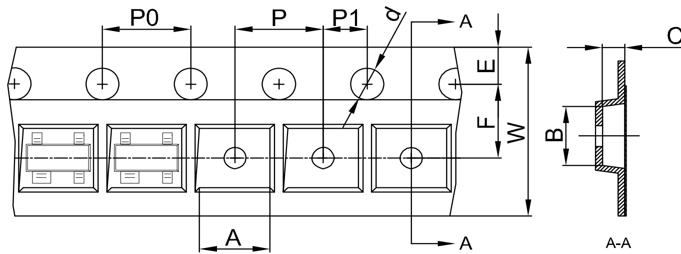
## Package Dimensions—SOT143

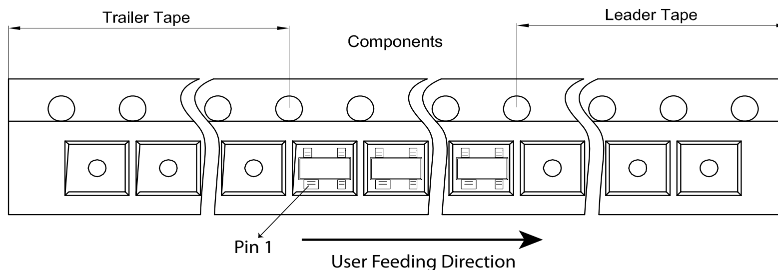



| Package | SOT143 | | | |
|---|---|---|---|---|
| Pins | 4 | | | |
| JEDEC | TO-253 | | | |
| | Millimeters | | Inches | |
| | Min | Max | Min | Max |
| **A** | 0.8 | 1.22 | 0.03 | 0.048 |
| **A1** | 0.05 | 0.15 | 0.002 | 0.006 |
| **b** | 0.30 | 0.50 | 0.012 | 0.020 |
| **b2** | 0.76 | 0.89 | 0.030 | 0.035 |
| **c** | 0.08 | 0.20 | 0.003 | 0.008 |
| **D** | 2.80 | 3.04 | 0.110 | 0.120 |
| **E** | 2.10 | 2.64 | 0.082 | 0.104 |
| **E1** | 1.20 | 1.40 | 0.047 | 0.055 |
| **e** | 1.92 BSC | | 0.076 BSC | |
| **e1** | 0.20 BSC | | 0.008 BSC | |
| **L** | 0.4 | 0.6 | 0.016 | 0.024 |
| **L1** | 0.550 REF | | 0.022 REF | |

## Embossed Carrier Tape & Reel Specification—SOT143




| Symbol | Millimeters |
|---|---|
| **A** | 3.19±0.10 |
| **B** | 2.8±0.10 |
| **C** | 1.31±0.10 |
| **d** | ⌀ 1.50±0.10 |
| **E** | 1.75±0.10 |
| **F** | 3.50±0.10 |
| **P0** | 4.00±0.10 |
| **P** | 4.00±0.10 |
| **P1** | 2.00±0.10 |
| **W** | 8.00±0.10 |




Notes :
1. All dimensions are in millimeters

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